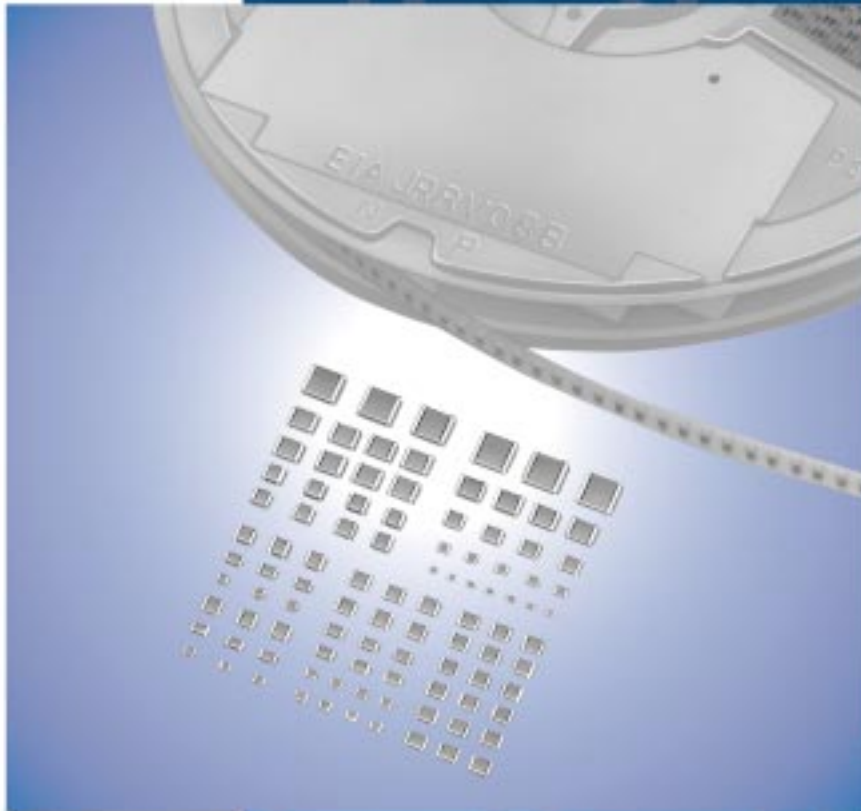


Chip Monolithic Ceramic Capacitors



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for EU RoHS Compliant

- All the products in this catalog comply with EU RoHS.
- EU RoHS is "the European Directive 2002/95/EC on the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment".
- For more details, please refer to our website 'Murata's Approach for EU RoHS' (<http://www.murata.com/info/rohs.html>).

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Please check the MURATA home page (<http://www.murata.com/>) if you cannot find the part number in the catalog.

● Part Numbering

Chip Monolithic Ceramic Capacitors

(Part Number)

GR	M	18	8	B1	1H	102	K	A01	D
①	②	③	④	⑤	⑥	⑦	⑧	⑨	⑩

① Product ID

② Series

Product ID	Code	Series
GR	J	Soft Termination Type
	M	Tin Plated Layer
	4	Only for Information Devices / Tip & Ring
	7	Only for Camera Flash Circuit
GQ	M	High Frequency for Flow/Reflow Soldering
GM	A	Monolithic Microchip
	D	For Bonding
GN	M	Capacitor Array
LL	L	Low ESL Type
	R	Controlled ESR Low ESL Type
	A	8-termination Low ESL Type
	M	10-termination Low ESL Type
GJ	M	High Frequency Low Loss Type
GA	2	For AC250V (r.m.s.)
	3	Safety Standard Certified Type

③ Dimensions (L×W)


Code	Dimensions (L×W)	EIA
02	0.4×0.2mm	01005
03	0.6×0.3mm	0201
05	0.5×0.5mm	0202
08	0.8×0.8mm	0303
0D	0.38×0.38mm	015015
0M	0.9×0.6mm	0302
15	1.0×0.5mm	0402
18	1.6×0.8mm	0603
1M	1.37×1.0mm	0504
21	2.0×1.25mm	0805
22	2.8×2.8mm	1111
31	3.2×1.6mm	1206
32	3.2×2.5mm	1210
42	4.5×2.0mm	1808
43	4.5×3.2mm	1812
52	5.7×2.8mm	2211
55	5.7×5.0mm	2220

④ Dimension (T) (Except GNM)

Code	Dimension (T)
2	0.2mm
3	0.3mm
5	0.5mm
6	0.6mm
7	0.7mm
8	0.8mm
9	0.85mm
A	1.0mm
B	1.25mm
C	1.6mm
D	2.0mm
E	2.5mm
F	3.2mm
M	1.15mm
N	1.35mm
Q	1.5mm
R	1.8mm
S	2.8mm
X	Depends on individual standards.

④ Elements (GNM Only)

Code	Elements
2	2-elements
4	4-elements

Continued on the following page. 

Please check the MURATA home page (<http://www.murata.com/>) if you cannot find the part number in the catalog.

Continued from the preceding page.

5 Temperature Characteristics

Temperature Characteristic Codes			Temperature Characteristics			Operating Temperature Range
Code	Public STD Code		Reference Temperature	Temperature Range	Capacitance Change or Temperature Coefficient	
1X	SL *1	JIS	20°C	20 to 85°C	+350 to -1000ppm/°C	-55 to 125°C
2C	CH *1	JIS	20°C	20 to 125°C	0±60ppm/°C	-55 to 125°C
2P	PH *1	JIS	20°C	20 to 85°C	-150±60ppm/°C	-25 to 85°C
2R	RH *1	JIS	20°C	20 to 85°C	-220±60ppm/°C	-25 to 85°C
2S	SH *1	JIS	20°C	20 to 85°C	-330±60ppm/°C	-25 to 85°C
2T	TH *1	JIS	20°C	20 to 85°C	-470±60ppm/°C	-25 to 85°C
3C	CJ *1	JIS	20°C	20 to 125°C	0±120ppm/°C	-55 to 125°C
3P	PJ *1	JIS	20°C	20 to 85°C	-150±120ppm/°C	-25 to 85°C
3R	RJ *1	JIS	20°C	20 to 85°C	-220±120ppm/°C	-25 to 85°C
3S	SJ *1	JIS	20°C	20 to 85°C	-330±120ppm/°C	-25 to 85°C
3T	TJ *1	JIS	20°C	20 to 85°C	-470±120ppm/°C	-25 to 85°C
3U	UJ *1	JIS	20°C	20 to 85°C	-750±120ppm/°C	-25 to 85°C
4C	CK *1	JIS	20°C	20 to 125°C	0±250ppm/°C	-55 to 125°C
5C	COG *1	EIA	25°C	25 to 125°C	0±30ppm/°C	-55 to 125°C
5G	X8G *1	EIA	25°C	25 to 150°C	0±30ppm/°C	-55 to 150°C
6C	COH *1	EIA	25°C	25 to 125°C	0±60ppm/°C	-55 to 125°C
6P	P2H *1	EIA	25°C	25 to 85°C	-150±60ppm/°C	-55 to 125°C
6R	R2H *1	EIA	25°C	25 to 85°C	-220±60ppm/°C	-55 to 125°C
6S	S2H *1	EIA	25°C	25 to 85°C	-330±60ppm/°C	-55 to 125°C
6T	T2H *1	EIA	25°C	25 to 85°C	-470±60ppm/°C	-55 to 125°C
7U	U2J *1	EIA	25°C	25 to 125°C *6	-750±120ppm/°C	-55 to 125°C
B1	B *2	JIS	20°C	-25 to 85°C	±10%	-25 to 85°C
B3	B	JIS	20°C	-25 to 85°C	±10%	-25 to 85°C
C7	X7S	EIA	25°C	-55 to 125°C	±22%	-55 to 125°C
C8	X6S	EIA	25°C	-55 to 105°C	±22%	-55 to 105°C
D7	X7T	EIA	25°C	-55 to 125°C	+22, -33%	-55 to 125°C
D8	X6T	EIA	25°C	-55 to 105°C	+22, -33%	-55 to 105°C
E7	X7U	EIA	25°C	-55 to 125°C	+22, -56%	-55 to 125°C
F1	F *2	JIS	20°C	-25 to 85°C	+30, -80%	-25 to 85°C
F5	Y5V	EIA	25°C	-30 to 85°C	+22, -82%	-30 to 85°C
L8	X8L	*3	25°C	-55 to 150°C	+15, -40%	-55 to 150°C
R1	R *2	JIS	20°C	-55 to 125°C	±15%	-55 to 125°C
R3	R	JIS	20°C	-55 to 125°C	±15%	-55 to 125°C
R6	X5R	EIA	25°C	-55 to 85°C	±15%	-55 to 85°C
R7	X7R	EIA	25°C	-55 to 125°C	±15%	-55 to 125°C
R9	X8R	EIA	25°C	-55 to 150°C	±15%	-55 to 150°C
W0	-	-	25°C	-55 to 125°C	±10% *4	-55 to 125°C
					+22, -33% *5	

*1 Please refer to table for Capacitance Change under reference temperature.


*2 Capacitance change is specified with 50% rated voltage applied.

*3 Murata Temperature Characteristic Code.

*4 Apply DC350V bias.

*5 No DC bias.

*6 Rated Voltage 100Vdc max : 25 to 85°C

Continued on the following page. 

Continued from the preceding page.

●Capacitance Change from each temperature

JIS Code

Murata Code	Capacitance Change from 20°C (%)					
	-55°C		-25°C		-10°C	
	Max.	Min.	Max.	Min.	Max.	Min.
1X	-	-	-	-	-	-
2C	0.82	-0.45	0.49	-0.27	0.33	-0.18
2P	-	-	1.32	0.41	0.88	0.27
2R	-	-	1.70	0.72	1.13	0.48
2S	-	-	2.30	1.22	1.54	0.81
2T	-	-	3.07	1.85	2.05	1.23
3C	1.37	-0.90	0.82	-0.54	0.55	-0.36
3P	-	-	1.65	0.14	1.10	0.09
3R	-	-	2.03	0.45	1.35	0.30
3S	-	-	2.63	0.95	1.76	0.63
3T	-	-	3.40	1.58	2.27	1.05
3U	-	-	4.94	2.84	3.29	1.89
4C	2.56	-1.88	1.54	-1.13	1.02	-0.75

EIA Code

Murata Code	Capacitance Change from 25°C (%)					
	-55°C		-30°C		-10°C	
	Max.	Min.	Max.	Min.	Max.	Min.
5C/5G	0.58	-0.24	0.40	-0.17	0.25	-0.11
6C	0.87	-0.48	0.59	-0.33	0.38	-0.21
6P	2.33	0.72	1.61	0.50	1.02	0.32
6R	3.02	1.28	2.08	0.88	1.32	0.56
6S	4.09	2.16	2.81	1.49	1.79	0.95
6T	5.46	3.28	3.75	2.26	2.39	1.44
7U	8.78	5.04	6.04	3.47	3.84	2.21


⑥ Rated Voltage

Code	Rated Voltage
0E	DC2.5V
0G	DC4V
0J	DC6.3V
1A	DC10V
1C	DC16V
1E	DC25V
YA	DC35V
1H	DC50V
2A	DC100V
2D	DC200V
2E	DC250V
YD	DC300V
2H	DC500V
2J	DC630V
3A	DC1kV
3D	DC2kV
3F	DC3.15kV
BB	DC350V (for Camera Flash Circuit)
E2	AC250V
GC	X1/Y2; AC250V (Safety Standard Certified Type GC)
GF	Y2, X1/Y2; AC250V (Safety Standard Certified Type GF)
GD	Y3; AC250V (Safety Standard Certified Type GD)
GB	X2; AC250V (Safety Standard Certified Type GB)

⑦ Capacitance

Expressed by three-digit alphanumerics. The unit is picofarad (pF). The first and second figures are significant digits, and the third figure expresses the number of zeros which follow the two numbers. If there is a decimal point, it is expressed by the capital letter "R." In this case, all figures are significant digits.

Ex.) Code	Capacitance
R50	0.5pF
1R0	1.0pF
100	10pF
103	10000pF

Continued on the following page. 

Please check the MURATA home page (<http://www.murata.com/>) if you cannot find the part number in the catalog.

Continued from the preceding page.

⑧ Capacitance Tolerance

Code	Capacitance Tolerance	TC	Series	Capacitance Step	
W	±0.05pF	CΔ	GRM/GJM	≤9.9pF	0.1pF
B	±0.1pF	CΔ	GRM/GJM	≤9.9pF	0.1pF
			GQM	≤1pF	0.1pF
C	±0.25pF	CΔ	GRM/GJM	≤9.9pF	0.1pF
		except CΔ	GRM	≤5pF	* 1pF
		CΔ	GQM	≤1pF	0.1pF
D	±0.5pF	CΔ	GRM/GJM	5.1 to 9.9pF	0.1pF
		except CΔ	GRM	5.1 to 9.9pF	* 1pF
		CΔ	GQM	5.1 to 9.9pF	1pF Step and E24 Series
G	±2%	CΔ	GJM	≥10pF	E12 Series
		CΔ	GQM	≥10pF	E24 Series
J	±5%	CΔ, SL, U2J	GRM/GA3	≥10pF	E12 Series
		CΔ	GQM/GJM	≥10pF	E24 Series
K	±10%	B, R, X7R, X5R, ZLM	GRJ/GRM/GR7/GA3	E6 Series	
		C0G	GNM	E6 Series	
		B, R, X7R, X5R, ZLM	GR4, GMD	E12 Series	
M	±20%	B, R, X7R, X7S	GRM/GMA	E6 Series	
		X5R, X7R, X7S	GNM	E3 Series	
		X7R	GA2	E3 Series	
		X5R, X7R, X7S, X6S	LLL/LLR/LLA/LLM	E3 Series	
Z	+80%, -20%	F, Y5V	GRM	E3 Series	
R	Depends on individual standards.				

* E24 series is also available.

⑨ Individual Specification Code (Except LLR)

Expressed by three figures.

⑨ ESR (LLR Only)

Code	ESR
E01	100mΩ
E03	220mΩ
E05	470mΩ
E07	1000mΩ

⑩ Packaging

Code	Packaging
L	ø180mm Embossed Taping
D	ø180mm Paper Taping
E	ø180mm Paper Taping (LLL15)
K	ø330mm Embossed Taping
J	ø330mm Paper Taping
F	ø330mm Paper Taping (LLL15)
B	Bulk
C	Bulk Case
T	Bulk Tray

Please check the MURATA home page (<http://www.murata.com/>) if you cannot find the part number in the catalog.

Selection Guide For Chip Monolithic Ceramic Capacitors

Function	Type	Series
Decoupling, Smoothing	High Capacitance	GRM (X5R, X7R, Y5V etc.) 68pF-100μF
	Array (2 or 4 Elements)	GNM 10pF-2.2μF
Frequency Control/Tuning, Impedance Matching	Class 1 TC's	GRM (C0G) 0.1pF-0.1μF
		GRM (U2J etc.)
High Speed Decoupling	Low Inductance (Reverse Geometry)	LLL 2200pF-10μF
	Low Inductance (Controlled ESR)	LLR 1.0μF
	Low Inductance (Multi-Termination)	LLA/LLM (From 1GHz) 0.01μF-4.7μF
High Frequency	Low ESR, Ultra Small	GJM (500MHz to 10GHz) 0.1pF-33pF
	Lowest ESR	GQM (500MHz to 10GHz) 0.1pF-100pF
Optical Communications	Wire-Die-Bonding	GMA 100pF-0.47μF GMD 100pF-1μF
Medium Voltage High Frequency Snubber	250V/630V/1kV/2kV/3.15kV Low Dissipation	GRM (C0G, U2J) 10pF-10000pF
Medium Voltage LCD Backlight Inverter	3.15kV Low Dissipation	GRM (C0G) 5pF-47pF
Medium Voltage Decoupling, Smoothing	250V/630V/1kV High Capacitance	GRM (X7R) 220pF-1μF
	250V/630V/1kV Soft Termination Type	GRJ (X7R) 470pF-1μF
Medium Voltage Only for Camera Flash Circuit	350V High Capacitance	GR7 10000pF-47000pF
Medium Voltage Only for Information Devices	2kV High Capacitance	GR4 100pF-10000pF
	Safety Standard Certified	Type GD 10pF-4700pF Type GF 10pF-4700pF
AC Lines Noise Removal	Safety Standard Certified	Type GC 100pF-330pF Type GF 470pF-4700pF Type GB 10000pF-56000pF
	AC250V which meets Japanese Law	GA2 470pF-0.1μF
Automotive (Powertrain, Safety Equipment)	High Capacitance	GCM (X7R etc.) 100pF-47μF
	Class 1 TC's	GCM (C0G etc.) 1.0pF-56000pF
Medium Voltage for Automotive (Powertrain, Safety Equipment)	250V/630V Low Dissipation	GCM (U2J) 10pF-10000pF
	250V/630V Soft Termination Type	GCJ (X7R) 1000pF-0.47μF

Applications?

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For General
GRM Series

Array
GNM Series

Low ESL
LLL Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



For General Purpose GRM Series

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

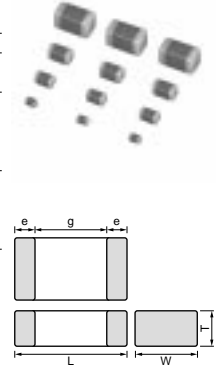
■ Features

1. Higher resistance of solder-leaching due to the Ni-barriered termination, applicable for reflow-soldering, and flow-soldering (GRM18/21/31 type only).
2. The GRM series is a lead free product.
3. Smaller size and higher capacitance value.
4. High reliability and no polarity.
5. Excellent pulse response and noise reduction due to the low impedance at high frequency.
6. The GRM series is available in paper or embossed tape and reel packaging for automatic placement. Bulk case packaging is also available for GRM15/18/21(T=0.6,1.25).
7. TA replacement.

■ Applications

General electronic equipment

Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRM022	0.4 ±0.02	0.2 ±0.02	0.2 ±0.02	0.07 to 0.14	0.13
GRM033	0.6 ±0.03	0.3 ±0.03	0.3 ±0.03	0.1 to 0.2	0.2
GRM15X	1.0 ±0.05	0.5 ±0.05	0.25 ±0.05	0.1 to 0.3	0.4
GRM153			0.3 ±0.03		
GRM155	1.6 ±0.1	0.8 ±0.1	0.5 ±0.05	0.15 to 0.35	0.3
GRM185			0.8 ±0.1		
GRM188*	2.0 ±0.1	1.25 ±0.1	0.6 ±0.1	0.2 to 0.7	0.7
GRM216			0.85 ±0.1		
GRM219	3.2 ±0.15	1.6 ±0.15	1.0 ±0/-0.2	0.3 to 0.8	1.5
GRM21A			1.25 ±0.1		
GRM21B	3.2 ±0.2	1.6 ±0.2	0.6 ±0.1	0.3 min.	1.0
GRM316			0.85 ±0.1		
GRM319	3.2 ±0.3	2.5 ±0.2	1.15 ±0.1	0.3 min.	1.0
GRM31M			1.6 ±0.2		
GRM31C	3.2 ±0.3	2.5 ±0.2	0.85 ±0.15/-0.05	0.3 min.	1.0
GRM329			1.0 ±0/-0.2		
GRM32A	3.2 ±0.3	2.5 ±0.2	1.15 ±0.1	0.3 min.	1.0
GRM32M			1.35 ±0.15		
GRM32N	3.2 ±0.3	2.5 ±0.2	1.6 ±0.2	0.3 min.	1.0
GRM32C			1.8 ±0.2		
GRM32R	3.2 ±0.3	2.5 ±0.2	2.0 ±0.2	0.3 min.	1.0
GRM32D			2.5 ±0.2		
GRM32E	3.2 ±0.3	2.5 ±0.2	2.5 ±0.2	0.3 min.	1.0
GRM32Z			2.5 ±0.2		



* Bulk Case: 1.6 ±0.07(L) × 0.8 ±0.07(W) × 0.8 ±0.07(T)
The figures indicate typical specification.

Capacitance Table

Temperature Compensating Type C0G(5C),U2J(7U) Characteristics

6		ex.6: T Dimension [mm]																							
Capacitance	TC	LxW [mm]	C0G(5C)										U2J(7U)												
			0.4x0.2 (02) <01005>			0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>		0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>	
			16 (1C)	10 (1A)	6.3 (0J)	50 (1H)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	50 (1H)	25 (1E)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	
0.1pF(R10)				3	3, 5																				
0.2pF(R20)	2			3	3, 5																				
0.3pF(R30)	2			3	3, 5																				
0.4pF(R40)	2			3	3, 5																				
0.5pF(R50)	2			3	3, 5																				
0.6pF(R60)	2			3	3, 5																				
0.7pF(R70)	2			3	3, 5																				
0.8pF(R80)	2			3	3, 5																				
0.9pF(R90)	2			3	3, 5																				
1.0pF(1R0)	2			3	3, 5								3		5										
1.1pF(1R1)	2			3	3, 5																				
1.2pF(1R2)	2			3	3, 5																				
1.3pF(1R3)	2			3	3, 5																				
1.4pF(1R4)	2			3	3, 5																				
1.5pF(1R5)	2			3	3, 5																				
1.6pF(1R6)	2			3	3, 5																				
1.7pF(1R7)	2			3	3, 5																				
1.8pF(1R8)	2			3	3, 5																				
1.9pF(1R9)	2			3	3, 5																				
2.0pF(2R0)	2			3	3, 5								3		5										
2.1pF(2R1)	2			3	3, 5																				
2.2pF(2R2)	2			3	3, 5																				
2.3pF(2R3)	2			3	3, 5																				
2.4pF(2R4)	2			3	3, 5																				
2.5pF(2R5)	2			3	3, 5																				
2.6pF(2R6)	2			3	3, 5																				
2.7pF(2R7)	2			3	3, 5																				
2.8pF(2R8)	2			3	3, 5																				
2.9pF(2R9)	2			3	3, 5																				
3.0pF(3R0)	2			3	3, 5								3		5										
3.1pF(3R1)	2			3	3, 5																				
3.2pF(3R2)	2			3	3, 5																				
3.3pF(3R3)	2			3	3, 5																				
3.4pF(3R4)	2			3	3, 5																				
3.5pF(3R5)	2			3	3, 5																				
3.6pF(3R6)	2			3	3, 5																				
3.7pF(3R7)	2			3	3, 5																				
3.8pF(3R8)	2			3	3, 5																				
3.9pF(3R9)	2			3	3, 5																				
4.0pF(4R0)	2			3	3, 5								3		5										
4.1pF(4R1)	2			3	3, 5																				
4.2pF(4R2)	2			3	3, 5																				
4.3pF(4R3)	2			3	3, 5																				
4.4pF(4R4)	2			3	3, 5																				
4.5pF(4R5)	2			3	3, 5																				
4.6pF(4R6)	2			3	3, 5																				
4.7pF(4R7)	2			3	3, 5																				
4.8pF(4R8)	2			3	3, 5																				
4.9pF(4R9)	2			3	3, 5																				

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Continued on the following page.

Capacitance Table

Continued from the preceding page.

6 ex.6: T Dimension [mm]

TC	LxW [mm]	C0G(5C)										U2J(7U)									
		0.4x0.2 (02) <01005>			0.6x0.3 (03) (15) <0201> <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>		0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>
Rated Voltage [Vdc]		16 (1C)	10 (1A)	6.3 (0J)	50 (1H)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	50 (1H)	25 (1E)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)
Capacitance																					
5.0pF(5R0)	2				3	3, 5								3		5					
5.1pF(5R1)	2				3	3, 5															
5.2pF(5R2)	2				3	3, 5															
5.3pF(5R3)	2				3	3, 5															
5.4pF(5R4)	2				3	3, 5															
5.5pF(5R5)	2				3	3, 5															
5.6pF(5R6)	2				3	3, 5															
5.7pF(5R7)	2				3	3, 5															
5.8pF(5R8)	2				3	3, 5															
5.9pF(5R9)	2				3	3, 5															
6.0pF(6R0)	2				3	3, 5								3		5					
6.1pF(6R1)	2				3	3, 5															
6.2pF(6R2)	2				3	3, 5															
6.3pF(6R3)	2				3	3, 5															
6.4pF(6R4)	2				3	3, 5															
6.5pF(6R5)	2				3	3, 5															
6.6pF(6R6)	2				3	3, 5															
6.7pF(6R7)	2				3	3, 5															
6.8pF(6R8)	2				3	3, 5															
6.9pF(6R9)	2				3	3, 5															
7.0pF(7R0)	2				3	3, 5								3		5					
7.1pF(7R1)	2				3	3, 5															
7.2pF(7R2)	2				3	3, 5															
7.3pF(7R3)	2				3	3, 5															
7.4pF(7R4)	2				3	3, 5															
7.5pF(7R5)	2				3	3, 5															
7.6pF(7R6)	2				3	3, 5															
7.7pF(7R7)	2				3	3, 5															
7.8pF(7R8)	2				3	3, 5															
7.9pF(7R9)	2				3	3, 5															
8.0pF(8R0)	2				3	3, 5								3		5					
8.1pF(8R1)	2				3	3, 5															
8.2pF(8R2)	2				3	3, 5															
8.3pF(8R3)	2				3	3, 5															
8.4pF(8R4)	2				3	3, 5															
8.5pF(8R5)	2				3	3, 5															
8.6pF(8R6)	2				3	3, 5															
8.7pF(8R7)	2				3	3, 5															
8.8pF(8R8)	2				3	3, 5															
8.9pF(8R9)	2				3	3, 5															
9.0pF(9R0)	2				3	3, 5								3		5					
9.1pF(9R1)	2				3	3, 5															
9.2pF(9R2)	2				3	3, 5															
9.3pF(9R3)	2				3	3, 5															
9.4pF(9R4)	2				3	3, 5															
9.5pF(9R5)	2				3	3, 5															
9.6pF(9R6)	2				3	3, 5															
9.7pF(9R7)	2				3	3, 5															
9.8pF(9R8)	2				3	3, 5															
9.9pF(9R9)	2				3	3, 5															

The part number code is shown in () and Unit is shown in []. <->: EIA [inch] Code

Continued on the following page. ↗

Capacitance Table

Continued from the preceding page.

6 ex.6: T Dimension [mm]

TC LxW [mm] Rated Voltage [Vdc] Capacitance	C0G(5C)										U2J(7U)												
	0.4x0.2 (02) <01005>			0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>		0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		1.6x0.8 (18) <0603>		2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>	
	16 (1C)	10 (1A)	6.3 (0J)	50 (1H)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	100 (1E)	50 (1H)	50 (1H)	25 (1E)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	10 (1A)	50 (1H)	
10pF(100)	2			3	3,5	8	8						3		5								
12pF(120)	2			3	3,5	8	8						3		5								
15pF(150)	2			3	3,5	8	8						3		5								
18pF(180)	2			3	3,5	8	8						3	5									
22pF(220)	2			3	3,5	8	8						3	5									
27pF(270)	2			3	3,5	8	8						3	5									
33pF(330)	2			3	3,5	8	8						3	5									
39pF(390)	2			3	3,5	8	8						3	5									
47pF(470)	2			3	3,5	8	8						3	5									
56pF(560)		2	2	3	3,5	8	8						3	5									
68pF(680)		2	2	3	3,5	8	8						3	5									
82pF(820)		2	2	3	3,5	8	8						3	5									
100pF(101)		2	2	3	3,5	8	8	6					3	5									
120pF(121)				3,5	8	8	6							5									
150pF(151)				3,5	8	8	6							5									
180pF(181)				3,5	8	8	6							5									
220pF(221)				3,5	8	8	6																
270pF(271)				3,5	8	8	6																
330pF(331)				3,5	8	8	6																
390pF(391)				3,5	8	8	6																
470pF(471)				3,5	8	8	6																
560pF(561)				3,5	8	8	6																
680pF(681)				3,5	8	8	6																
820pF(821)				5	8	8	6																
1000pF(102)				5	8	8	6										8						
1200pF(122)					8	8	6	6								5	8						
1500pF(152)					8	8	6	6								5	8						
1800pF(182)						8	6	6	9							5	8						
2200pF(222)						8	6	6	9							5	5,8						
2700pF(272)						8	6	6	9							5	5,8						
3300pF(332)						8	6	6	9							5	5,8						
3900pF(392)						8		6	9							5	5,8						
4700pF(472)								6	9	9						5	5,8						
5600pF(562)								9	9	9							8	5					
6800pF(682)								9	9	9							8	5					
8200pF(822)								9	9	9							8	5					
10000pF(103)								9	9	9							8	5	6				
12000pF(123)								9	9	9								8	6				
15000pF(153)								9	9	9								8	6				
18000pF(183)								B	9	9								8	6				
22000pF(223)								B	9	9								8	9				
27000pF(273)									9										9				
33000pF(333)									9										A				
39000pF(393)									9										B				
47000pF(473)									M										B				
56000pF(563)									M												9	9	
68000pF(683)									C												B	M	
82000pF(823)									C												B	M	
0.1μF(104)									C												B	M	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Capacitance Table

Temperature Compensating Type P2H(6P),R2H(6R),S2H(6S),T2H(6T) Characteristics

6		ex.6: T Dimension [mm]							
TC	LxW [mm]	P2H (6P)		R2H (6R)		S2H (6S)		T2H (6T)	
		1.0x0.5 (15)	0.6x0.3 (03)	1.0x0.5 (15)	0.6x0.3 (03)	1.0x0.5 (15)	0.6x0.3 (03)	1.0x0.5 (15)	0.6x0.3 (03)
Rated Voltage [Vdc]		50 (1H)	25 (1E)	50 (1H)	25 (1E)	50 (1H)	25 (1E)	50 (1H)	25 (1E)
Capacitance									
1.0pF(1R0)	5	3	5	3	5	3	5	3	5
2.0pF(2R0)	5	3	5	3	5	3	5	3	5
3.0pF(3R0)	5	3	5	3	5	3	5	3	5
4.0pF(4R0)	5	3	5	3	5	3	5	3	5
5.0pF(5R0)	5	3	5	3	5	3	5	3	5
6.0pF(6R0)	5	3	5	3	5	3	5	3	5
7.0pF(7R0)	5	3	5	3	5	3	5	3	5
8.0pF(8R0)	5	3	5	3	5	3	5	3	5
9.0pF(9R0)	5	3	5	3	5	3	5	3	5
10pF(100)	5	3	5	3	5	3	5	3	5
12pF(120)	5	3	5	3	5	3	5	3	5
15pF(150)	5	3	5	3	5	3	5	3	5
18pF(180)	5	3	5	3	5	3	5	3	5
22pF(220)	5	3	5	3	5	3	5	3	5
27pF(270)	5	3	5	3	5	3	5	3	5
33pF(330)		3	5	3	5	3	5	3	5
39pF(390)		3		3	5	3	5	3	5
47pF(470)		3		3		3	5	3	5
56pF(560)		3		3		3		3	5
68pF(680)		3		3		3		3	5
82pF(820)		3		3		3		3	5
100pF(101)			3		3			3	5

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information


Capacitance Table

Continued from the preceding page.

High Dielectric Constant Type X7R(R7)/X7S(C7)/X7T(D7)/X7U(E7) Characteristics

5		ex.5: T Dimension [mm]																			
Capacitance	LxW [mm]	0.4x0.2 (02) <01005>					0.6x0.3 (03) <0201>					1.0x0.5 (15) <0402>					1.6x0.8 (18) <0603>				
		10 (1A)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)			
68pF(680)		2																			
100pF(101)		2	3	3																	
150pF(151)		2	3	3																	
220pF(221)		2	3	3			5	X, 5				8	8								
330pF(331)		2	3	3			5	X, 5				8	8								
470pF(471)		2	3	3			5	X, 5				8	8								
680pF(681)			3	3			5	X, 5				8	8								
1000pF(102)			3	3			5	X, 5				8	8								
1500pF(152)			3	3			5	X, 5				8	8								
2200pF(222)				3	3		5	5	X			8	8	8							
3300pF(332)				3	3		5	5		X		8	8	8							
4700pF(472)					3	3	5	5	5	X		8	8	8							
6800pF(682)					3	3		5	5	X		8	8	8							
10000pF(103)					3	3		5	5	X		8	8	8							
15000pF(153)								5	5	5			8	8							
22000pF(223)								5	5	5			8	8							
33000pF(333)									5	5			8	8							
47000pF(473)									5	5			8	8							
68000pF(683)										5	5		8	8							
0.10μF(104)										5	5	8	8	8							
0.15μF(154)										5			8	8							
0.22μF(224)										5			8	8							
0.33μF(334)														8	8						
0.47μF(474)														8	8	8					
0.68μF(684)														8	8						
1.0μF(105)														8	8	5, 8					
2.2μF(225)																8	8	8			

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Continued on the following page. 

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Capacitance Table

Continued from the preceding page.

LxW [mm]	2.0x1.25 (21) <0805>							3.2x1.6 (31) <1206>							3.2x2.5 (32) <1210>											
	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	100 (2A)	50 (1H)	35 (YA)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)				
Rated Voltage [Vdc]																										
Capacitance																										
6800pF(682)	9																									
10000pF(103)	B																									
15000pF(153)	B																									
22000pF(223)	B																									
33000pF(333)	B	9																								
47000pF(473)	B	B																								
68000pF(683)		B	9																							
0.10μF(104)		B	B																							
0.15μF(154)		B	B																							
0.22μF(224)	A	B	B																							
0.33μF(334)	A	9	B																							
0.47μF(474)	B	B	9																							
0.68μF(684)			9	9																C						
1.0μF(105)		B	9, B	B														C								
2.2μF(225)			B	B	B												E									
4.7μF(475)				B	B												E									
10μF(106)					B	B									C	C	C				E	D				
22μF(226)						B								C	C					E	E	E				
47μF(476)							B									C					E	E				
100μF(107)																	C							E		

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

These Part Numbers have individual testing conditions on Durability of GRM Series Specifications and Test Methods (2). Please refer to P60.

High Dielectric Constant Type X6S(C8)/X6T(D8) Characteristics

LxW [mm]	0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>		
	6.3 (0J)	4 (0G)	25 (1E)	6.3 (0J)	4 (0G)
Rated Voltage [Vdc]					
Capacitance					
15000pF(153)	3	3			
22000pF(223)	3	3			
33000pF(333)	3	3			
47000pF(473)	3	3			
68000pF(683)			5		
0.10μF(104)			5		
0.15μF(154)				5	5
0.22μF(224)				5	5
0.33μF(334)				5	5
0.47μF(474)				5	5
0.68μF(684)				5#	5

LxW [mm]	1.6x0.8 (18) <0603>					2.0x1.25 (21) <0805>					3.2x1.6 (31) <1206>					3.2x2.5 (32) <1210>								
	25 (1E)	10 (1A)	6.3 (0J)	4 (0G)	2.5 (0E)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	25 (1E)	10 (1A)	6.3 (0J)	4 (0G)					
Rated Voltage [Vdc]																								
Capacitance																								
1.0μF(105)	8	5	5																					
2.2μF(225)		8	8																					
4.7μF(475)				8	B	B	9	9								6	9							
10μF(106)				8#	8						B	9, B	C	M	9	9					D			
22μF(226)											B#	B				C	C			E	N			
47μF(476)															C	C			E	E				
100μF(107)																C					E	E		

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

These Part Numbers have individual testing conditions on Durability of GRM Series Specifications and Test Methods (2). Please refer to P60.

Capacitance Table

Continued from the preceding page.

High Dielectric Constant Type X5R(R6) Characteristics

5 ex.5: T Dimension [mm] : Please refer to X7R(R7) etc. Characteristics.

LxW [mm]	0.4x0.2 (02) <01005>		0.6x0.3 (03) <0201>				1.0x0.5 (15) <0402>						1.6x0.8 (18) <0603>							
	Rated Voltage [Vdc]	10 (1A)	6.3 (0J)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)
68pF(680)	2																			
100pF(101)	2																			
150pF(151)	2																			
220pF(221)	2																			
330pF(331)	2																			
470pF(471)	2																			
680pF(681)	2	2																		
1000pF(102)	2	2						5							8					
1500pF(152)	2	2				3														
2200pF(222)	2	2				3			5						8					
3300pF(332)	2	2				3														
4700pF(472)	2	2				3			5						8					
6800pF(682)	2	2				3														
10000pF(103)	2	2				3	3								8					
15000pF(153)							3													
22000pF(223)							3			5					8					
33000pF(333)							3			5	5									
47000pF(473)							3			5	5									
68000pF(683)									5	5	5									
0.10μF(104)									5	5	5				8					
0.15μF(154)										5	5									
0.22μF(224)										5	5				8	8				
0.33μF(334)										5	5									
0.47μF(474)										5	5				8	8				
0.68μF(684)										5	5									
1.0μF(105)											5				8	5, 8	5			
2.2μF(225)																8	8			
4.7μF(475)																			8	
10μF(106)																			8	8
22μF(226)																				8

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

Continued on the following page. ↗

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Capacitance Table

Continued from the preceding page.

LxW [mm]	2.0x1.25 (21) <0805>							3.2x1.6 (31) <1206>							3.2x2.5 (32) <1210>							
	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	100 (2A)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	100 (2A)	50 (1H)	35 (YA)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)
Rated Voltage [Vdc]																						
Capacitance																						
6800pF(682)																						
10000pF(103)																						
15000pF(153)																						
22000pF(223)																						
33000pF(333)																						
47000pF(473)																						
68000pF(683)																						
0.10μF(104)																						
0.15μF(154)																						
0.22μF(224)																						
0.33μF(334)																						
0.47μF(474)																						
0.68μF(684)																						
1.0μF(105)				6	6, B																	
2.2μF(225)			9, B	9, B	B					C	6											
4.7μF(475)			B	9, B	9, B	B				9, C	9, C											
10μF(106)				B	9, B	9, B				C	9, C	9					E	D				
22μF(226)					B	9				C	C	C					E					
47μF(476)											C	C						E	E			
100μF(107)												C	C								E	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		0.4x0.2(02)<01005>	0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		16(1C)	50(1H)	50(1H)
Capacitance	Tolerance	Part Number		
3.6pF(3R6)	±0.05pF(W)	GRM0225C1C3R6WD05L	GRM0335C1H3R6WD01D	GRM1555C1H3R6WA01D
	±0.1pF(B)	GRM0225C1C3R6BD05L	GRM0335C1H3R6BD01D	GRM1555C1H3R6BA01D
	±0.25pF(C)	GRM0225C1C3R6CD05L	GRM0335C1H3R6CD01D	GRM1555C1H3R6CA01D
3.7pF(3R7)	±0.05pF(W)	GRM0225C1C3R7WD05L	GRM0335C1H3R7WD01D	GRM1555C1H3R7WA01D
	±0.1pF(B)	GRM0225C1C3R7BD05L	GRM0335C1H3R7BD01D	GRM1555C1H3R7BA01D
	±0.25pF(C)	GRM0225C1C3R7CD05L	GRM0335C1H3R7CD01D	GRM1555C1H3R7CA01D
3.8pF(3R8)	±0.05pF(W)	GRM0225C1C3R8WD05L	GRM0335C1H3R8WD01D	GRM1555C1H3R8WA01D
	±0.1pF(B)	GRM0225C1C3R8BD05L	GRM0335C1H3R8BD01D	GRM1555C1H3R8BA01D
	±0.25pF(C)	GRM0225C1C3R8CD05L	GRM0335C1H3R8CD01D	GRM1555C1H3R8CA01D
3.9pF(3R9)	±0.05pF(W)	GRM0225C1C3R9WD05L	GRM0335C1H3R9WD01D	GRM1555C1H3R9WA01D
	±0.1pF(B)	GRM0225C1C3R9BD05L	GRM0335C1H3R9BD01D	GRM1555C1H3R9BA01D
	±0.25pF(C)	GRM0225C1C3R9CD05L	GRM0335C1H3R9CD01D	GRM1555C1H3R9CA01D
4.0pF(4R0)	±0.05pF(W)	GRM0225C1C4R0WD05L	GRM0335C1H4R0WD01D	GRM1555C1H4R0WA01D
	±0.1pF(B)	GRM0225C1C4R0BD05L	GRM0335C1H4R0BD01D	GRM1555C1H4R0BA01D
	±0.25pF(C)	GRM0225C1C4R0CD05L	GRM0335C1H4R0CD01D	GRM1555C1H4R0CA01D
4.1pF(4R1)	±0.05pF(W)	GRM0225C1C4R1WD05L	GRM0335C1H4R1WD01D	GRM1555C1H4R1WA01D
	±0.1pF(B)	GRM0225C1C4R1BD05L	GRM0335C1H4R1BD01D	GRM1555C1H4R1BA01D
	±0.25pF(C)	GRM0225C1C4R1CD05L	GRM0335C1H4R1CD01D	GRM1555C1H4R1CA01D
4.2pF(4R2)	±0.05pF(W)	GRM0225C1C4R2WD05L	GRM0335C1H4R2WD01D	GRM1555C1H4R2WA01D
	±0.1pF(B)	GRM0225C1C4R2BD05L	GRM0335C1H4R2BD01D	GRM1555C1H4R2BA01D
	±0.25pF(C)	GRM0225C1C4R2CD05L	GRM0335C1H4R2CD01D	GRM1555C1H4R2CA01D
4.3pF(4R3)	±0.05pF(W)	GRM0225C1C4R3WD05L	GRM0335C1H4R3WD01D	GRM1555C1H4R3WA01D
	±0.1pF(B)	GRM0225C1C4R3BD05L	GRM0335C1H4R3BD01D	GRM1555C1H4R3BA01D
	±0.25pF(C)	GRM0225C1C4R3CD05L	GRM0335C1H4R3CD01D	GRM1555C1H4R3CA01D
4.4pF(4R4)	±0.05pF(W)	GRM0225C1C4R4WD05L	GRM0335C1H4R4WD01D	GRM1555C1H4R4WA01D
	±0.1pF(B)	GRM0225C1C4R4BD05L	GRM0335C1H4R4BD01D	GRM1555C1H4R4BA01D
	±0.25pF(C)	GRM0225C1C4R4CD05L	GRM0335C1H4R4CD01D	GRM1555C1H4R4CA01D
4.5pF(4R5)	±0.05pF(W)	GRM0225C1C4R5WD05L	GRM0335C1H4R5WD01D	GRM1555C1H4R5WA01D
	±0.1pF(B)	GRM0225C1C4R5BD05L	GRM0335C1H4R5BD01D	GRM1555C1H4R5BA01D
	±0.25pF(C)	GRM0225C1C4R5CD05L	GRM0335C1H4R5CD01D	GRM1555C1H4R5CA01D
4.6pF(4R6)	±0.05pF(W)	GRM0225C1C4R6WD05L	GRM0335C1H4R6WD01D	GRM1555C1H4R6WA01D
	±0.1pF(B)	GRM0225C1C4R6BD05L	GRM0335C1H4R6BD01D	GRM1555C1H4R6BA01D
	±0.25pF(C)	GRM0225C1C4R6CD05L	GRM0335C1H4R6CD01D	GRM1555C1H4R6CA01D
4.7pF(4R7)	±0.05pF(W)	GRM0225C1C4R7WD05L	GRM0335C1H4R7WD01D	GRM1555C1H4R7WA01D
	±0.1pF(B)	GRM0225C1C4R7BD05L	GRM0335C1H4R7BD01D	GRM1555C1H4R7BA01D
	±0.25pF(C)	GRM0225C1C4R7CD05L	GRM0335C1H4R7CD01D	GRM1555C1H4R7CA01D
4.8pF(4R8)	±0.05pF(W)	GRM0225C1C4R8WD05L	GRM0335C1H4R8WD01D	GRM1555C1H4R8WA01D
	±0.1pF(B)	GRM0225C1C4R8BD05L	GRM0335C1H4R8BD01D	GRM1555C1H4R8BA01D
	±0.25pF(C)	GRM0225C1C4R8CD05L	GRM0335C1H4R8CD01D	GRM1555C1H4R8CA01D
4.9pF(4R9)	±0.05pF(W)	GRM0225C1C4R9WD05L	GRM0335C1H4R9WD01D	GRM1555C1H4R9WA01D
	±0.1pF(B)	GRM0225C1C4R9BD05L	GRM0335C1H4R9BD01D	GRM1555C1H4R9BA01D
	±0.25pF(C)	GRM0225C1C4R9CD05L	GRM0335C1H4R9CD01D	GRM1555C1H4R9CA01D
5.0pF(5R0)	±0.05pF(W)	GRM0225C1C5R0WD05L	GRM0335C1H5R0WD01D	GRM1555C1H5R0WA01D
	±0.1pF(B)	GRM0225C1C5R0BD05L	GRM0335C1H5R0BD01D	GRM1555C1H5R0BA01D
	±0.25pF(C)	GRM0225C1C5R0CD05L	GRM0335C1H5R0CD01D	GRM1555C1H5R0CA01D
5.1pF(5R1)	±0.05pF(W)	GRM0225C1C5R1WD05L	GRM0335C1H5R1WD01D	GRM1555C1H5R1WA01D
	±0.1pF(B)	GRM0225C1C5R1BD05L	GRM0335C1H5R1BD01D	GRM1555C1H5R1BA01D
	±0.25pF(C)	GRM0225C1C5R1CD05L	GRM0335C1H5R1CD01D	GRM1555C1H5R1CA01D
	±0.5pF(D)	GRM0225C1C5R1DD05L	GRM0335C1H5R1DD01D	GRM1555C1H5R1DA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		0.4x0.2(02)<01005>	0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		16(1C)	50(1H)	50(1H)
Capacitance	Tolerance	Part Number		
6.4pF(6R4)	±0.05pF(W)	GRM0225C1C6R4WD05L	GRM0335C1H6R4WD01D	GRM1555C1H6R4WA01D
	±0.1pF(B)	GRM0225C1C6R4BD05L	GRM0335C1H6R4BD01D	GRM1555C1H6R4BA01D
	±0.25pF(C)	GRM0225C1C6R4CD05L	GRM0335C1H6R4CD01D	GRM1555C1H6R4CA01D
	±0.5pF(D)	GRM0225C1C6R4DD05L	GRM0335C1H6R4DD01D	GRM1555C1H6R4DA01D
6.5pF(6R5)	±0.05pF(W)	GRM0225C1C6R5WD05L	GRM0335C1H6R5WD01D	GRM1555C1H6R5WA01D
	±0.1pF(B)	GRM0225C1C6R5BD05L	GRM0335C1H6R5BD01D	GRM1555C1H6R5BA01D
	±0.25pF(C)	GRM0225C1C6R5CD05L	GRM0335C1H6R5CD01D	GRM1555C1H6R5CA01D
	±0.5pF(D)	GRM0225C1C6R5DD05L	GRM0335C1H6R5DD01D	GRM1555C1H6R5DA01D
6.6pF(6R6)	±0.05pF(W)	GRM0225C1C6R6WD05L	GRM0335C1H6R6WD01D	GRM1555C1H6R6WA01D
	±0.1pF(B)	GRM0225C1C6R6BD05L	GRM0335C1H6R6BD01D	GRM1555C1H6R6BA01D
	±0.25pF(C)	GRM0225C1C6R6CD05L	GRM0335C1H6R6CD01D	GRM1555C1H6R6CA01D
	±0.5pF(D)	GRM0225C1C6R6DD05L	GRM0335C1H6R6DD01D	GRM1555C1H6R6DA01D
6.7pF(6R7)	±0.05pF(W)	GRM0225C1C6R7WD05L	GRM0335C1H6R7WD01D	GRM1555C1H6R7WA01D
	±0.1pF(B)	GRM0225C1C6R7BD05L	GRM0335C1H6R7BD01D	GRM1555C1H6R7BA01D
	±0.25pF(C)	GRM0225C1C6R7CD05L	GRM0335C1H6R7CD01D	GRM1555C1H6R7CA01D
	±0.5pF(D)	GRM0225C1C6R7DD05L	GRM0335C1H6R7DD01D	GRM1555C1H6R7DA01D
6.8pF(6R8)	±0.05pF(W)	GRM0225C1C6R8WD05L	GRM0335C1H6R8WD01D	GRM1555C1H6R8WA01D
	±0.1pF(B)	GRM0225C1C6R8BD05L	GRM0335C1H6R8BD01D	GRM1555C1H6R8BA01D
	±0.25pF(C)	GRM0225C1C6R8CD05L	GRM0335C1H6R8CD01D	GRM1555C1H6R8CA01D
	±0.5pF(D)	GRM0225C1C6R8DD05L	GRM0335C1H6R8DD01D	GRM1555C1H6R8DA01D
6.9pF(6R9)	±0.05pF(W)	GRM0225C1C6R9WD05L	GRM0335C1H6R9WD01D	GRM1555C1H6R9WA01D
	±0.1pF(B)	GRM0225C1C6R9BD05L	GRM0335C1H6R9BD01D	GRM1555C1H6R9BA01D
	±0.25pF(C)	GRM0225C1C6R9CD05L	GRM0335C1H6R9CD01D	GRM1555C1H6R9CA01D
	±0.5pF(D)	GRM0225C1C6R9DD05L	GRM0335C1H6R9DD01D	GRM1555C1H6R9DA01D
7.0pF(7R0)	±0.05pF(W)	GRM0225C1C7R0WD05L	GRM0335C1H7R0WD01D	GRM1555C1H7R0WA01D
	±0.1pF(B)	GRM0225C1C7R0BD05L	GRM0335C1H7R0BD01D	GRM1555C1H7R0BA01D
	±0.25pF(C)	GRM0225C1C7R0CD05L	GRM0335C1H7R0CD01D	GRM1555C1H7R0CA01D
	±0.5pF(D)	GRM0225C1C7R0DD05L	GRM0335C1H7R0DD01D	GRM1555C1H7R0DA01D
7.1pF(7R1)	±0.05pF(W)	GRM0225C1C7R1WD05L	GRM0335C1H7R1WD01D	GRM1555C1H7R1WA01D
	±0.1pF(B)	GRM0225C1C7R1BD05L	GRM0335C1H7R1BD01D	GRM1555C1H7R1BA01D
	±0.25pF(C)	GRM0225C1C7R1CD05L	GRM0335C1H7R1CD01D	GRM1555C1H7R1CA01D
	±0.5pF(D)	GRM0225C1C7R1DD05L	GRM0335C1H7R1DD01D	GRM1555C1H7R1DA01D
7.2pF(7R2)	±0.05pF(W)	GRM0225C1C7R2WD05L	GRM0335C1H7R2WD01D	GRM1555C1H7R2WA01D
	±0.1pF(B)	GRM0225C1C7R2BD05L	GRM0335C1H7R2BD01D	GRM1555C1H7R2BA01D
	±0.25pF(C)	GRM0225C1C7R2CD05L	GRM0335C1H7R2CD01D	GRM1555C1H7R2CA01D
	±0.5pF(D)	GRM0225C1C7R2DD05L	GRM0335C1H7R2DD01D	GRM1555C1H7R2DA01D
7.3pF(7R3)	±0.05pF(W)	GRM0225C1C7R3WD05L	GRM0335C1H7R3WD01D	GRM1555C1H7R3WA01D
	±0.1pF(B)	GRM0225C1C7R3BD05L	GRM0335C1H7R3BD01D	GRM1555C1H7R3BA01D
	±0.25pF(C)	GRM0225C1C7R3CD05L	GRM0335C1H7R3CD01D	GRM1555C1H7R3CA01D
	±0.5pF(D)	GRM0225C1C7R3DD05L	GRM0335C1H7R3DD01D	GRM1555C1H7R3DA01D
7.4pF(7R4)	±0.05pF(W)	GRM0225C1C7R4WD05L	GRM0335C1H7R4WD01D	GRM1555C1H7R4WA01D
	±0.1pF(B)	GRM0225C1C7R4BD05L	GRM0335C1H7R4BD01D	GRM1555C1H7R4BA01D
	±0.25pF(C)	GRM0225C1C7R4CD05L	GRM0335C1H7R4CD01D	GRM1555C1H7R4CA01D
	±0.5pF(D)	GRM0225C1C7R4DD05L	GRM0335C1H7R4DD01D	GRM1555C1H7R4DA01D
7.5pF(7R5)	±0.05pF(W)	GRM0225C1C7R5WD05L	GRM0335C1H7R5WD01D	GRM1555C1H7R5WA01D
	±0.1pF(B)	GRM0225C1C7R5BD05L	GRM0335C1H7R5BD01D	GRM1555C1H7R5BA01D
	±0.25pF(C)	GRM0225C1C7R5CD05L	GRM0335C1H7R5CD01D	GRM1555C1H7R5CA01D
	±0.5pF(D)	GRM0225C1C7R5DD05L	GRM0335C1H7R5DD01D	GRM1555C1H7R5DA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		0.4x0.2(02)<01005>	0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		16(1C)	50(1H)	50(1H)
Capacitance	Tolerance	Part Number		
8.8pF(8R8)	±0.05pF(W)	GRM0225C1C8R8WD05L	GRM0335C1H8R8WD01D	GRM1555C1H8R8WA01D
	±0.1pF(B)	GRM0225C1C8R8BD05L	GRM0335C1H8R8BD01D	GRM1555C1H8R8BA01D
	±0.25pF(C)	GRM0225C1C8R8CD05L	GRM0335C1H8R8CD01D	GRM1555C1H8R8CA01D
	±0.5pF(D)	GRM0225C1C8R8DD05L	GRM0335C1H8R8DD01D	GRM1555C1H8R8DA01D
8.9pF(8R9)	±0.05pF(W)	GRM0225C1C8R9WD05L	GRM0335C1H8R9WD01D	GRM1555C1H8R9WA01D
	±0.1pF(B)	GRM0225C1C8R9BD05L	GRM0335C1H8R9BD01D	GRM1555C1H8R9BA01D
	±0.25pF(C)	GRM0225C1C8R9CD05L	GRM0335C1H8R9CD01D	GRM1555C1H8R9CA01D
	±0.5pF(D)	GRM0225C1C8R9DD05L	GRM0335C1H8R9DD01D	GRM1555C1H8R9DA01D
9.0pF(9R0)	±0.05pF(W)	GRM0225C1C9R0WD05L	GRM0335C1H9R0WD01D	GRM1555C1H9R0WA01D
	±0.1pF(B)	GRM0225C1C9R0BD05L	GRM0335C1H9R0BD01D	GRM1555C1H9R0BA01D
	±0.25pF(C)	GRM0225C1C9R0CD05L	GRM0335C1H9R0CD01D	GRM1555C1H9R0CA01D
	±0.5pF(D)	GRM0225C1C9R0DD05L	GRM0335C1H9R0DD01D	GRM1555C1H9R0DA01D
9.1pF(9R1)	±0.05pF(W)	GRM0225C1C9R1WD05L	GRM0335C1H9R1WD01D	GRM1555C1H9R1WA01D
	±0.1pF(B)	GRM0225C1C9R1BD05L	GRM0335C1H9R1BD01D	GRM1555C1H9R1BA01D
	±0.25pF(C)	GRM0225C1C9R1CD05L	GRM0335C1H9R1CD01D	GRM1555C1H9R1CA01D
	±0.5pF(D)	GRM0225C1C9R1DD05L	GRM0335C1H9R1DD01D	GRM1555C1H9R1DA01D
9.2pF(9R2)	±0.05pF(W)	GRM0225C1C9R2WD05L	GRM0335C1H9R2WD01D	GRM1555C1H9R2WA01D
	±0.1pF(B)	GRM0225C1C9R2BD05L	GRM0335C1H9R2BD01D	GRM1555C1H9R2BA01D
	±0.25pF(C)	GRM0225C1C9R2CD05L	GRM0335C1H9R2CD01D	GRM1555C1H9R2CA01D
	±0.5pF(D)	GRM0225C1C9R2DD05L	GRM0335C1H9R2DD01D	GRM1555C1H9R2DA01D
9.3pF(9R3)	±0.05pF(W)	GRM0225C1C9R3WD05L	GRM0335C1H9R3WD01D	GRM1555C1H9R3WA01D
	±0.1pF(B)	GRM0225C1C9R3BD05L	GRM0335C1H9R3BD01D	GRM1555C1H9R3BA01D
	±0.25pF(C)	GRM0225C1C9R3CD05L	GRM0335C1H9R3CD01D	GRM1555C1H9R3CA01D
	±0.5pF(D)	GRM0225C1C9R3DD05L	GRM0335C1H9R3DD01D	GRM1555C1H9R3DA01D
9.4pF(9R4)	±0.05pF(W)	GRM0225C1C9R4WD05L	GRM0335C1H9R4WD01D	GRM1555C1H9R4WA01D
	±0.1pF(B)	GRM0225C1C9R4BD05L	GRM0335C1H9R4BD01D	GRM1555C1H9R4BA01D
	±0.25pF(C)	GRM0225C1C9R4CD05L	GRM0335C1H9R4CD01D	GRM1555C1H9R4CA01D
	±0.5pF(D)	GRM0225C1C9R4DD05L	GRM0335C1H9R4DD01D	GRM1555C1H9R4DA01D
9.5pF(9R5)	±0.05pF(W)	GRM0225C1C9R5WD05L	GRM0335C1H9R5WD01D	GRM1555C1H9R5WA01D
	±0.1pF(B)	GRM0225C1C9R5BD05L	GRM0335C1H9R5BD01D	GRM1555C1H9R5BA01D
	±0.25pF(C)	GRM0225C1C9R5CD05L	GRM0335C1H9R5CD01D	GRM1555C1H9R5CA01D
	±0.5pF(D)	GRM0225C1C9R5DD05L	GRM0335C1H9R5DD01D	GRM1555C1H9R5DA01D
9.6pF(9R6)	±0.05pF(W)	GRM0225C1C9R6WD05L	GRM0335C1H9R6WD01D	GRM1555C1H9R6WA01D
	±0.1pF(B)	GRM0225C1C9R6BD05L	GRM0335C1H9R6BD01D	GRM1555C1H9R6BA01D
	±0.25pF(C)	GRM0225C1C9R6CD05L	GRM0335C1H9R6CD01D	GRM1555C1H9R6CA01D
	±0.5pF(D)	GRM0225C1C9R6DD05L	GRM0335C1H9R6DD01D	GRM1555C1H9R6DA01D
9.7pF(9R7)	±0.05pF(W)	GRM0225C1C9R7WD05L	GRM0335C1H9R7WD01D	GRM1555C1H9R7WA01D
	±0.1pF(B)	GRM0225C1C9R7BD05L	GRM0335C1H9R7BD01D	GRM1555C1H9R7BA01D
	±0.25pF(C)	GRM0225C1C9R7CD05L	GRM0335C1H9R7CD01D	GRM1555C1H9R7CA01D
	±0.5pF(D)	GRM0225C1C9R7DD05L	GRM0335C1H9R7DD01D	GRM1555C1H9R7DA01D
9.8pF(9R8)	±0.05pF(W)	GRM0225C1C9R8WD05L	GRM0335C1H9R8WD01D	GRM1555C1H9R8WA01D
	±0.1pF(B)	GRM0225C1C9R8BD05L	GRM0335C1H9R8BD01D	GRM1555C1H9R8BA01D
	±0.25pF(C)	GRM0225C1C9R8CD05L	GRM0335C1H9R8CD01D	GRM1555C1H9R8CA01D
	±0.5pF(D)	GRM0225C1C9R8DD05L	GRM0335C1H9R8DD01D	GRM1555C1H9R8DA01D
9.9pF(9R9)	±0.05pF(W)	GRM0225C1C9R9WD05L	GRM0335C1H9R9WD01D	GRM1555C1H9R9WA01D
	±0.1pF(B)	GRM0225C1C9R9BD05L	GRM0335C1H9R9BD01D	GRM1555C1H9R9BA01D
	±0.25pF(C)	GRM0225C1C9R9CD05L	GRM0335C1H9R9CD01D	GRM1555C1H9R9CA01D
	±0.5pF(D)	GRM0225C1C9R9DD05L	GRM0335C1H9R9DD01D	GRM1555C1H9R9DA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series
 Array GNM Series
 Low ESL LL□ Series
 High-Q GJM Series
 High Frequency GQM Series
 Monolithic Microchip GMA Series
 For Bonding GMD Series
 Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		1.0x0.5(15)<0402>
Rated Volt. [Vdc]		50(1H)
TC		C0G(5C)
Capacitance	Tolerance	Part Number
10pF(100)	±2%(G)	GRM1555C1H100GA01D
	±5%(J)	GRM1555C1H100JA01D
12pF(120)	±2%(G)	GRM1555C1H120GA01D
	±5%(J)	GRM1555C1H120JA01D
15pF(150)	±2%(G)	GRM1555C1H150GA01D
	±5%(J)	GRM1555C1H150JA01D
18pF(180)	±2%(G)	GRM1555C1H180GA01D
	±5%(J)	GRM1555C1H180JA01D
22pF(220)	±2%(G)	GRM1555C1H220GA01D
	±5%(J)	GRM1555C1H220JA01D
27pF(270)	±2%(G)	GRM1555C1H270GA01D
	±5%(J)	GRM1555C1H270JA01D
33pF(330)	±2%(G)	GRM1555C1H330GA01D
	±5%(J)	GRM1555C1H330JA01D
39pF(390)	±2%(G)	GRM1555C1H390GA01D
	±5%(J)	GRM1555C1H390JA01D
47pF(470)	±2%(G)	GRM1555C1H470GA01D
	±5%(J)	GRM1555C1H470JA01D
56pF(560)	±2%(G)	GRM1555C1H560GA01D
	±5%(J)	GRM1555C1H560JA01D
68pF(680)	±2%(G)	GRM1555C1H680GA01D
	±5%(J)	GRM1555C1H680JA01D
82pF(820)	±2%(G)	GRM1555C1H820GA01D
	±5%(J)	GRM1555C1H820JA01D
100pF(101)	±2%(G)	GRM1555C1H101GA01D
	±5%(J)	GRM1555C1H101JA01D
120pF(121)	±2%(G)	GRM1555C1H121GA01D
	±5%(J)	GRM1555C1H121JA01D
150pF(151)	±2%(G)	GRM1555C1H151GA01D
	±5%(J)	GRM1555C1H151JA01D
180pF(181)	±2%(G)	GRM1555C1H181GA01D
	±5%(J)	GRM1555C1H181JA01D
220pF(221)	±2%(G)	GRM1555C1H221GA01D
	±5%(J)	GRM1555C1H221JA01D
270pF(271)	±2%(G)	GRM1555C1H271GA01D
	±5%(J)	GRM1555C1H271JA01D
330pF(331)	±2%(G)	GRM1555C1H331GA01D
	±5%(J)	GRM1555C1H331JA01D
390pF(391)	±2%(G)	GRM1555C1H391GA01D
	±5%(J)	GRM1555C1H391JA01D
470pF(471)	±2%(G)	GRM1555C1H471GA01D
	±5%(J)	GRM1555C1H471JA01D
560pF(561)	±2%(G)	GRM1555C1H561GA01D
	±5%(J)	GRM1555C1H561JA01D
680pF(681)	±2%(G)	GRM1555C1H681GA01D
	±5%(J)	GRM1555C1H681JA01D
820pF(821)	±2%(G)	GRM1555C1H821GA01D
	±5%(J)	GRM1555C1H821JA01D
1000pF(102)	±2%(G)	GRM1555C1H102GA01D
	±5%(J)	GRM1555C1H102JA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		2.0x1.25(21)<0805>		3.2x1.6(31)<1206>	
Rated Volt. [Vdc]		100(2A)	50(1H)	100(2A)	50(1H)
Capacitance	Tolerance	Part Number			
100pF(101)	±5%(J)	GRM2165C2A101JA01D			
120pF(121)	±5%(J)	GRM2165C2A121JA01D			
150pF(151)	±5%(J)	GRM2165C2A151JA01D			
180pF(181)	±5%(J)	GRM2165C2A181JA01D			
220pF(221)	±5%(J)	GRM2165C2A221JA01D			
270pF(271)	±5%(J)	GRM2165C2A271JA01D			
330pF(331)	±5%(J)	GRM2165C2A331JA01D			
390pF(391)	±5%(J)	GRM2165C2A391JA01D			
470pF(471)	±5%(J)	GRM2165C2A471JA01D			
560pF(561)	±5%(J)	GRM2165C2A561JA01D			
680pF(681)	±5%(J)	GRM2165C2A681JA01D			
820pF(821)	±5%(J)	GRM2165C2A821JA01D			
1000pF(102)	±5%(J)	GRM2165C2A102JA01D			
1200pF(122)	±5%(J)	GRM2165C2A122JA01D	GRM2165C1H122JA01D		
1500pF(152)	±5%(J)	GRM2165C2A152JA01D	GRM2165C1H152JA01D		
1800pF(182)	±5%(J)	GRM2165C2A182JA01D	GRM2165C1H182JA01D	GRM3195C2A182JA01D	
2200pF(222)	±5%(J)	GRM2165C2A222JA01D	GRM2165C1H222JA01D	GRM3195C2A222JA01D	
2700pF(272)	±5%(J)	GRM2165C2A272JA01D	GRM2165C1H272JA01D	GRM3195C2A272JA01D	
3300pF(332)	±5%(J)	GRM2165C2A332JA01D	GRM2165C1H332JA01D	GRM3195C2A332JA01D	
3900pF(392)	±5%(J)		GRM2165C1H392JA01D	GRM3195C2A392JA01D	
4700pF(472)	±5%(J)		GRM2165C1H472JA01D	GRM3195C2A472JA01D	GRM3195C1H472JA01D
5600pF(562)	±5%(J)		GRM2195C1H562JA01D	GRM3195C2A562JA01D	GRM3195C1H562JA01D
6800pF(682)	±5%(J)		GRM2195C1H682JA01D	GRM3195C2A682JA01D	GRM3195C1H682JA01D
8200pF(822)	±5%(J)		GRM2195C1H822JA01D	GRM3195C2A822JA01D	GRM3195C1H822JA01D
10000pF(103)	±5%(J)		GRM2195C1H103JA01D	GRM3195C2A103JA01D	GRM3195C1H103JA01D
12000pF(123)	±5%(J)		GRM2195C1H123JA01D	GRM3195C2A123JA01D	GRM3195C1H123JA01D
15000pF(153)	±5%(J)		GRM2195C1H153JA01D	GRM3195C2A153JA01D	GRM3195C1H153JA01D
18000pF(183)	±5%(J)		GRM21B5C1H183JA01L	GRM3195C2A183JA01D	GRM3195C1H183JA01D
22000pF(223)	±5%(J)		GRM21B5C1H223JA01L	GRM3195C2A223JA01D	GRM3195C1H223JA01D
27000pF(273)	±5%(J)				GRM3195C1H273JA01D
33000pF(333)	±5%(J)				GRM3195C1H333JA01D
39000pF(393)	±5%(J)				GRM3195C1H393JA01D
47000pF(473)	±5%(J)				GRM31M5C1H473JA01L
56000pF(563)	±5%(J)				GRM31M5C1H563JA01L
68000pF(683)	±5%(J)				GRM31C5C1H683JA01L
82000pF(823)	±5%(J)				GRM31C5C1H823JA01L
100000pF(104)	±5%(J)				GRM31C5C1H104JA01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics-Low Profile

LxW [mm]		1.0x0.5(15)<402>	
Rated Volt. [Vdc]		50(1H)	
Capacitance	Tolerance	Part Number	
0.1pF(R10)	±0.1pF(B)	GRM1535C1HR10BDD5D	
0.2pF(R20)	±0.1pF(B)	GRM1535C1HR20BDD5D	
0.3pF(R30)	±0.1pF(B)	GRM1535C1HR30BDD5D	
0.4pF(R40)	±0.1pF(B)	GRM1535C1HR40BDD5D	
0.5pF(R50)	±0.1pF(B)	GRM1535C1HR50BDD5D	
0.6pF(R60)	±0.1pF(B)	GRM1535C1HR60BDD5D	
0.7pF(R70)	±0.1pF(B)	GRM1535C1HR70BDD5D	
0.8pF(R80)	±0.1pF(B)	GRM1535C1HR80BDD5D	
0.9pF(R90)	±0.1pF(B)	GRM1535C1HR90BDD5D	
1.0pF(1R0)	±0.25pF(C)	GRM1535C1H1R0CDD5D	
1.1pF(1R1)	±0.25pF(C)	GRM1535C1H1R1CDD5D	
1.2pF(1R2)	±0.25pF(C)	GRM1535C1H1R2CDD5D	
1.3pF(1R3)	±0.25pF(C)	GRM1535C1H1R3CDD5D	
1.4pF(1R4)	±0.25pF(C)	GRM1535C1H1R4CDD5D	
1.5pF(1R5)	±0.25pF(C)	GRM1535C1H1R5CDD5D	
1.6pF(1R6)	±0.25pF(C)	GRM1535C1H1R6CDD5D	
1.7pF(1R7)	±0.25pF(C)	GRM1535C1H1R7CDD5D	
1.8pF(1R8)	±0.25pF(C)	GRM1535C1H1R8CDD5D	
1.9pF(1R9)	±0.25pF(C)	GRM1535C1H1R9CDD5D	
2.0pF(2R0)	±0.25pF(C)	GRM1535C1H2R0CDD5D	
2.1pF(2R1)	±0.25pF(C)	GRM1535C1H2R1CDD5D	
2.2pF(2R2)	±0.25pF(C)	GRM1535C1H2R2CDD5D	
2.3pF(2R3)	±0.25pF(C)	GRM1535C1H2R3CDD5D	
2.4pF(2R4)	±0.25pF(C)	GRM1535C1H2R4CDD5D	
2.5pF(2R5)	±0.25pF(C)	GRM1535C1H2R5CDD5D	
2.6pF(2R6)	±0.25pF(C)	GRM1535C1H2R6CDD5D	
2.7pF(2R7)	±0.25pF(C)	GRM1535C1H2R7CDD5D	
2.8pF(2R8)	±0.25pF(C)	GRM1535C1H2R8CDD5D	
2.9pF(2R9)	±0.25pF(C)	GRM1535C1H2R9CDD5D	
3.0pF(3R0)	±0.25pF(C)	GRM1535C1H3R0CDD5D	
3.1pF(3R1)	±0.25pF(C)	GRM1535C1H3R1CDD5D	
3.2pF(3R2)	±0.25pF(C)	GRM1535C1H3R2CDD5D	
3.3pF(3R3)	±0.25pF(C)	GRM1535C1H3R3CDD5D	
3.4pF(3R4)	±0.25pF(C)	GRM1535C1H3R4CDD5D	
3.5pF(3R5)	±0.25pF(C)	GRM1535C1H3R5CDD5D	
3.6pF(3R6)	±0.25pF(C)	GRM1535C1H3R6CDD5D	
3.7pF(3R7)	±0.25pF(C)	GRM1535C1H3R7CDD5D	
3.8pF(3R8)	±0.25pF(C)	GRM1535C1H3R8CDD5D	
3.9pF(3R9)	±0.25pF(C)	GRM1535C1H3R9CDD5D	
4.0pF(4R0)	±0.25pF(C)	GRM1535C1H4R0CDD5D	
4.1pF(4R1)	±0.25pF(C)	GRM1535C1H4R1CDD5D	
4.2pF(4R2)	±0.25pF(C)	GRM1535C1H4R2CDD5D	
4.3pF(4R3)	±0.25pF(C)	GRM1535C1H4R3CDD5D	
4.4pF(4R4)	±0.25pF(C)	GRM1535C1H4R4CDD5D	
4.5pF(4R5)	±0.25pF(C)	GRM1535C1H4R5CDD5D	
4.6pF(4R6)	±0.25pF(C)	GRM1535C1H4R6CDD5D	
4.7pF(4R7)	±0.25pF(C)	GRM1535C1H4R7CDD5D	
4.8pF(4R8)	±0.25pF(C)	GRM1535C1H4R8CDD5D	

LxW [mm]		1.0x0.5(15)<402>	
Rated Volt. [Vdc]		50(1H)	
Capacitance	Tolerance	Part Number	
4.9pF(4R9)	±0.25pF(C)	GRM1535C1H4R9CDD5D	
5.0pF(5R0)	±0.25pF(C)	GRM1535C1H5R0CDD5D	
5.1pF(5R1)	±0.5pF(D)	GRM1535C1H5R1DDD5D	
5.2pF(5R2)	±0.5pF(D)	GRM1535C1H5R2DDD5D	
5.3pF(5R3)	±0.5pF(D)	GRM1535C1H5R3DDD5D	
5.4pF(5R4)	±0.5pF(D)	GRM1535C1H5R4DDD5D	
5.5pF(5R5)	±0.5pF(D)	GRM1535C1H5R5DDD5D	
5.6pF(5R6)	±0.5pF(D)	GRM1535C1H5R6DDD5D	
5.7pF(5R7)	±0.5pF(D)	GRM1535C1H5R7DDD5D	
5.8pF(5R8)	±0.5pF(D)	GRM1535C1H5R8DDD5D	
5.9pF(5R9)	±0.5pF(D)	GRM1535C1H5R9DDD5D	
6.0pF(6R0)	±0.5pF(D)	GRM1535C1H6R0DDD5D	
6.1pF(6R1)	±0.5pF(D)	GRM1535C1H6R1DDD5D	
6.2pF(6R2)	±0.5pF(D)	GRM1535C1H6R2DDD5D	
6.3pF(6R3)	±0.5pF(D)	GRM1535C1H6R3DDD5D	
6.4pF(6R4)	±0.5pF(D)	GRM1535C1H6R4DDD5D	
6.5pF(6R5)	±0.5pF(D)	GRM1535C1H6R5DDD5D	
6.6pF(6R6)	±0.5pF(D)	GRM1535C1H6R6DDD5D	
6.7pF(6R7)	±0.5pF(D)	GRM1535C1H6R7DDD5D	
6.8pF(6R8)	±0.5pF(D)	GRM1535C1H6R8DDD5D	
6.9pF(6R9)	±0.5pF(D)	GRM1535C1H6R9DDD5D	
7.0pF(7R0)	±0.5pF(D)	GRM1535C1H7R0DDD5D	
7.1pF(7R1)	±0.5pF(D)	GRM1535C1H7R1DDD5D	
7.2pF(7R2)	±0.5pF(D)	GRM1535C1H7R2DDD5D	
7.3pF(7R3)	±0.5pF(D)	GRM1535C1H7R3DDD5D	
7.4pF(7R4)	±0.5pF(D)	GRM1535C1H7R4DDD5D	
7.5pF(7R5)	±0.5pF(D)	GRM1535C1H7R5DDD5D	
7.6pF(7R6)	±0.5pF(D)	GRM1535C1H7R6DDD5D	
7.7pF(7R7)	±0.5pF(D)	GRM1535C1H7R7DDD5D	
7.8pF(7R8)	±0.5pF(D)	GRM1535C1H7R8DDD5D	
7.9pF(7R9)	±0.5pF(D)	GRM1535C1H7R9DDD5D	
8.0pF(8R0)	±0.5pF(D)	GRM1535C1H8R0DDD5D	
8.1pF(8R1)	±0.5pF(D)	GRM1535C1H8R1DDD5D	
8.2pF(8R2)	±0.5pF(D)	GRM1535C1H8R2DDD5D	
8.3pF(8R3)	±0.5pF(D)	GRM1535C1H8R3DDD5D	
8.4pF(8R4)	±0.5pF(D)	GRM1535C1H8R4DDD5D	
8.5pF(8R5)	±0.5pF(D)	GRM1535C1H8R5DDD5D	
8.6pF(8R6)	±0.5pF(D)	GRM1535C1H8R6DDD5D	
8.7pF(8R7)	±0.5pF(D)	GRM1535C1H8R7DDD5D	
8.8pF(8R8)	±0.5pF(D)	GRM1535C1H8R8DDD5D	
8.9pF(8R9)	±0.5pF(D)	GRM1535C1H8R9DDD5D	
9.0pF(9R0)	±0.5pF(D)	GRM1535C1H9R0DDD5D	
9.1pF(9R1)	±0.5pF(D)	GRM1535C1H9R1DDD5D	
9.2pF(9R2)	±0.5pF(D)	GRM1535C1H9R2DDD5D	
9.3pF(9R3)	±0.5pF(D)	GRM1535C1H9R3DDD5D	
9.4pF(9R4)	±0.5pF(D)	GRM1535C1H9R4DDD5D	
9.5pF(9R5)	±0.5pF(D)	GRM1535C1H9R5DDD5D	
9.6pF(9R6)	±0.5pF(D)	GRM1535C1H9R6DDD5D	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

(Part Number) GR M 15 3 5C 1H R10 B DD5 D

1
 2
 3
 4
 5
 6
 7
 8
 9
 10

- ① Product ID
- ② Series
- ③ Dimensions (LxW)
- ④ Dimension (T)
- ⑤ Temperature Characteristics
- ⑥ Rated Voltage
- ⑦ Capacitance
- ⑧ Capacitance Tolerance
- ⑨ Individual Specification Code
- ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

Temperature Compensating Type C0G(5C) Characteristics-Low Profile

LxW [mm]		1.0x0.5(15)<0402>
Rated Volt. [Vdc]		50(1H)
Capacitance	Tolerance	Part Number
9.7pF(9R7)	±0.5pF(D)	GRM1535C1H9R7DDD5D
9.8pF(9R8)	±0.5pF(D)	GRM1535C1H9R8DDD5D
9.9pF(9R9)	±0.5pF(D)	GRM1535C1H9R9DDD5D
10pF(100)	±5%(J)	GRM1535C1H100JDD5D
12pF(120)	±5%(J)	GRM1535C1H120JDD5D
15pF(150)	±5%(J)	GRM1535C1H150JDD5D
18pF(180)	±5%(J)	GRM1535C1H180JDD5D
22pF(220)	±5%(J)	GRM1535C1H220JDD5D
27pF(270)	±5%(J)	GRM1535C1H270JDD5D
33pF(330)	±5%(J)	GRM1535C1H330JDD5D
39pF(390)	±5%(J)	GRM1535C1H390JDD5D
47pF(470)	±5%(J)	GRM1535C1H470JDD5D
56pF(560)	±5%(J)	GRM1535C1H560JDD5D
68pF(680)	±5%(J)	GRM1535C1H680JDD5D
82pF(820)	±5%(J)	GRM1535C1H820JDD5D
100pF(101)	±5%(J)	GRM1535C1H101JDD5D
120pF(121)	±5%(J)	GRM1535C1H121JDD5D
150pF(151)	±5%(J)	GRM1535C1H151JDD5D
180pF(181)	±5%(J)	GRM1535C1H181JDD5D
220pF(221)	±5%(J)	GRM1535C1H221JDD5D
270pF(271)	±5%(J)	GRM1535C1H271JDD5D
330pF(331)	±5%(J)	GRM1535C1H331JDD5D
390pF(391)	±5%(J)	GRM1535C1H391JDD5D
470pF(471)	±5%(J)	GRM1535C1H471JDD5D
560pF(561)	±5%(J)	GRM1535C1H561JDD5D
680pF(681)	±5%(J)	GRM1535C1H681JDD5D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics-Low Profile

LxW [mm]		2.0x1.25(21)<0805>		3.2x1.6(31)<1206>	
Rated Volt. [Vdc]		100(2A)	50(1H)	100(2A)	50(1H)
Capacitance	Tolerance	Part Number			
100pF(101)	±5%(J)	GRM2165C2A101JA01D			
120pF(121)	±5%(J)	GRM2165C2A121JA01D			
150pF(151)	±5%(J)	GRM2165C2A151JA01D			
180pF(181)	±5%(J)	GRM2165C2A181JA01D			
220pF(221)	±5%(J)	GRM2165C2A221JA01D			
270pF(271)	±5%(J)	GRM2165C2A271JA01D			
330pF(331)	±5%(J)	GRM2165C2A331JA01D			
390pF(391)	±5%(J)	GRM2165C2A391JA01D			
470pF(471)	±5%(J)	GRM2165C2A471JA01D			
560pF(561)	±5%(J)	GRM2165C2A561JA01D			
680pF(681)	±5%(J)	GRM2165C2A681JA01D			
820pF(821)	±5%(J)	GRM2165C2A821JA01D			
1000pF(102)	±5%(J)	GRM2165C2A102JA01D			
1200pF(122)	±5%(J)	GRM2165C2A122JA01D	GRM2165C1H122JA01D		
1500pF(152)	±5%(J)	GRM2165C2A152JA01D	GRM2165C1H152JA01D		
1800pF(182)	±5%(J)	GRM2165C2A182JA01D	GRM2165C1H182JA01D	GRM3195C2A182JA01D	
2200pF(222)	±5%(J)	GRM2165C2A222JA01D	GRM2165C1H222JA01D	GRM3195C2A222JA01D	
2700pF(272)	±5%(J)	GRM2165C2A272JA01D	GRM2165C1H272JA01D	GRM3195C2A272JA01D	
3300pF(332)	±5%(J)	GRM2165C2A332JA01D	GRM2165C1H332JA01D	GRM3195C2A332JA01D	
3900pF(392)	±5%(J)		GRM2165C1H392JA01D	GRM3195C2A392JA01D	
4700pF(472)	±5%(J)		GRM2165C1H472JA01D	GRM3195C2A472JA01D	GRM3195C1H472JA01D
5600pF(562)	±5%(J)		GRM2195C1H562JA01D	GRM3195C2A562JA01D	GRM3195C1H562JA01D
6800pF(682)	±5%(J)		GRM2195C1H682JA01D	GRM3195C2A682JA01D	GRM3195C1H682JA01D
8200pF(822)	±5%(J)		GRM2195C1H822JA01D	GRM3195C2A822JA01D	GRM3195C1H822JA01D
10000pF(103)	±5%(J)		GRM2195C1H103JA01D	GRM3195C2A103JA01D	GRM3195C1H103JA01D
12000pF(123)	±5%(J)		GRM2195C1H123JA01D		GRM3195C1H123JA01D
15000pF(153)	±5%(J)		GRM2195C1H153JA01D		GRM3195C1H153JA01D
18000pF(183)	±5%(J)				GRM3195C1H183JA01D
22000pF(223)	±5%(J)				GRM3195C1H223JA01D
27000pF(273)	±5%(J)				GRM3195C1H273JA01D
33000pF(333)	±5%(J)				GRM3195C1H333JA01D
39000pF(393)	±5%(J)				GRM3195C1H393JA01D
47000pF(473)	±5%(J)				GRM31M5C1H473JA01L
56000pF(563)	±5%(J)				GRM31M5C1H563JA01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

(Part Number) GR M 21 6 5C 2A 101 J A01 D ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩

① Product ID ② Series ③ Dimensions (LxW) ④ Dimension (T)
 ⑤ Temperature Characteristics ⑥ Rated Voltage ⑦ Capacitance
 ⑧ Capacitance Tolerance ⑨ Individual Specification Code ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

For General GRM Series
Array GNM Series
Low ESL LL Series
High-Q GJM Series
High Frequency GQM Series
Monolithic Microchip GMA Series
For Bonding GMD Series
Product Information

Temperature Compensating Type U2J(7U) Characteristics

LxW [mm]		0.6x0.3(03)<0201>		1.0x0.5(15)<0402>	
Rated Volt. [Vdc]		50(1H)	25(1E)	50(1H)	10(1A)
Capacitance	Tolerance	Part Number			
1.0pF(1R0)	±0.25pF(C)	GRM0337U1H1R0CD01D		GRM1557U1H1R0CZ01D	
2.0pF(2R0)	±0.25pF(C)	GRM0337U1H2R0CD01D		GRM1557U1H2R0CZ01D	
3.0pF(3R0)	±0.25pF(C)	GRM0337U1H3R0CD01D		GRM1557U1H3R0CZ01D	
4.0pF(4R0)	±0.25pF(C)	GRM0337U1H4R0CD01D		GRM1557U1H4R0CZ01D	
5.0pF(5R0)	±0.25pF(C)	GRM0337U1H5R0CD01D		GRM1557U1H5R0CZ01D	
6.0pF(6R0)	±0.5pF(D)	GRM0337U1H6R0DD01D		GRM1557U1H6R0DZ01D	
7.0pF(7R0)	±0.5pF(D)	GRM0337U1H7R0DD01D		GRM1557U1H7R0DZ01D	
8.0pF(8R0)	±0.5pF(D)	GRM0337U1H8R0DD01D		GRM1557U1H8R0DZ01D	
9.0pF(9R0)	±0.5pF(D)	GRM0337U1H9R0DD01D		GRM1557U1H9R0DZ01D	
10pF(100)	±5%(J)	GRM0337U1H100JD01D		GRM1557U1H100JZ01D	
12pF(120)	±5%(J)	GRM0337U1H120JD01D		GRM1557U1H120JZ01D	
15pF(150)	±5%(J)	GRM0337U1H150JD01D		GRM1557U1H150JZ01D	
18pF(180)	±5%(J)		GRM0337U1E180JD01D	GRM1557U1H180JZ01D	
22pF(220)	±5%(J)		GRM0337U1E220JD01D	GRM1557U1H220JZ01D	
27pF(270)	±5%(J)		GRM0337U1E270JD01D	GRM1557U1H270JZ01D	
33pF(330)	±5%(J)		GRM0337U1E330JD01D	GRM1557U1H330JZ01D	
39pF(390)	±5%(J)		GRM0337U1E390JD01D	GRM1557U1H390JZ01D	
47pF(470)	±5%(J)		GRM0337U1E470JD01D	GRM1557U1H470JZ01D	
56pF(560)	±5%(J)		GRM0337U1E560JD01D	GRM1557U1H560JZ01D	
68pF(680)	±5%(J)		GRM0337U1E680JD01D	GRM1557U1H680JZ01D	
82pF(820)	±5%(J)		GRM0337U1E820JD01D	GRM1557U1H820JZ01D	
100pF(101)	±5%(J)		GRM0337U1E101JD01D	GRM1557U1H101JZ01D	
120pF(121)	±5%(J)			GRM1557U1H121JZ01D	
150pF(151)	±5%(J)			GRM1557U1H151JZ01D	
180pF(181)	±5%(J)			GRM1557U1H181JZ01D	
1200pF(122)	±5%(J)				GRM1557U1A122JA01D
1500pF(152)	±5%(J)				GRM1557U1A152JA01D
1800pF(182)	±5%(J)				GRM1557U1A182JA01D
2200pF(222)	±5%(J)				GRM1557U1A222JA01D
2700pF(272)	±5%(J)				GRM1557U1A272JA01D
3300pF(332)	±5%(J)				GRM1557U1A332JA01D
3900pF(392)	±5%(J)				GRM1557U1A392JA01D
4700pF(472)	±5%(J)				GRM1557U1A472JA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type U2J(7U) Characteristics-Low Profile

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		50(1H)	10(1A)
Capacitance	Tolerance	Part Number	
2200pF(222)	±5%(J)	GRM1857U1H222JA44D	
2700pF(272)	±5%(J)	GRM1857U1H272JA44D	
3300pF(332)	±5%(J)	GRM1857U1H332JA44D	
3900pF(392)	±5%(J)	GRM1857U1H392JA44D	
4700pF(472)	±5%(J)	GRM1857U1H472JA44D	
5600pF(562)	±5%(J)	GRM1857U1A562JA44D	
6800pF(682)	±5%(J)	GRM1857U1A682JA44D	
8200pF(822)	±5%(J)	GRM1857U1A822JA44D	
10000pF(103)	±5%(J)	GRM1857U1A103JA44D	

LxW [mm]		2.0x1.25(21)<0805>		3.2x1.6(31)<1206>
Rated Volt. [Vdc]		50(1H)	10(1A)	50(1H)
Capacitance	Tolerance	Part Number		
10000pF(103)	±5%(J)	GRM2167U1H103JA01D		
12000pF(123)	±5%(J)	GRM2167U1H123JA01D		
15000pF(153)	±5%(J)	GRM2167U1H153JA01D		
18000pF(183)	±5%(J)	GRM2167U1H183JA01D		
22000pF(223)	±5%(J)	GRM2197U1H223JA01D		
27000pF(273)	±5%(J)	GRM2197U1H273JA01D		
33000pF(333)	±5%(J)	GRM21A7U1H333JA39L		
56000pF(563)	±5%(J)	GRM2197U1A563JA01D		GRM3197U1H563JA01D
68000pF(683)	±5%(J)			GRM31M7U1H683JA01L
82000pF(823)	±5%(J)			GRM31M7U1H823JA01L
100000pF(104)	±5%(J)			GRM31M7U1H104JA01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type S2H(6S), T2H(6T) Characteristics

TC		S2H		T2H	
LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>	0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	50(1H)	25(1E)	50(1H)
Capacitance	Tolerance	Part Number			
1.0pF(1R0)	±0.25pF(C)	GRM0336S1E1R0CD01D	GRM1556S1H1R0CD01D	GRM0336T1E1R0CD01D	GRM1556T1H1R0CD01D
2.0pF(2R0)	±0.25pF(C)	GRM0336S1E2R0CD01D	GRM1556S1H2R0CZ01D	GRM0336T1E2R0CD01D	GRM1556T1H2R0CD01D
3.0pF(3R0)	±0.25pF(C)	GRM0336S1E3R0CD01D	GRM1556S1H3R0CZ01D	GRM0336T1E3R0CD01D	GRM1556T1H3R0CD01D
4.0pF(4R0)	±0.25pF(C)	GRM0336S1E4R0CD01D	GRM1556S1H4R0CZ01D	GRM0336T1E4R0CD01D	GRM1556T1H4R0CD01D
5.0pF(5R0)	±0.25pF(C)	GRM0336S1E5R0CD01D	GRM1556S1H5R0CZ01D	GRM0336T1E5R0CD01D	GRM1556T1H5R0CD01D
6.0pF(6R0)	±0.5pF(D)	GRM0336S1E6R0DD01D	GRM1556S1H6R0DZ01D	GRM0336T1E6R0DD01D	GRM1556T1H6R0DD01D
7.0pF(7R0)	±0.5pF(D)	GRM0336S1E7R0DD01D	GRM1556S1H7R0DZ01D	GRM0336T1E7R0DD01D	GRM1556T1H7R0DD01D
8.0pF(8R0)	±0.5pF(D)	GRM0336S1E8R0DD01D	GRM1556S1H8R0DZ01D	GRM0336T1E8R0DD01D	GRM1556T1H8R0DD01D
9.0pF(9R0)	±0.5pF(D)	GRM0336S1E9R0DD01D	GRM1556S1H9R0DZ01D	GRM0336T1E9R0DD01D	GRM1556T1H9R0DD01D
10pF(100)	±5%(J)	GRM0336S1E100JD01D	GRM1556S1H100JZ01D	GRM0336T1E100JD01D	GRM1556T1H100JD01D
12pF(120)	±5%(J)	GRM0336S1E120JD01D	GRM1556S1H120JZ01D	GRM0336T1E120JD01D	GRM1556T1H120JD01D
15pF(150)	±5%(J)	GRM0336S1E150JD01D	GRM1556S1H150JZ01D	GRM0336T1E150JD01D	GRM1556T1H150JD01D
18pF(180)	±5%(J)	GRM0336S1E180JD01D	GRM1556S1H180JZ01D	GRM0336T1E180JD01D	GRM1556T1H180JD01D
22pF(220)	±5%(J)	GRM0336S1E220JD01D	GRM1556S1H220JZ01D	GRM0336T1E220JD01D	GRM1556T1H220JD01D
27pF(270)	±5%(J)	GRM0336S1E270JD01D	GRM1556S1H270JZ01D	GRM0336T1E270JD01D	GRM1556T1H270JD01D
33pF(330)	±5%(J)	GRM0336S1E330JD01D	GRM1556S1H330JZ01D	GRM0336T1E330JD01D	GRM1556T1H330JD01D
39pF(390)	±5%(J)	GRM0336S1E390JD01D	GRM1556S1H390JZ01D	GRM0336T1E390JD01D	GRM1556T1H390JD01D
47pF(470)	±5%(J)	GRM0336S1E470JD01D		GRM0336T1E470JD01D	GRM1556T1H470JD01D
56pF(560)	±5%(J)	GRM0336S1E560JD01D		GRM0336T1E560JD01D	GRM1556T1H560JD01D
68pF(680)	±5%(J)	GRM0336S1E680JD01D		GRM0336T1E680JD01D	GRM1556T1H680JD01D
82pF(820)	±5%(J)	GRM0336S1E820JD01D		GRM0336T1E820JD01D	GRM1556T1H820JD01D
100pF(101)	±5%(J)	GRM0336S1E101JD01D		GRM0336T1E101JD01D	GRM1556T1H101JD01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

High Dielectric Constant Type X7R(R7) Characteristics

LxW [mm]		1.0x0.5(15)<0402>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
220pF(221)	±10%(K)	GRM155R72A221KA01D	GRM155R71H221KA01D		
330pF(331)	±10%(K)	GRM155R72A331KA01D	GRM155R71H331KA01D		
470pF(471)	±10%(K)	GRM155R72A471KA01D	GRM155R71H471KA01D		
680pF(681)	±10%(K)	GRM155R72A681KA01D	GRM155R71H681KA01D		
1000pF(102)	±10%(K)	GRM155R72A102KA01D	GRM155R71H102KA01D		
1500pF(152)	±10%(K)	GRM155R72A152KA01D	GRM155R71H152KA01D		
2200pF(222)	±10%(K)	GRM155R72A222KA01D	GRM155R71H222KA01D		
3300pF(332)	±10%(K)	GRM155R72A332KA01D	GRM155R71H332KA01D		
4700pF(472)	±10%(K)	GRM155R72A472KA01D	GRM155R71H472KA01D	GRM155R71E472KA01D	
6800pF(682)	±10%(K)		GRM155R71H682KA88D	GRM155R71E682KA01D	
10000pF(103)	±10%(K)		GRM155R71H103KA88D	GRM155R71E103KA01D	
15000pF(153)	±10%(K)		GRM155R71H153KA12D	GRM155R71E153KA61D	GRM155R71C153KA01D
22000pF(223)	±10%(K)		GRM155R71H223KA12D	GRM155R71E223KA61D	GRM155R71C223KA01D
33000pF(333)	±10%(K)			GRM155R71E333KA88D	GRM155R71C333KA01D
47000pF(473)	±10%(K)			GRM155R71E473KA88D	GRM155R71C473KA01D
68000pF(683)	±10%(K)				GRM155R71C683KA88D
0.10μF(104)	±10%(K)				GRM155R71C104KA88D
0.15μF(154)	±10%(K)				GRM155R71C154KA12D*
0.22μF(224)	±10%(K)				GRM155R71C224KA12D*

LxW [mm]		1.0x0.5(15)<0402>
Rated Volt. [Vdc]		10(1A)
Capacitance	Tolerance	Part Number
68000pF(683)	±10%(K)	GRM155R71A683KA01D
0.10μF(104)	±10%(K)	GRM155R71A104KA01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code
 * Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GJM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X7R(R7)/X7U(E7) Characteristics

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
6800pF(682)	±10%(K)	GRM219R72A682KA01D			
10000pF(103)	±10%(K)	GRM21BR72A103KA01L			
15000pF(153)	±10%(K)	GRM21BR72A153KA01L			
22000pF(223)	±10%(K)	GRM21BR72A223KA01L			
33000pF(333)	±10%(K)	GRM21BR72A333KA01L	GRM219R71H333KA01D		
47000pF(473)	±10%(K)	GRM21BR72A473KA01L	GRM21BR71H473KA01L		
68000pF(683)	±10%(K)		GRM21BR71H683KA01L	GRM219R71E683KA01D	
0.10μF(104)	±10%(K)		GRM21BR71H104KA01L	GRM21BR71E104KA01L	
0.15μF(154)	±10%(K)		GRM21BR71H154KA01L	GRM21BR71E154KA01L	
0.22μF(224)	±10%(K)	GRM21AR72A224KAC5L	GRM21BR71H224KA01L	GRM21BR71E224KA01L	
0.33μF(334)	±10%(K)	GRM21AR72A334KAC5L	GRM219R71H334KA88D	GRM21BR71E334KA01L	
0.47μF(474)	±10%(K)	GRM21BR72A474KA73L	GRM21BR71H474KA88L	GRM219R71E474KA88D	
0.68μF(684)	±10%(K)			GRM219R71E684KA88D	GRM219R71C684KA01D
1.0μF(105)	±10%(K)		GRM21BR71H105KA12L	GRM21BR71E105KA99L GRM219R71E105KA88D	GRM21BR71C105KA01L
2.2μF(225)	±10%(K)			GRM21BR71E225KA73L*	GRM21BR71C225KA12L
4.7μF(475)	±10%(K)				GRM21BR71C475KA73L*

LxW [mm]		2.0x1.25(21)<0805>		
Rated Volt. [Vdc]		10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
2.2μF(225)	±10%(K)	GRM21BR71A225KA01L		
4.7μF(475)	±10%(K)	GRM21BR71A475KA73L*		
10μF(106)	±10%(K)	GRM21BR71A106KE51L*	GRM21BR70J106KE76L*	
22μF(226)	±20%(M)			GRM21BE70G226ME51L*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X7R(R7)/X7T(D7) Characteristics-Low Profile

LxW [mm]		1.0x0.5(15)<0402>			1.6x0.8(18)<0603>
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
220pF(221)	±10%(K)	GRM15XR71H221KA86D			
330pF(331)	±10%(K)	GRM15XR71H331KA86D			
470pF(471)	±10%(K)	GRM15XR71H471KA86D			
680pF(681)	±10%(K)	GRM15XR71H681KA86D			
1000pF(102)	±10%(K)	GRM15XR71H102KA86D			
1500pF(152)	±10%(K)	GRM15XR71H152KA86D			
2200pF(222)	±10%(K)		GRM15XR71E222KA86D		
3300pF(332)	±10%(K)			GRM15XR71C332KA86D	
4700pF(472)	±10%(K)			GRM15XR71C472KA86D	
6800pF(682)	±10%(K)			GRM15XR71C682KA86D	
10000pF(103)	±10%(K)			GRM15XR71C103KA86D	
1.0μF(105)	±10%(K)				GRM185D71A105KE36D*

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
6800pF(682)	±10%(K)	GRM219R72A682KA01D			
33000pF(333)	±10%(K)		GRM219R71H333KA01D		
68000pF(683)	±10%(K)			GRM219R71E683KA01D	
0.22μF(224)	±10%(K)	GRM21AR72A224KAC5L			
0.33μF(334)	±10%(K)	GRM21AR72A334KAC5L	GRM219R71H334KA88D		
0.47μF(474)	±10%(K)			GRM219R71E474KA88D	
0.68μF(684)	±10%(K)			GRM219R71E684KA88D	GRM219R71C684KA01D
1.0μF(105)	±10%(K)			GRM219R71E105KA88D	

LxW [mm]		3.2x1.6(31)<1206>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
15000pF(153)	±10%(K)	GRM319R72A153KA01L			
22000pF(223)	±10%(K)	GRM31MR72A223KA01L			
33000pF(333)	±10%(K)	GRM31MR72A333KA01L			
47000pF(473)	±10%(K)	GRM31MR72A473KA01L			
68000pF(683)	±10%(K)	GRM31MR72A683KA01L			
0.10μF(104)	±10%(K)	GRM319R72A104KA01D			
0.15μF(154)	±10%(K)	GRM31MR72A154KA01L	GRM31MR71H154KA01L		
0.22μF(224)	±10%(K)	GRM31MR72A224KA01L	GRM31MR71H224KA01L		
0.33μF(334)	±10%(K)		GRM319R71H334KA01D		
0.47μF(474)	±10%(K)	GRM31MR72A474KA35L	GRM31MR71H474KA01L		
0.68μF(684)	±10%(K)	GRM31MR72A684KA35L	GRM31MR71H684KA88L		
1.0μF(105)	±10%(K)		GRM31MR71H105KA88L		
2.2μF(225)	±10%(K)			GRM31MR71E225KA93L	GRM31MR71C225KA35L
4.7μF(475)	±10%(K)				GRM319D71C475KA12D**

LxW [mm]		3.2x2.5(32)<1210>	
Rated Volt. [Vdc]		100(2A)	50(1H)
Capacitance	Tolerance	Part Number	
0.68μF(684)	±10%(K)	GRM32CR72A684KA01L	GRM32NR71H684KA01L
1.0μF(105)	±10%(K)	GRM32CR72A105KA35L	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GRM Series Specifications and Test Method (2).

** These Part Numbers have individual testing conditions on Durability of GRM Series Specifications and Test Methods (2). Please refer to P60.

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X6S(C8) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	
Rated Volt. [Vdc]		6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number	
15000pF(153)	±10%(K)	GRM033C80J153KE01D*	GRM033C80G153KE01D*
22000pF(223)	±10%(K)	GRM033C80J223KE01D*	GRM033C80G223KE01D*
33000pF(333)	±10%(K)	GRM033C80J333KE01D*	GRM033C80G333KE01D*
47000pF(473)	±10%(K)	GRM033C80J473KE19D*	GRM033C80G473KE01D*

LxW [mm]		1.0x0.5(15)<0402>		
Rated Volt. [Vdc]		25(1E)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
68000pF(683)	±10%(K)	GRM155C81E683KA12D		
0.10μF(104)	±10%(K)	GRM155C81E104KA12D		
0.15μF(154)	±10%(K)		GRM155C80J154KE01D*	GRM155C80G154KE01D*
0.22μF(224)	±10%(K)		GRM155C80J224KE01D*	GRM155C80G224KE01D*
0.33μF(334)	±10%(K)		GRM155C80J334KE01D*	GRM155C80G334KE01D*
0.47μF(474)	±10%(K)		GRM155C80J474KE19D*	GRM155C80G474KE01D*
0.68μF(684)	±10%(K)		GRM155C80J684KE15D**	GRM155C80G684KE19D*

LxW [mm]		1.6x0.8(18)<0603>			
Rated Volt. [Vdc]		25(1E)	10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number			
1.0μF(105)	±10%(K)	GRM188C81E105KAADD			
2.2μF(225)	±10%(K)		GRM188C81A225KE34D*	GRM188C80J225KE19D*	
4.7μF(475)	±10%(K)				GRM188C80G475KE19D*
10μF(106)	±20%(M)				GRM188C80G106ME47D**

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		2.5(0E)	
Capacitance	Tolerance	Part Number	
10μF(106)	±20%(M)	GRM188C80E106ME47D*	

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		25(1E)	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
1.0μF(105)	±10%(K)		GRM216C81C105KA12D*		
2.2μF(225)	±10%(K)		GRM219C81C225KA12D*		
4.7μF(475)	±10%(K)	GRM21BC81E475KA12L*	GRM21BC81C475KA88L*	GRM219C81A475KE34D*	GRM219C80J475KE19D*
10μF(106)	±10%(K)			GRM21BC81A106KE18L*	GRM21BC80J106KE19L*
					GRM219C80J106KE39D*
22μF(226)	±20%(M)				GRM21BC80J226ME51L**

LxW [mm]		2.0x1.25(21)<0805>	
Rated Volt. [Vdc]		4(0G)	
Capacitance	Tolerance	Part Number	
22μF(226)	±20%(M)	GRM21BC80G226ME39L*	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GRM Series Specifications and Test Method (2).

These Part Numbers have individual testing conditions on Durability of GRM Series Specifications and Test Methods (2). Please refer to P60.

(Part Number) **GR M 03 3 C8 0J 153 K E01 D** ①Product ID ②Series ③Dimensions (LxW) ④Dimension (T)
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

High Dielectric Constant Type X6S(C8)/X6T(D8) Characteristics

LxW [mm]		3.2x1.6(31)<1206>			
Rated Volt. [Vdc]		25(1E)	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
2.2μF(225)	±10%(K)		GRM316C81C225KA12D*		
4.7μF(475)	±10%(K)		GRM319C81C475KA12D*		
10μF(106)	±10%(K)	GRM31CC81E106KE15L*	GRM31MC81C106KA12L	GRM319C81A106KA12D	GRM319C80J106KE19D*
22μF(226)	±20%(M)			GRM31CC81A226ME19L*	GRM31CC80J226ME19L*
47μF(476)	±20%(M)				GRM31CC80J476ME18L*

LxW [mm]		3.2x1.6(31)<1206>	
Rated Volt. [Vdc]		4(0G)	
Capacitance	Tolerance	Part Number	
47μF(476)	±20%(M)	GRM31CC80G476ME19L*	
100μF(107)	±20%(M)	GRM31CD80G107ME39L*	

LxW [mm]		3.2x2.5(32)<1210>			
Rated Volt. [Vdc]		25(1E)	10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number			
10μF(106)	±10%(K)	GRM32DC81E106KA12L			
22μF(226)	±20%(M)	GRM32EC81E226ME15L*	GRM32NC81A226ME19L*		
47μF(476)	±20%(M)		GRM32EC81A476ME19L*	GRM32EC80J476ME64L*	
100μF(107)	±20%(M)			GRM32EC80J107ME20L*	GRM32EC80G107ME20L*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

*: Please refer to GRM Series Specifications and Test Method(2).

High Dielectric Constant Type X6S(C8) Characteristics-Low Profile

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number	
1.0μF(105)	±10%(K)	GRM185C81A105KE36D*	GRM185C80J105KE26D*

LxW [mm]		2.0x1.25(21)<0805>		
Rated Volt. [Vdc]		16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number		
1.0μF(105)	±10%(K)	GRM216C81C105KA12D*		
2.2μF(225)	±10%(K)	GRM219C81C225KA12D*		
4.7μF(475)	±10%(K)		GRM219C81A475KE34D*	GRM219C80J475KE19D*
10μF(106)	±10%(K)			GRM219C80J106KE39D*

LxW [mm]		3.2x1.6(31)<1206>	
Rated Volt. [Vdc]		16(1C)	
Capacitance	Tolerance	Part Number	
2.2μF(225)	±10%(K)	GRM316C81C225KA12D*	
4.7μF(475)	±10%(K)	GRM319C81C475KA12D*	

LxW [mm]		3.2x2.5(32)<1210>	
Rated Volt. [Vdc]		25(1E)	
Capacitance	Tolerance	Part Number	
10μF(106)	±10%(K)	GRM32DC81E106KA12L	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X5R(R) Characteristics

LxW [mm]		1.0x0.5(15)<0402>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
220pF(221)	±10%(K)				
330pF(331)	±10%(K)				
470pF(471)	±10%(K)				
680pF(681)	±10%(K)				
1000pF(102)	±10%(K)		GRM155R61H102KA01D		
1500pF(152)	±10%(K)				
2200pF(222)	±10%(K)		GRM155R61H222KA01D		
3300pF(332)	±10%(K)				
4700pF(472)	±10%(K)		GRM155R61H472KA01D		
6800pF(682)	±10%(K)				
10000pF(103)	±10%(K)				
15000pF(153)	±10%(K)				
22000pF(223)	±10%(K)				GRM155R61C223KA01D
33000pF(333)	±10%(K)				GRM155R61C333KA01D
47000pF(473)	±10%(K)				GRM155R61C473KA01D
68000pF(683)	±10%(K)			GRM155R61E683KA87D	GRM155R61C683KA88D
0.10μF(104)	±10%(K)			GRM155R61E104KA87D	GRM155R61C104KA88D

LxW [mm]		1.0x0.5(15)<0402>	
Rated Volt. [Vdc]		10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number	
33000pF(333)	±10%(K)	GRM155R61A333KA01D	
47000pF(473)	±10%(K)	GRM155R61A473KA01D	
68000pF(683)	±10%(K)	GRM155R61A683KA01D	
0.10μF(104)	±10%(K)	GRM155R61A104KA01D	
0.15μF(154)	±10%(K)	GRM155R61A154KE19D*	GRM155R60J154KE01D*
0.22μF(224)	±10%(K)	GRM155R61A224KE19D*	GRM155R60J224KE01D*
0.33μF(334)	±10%(K)	GRM155R61A334KE15D*	GRM155R60J334KE01D*
0.47μF(474)	±10%(K)	GRM155R61A474KE15D*	GRM155R60J474KE19D*
0.68μF(684)	±10%(K)	GRM155R61A684KE15D*	GRM155R60J684KE19D*
1.0μF(105)	±10%(K)	GRM155R61A105KE15D*	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

□: Please refer to X7R(R7) etc. Characteristics.

* Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GNM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X5R(R6) Characteristics

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
6800pF(682)	±10%(K)				
10000pF(103)	±10%(K)				
15000pF(153)	±10%(K)				
22000pF(223)	±10%(K)				
33000pF(333)	±10%(K)				
47000pF(473)	±10%(K)				
68000pF(683)	±10%(K)				
0.10μF(104)	±10%(K)				
0.15μF(154)	±10%(K)				
0.22μF(224)	±10%(K)				
0.33μF(334)	±10%(K)				
0.47μF(474)	±10%(K)				
0.68μF(684)	±10%(K)				
1.0μF(105)	±10%(K)			GRM216R61E105KA12D	GRM21BR61C105KA01L GRM216R61C105KA88D*
2.2μF(225)	±10%(K)			GRM21BR61E225KA12L GRM219R61E225KA12D*	GRM21BR61C225KA88L* GRM219R61C225KA88D*
4.7μF(475)	±10%(K)			GRM21BR61E475KA12L*	GRM21BR61C475KA88L* GRM219R61C475KE15D*
10μF(106)	±10%(K)				GRM21BR61C106KE15L*

LxW [mm]		2.0x1.25(21)<0805>		
Rated Volt. [Vdc]		10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
2.2μF(225)	±10%(K)	GRM21BR61A225KA01L		
4.7μF(475)	±10%(K)	GRM21BR61A475KA73L* GRM219R61A475KE34D*	GRM21BR60J475KA11L*	
10μF(106)	±10%(K)	GRM21BR61A106KE19L* GRM219R61A106KE44D*	GRM21BR60J106KE19L* GRM219R60J106KE19D*	
22μF(226)	±20%(M)		GRM21BR60J226ME39L*	GRM219R60G226ME66D*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

□: Please refer to X7R(R7) etc. Characteristics.

* Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GNM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X5R(R6) Characteristics

LxW [mm]		3.2x1.6(31)<1206>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
15000pF(153)	±10%(K)				
22000pF(223)	±10%(K)				
33000pF(333)	±10%(K)				
47000pF(473)	±10%(K)				
68000pF(683)	±10%(K)				
0.10μF(104)	±10%(K)				
0.15μF(154)	±10%(K)				
0.22μF(224)	±10%(K)				
0.33μF(334)	±10%(K)				
0.47μF(474)	±10%(K)				
0.68μF(684)	±10%(K)				
1.0μF(105)	±10%(K)				
2.2μF(225)	±10%(K)		GRM31CR61H225KA88L	GRM316R61E225KA12D*	
4.7μF(475)	±10%(K)			GRM31CR61E475KA88L	GRM31CR61C475KA01L
				GRM319R61E475KA12D*	GRM319R61C475KA88D*
10μF(106)	±10%(K)			GRM31CR61E106KA12L*	GRM31CR61C106KA88L
					GRM319R61C106KE15D*
22μF(226)	±20%(M)				GRM31CR61C226ME15L*

LxW [mm]		3.2x1.6(31)<1206>		
Rated Volt. [Vdc]		10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
10μF(106)	±10%(K)	GRM319R61A106KE19L*		
22μF(226)	±20%(M)	GRM31CR61A226ME19L*	GRM31CR60J226ME19L*	
47μF(476)	±20%(M)	GRM31CR61A476ME15L*	GRM31CR60J476ME19L*	
100μF(107)	±20%(M)		GRM31CR60J107ME39L*	GRM31CR60G107ME39L*

LxW [mm]		3.2x2.5(32)<1210>			
Rated Volt. [Vdc]		100(2A)	50(1H)	35(YA)	25(1E)
Capacitance	Tolerance	Part Number			
0.68μF(684)	±10%(K)				
1.0μF(105)	±10%(K)				
2.2μF(225)	±10%(K)				
4.7μF(475)	±10%(K)				
10μF(106)	±10%(K)			GRM32ER6YA106KA12L	GRM32DR61E106KA12L
22μF(226)	±20%(M)				GRM32ER61E226ME15L*

LxW [mm]		3.2x2.5(32)<1210>		
Rated Volt. [Vdc]		16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number		
22μF(226)	±20%(M)			
47μF(476)	±20%(M)	GRM32ER61C476ME15L*	GRM32ER61A476ME20L*	
100μF(107)	±20%(M)			GRM32ER60J107ME20L*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

□ : Please refer to X7R(R7) etc. Characteristics.

* Please refer to GRM Series Specifications and Test Method (2).

(Part Number) **GR M 31 C R6 1H 225 K A88 L** ①Product ID ②Series ③Dimensions (LxW) ④Dimension (T)
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

High Dielectric Constant Type X5R(R6) Characteristics-Low Profile

LxW [mm]		1.0x0.5(15)<0402>		
Rated Volt. [Vdc]		16(1C)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number		
220pF(221)	±10%(K)			
330pF(331)	±10%(K)			
470pF(471)	±10%(K)			
680pF(681)	±10%(K)			
1000pF(102)	±10%(K)			
1500pF(152)	±10%(K)			
2200pF(222)	±10%(K)			
3300pF(332)	±10%(K)			
4700pF(472)	±10%(K)			
6800pF(682)	±10%(K)			
10000pF(103)	±10%(K)			

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		16(1C)	10(1A)
Capacitance	Tolerance	Part Number	
1.0μF(105)	±10%(K)	GRM185R61C105KE44D*	GRM185R61A105KE36D*

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
6800pF(682)	±10%(K)				
33000pF(333)	±10%(K)				
68000pF(683)	±10%(K)				
0.22μF(224)	±10%(K)				
0.33μF(334)	±10%(K)				
0.47μF(474)	±10%(K)				
0.68μF(684)	±10%(K)				
1.0μF(105)	±10%(K)			GRM216R61E105KA12D	GRM216R61C105KA88D
2.2μF(225)	±10%(K)			GRM219R61E225KA12D*	GRM219R61C225KA88D*
4.7μF(475)	±10%(K)				GRM219R61C475KE15D*

LxW [mm]		2.0x1.25(21)<0805>		
Rated Volt. [Vdc]		10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
4.7μF(475)	±10%(K)	GRM219R61A475KE34D*		
10μF(106)	±10%(K)	GRM219R61A106KE44D*	GRM219R60J106KE19D*	
22μF(226)	±20%(M)			GRM219R60G226ME66D*

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

□: Please refer to X7R(R7) etc. Characteristics.

* Please refer to GRM Series Specifications and Test Method (2).

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

High Dielectric Constant Type X5R(R6) Characteristics-Low Profile

LxW [mm]		3.2x1.6(31)<1206>			
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number			
15000pF(153)	±10%(K)				
22000pF(223)	±10%(K)				
33000pF(333)	±10%(K)				
47000pF(473)	±10%(K)				
68000pF(683)	±10%(K)				
0.10μF(104)	±10%(K)				
0.15μF(154)	±10%(K)				
0.22μF(224)	±10%(K)				
0.33μF(334)	±10%(K)				
0.47μF(474)	±10%(K)				
0.68μF(684)	±10%(K)				
1.0μF(105)	±10%(K)				
2.2μF(225)	±10%(K)			GRM316R61E225KA12D*	
4.7μF(475)	±10%(K)			GRM319R61E475KA12D*	GRM319R61C475KA88D*
10μF(106)	±10%(K)				GRM319R61C106KE15D*

LxW [mm]		3.2x1.6(31)<1206>
Rated Volt. [Vdc]		10(1A)
Capacitance	Tolerance	Part Number
10μF(106)	±10%(K)	GRM319R61A106KE19D*

LxW [mm]		3.2x2.5(32)<1210>		
Rated Volt. [Vdc]		100(2A)	50(1H)	25(1E)
Capacitance	Tolerance	Part Number		
0.68μF(684)	±10%(K)			
1.0μF(105)	±10%(K)			
10μF(106)	±10%(K)			GRM32DR61E106KA12L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

[] : Please refer to X7R(R7) etc. Characteristics.

* Please refer to GRM Series Specifications and Test Method (2).

(Part Number) **GR** **M** **31** **6** **R6** **1E** **225** **K** **A12** **D** ① Product ID ② Series ③ Dimensions (LxW) ④ Dimension (T)
 ⑤ Temperature Characteristics ⑥ Rated Voltage ⑦ Capacitance
 ⑧ Capacitance Tolerance ⑨ Individual Specification Code ⑩ Packaging


Packaging Code in Part Number shows STD 180mm Reel Taping.

GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

(Note 1) These Specifications and Test Methods indicate typical inspection. Please refer to individual specifications (our product specifications or the approval sheet).
 When no "***" is added in PNs table, please refer to GRM Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GRM Series Specifications and Test Methods (2).

No.	Item	Specifications		Test Method
		Temperature Compensating Type	High Dielectric Type	
1	Operating Temperature Range	-55 to +125°C (2P/R/S/T, 3P/R/S/T/U, 4P/R/S/T/U: -25 to +85°C)	B1, B3, F1: -25 to +85°C R1, R7: -55 to +125°C R6: -55 to +85°C C8: -55 to +105°C E4: +10 to +85°C F5: -30 to +85°C	Reference temperature: 25°C (2Δ, 3Δ, 4Δ, B1, B3, F1, R1: 20°C)
2	Rated Voltage	See the previous pages.		The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.
3	Appearance	No defects or abnormalities		Visual inspection
4	Dimensions	Within the specified dimensions		Using calipers (GRM02 size is based on Microscope)
5	Dielectric Strength	No defects or abnormalities		No failure should be observed when 300%* of the rated voltage (temperature compensating type) or 250% of the rated voltage (high dielectric constant type) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *200% for 500V
6	Insulation Resistance	C≤0.047μF: More than 10,000MΩ C>0.047μF: More than 500Ω · F C: Nominal Capacitance		The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 20/25°C and 75%RH max. and within 2 minutes of charging, provided the charge/discharge current is less than 50mA.
7	Capacitance	Within the specified tolerance		The capacitance/Q/D.F. should be measured at 20/25°C at the frequency and voltage shown in the table.
8	Q/ Dissipation Factor (D.F.)	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.025 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.	

Char.	ΔC to 7U, 1X (1000pF and below)	ΔC to 7U, 1X (more than 1000pF) R6, R7, C8, F5, B1, B3, F1	R6, R7, F5 (C>10μF)	E4
Item				
Frequency	1±0.1MHz	1±0.1kHz	120±24Hz	1±0.1kHz
Voltage	0.5 to 5Vrms	1±0.2Vrms	0.5±0.1Vrms	0.5±0.05Vrms

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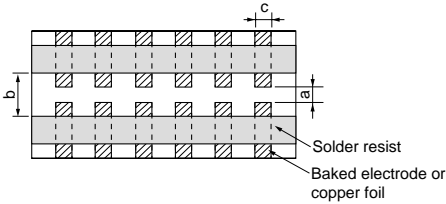
For General GRM Series
Array GNM Series
Low ESL LL□ Series
High-Q GJM Series
High Frequency GOM Series
Monolithic Microchip GMA Series
For Bonding GMD Series
Product Information

GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

(Note 1) These Specifications and Test Methods indicate typical inspection.

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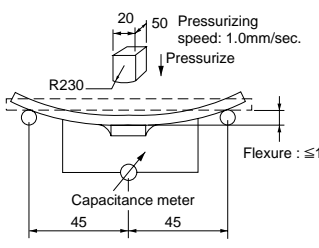
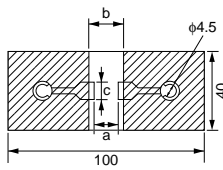
No.	Item	Specifications		Test Method																																						
		Temperature Compensating Type	High Dielectric Type																																							
9	Capacitance Temperature Characteristics	No bias	B1, B3: Within $\pm 10\%$ (-25 to +85°C) R1, R7: Within $\pm 15\%$ (-55 to +125°C) R6: Within $\pm 15\%$ (-55 to +85°C) E4: Within +22/-56% (+10 to +85°C) F1: Within +30/-80% (-25 to +85°C) F5: Within +22/-82% (-30 to +85°C) C8: Within $\pm 22\%$ (-55 to +105°C)	The capacitance change should be measured after 5 min. at each specified temp. stage. (1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from steps 1 through 5 (5C: +25 to +125°C/ Δ C: +20 to +125°C: other temp. coeffs.: +25 to +85°C/+20 to +85°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as in Table A-1. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the steps 1, 3 and 5 by the cap. value in step 3.																																						
		50% of the Rated Voltage	B1: Within +10/-30% R1: Within +15/-40% F1: Within +30/-95%																																							
		Capacitance Drift	Within $\pm 0.2\%$ or $\pm 0.05\text{pF}$ (whichever is larger.) *Do not apply to 1X/25V		*Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour and then set for 24 \pm 2 hours at room temperature. Perform the initial measurement.																																					
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.		Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1a using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10 \pm 1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *1N (GRM02), 2N (GRM03), 5N (GRM15, GRM18)																																						
		 <p>Fig. 1a</p>			<table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GRM02</td> <td>0.2</td> <td>0.56</td> <td>0.23</td> </tr> <tr> <td>GRM03</td> <td>0.3</td> <td>0.9</td> <td>0.3</td> </tr> <tr> <td>GRM15</td> <td>0.4</td> <td>1.5</td> <td>0.5</td> </tr> <tr> <td>GRM18</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> </tr> <tr> <td>GRM21</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>GRM31</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>GRM32</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>GRM43</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>GRM55</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table>	Type	a	b	c	GRM02	0.2	0.56	0.23	GRM03	0.3	0.9	0.3	GRM15	0.4	1.5	0.5	GRM18	1.0	3.0	1.2	GRM21	1.2	4.0	1.65	GRM31	2.2	5.0	2.0	GRM32	2.2	5.0	2.9	GRM43	3.5	7.0	3.7	GRM55
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GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

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Continued from the preceding page.

No.	Item	Specifications		Test Method																																								
		Temperature Compensating Type	High Dielectric Type																																									
11	Appearance	No defects or abnormalities		Solder the capacitor on the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																																								
	Capacitance	Within the specified tolerance																																										
11	Vibration Resistance	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF)																																										
	Q/D.F.	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)																																										
12	Appearance	No marking defects		Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2a using a eutectic solder. Then apply a force in the direction shown in Fig. 3a for 5±1 sec. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																																								
	Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	Within ±10%																																									
12	Deflection	 <p>Fig. 3a</p>		 <p>Fig. 2a</p> <p>t: 1.6mm (GRM02/03/15: t: 0.8mm)</p> <table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GRM02</td> <td>0.2</td> <td>0.56</td> <td>0.23</td> </tr> <tr> <td>GRM03</td> <td>0.3</td> <td>0.9</td> <td>0.3</td> </tr> <tr> <td>GRM15</td> <td>0.4</td> <td>1.5</td> <td>0.5</td> </tr> <tr> <td>GRM18</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> </tr> <tr> <td>GRM21</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>GRM31</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>GRM32</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>GRM43</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>GRM55</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table> <p>(in mm)</p>	Type	a	b	c	GRM02	0.2	0.56	0.23	GRM03	0.3	0.9	0.3	GRM15	0.4	1.5	0.5	GRM18	1.0	3.0	1.2	GRM21	1.2	4.0	1.65	GRM31	2.2	5.0	2.0	GRM32	2.2	5.0	2.9	GRM43	3.5	7.0	3.7	GRM55	4.5	8.0	5.6
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13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in a eutectic solder solution for 2±0.5 seconds at 230±5°C or Sn-3.0Ag-0.5Cu solder solution for 2±0.5 seconds at 245±5°C.																																								

Continued on the following page. 

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

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Continued from the preceding page.

No.	Item	Specifications		Test Method															
		Temperature Compensating Type	High Dielectric Type																
14		The measured and observed characteristics should satisfy the specifications in the following table.		Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at 270±5°C for 10±0.5 seconds. Set at room temperature for 24±2 hours, then measure. •Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour and then set at room temperature for 24±2 hours. Perform the initial measurement. •Preheating for GRM32/43/55															
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
	Resistance to Soldering Heat	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.025 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																
	Q/D.F.																		
	I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																	
15		The measured and observed characteristics should satisfy the specifications in the following table.		Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments shown in the following table. Set for 24±2 hours at room temperature, then measure.															
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
	Temperature Cycle	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																
	Q/D.F.																		
	I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																	
15		The measured and observed characteristics should satisfy the specifications in the following table.		Perform the initial measurement. •Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour and then set at room temperature for 24±2 hours. Perform the initial measurement.															
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
	Temperature Cycle	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																
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15		The measured and observed characteristics should satisfy the specifications in the following table.		<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.						
	Step	Temperature	Time																
	1	100 to 120°C	1 min.																
	2	170 to 200°C	1 min.																
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
Temperature Cycle	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																	
Q/D.F.																			
I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																		
15		The measured and observed characteristics should satisfy the specifications in the following table.		<table border="1"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3
	Step	1	2		3	4													
	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.		Max. Operating Temp. +3/-0	Room Temp.													
	Time (min.)	30±3	2 to 3		30±3	2 to 3													
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
Temperature Cycle	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																	
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I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																		
15		The measured and observed characteristics should satisfy the specifications in the following table.		Perform the initial measurement.															
	Appearance	No defects or abnormalities																	
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	B1, B3, R1, R6, R7, C8: Within ±7.5% F1, F5, E4: Within ±20%																
	Temperature Cycle	30pF and over: Q≥1000 30pF and below: Q≥400+20C C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.025 max. (C<0.068μF) : 0.05 max. (C≥0.068μF) W.V.: 50/35/25V: : 0.025 max.* *GRM32D R7/R6/C8 1E106: 0.035 max. W.V.: 16/10V: 0.035 max. W.V.: 6.3/4V : 0.05 max. (C<3.3μF) : 0.1 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.05 max. (C<0.1μF) : 0.09 max. (C≥0.1μF) W.V.: 16/10V: 0.125 max. W.V.: 6.3V: 0.15 max.																
	Q/D.F.																		
	I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																	

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GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

(Note 1) These Specifications and Test Methods indicate typical inspection.
 Please refer to individual specifications (our product specifications or the approval sheet).
 When no "*" is added in PNs table, please refer to GRM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GRM Series Specifications and Test Methods (2).

Continued from the preceding page.

No.	Item	Specifications		Test Method	
		Temperature Compensating Type	High Dielectric Type		
16	Humidity (Steady State)	The measured and observed characteristics should satisfy the specifications in the following table.		Set the capacitor at 40±2°C and in 90 to 95% humidity for 500±12 hours. Remove and set for 24±2 hours at room temperature, then measure.	
		Appearance	No defects or abnormalities		
		Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)		B1, B3, R1, R6, R7, C8: Within ±12.5% F1, F5, E4: Within ±30%
		Q/D.F.	30pF and over: Q≥350 10pF and over: Q≥275+2.5C 30pF and below: Q≥200+10C C: Nominal Capacitance (pF)		[R6, R7, C8] W.V.: 100V : 0.05 max. (C<0.068μF) : 0.075 max. (C≥0.068μF) W.V.: 50/35/25/16/10V : 0.05 max. W.V.: 6.3/4V : 0.075 max. (C<3.3μF) : 0.125 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.075 max. (C<0.1μF) : 0.125 max. (C≥0.1μF) W.V.: 16/10V: 0.15 max. W.V.: 6.3V: 0.2 max.
		I.R.	More than 1,000MΩ or 50Ω · F (whichever is smaller)		
17	Humidity Load	The measured and observed characteristics should satisfy the specifications in the following table.		Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and set for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. •Initial measurement for F1, F5/10V max. Apply the rated DC voltage for 1 hour at 40±2°C. Remove and set for 24±2 hours at room temperature. Perform initial measurement.	
		Appearance	No defects or abnormalities		
		Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)		B1, B3, R1, R6, R7, C8: Within ±12.5% F1, F5, E4: Within ±30% [W.V.: 10V max.] F1, F5: Within +30/-40%
		Q/D.F.	30pF and over: Q≥200 30pF and below: Q≥100+10C/3 C: Nominal Capacitance (pF)		[B1, B3, R6, R7, C8] W.V.: 100V : 0.05 max. (C<0.068μF) : 0.075 max. (C≥0.068μF) W.V.: 50/35/25/16/10V : 0.05 max. W.V.: 6.3/4V : 0.075 max. (C<3.3μF) : 0.125 max. (C≥3.3μF) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.075 max. (C<0.1μF) : 0.125 max. (C≥0.1μF) W.V.: 16/10V: 0.15 max. W.V.: 6.3V: 0.2 max.
		I.R.	More than 500MΩ or 25Ω · F (whichever is smaller)		

Continued on the following page. ↗

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GRM Series Specifications and Test Methods (1) (Note 1)-Typical Inspection

(Note 1) These Specifications and Test Methods indicate typical inspection.

Please refer to individual specifications (our product specifications or the approval sheet).
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Continued from the preceding page.

No.	Item	Specifications		Test Method
		Temperature Compensating Type	High Dielectric Type	
18		The measured and observed characteristics should satisfy the specifications in the following table.		Apply 200%* of the rated voltage at the maximum operating temperature $\pm 3^{\circ}\text{C}$ for 1000 ± 12 hours. Set for 24 ± 2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. *Initial measurement for high dielectric constant type. Apply 200% of the rated voltage* at the maximum operating temperature $\pm 3^{\circ}\text{C}$ for one hour. Remove and set for 24 ± 2 hours at room temperature. Perform initial measurement. *GRM155C81E 683/104, GRM188C81E105, GRM188C81E105, GRM21BR71H105, GRM21BR72A474, GRM21BR71C225, GRM31CR71H475, GRM32E R6/R7 YA106, GRM32D R7/R6/C8 1E106 : 150% of the rated voltage.
	Appearance	No defects or abnormalities		
	Capacitance Change	Within $\pm 3\%$ or $\pm 0.3\text{pF}$ (whichever is larger)	B1, B3, R1, R6, R7, C8: Within $\pm 12.5\%$ F1, F5, E4: Within $\pm 30\%$ [Except 10V max. and $C \geq 1.0\mu\text{F}$] F1, F5: Within $+30/-40\%$ [10V max. and $C \geq 1.0\mu\text{F}$]	
	Q/D.F.	30pF and over: $Q \geq 350$ 10pF and over 30pF and below: $Q \geq 275+2.5C$ 10pF and below: $Q \geq 200+10C$ C: Nominal Capacitance (pF)	[B1, B3, R6, R7, C8] W.V.: 100V : 0.05 max. ($C < 0.068\mu\text{F}$) : 0.075 max. ($C \geq 0.068\mu\text{F}$) W.V.: 50/35/25/16/10V : 0.05 max. W.V.: 6.3/4V : 0.075 max. ($C < 3.3\mu\text{F}$) : 0.125 max. ($C \geq 3.3\mu\text{F}$) [E4] W.V.: 25Vmin: 0.05 max. [F1, F5] W.V.: 25V min. : 0.075 max. ($C < 0.1\mu\text{F}$) : 0.125 max. ($C \geq 0.1\mu\text{F}$) W.V.: 16/10V: 0.15 max. W.V.: 6.3V: 0.2 max.	
	I.R.	More than $1,000\text{M}\Omega$ or $50\Omega \cdot \text{F}$ (whichever is smaller)		

Table A-1
(1)

Char.	Nominal Values (ppm/ $^{\circ}\text{C}$)*1	Capacitance Change from 25 $^{\circ}\text{C}$ (%)					
		-55		-30		-10	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0 \pm 30	0.58	-0.24	0.40	-0.17	0.25	-0.11
6C	0 \pm 60	0.87	-0.48	0.59	-0.33	0.38	-0.21
6P	-150 \pm 60	2.33	0.72	1.61	0.50	1.02	0.32
6R	-220 \pm 60	3.02	1.28	2.08	0.88	1.32	0.56
6S	-330 \pm 60	4.09	2.16	2.81	1.49	1.79	0.95
6T	-470 \pm 60	5.46	3.28	3.75	2.26	2.39	1.44
7U	-750 \pm 120	8.78	5.04	6.04	3.47	3.84	2.21
1X	+350 to -1000	-	-	-	-	-	-

*1: Nominal values denote the temperature coefficient within a range of 25 $^{\circ}\text{C}$ to 125 $^{\circ}\text{C}$ (for ΔC)/85 $^{\circ}\text{C}$ (for other TC).

(2)

Char.	Nominal Values (ppm/ $^{\circ}\text{C}$)*2	Capacitance Change from 20 $^{\circ}\text{C}$ (%)					
		-55		-25		-10	
		Max.	Min.	Max.	Min.	Max.	Min.
2C	0 \pm 60	0.82	-0.45	0.49	-0.27	0.33	-0.18
3C	0 \pm 120	1.37	-0.90	0.82	-0.54	0.55	-0.36
4C	0 \pm 250	2.56	-1.88	1.54	-1.13	1.02	-0.75
2P	-150 \pm 60	-	-	1.32	0.41	0.88	0.27
3P	-150 \pm 120	-	-	1.65	0.14	1.10	0.09
4P	-150 \pm 250	-	-	2.36	-0.45	1.57	-0.30
2R	-220 \pm 60	-	-	1.70	0.72	1.13	0.48
3R	-220 \pm 120	-	-	2.03	0.45	1.35	0.30
4R	-220 \pm 250	-	-	2.74	-0.14	1.83	-0.09
2S	-330 \pm 60	-	-	2.30	1.22	1.54	0.81
3S	-330 \pm 120	-	-	2.63	0.95	1.76	0.63
4S	-330 \pm 250	-	-	3.35	0.36	2.23	0.24
2T	-470 \pm 60	-	-	3.07	1.85	2.05	1.23
3T	-470 \pm 120	-	-	3.40	1.58	2.27	1.05
4T	-470 \pm 250	-	-	4.12	0.99	2.74	0.66
3U	-750 \pm 120	-	-	4.94	2.84	3.29	1.89
4U	-750 \pm 250	-	-	5.65	2.25	3.77	1.50

*2: Nominal values denote the temperature coefficient within a range of 20 $^{\circ}\text{C}$ to 125 $^{\circ}\text{C}$ (for ΔC)/85 $^{\circ}\text{C}$ (for other TC).

GRM Series Specifications and Test Methods (2) (Note 1)-Typical Inspection

(Note 1) These Specifications and Test Methods indicate typical inspection.
 Please refer to individual specifications (our product specifications or the approval sheet).
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No.	Item	Specifications	Test Method																																																																							
1	Operating Temperature Range	B1, B3, F1: -25 to +85°C R1, R7, C7, D7, E7: -55 to +125°C C6, R6: -55 to +85°C F5: -30 to +85°C C8, D8: -55 to +105°C,	Reference temperature: 25°C (B1, B3, R1, F1: 20°C)																																																																							
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.																																																																							
3	Appearance	No defects or abnormalities	Visual inspection																																																																							
4	Dimensions	Within the specified dimensions	Using calipers (GRM02 size is based on Microscope)																																																																							
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.																																																																							
6	Insulation Resistance	More than $50\Omega \cdot F$	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at reference temperature and 75%RH max. and within 1 minutes of charging, provided the charge/discharge current is less than 50mA.																																																																							
7	Capacitance	Within the specified tolerance *Table 1 <table border="1"> <thead> <tr> <th>Part No.</th> <th>Case</th> <th>Temp. Coef.</th> <th>Capacitance</th> </tr> </thead> <tbody> <tr> <td>GRM022</td> <td>B3/R6</td> <td>1A</td> <td>681 to 103</td> </tr> <tr> <td>GRM155</td> <td>B3/R6</td> <td>1A</td> <td>124 to 105</td> </tr> <tr> <td>GRM185</td> <td>B3/R6</td> <td>1C/1A</td> <td>105</td> </tr> <tr> <td>GRM185</td> <td>C8/D7</td> <td>1A</td> <td>105</td> </tr> <tr> <td>GRM188</td> <td>B3/R6</td> <td>1C/1A</td> <td>225</td> </tr> <tr> <td>GRM188</td> <td>R7/C8</td> <td>1A</td> <td>225</td> </tr> <tr> <td>GRM188</td> <td>B3/R6</td> <td>1A</td> <td>335</td> </tr> <tr> <td>GRM219</td> <td>B3/R6</td> <td>1C/1A</td> <td>475</td> </tr> <tr> <td>GRM219</td> <td>C8</td> <td>1A</td> <td>475</td> </tr> <tr> <td>GRM219</td> <td>B3/R6</td> <td>1A</td> <td>106</td> </tr> <tr> <td>GRM21B</td> <td>B3/R6</td> <td>1C/1A</td> <td>106</td> </tr> <tr> <td>GRM21B</td> <td>R7/C8</td> <td>1A</td> <td>106</td> </tr> <tr> <td>GRM319</td> <td>B3/R6</td> <td>1C/1A</td> <td>106</td> </tr> </tbody> </table>	Part No.	Case	Temp. Coef.	Capacitance	GRM022	B3/R6	1A	681 to 103	GRM155	B3/R6	1A	124 to 105	GRM185	B3/R6	1C/1A	105	GRM185	C8/D7	1A	105	GRM188	B3/R6	1C/1A	225	GRM188	R7/C8	1A	225	GRM188	B3/R6	1A	335	GRM219	B3/R6	1C/1A	475	GRM219	C8	1A	475	GRM219	B3/R6	1A	106	GRM21B	B3/R6	1C/1A	106	GRM21B	R7/C8	1A	106	GRM319	B3/R6	1C/1A	106	The capacitance/D.F. should be measured at reference temperature at the measuring frequency and voltage shown in the table. <table border="1"> <thead> <tr> <th>Nominal Capacitance</th> <th>Measuring Frequency</th> <th>Measuring Voltage</th> </tr> </thead> <tbody> <tr> <td>$C \leq 10\mu F$ (10V min.)*</td> <td>1±0.1kHz</td> <td>1.0±0.2Vrms</td> </tr> <tr> <td>$C \leq 10\mu F$ (6.3V max.)</td> <td>1±0.1kHz</td> <td>0.5±0.1Vrms</td> </tr> <tr> <td>$C > 10\mu F$</td> <td>120±24Hz</td> <td>0.5±0.1Vrms</td> </tr> <tr> <td>*For items in Table1</td> <td>1±0.1kHz</td> <td>0.5±0.1Vrms</td> </tr> </tbody> </table>	Nominal Capacitance	Measuring Frequency	Measuring Voltage	$C \leq 10\mu F$ (10V min.)*	1±0.1kHz	1.0±0.2Vrms	$C \leq 10\mu F$ (6.3V max.)	1±0.1kHz	0.5±0.1Vrms	$C > 10\mu F$	120±24Hz	0.5±0.1Vrms	*For items in Table1	1±0.1kHz	0.5±0.1Vrms
Part No.	Case	Temp. Coef.	Capacitance																																																																							
GRM022	B3/R6	1A	681 to 103																																																																							
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GRM188	R7/C8	1A	225																																																																							
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GRM219	B3/R6	1C/1A	475																																																																							
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8	Dissipation Factor (D.F.)	B1, B3, R1, *R6, *R7, C7, C8, E7, D7: 0.1 max. C6: 0.125 max. D8: 0.15 max. F1, F5: 0.2 max. *GRM31CR71E106: 0.125 max. GRM31CR6 0J/0G 107: 0.15 max.	GRM188C80E106: Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature.																																																																							

Continued on the following page. 

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

GRM Series Specifications and Test Methods (2) (Note 1)-Typical Inspection

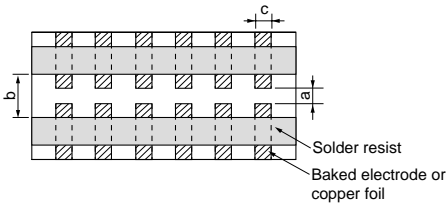
(Note 1) These Specifications and Test Methods indicate typical inspection.

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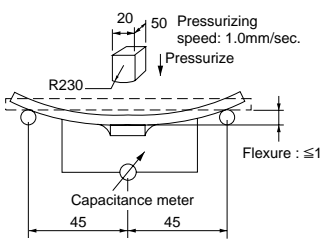
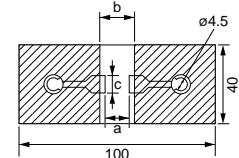
No.	Item	Specifications	Test Method																				
9	No bias	B1, B3 : Within $\pm 10\%$ (-25 to $+85^\circ\text{C}$) F1 : Within $+30/-80\%$ (-25 to $+85^\circ\text{C}$) R6 : Within $\pm 15\%$ (-55 to $+85^\circ\text{C}$) R1, R7 : Within $\pm 15\%$ (-55 to $+125^\circ\text{C}$) F5 : Within $+22/-82\%$ (-30 to $+85^\circ\text{C}$) C6 : Within $\pm 22\%$ (-55 to $+85^\circ\text{C}$) C7 : Within $\pm 22\%$ (-55 to $+125^\circ\text{C}$) C8 : Within $\pm 22\%$ (-55 to $+105^\circ\text{C}$) D7 : Within $+22/-33\%$ (-55 to $+125^\circ\text{C}$) E7 : Within $+22/-56\%$ (-55 to $+125^\circ\text{C}$) D8 : Within $+22/-33\%$ (-55 to $+105^\circ\text{C}$)	The capacitance change should be measured after 5 min. at each specified temp. stage. The ranges of capacitance change compared with the reference temperature value over the temperature ranges shown in the table should be within the specified ranges.* In case of applying voltage, the capacitance change should be measured after 1 more min. with applying voltage in equilibration of each temp. stage. *GRM32DR60J226, GRM43 B1/B3/R6 0J/1A 336/476: $1.0\pm 0.2V_{rms}$ GRM155B30G475, GRM155B30J 225, GRM21BB30J476, GRM155R60E106, GRM188 B3/R6 0E/0G/0J 226: $0.2\pm 0.05V_{rms}$																				
	Capacitance Temperature Characteristics	B1: Within $+10/-30\%$ R1: Within $+15/-40\%$ F1: Within $+30/-95\%$	<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature ($^\circ\text{C}$)</th> <th>Applying Voltage (V)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)</td> <td rowspan="4">No bias</td> </tr> <tr> <td>2</td> <td>-55 ± 3 (for R1, R6, R7, C6, C7, C8, D7, D8, E7) -30 ± 3 (for F5) -25 ± 3 (for B1, B3, F1)</td> </tr> <tr> <td>3</td> <td>25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)</td> </tr> <tr> <td>4</td> <td>125 ± 3 (for R1, R7, C7, D7, E7) 105 ± 3 (for C8, D8) 85 ± 3 (for B1, B3, F1, F5, R6, C6)</td> </tr> <tr> <td>5</td> <td>20 ± 2 (for B1, F1, R1)</td> <td rowspan="4">50% of the rated voltage</td> </tr> <tr> <td>6</td> <td>-55 ± 3 (for R1) -25 ± 3 (for B1, F1)</td> </tr> <tr> <td>7</td> <td>20 ± 2 (for B1, F1, R1)</td> </tr> <tr> <td>8</td> <td>125 ± 3 (for R1) 85 ± 3 (for B1, F1)</td> </tr> </tbody> </table> <p>*Initial measurement for high dielectric constant type Perform a heat treatment at $150 \pm 0/-10^\circ\text{C}$ for one hour and then set for 24 ± 2 hours at room temperature. Perform the initial measurement.</p>	Step	Temperature ($^\circ\text{C}$)	Applying Voltage (V)	1	25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)	No bias	2	-55 ± 3 (for R1, R6, R7, C6, C7, C8, D7, D8, E7) -30 ± 3 (for F5) -25 ± 3 (for B1, B3, F1)	3	25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)	4	125 ± 3 (for R1, R7, C7, D7, E7) 105 ± 3 (for C8, D8) 85 ± 3 (for B1, B3, F1, F5, R6, C6)	5	20 ± 2 (for B1, F1, R1)	50% of the rated voltage	6	-55 ± 3 (for R1) -25 ± 3 (for B1, F1)	7	20 ± 2 (for B1, F1, R1)	8
Step	Temperature ($^\circ\text{C}$)	Applying Voltage (V)																					
1	25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)	No bias																					
2	-55 ± 3 (for R1, R6, R7, C6, C7, C8, D7, D8, E7) -30 ± 3 (for F5) -25 ± 3 (for B1, B3, F1)																						
3	25 ± 2 (for R6, R7, C6, C7, C8, D7, D8, E7, F5) 20 ± 2 (for B1, B3, F1, R1)																						
4	125 ± 3 (for R1, R7, C7, D7, E7) 105 ± 3 (for C8, D8) 85 ± 3 (for B1, B3, F1, F5, R6, C6)																						
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6	-55 ± 3 (for R1) -25 ± 3 (for B1, F1)																						
7	20 ± 2 (for B1, F1, R1)																						
8	125 ± 3 (for R1) 85 ± 3 (for B1, F1)																						
10	Adhesive Strength of Termination	No removal of the terminations or other defects should occur.  <p>Fig. 1a</p>	Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 1a using a eutectic solder. Then apply $10N^*$ force in parallel with the test jig for 10 ± 1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *1N: GRM02, 2N: GRM03, 5N: GRM15/GRM18																				
11	Appearance	No defects or abnormalities	Solder the capacitor on the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																				
	Capacitance	Within the specified tolerance																					
	D.F.	B1, B3, R1, *R6, *R7, C7, C8, E7, D7: 0.1 max. C6: 0.125 max. D8: 0.15 max. F1, F5: 0.2 max. *GRM31CR71E106: 0.125 max. GRM31CR6 0J/0G 107: 0.15 max.																					


Continued on the following page.

GRM Series Specifications and Test Methods (2) (Note 1)-Typical Inspection

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 When "*" is added in PNs table, please refer to GRM Series Specifications and Test Methods (2).

Continued from the preceding page.

No.	Item	Specifications	Test Method																																								
12	Appearance	No marking defects	Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2a using a eutectic solder. Then apply a force in the direction shown in Fig. 3a for 5±1 sec. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																																								
	Capacitance Change	Within ±10%																																									
12	Deflection	 <p>Fig.3a</p>	 <p>Fig. 2a</p> <p>(GRM02/03/15: t: 0.8mm)</p> <table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GRM02</td> <td>0.2</td> <td>0.56</td> <td>0.23</td> </tr> <tr> <td>GRM03</td> <td>0.3</td> <td>0.9</td> <td>0.3</td> </tr> <tr> <td>GRM15</td> <td>0.4</td> <td>1.5</td> <td>0.5</td> </tr> <tr> <td>GRM18</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> </tr> <tr> <td>GRM21</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>GRM31</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>GRM32</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>GRM43</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>GRM55</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table> <p>(in mm)</p>	Type	a	b	c	GRM02	0.2	0.56	0.23	GRM03	0.3	0.9	0.3	GRM15	0.4	1.5	0.5	GRM18	1.0	3.0	1.2	GRM21	1.2	4.0	1.65	GRM31	2.2	5.0	2.0	GRM32	2.2	5.0	2.9	GRM43	3.5	7.0	3.7	GRM55	4.5	8.0	5.6
		Type	a	b	c																																						
GRM02	0.2	0.56	0.23																																								
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GRM43	3.5	7.0	3.7																																								
GRM55	4.5	8.0	5.6																																								
13	Solderability of Termination	75% of the terminations is to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in a eutectic solder solution for 2±0.5 seconds at 230±5°C or Sn-3.0Ag-0.5Cu solder solution for 2±0.5 seconds at 245±5°C.																																								
14	Resistance to Soldering Heat	Appearance	No defects or abnormalities																																								
		Capacitance Change	B1, B3, R1, *R6, R7, C6, C7, *C8, E7, D7, D8: Within ±7.5% F1, F5: Within ±20% *GRM188R6 0J/0G 106, GRM188C8 0E/0G 106, GRM219R60G226: Within ±12.5% GRM155R60G475, GRM155R60E106, GRM188R60G226: Within ±15%																																								
		D.F.	B1, B3, R1, *R6, *R7, C7, C8, E7, D7: 0.1 max. C6: 0.125 max. D8: 0.15 max. F1, F5: 0.2 max. *GRM31CR71E106: 0.125 max. GRM31CR6 0J/0G 107: 0.15 max.																																								
		I.R.	More than 50Ω · F																																								
		Dielectric Strength	No defects																																								
15	Temperature Sudden Change	Appearance	No defects or abnormalities																																								
		Capacitance Change	B1, B3, R1, R6, R7, C6, C7, C8, D7, D8: Within ±7.5% E7: Within ±30% F1, F5: Within ±20%																																								
		D.F.	B1, B3, R1, *R6, *R7, C7, C8, E7, D7: 0.1 max. C6: 0.125 max. D8: 0.15 max. F1, F5: 0.2 max. *GRM31CR71E106: 0.125 max. GRM31CR6 0J/0G 107: 0.15 max.																																								
		I.R.	More than 50Ω · F																																								
		Dielectric Strength	No defects																																								

Continued on the following page. 

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

GRM Series Specifications and Test Methods (2) (Note 1)-Typical Inspection

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 When "*" is added in PNs table, please refer to GRM Series Specifications and Test Methods (2).

Continued from the preceding page.

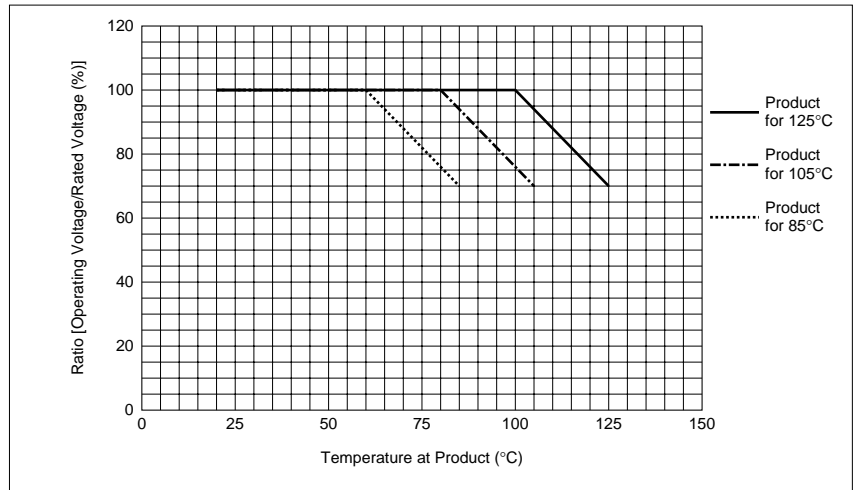
No.	Item	Specifications	Test Method
16	Appearance	No defects or abnormalities	Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. The charge/discharge current is less than 50mA. •Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. •Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.
	High Temperature High Humidity (Steady)	Capacitance Change B1, B3, R1, R6, R7, C6, C7, C8, E7, D7, D8: Within ±12.5% F1, F5: Within ±30%	
	D.F.	B1, B3, R1, R6, R7, C6, C7, *C8, E7, D7, D8: 0.2 max. F1, F5: 0.4 max. *GRM319C81A106, GRM31MC81A106: 0.125 max.	
	I.R.	More than 12.5Ω · F	
17	Appearance	No defects or abnormalities	Apply 150%* of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. * Part Numbers with # have individual specification. As for these Part Numbers, please refer to table A. •Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. •Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.
	Durability	Capacitance Change B1, B3, R1, *R6, R7, C6, C7, *C8, E7, D7, D8: Within ±12.5% F1, F5: Within ±30% *GRM188C8 0E/0G 106, GRM219R60G226: within ±15%	
	D.F.	B1, B3, R1, R6, R7, C6, C7, *C8, E7, D7, D8: 0.2 max. F1, F5: 0.4 max. *GRM319C81A106, GRM31MC81A106: 0.125 max.	
	I.R.	More than 25Ω · F	

Table A

Part Number	Dimension LxW (mm)	Temp. Char.	Rated Volt. (Vdc)	Capacitance (F)	Cap. Tol (%)	Spec. Test Methods	Applied Testing Voltage at Durability
GRM155C80J684KE15D	1.0X0.5	X6S	6.3	0.68μ	±10%	(2)	Rated Volt. X100%
GRM155C80J684ME15D	1.0X0.5	X6S	6.3	0.68μ	±20%	(2)	Rated Volt. X100%
GRM188C80G106ME47D	1.6X0.8	X6S	4	10μ	±20%	(2)	Rated Volt. X100%
GRM21BC80J226ME51L	2.0X1.25	X6S	6.3	22μ	±20%	(2)	Rated Volt. X100%
GRM319D71C475KA12D	3.2X1.6	X7T	16	4.7μ	±10%	(2)	Rated Volt. X100%
GRM319D71C475MA12D	3.2X1.6	X7T	16	4.7μ	±20%	(2)	Rated Volt. X100%

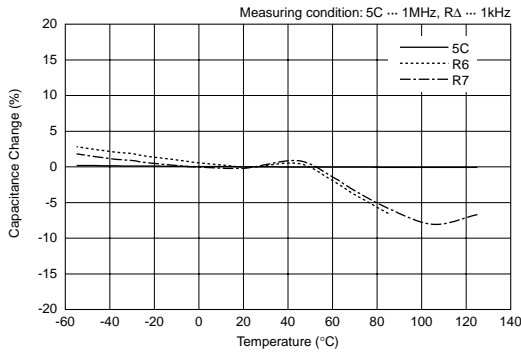
Part Numbers of table A are designed for use in the circuits where continuous applied voltage to the capacitor is derated than rated voltage. These Part Numbers guarantee Durability Test with 100% x rated voltage as testing voltage at the maximum operating temperature. The following voltage and temperature derating conditions are recommended for use to ensure the same reliability level as normal specification.

• Recommended Derating Conditions on Voltage and Temperature

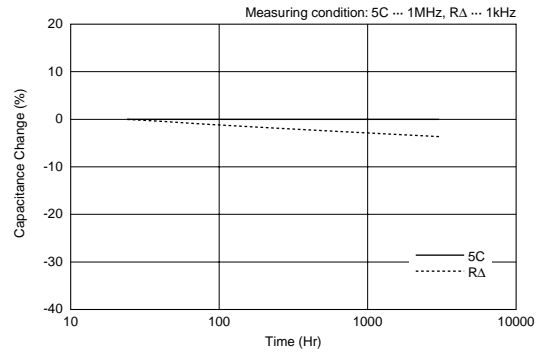


GRM Series Data

■ Capacitance - Temperature Characteristics

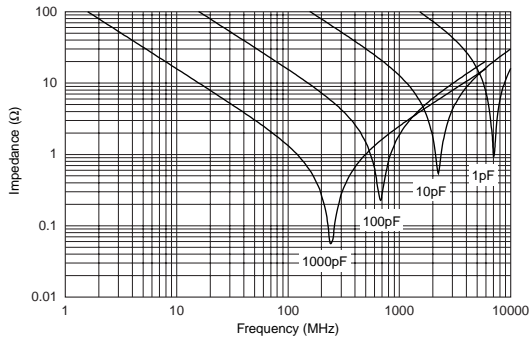


■ Capacitance Change - Aging

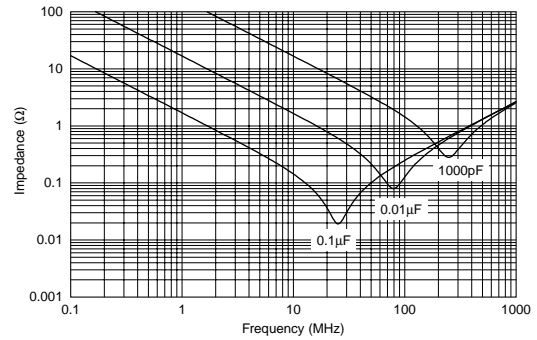


■ Impedance - Frequency Characteristics

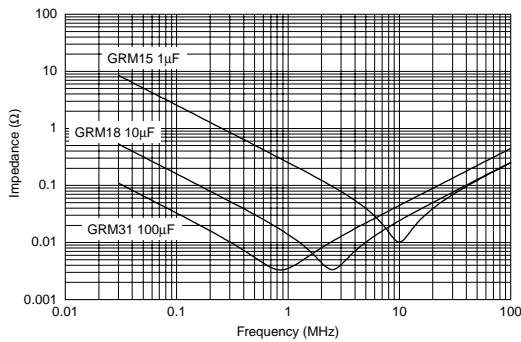
5C: GRM15



R Δ : GRM15



R Δ



The data herein are given in typical values, not guaranteed ratings.
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For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

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GOM Series

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For Bonding
GMD Series

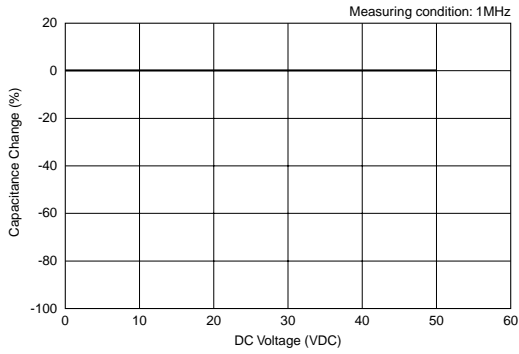
Product Information

GRM Series Data

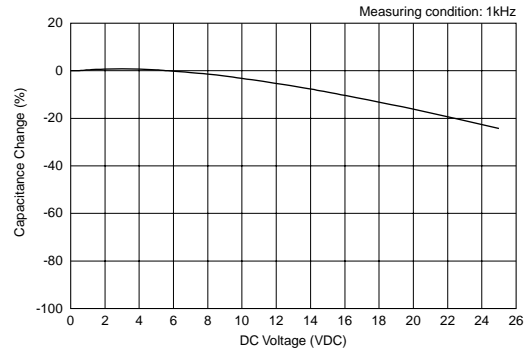
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Capacitance - DC Voltage Characteristics

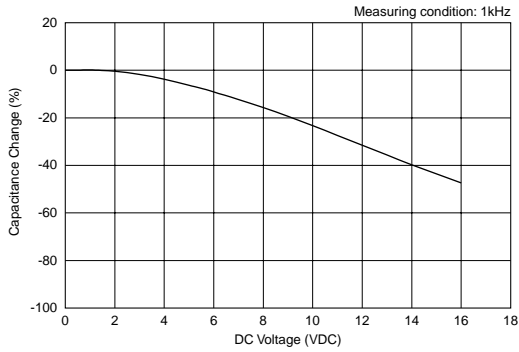
Temperature Compensating Type: GRM1555C1H102JA01



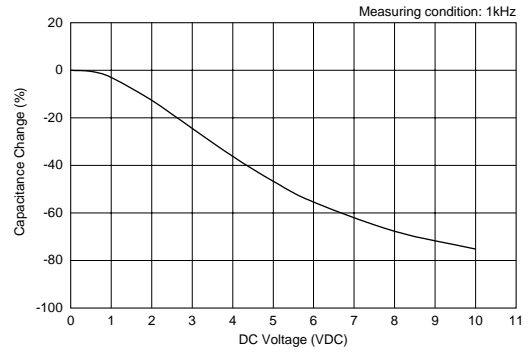
High Dielectric Constant Type: GRM155R71E103KA01



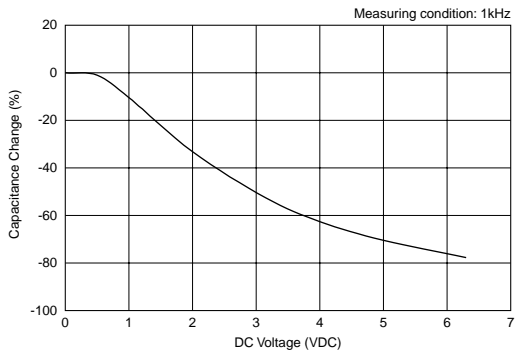
High Dielectric Constant Type: GRM155R71C104KA88



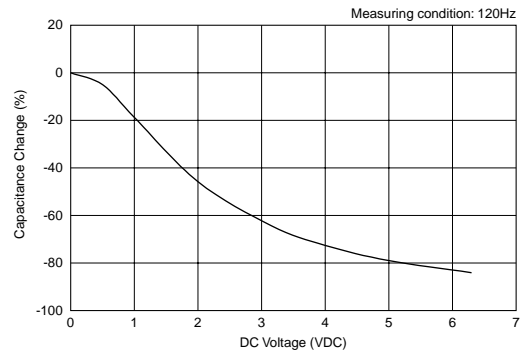
High Dielectric Constant Type: GRM155R61A105KE15



High Dielectric Constant Type: GRM188R60J106ME47



High Dielectric Constant Type: GRM31CR60J107ME39



The data herein are given in typical values, not guaranteed ratings.
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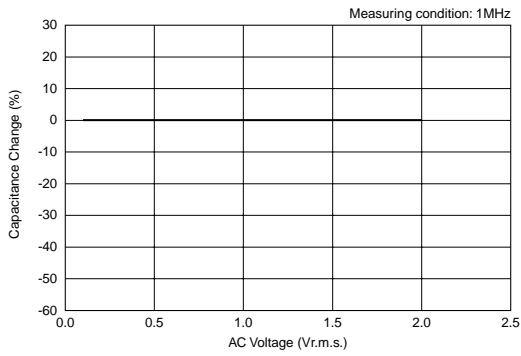
Product Information

GRM Series Data

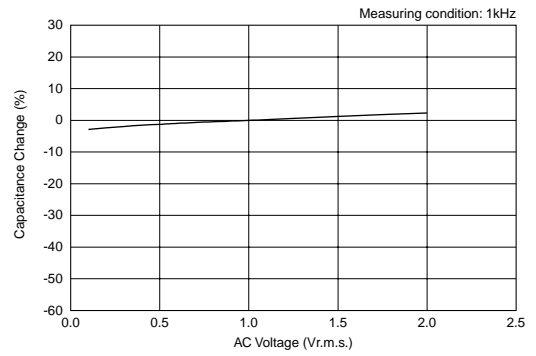
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Capacitance - AC Voltage Characteristics

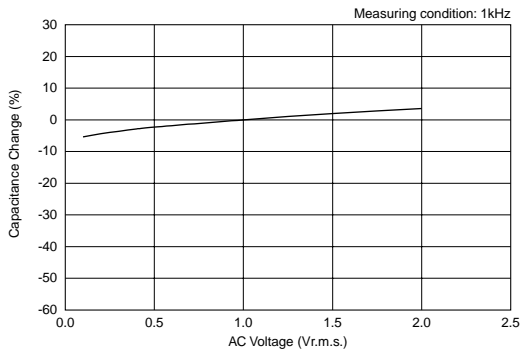
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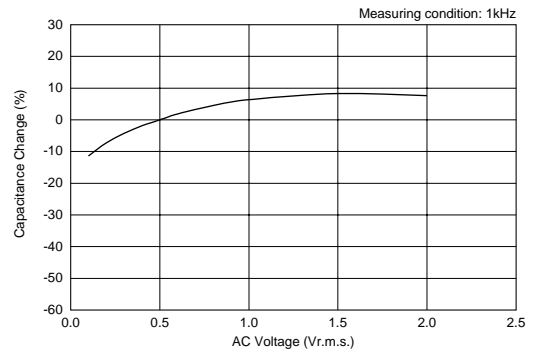
High Dielectric Constant Type: GRM155R71E103KA01



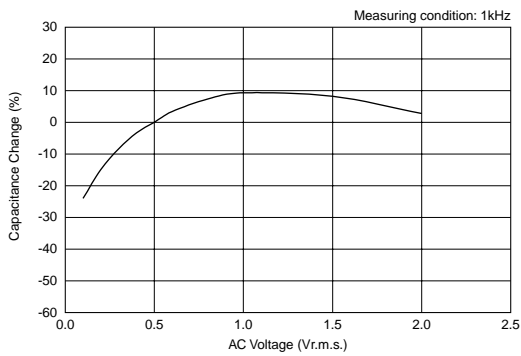
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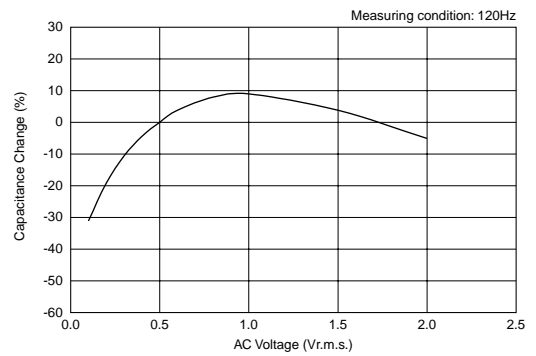
High Dielectric Constant Type: GRM155R61A105KE15



High Dielectric Constant Type: GRM188R60J106ME47



High Dielectric Constant Type: GRM31CR60J107ME39



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GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



Capacitor Array GNM Series

■ Features

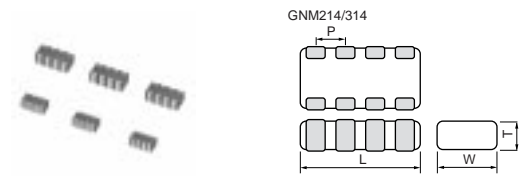
1. High density mounting due to mounting space saving
2. Mounting cost saving

■ Applications

General electronic equipment



Part Number	Dimensions (mm)			
	L	W	T	P
GNM0M2	0.9 ±0.05	0.6 ±0.05	0.45 ±0.05	0.45 ±0.05
GNM1M2	1.37 ±0.15	1.0 ±0.15	0.5 +0.05/-0.10	0.64 ±0.05
			0.6 ±0.1	
			0.8 +0/-0.15	
GNM212	2.0 ±0.15	1.25 ±0.15	0.6 ±0.1	1.0 ±0.1
			0.85 ±0.1	
			0.85 ±0.1	



Part Number	Dimensions (mm)			
	L	W	T	P
GNM214	2.0 ±0.15	1.25 ±0.15	0.5 +0.05/-0.1	0.5 ±0.05
			0.6 ±0.1	
			0.85 ±0.1	
GNM314	3.2 ±0.15	1.6 ±0.15	0.8 ±0.1	0.8 ±0.1
			0.85 ±0.1	
			1.0 ±0.1	
			1.15 ±0.1	

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Product Information

Capacitance Table

Temperature Compensating Type C0G(5C) Characteristics

0.6		ex.0.6: T Dimension [mm]			
Capacitance	LxW [mm]	1.37x1.0 (1M) <0504>	2.0x1.25 (21) <0805>	3.2x1.6 (31) <1206>	
	Number of Elements	2(2)		4(4)	
	Rated Voltage [Vdc]	50 (1H)	50 (1H)	100 (2A)	50 (1H)
	10pF(100)	0.6	0.6	0.8	0.8
	15pF(150)	0.6	0.6	0.8	0.8
	22pF(220)	0.6	0.6	0.8	0.8
	33pF(330)	0.6	0.6	0.8	0.8
	47pF(470)	0.6	0.6	0.8	0.8
	68pF(680)	0.6	0.6	0.8	0.8
	100pF(101)	0.6	0.6	0.8	0.8
	150pF(151)	0.6	0.6	0.8	0.8
	220pF(221)	0.6	0.6		0.8
	330pF(331)				0.8

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

High Dielectric Constant Type X7R(R7)/X7S(C7) Characteristics

0.6		ex.0.6: T Dimension [mm]											
Capacitance	LxW [mm]	1.37x1.0 (1M) <0504>				2.0x1.25 (21) <0805>				3.2x1.6 (31) <1206>			
	Number of Elements	2(2)				4(4)							
	Rated Voltage [Vdc]	50 (1H)	25 (1E)	16 (1C)	10 (1A)	50 (1H)	25 (1E)	16 (1C)	50 (1H)	25 (1E)	16 (1C)	6.3 (0J)	
	470pF(471)					0.6							
	1000pF(102)	0.6				0.6							
	2200pF(222)		0.6				0.6						
	4700pF(472)		0.6				0.6						
	10000pF(103)		0.6				0.6						
	22000pF(223)			0.6	0.6			0.85					
	47000pF(473)			0.6	0.6			0.85	0.85		1.0		
	0.10μF(104)			0.6	0.6			0.85	0.85	0.85	1.0		
	1.0μF(105)											1.15	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

High Dielectric Constant Type X7R(R7) Characteristics-Low Profile

0.5		ex.0.5: T Dimension [mm]	
Capacitance	LxW [mm]	1.37x1.0 (1M) <0504>	2.0x1.25 (21) <0805>
	Number of Elements	2(2)	4(4)
	Rated Voltage [Vdc]	16 (1C)	16 (1C)
	0.10μF(104)	0.5	0.5

The part number code is shown in () and Unit is shown in [].
< >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Capacitance Table

High Dielectric Constant Type X5R(R6) Characteristics

0.6 ex.0.6: T Dimension [mm]		0.9x0.6 (0M) <0302>				1.37x1.0 (1M) <0504>				2.0x1.25 (21) <0805>			2.0x1.25 (21) <0805>		3.2x1.6 (31) <1206>						
LxW [mm]																					
Number of Elements		2(2)										4(4)									
Rated Voltage [Vdc]		16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	16 (1C)	10 (1A)	6.3 (0J)	10 (1A)	6.3 (0J)	16 (1C)	10 (1A)				
Capacitance																					
1000pF(102)						0.6															
2200pF(222)							0.6														
4700pF(472)							0.6														
10000pF(103)		0.45	0.45	0.45					0.6												
22000pF(223)		0.45	0.45	0.45					0.6	0.6											
47000pF(473)		0.45	0.45	0.45					0.6	0.6											
0.10μF(104)		0.45	0.45	0.45						0.6											
0.22μF(224)										0.8											
0.47μF(474)												0.85									
1.0μF(105)						0.45					0.8	0.8	0.8	0.85	0.85		0.85	0.85	0.85	0.85	
2.2μF(225)											0.8	0.8		0.85	0.85		0.85				

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

High Dielectric Constant Type X5R(R6) Characteristics-Low Profile

0.5 ex.0.5: T Dimension [mm]		1.37x1.0 (1M) <0504>		2.0x1.25 (21) <0805>
LxW [mm]				
Number of Elements		2(2)		4(4)
Rated Voltage [Vdc]		16 (1C)	10 (1A)	10 (1A)
Capacitance				
1.0μF(105)		0.5	0.5	0.5

The part number code is shown in () and Unit is shown in [].
< >: EIA [inch] Code

For General
GRM Series

Array
GNM Series

Low ESL
LL Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		1.37x1.0(1M)<0504>	2.0x1.25(21)<0805>	3.2x1.6(31)<1206>	
Number of Elements		2(2)		4(4)	
Rated Volt. [Vdc]		50(1H)	50(1H)	100(2A)	50(1H)
Capacitance	Tolerance	Part Number			
10pF(100)	±10%(K)	GNM1M25C1H100KD01D	GNM2145C1H100KD01D	GNM3145C2A100KD01D	GNM3145C1H100KD01D
15pF(150)	±10%(K)	GNM1M25C1H150KD01D	GNM2145C1H150KD01D	GNM3145C2A150KD01D	GNM3145C1H150KD01D
22pF(220)	±10%(K)	GNM1M25C1H220KD01D	GNM2145C1H220KD01D	GNM3145C2A220KD01D	GNM3145C1H220KD01D
33pF(330)	±10%(K)	GNM1M25C1H330KD01D	GNM2145C1H330KD01D	GNM3145C2A330KD01D	GNM3145C1H330KD01D
47pF(470)	±10%(K)	GNM1M25C1H470KD01D	GNM2145C1H470KD01D	GNM3145C2A470KD01D	GNM3145C1H470KD01D
68pF(680)	±10%(K)	GNM1M25C1H680KD01D	GNM2145C1H680KD01D	GNM3145C2A680KD01D	GNM3145C1H680KD01D
100pF(101)	±10%(K)	GNM1M25C1H101KD01D	GNM2145C1H101KD01D	GNM3145C2A101KD01D	GNM3145C1H101KD01D
150pF(151)	±10%(K)	GNM1M25C1H151KD01D	GNM2145C1H151KD01D	GNM3145C2A151KD01D	GNM3145C1H151KD01D
220pF(221)	±10%(K)	GNM1M25C1H221KD01D	GNM2145C1H221KD01D		GNM3145C1H221KD01D
330pF(331)	±10%(K)				GNM3145C1H331KD01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

High Dielectric Constant Type X7R(R7)/X7S(C7) Characteristics

LxW [mm]		1.37x1.0(1M)<0504>			
Number of Elements		2(2)			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
1000pF(102)	±20%(M)	GNM1M2R71H102MA01D			
2200pF(222)	±20%(M)		GNM1M2R71E222MA01D		
4700pF(472)	±20%(M)		GNM1M2R71E472MA01D		
10000pF(103)	±20%(M)		GNM1M2R71E103MA01D		
22000pF(223)	±20%(M)			GNM1M2R71C223MA01D	GNM1M2R71A223MA01D
47000pF(473)	±20%(M)			GNM1M2R71C473MA01D	GNM1M2R71A473MA01D
0.10μF(104)	±20%(M)			GNM1M2R71C104MA01D	GNM1M2C71A104MA01D

LxW [mm]		2.0x1.25(21)<0805>		
Number of Elements		4(4)		
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number		
470pF(471)	±20%(M)	GNM214R71H471MA01D		
1000pF(102)	±20%(M)	GNM214R71H102MA01D		
2200pF(222)	±20%(M)		GNM214R71E222MA01D	
4700pF(472)	±20%(M)		GNM214R71E472MA01D	
10000pF(103)	±20%(M)		GNM214R71E103MA01D	
22000pF(223)	±20%(M)			GNM214R71C223MA01D
47000pF(473)	±20%(M)			GNM214R71C473MA01D
0.10μF(104)	±20%(M)			GNM214R71C104MA01D

LxW [mm]		3.2x1.6(31)<1206>			
Number of Elements		4(4)			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	6.3(0J)
Capacitance	Tolerance	Part Number			
47000pF(473)	±20%(M)	GNM314R71H473MA11D		GNM314R71C473MA01L	
0.10μF(104)	±20%(M)	GNM314R71H104MA11D	GNM314R71E104MA11D	GNM314R71C104MA01L	
1.0μF(105)	±20%(M)				GNM314R70J105MA01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GNM series Specifications and Test Method (2).

(Part Number) **GN** **M** **1M** **2** **5C** **1H** **100** **K** **D01** **D** ①Product ID ②Series ③Dimensions (LxW) ④Number of Elements
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

For General GRM Series

High Dielectric Constant Type X7R(R7) Characteristics-Low Profile

LxW [mm]	1.37x1.0(1M)<0504>		2.0x1.25(21)<0805>	
Number of Elements	2(2)		4(4)	
Rated Volt. [Vdc]	16(1C)		16(1C)	
Capacitance	Tolerance	Part Number		
0.10μF(104)	±20%(M)	GNM1M2R71C104MAA1D	GNM214R71C104MAA1D	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Array GNM Series

High Dielectric Constant Type X5R(R6) Characteristics

LxW [mm]	0.9x0.6(0M)<0302>			
Number of Elements	2(2)			
Rated Volt. [Vdc]	16(1C)	10(1A)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number		
10000pF(103)	±20%(M)	GNM0M2R61C103ME18D*	GNM0M2R61A103ME17D*	GNM0M2R60J103ME17D*
22000pF(223)	±20%(M)	GNM0M2R61C223ME18D*	GNM0M2R61A223ME17D*	GNM0M2R60J223ME17D*
47000pF(473)	±20%(M)	GNM0M2R61C473ME18D*	GNM0M2R61A473ME17D*	GNM0M2R60J473ME17D*
0.10μF(104)	±20%(M)	GNM0M2R61C104ME18D*	GNM0M2R61A104ME17D*	GNM0M2R60J104ME17D*
1.0μF(105)	±20%(M)			GNM0M2R60G105ME17D*

Low ESL LL□ Series

High-Q GJM Series

LxW [mm]	1.37x1.0(1M)<0504>		
Number of Elements	2(2)		
Rated Volt. [Vdc]	50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number	
1000pF(102)	±20%(M)	GNM1M2R61H102MA01D	
2200pF(222)	±20%(M)		GNM1M2R61E222MA01D
4700pF(472)	±20%(M)		GNM1M2R61E472MA01D
10000pF(103)	±20%(M)		GNM1M2R61E103MA01D
22000pF(223)	±20%(M)		GNM1M2R61C223MA01D
47000pF(473)	±20%(M)		GNM1M2R61C473MA01D
0.22μF(224)	±20%(M)		GNM1M2R61C224ME18D*
1.0μF(105)	±20%(M)		GNM1M2R61C105ME18D*

High Frequency GQM Series

Monolithic Microchip GMA Series

LxW [mm]	1.37x1.0(1M)<0504>	
Number of Elements	2(2)	
Rated Volt. [Vdc]	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number
22000pF(223)	±20%(M)	GNM1M2R61A223MA01D
47000pF(473)	±20%(M)	GNM1M2R61A473MA01D
0.10μF(104)	±20%(M)	GNM1M2R61A104MA01D
1.0μF(105)	±20%(M)	GNM1M2R61A105ME17D* GNM1M2R60J105ME12D*
2.2μF(225)	±20%(M)	GNM1M2R61A225ME18D* GNM1M2R60J225ME18D*

For Bonding GMD Series

LxW [mm]	2.0x1.25(21)<0805>		
Number of Elements	2(2)		
Rated Volt. [Vdc]	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number	
0.47μF(474)	±20%(M)	GNM212R61C474MA16D	
1.0μF(105)	±20%(M)	GNM212R61C105MA16D	GNM212R61A105MA13D
2.2μF(225)	±20%(M)		GNM212R61A225ME16D* GNM212R60J225ME16D*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GNM series Specifications and Test Method (2).

Product Information

- (Part Number) **GN** **M** **1M** **2** **R7** **1C** **104** **M** **AA1** **D**
- ① Product ID
 - ② Series
 - ③ Dimensions (LxW)
 - ④ Number of Elements
 - ⑤ Temperature Characteristics
 - ⑥ Rated Voltage
 - ⑦ Capacitance
 - ⑧ Capacitance Tolerance
 - ⑨ Individual Specification Code
 - ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.



High Dielectric Constant Type X5R(R6) Characteristics

LxW [mm]		2.0x1.25(21)<0805>	
Number of Elements		4(4)	
Rated Volt. [Vdc]		10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number	
1.0μF(105)	±20%(M)	GNM214R61A105ME17D*	GNM214R60J105ME17D*
2.2μF(225)	±20%(M)		GNM214R60J225ME18D*

LxW [mm]		3.2x1.6(31)<1206>	
Number of Elements		4(4)	
Rated Volt. [Vdc]		16(1C)	10(1A)
Capacitance	Tolerance	Part Number	
1.0μF(105)	±20%(M)	GNM314R61C105MA15D	GNM314R61A105MA13D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GNM series Specifications and Test Method (2).

High Dielectric Constant Type X5R(R6) Characteristics-Low Profile

LxW [mm]		1.37x1.0(1M)<0504>	2.0x1.25(21)<0805>
Number of Elements		2(2)	4(4)
Rated Volt. [Vdc]		16(1C)	10(1A)
Capacitance	Tolerance	Part Number	
1.0μF(105)	±20%(M)	GNM1M2R61C105MEA2D*	GNM1M2R61A105MEA4D* GNM214R61A105MEA2D*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GNM series Specifications and Test Method (2).

For General
GRM Series

Array
GNM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

GNM Series Specifications and Test Methods (1)

When no "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).

No.	Item	Specifications		Test Method																									
		Temperature Compensating Type	High Dielectric Type																										
1	Operating Temperature Range	5C: -55 to +125°C	R7, C7: -55 to +125°C R6: -55 to +85°C																										
2	Rated Voltage	See the previous pages.		The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.																									
3	Appearance	No defects or abnormalities		Visual inspection																									
4	Dimensions	Within the specified dimensions		Using calipers																									
5	Dielectric Strength	No defects or abnormalities		No failure should be observed when 300% of the rated voltage (5C) or 250% of the rated voltage (R7) is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.																									
6	Insulation Resistance	More than 10,000MΩ or 500Ω · F (whichever is smaller)		The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging.																									
7	Capacitance	Within the specified tolerance		The capacitance/Q/D.F. should be measured at 25°C at the frequency and voltage shown in the table.																									
8	Q/ Dissipation Factor (D.F.)	30pF min.: $Q \geq 1000$ 30pF max.: $Q \geq 400+20C$ C: Nominal Capacitance (pF)	<table border="1"> <thead> <tr> <th>Char.</th> <th>25V min.</th> <th>16V</th> <th>10V</th> <th>6.3V</th> </tr> </thead> <tbody> <tr> <td>R7, R6, C7</td> <td>0.025 max.</td> <td>0.035 max.</td> <td>0.035 max.</td> <td>0.05 max.</td> </tr> </tbody> </table>	Char.	25V min.	16V	10V	6.3V	R7, R6, C7	0.025 max.	0.035 max.	0.035 max.	0.05 max.	<table border="1"> <thead> <tr> <th>Char.</th> <th>5C</th> <th>R7</th> </tr> </thead> <tbody> <tr> <td>Item</td> <td></td> <td></td> </tr> <tr> <td>Frequency</td> <td>1±0.1MHz</td> <td>1±0.1kHz</td> </tr> <tr> <td>Voltage</td> <td>0.5 to 5Vrms</td> <td>1.0±0.2Vrms</td> </tr> </tbody> </table>	Char.	5C	R7	Item			Frequency	1±0.1MHz	1±0.1kHz	Voltage	0.5 to 5Vrms	1.0±0.2Vrms			
			Char.	25V min.	16V	10V	6.3V																						
R7, R6, C7	0.025 max.	0.035 max.	0.035 max.	0.05 max.																									
Char.	5C	R7																											
Item																													
Frequency	1±0.1MHz	1±0.1kHz																											
Voltage	0.5 to 5Vrms	1.0±0.2Vrms																											
9	Capacitance Temperature Characteristics	Within the specified tolerance (Table A)	<table border="1"> <thead> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Reference Temp.</th> <th>Cap. Change</th> </tr> </thead> <tbody> <tr> <td>R7</td> <td>-55°C to +125°C</td> <td rowspan="3">25°C</td> <td rowspan="2">Within ±15%</td> </tr> <tr> <td>R6</td> <td>-55°C to +85°C</td> </tr> <tr> <td>C7</td> <td>-55°C to +125°C</td> <td>Within ±22%</td> </tr> </tbody> </table>	Char.	Temp. Range	Reference Temp.	Cap. Change	R7	-55°C to +125°C	25°C	Within ±15%	R6	-55°C to +85°C	C7	-55°C to +125°C	Within ±22%	<p>The capacitance change should be measured after 5 min. at each specified temperature stage.</p> <p>(1) Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from steps 1 through 5, the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the steps 1, 3 and 5 by the cap. value in step 3.</p> <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3 (for 5C/R7/C7), -30±3 (for F5)</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3 (for 5C/R7/C7), 85±3 (for F5)</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>(2) High Dielectric Constant Type The ranges of capacitance change compared with the above 25°C value over the temperature ranges shown in the table should be within the specified ranges.</p> <ul style="list-style-type: none"> Initial measurement for high dielectric constant type. Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement. 	Step	Temperature (°C)	1	25±2	2	-55±3 (for 5C/R7/C7), -30±3 (for F5)	3	25±2	4	125±3 (for 5C/R7/C7), 85±3 (for F5)	5	25±2
			Char.	Temp. Range	Reference Temp.	Cap. Change																							
			R7	-55°C to +125°C	25°C	Within ±15%																							
R6	-55°C to +85°C																												
C7	-55°C to +125°C	Within ±22%																											
Step	Temperature (°C)																												
1	25±2																												
2	-55±3 (for 5C/R7/C7), -30±3 (for F5)																												
3	25±2																												
4	125±3 (for 5C/R7/C7), 85±3 (for F5)																												
5	25±2																												
Capacitance Change	Within the specified tolerance (Table A)	Temperature Coefficient	Within the specified tolerance (Table A)																										
Capacitance Drift	Within ±0.2% or ±0.05pF (whichever is larger.)																												
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.		<p>Solder the capacitor to the test jig (glass epoxy board) shown in Fig.1 using a eutectic solder. Then apply 5N force in parallel with the test jig for 10±1 sec.</p> <p>The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p> <table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>GNM1M2</td> <td>0.5</td> <td>1.6</td> <td>0.32</td> <td>0.32</td> </tr> <tr> <td>GNM212</td> <td>0.6</td> <td>1.8</td> <td>0.5</td> <td>0.5</td> </tr> <tr> <td>GNM214</td> <td>0.6</td> <td>2.0</td> <td>0.25</td> <td>0.25</td> </tr> <tr> <td>GNM314</td> <td>0.8</td> <td>2.5</td> <td>0.4</td> <td>0.4</td> </tr> </tbody> </table> <p style="text-align: right;">(in mm)</p>	Type	a	b	c	d	GNM1M2	0.5	1.6	0.32	0.32	GNM212	0.6	1.8	0.5	0.5	GNM214	0.6	2.0	0.25	0.25	GNM314	0.8	2.5	0.4	0.4
Type	a	b	c	d																									
GNM1M2	0.5	1.6	0.32	0.32																									
GNM212	0.6	1.8	0.5	0.5																									
GNM214	0.6	2.0	0.25	0.25																									
GNM314	0.8	2.5	0.4	0.4																									

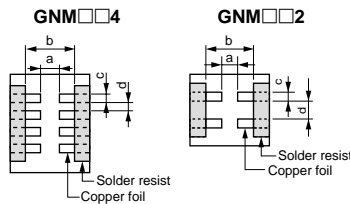


Fig. 1

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GNM Series Specifications and Test Methods (1)

Continued from the preceding page.

When no "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).

No.	Item	Specifications				Test Method																									
		Temperature Compensating Type	High Dielectric Type																												
11	Appearance	No defects or abnormalities				Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																									
	Capacitance	Within the specified tolerance																													
Vibration Resistance	Q/D.F.	30pF min.: $Q \geq 1000$ 30pF max.: $Q \geq 400+20C$ C: Nominal Capacitance (pF)	Char.	25V min.	16V		10V	6.3V																							
			R7, R6, C7	0.025 max.	0.035 max.		0.035 max.	0.05 max.																							
12	Appearance	No marking defects					Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3 for 5 ± 1 sec. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																								
	Capacitance Change	Within $\pm 5\%$ or $\pm 0.5\text{pF}$ (whichever is larger)		Within $\pm 10\%$																											
	Deflection																														
		<table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>GNM1M2</td> <td>2.0 ± 0.05</td> <td>0.5 ± 0.05</td> <td>0.32 ± 0.05</td> <td>0.32 ± 0.05</td> </tr> <tr> <td>GNM212</td> <td>2.0 ± 0.05</td> <td>0.6 ± 0.05</td> <td>0.5 ± 0.05</td> <td>0.5 ± 0.05</td> </tr> <tr> <td>GNM214</td> <td>2.0 ± 0.05</td> <td>0.7 ± 0.05</td> <td>0.3 ± 0.05</td> <td>0.2 ± 0.05</td> </tr> <tr> <td>GNM314</td> <td>2.5 ± 0.05</td> <td>0.8 ± 0.05</td> <td>0.4 ± 0.05</td> <td>0.4 ± 0.05</td> </tr> </tbody> </table>				Type		a	b	c	d	GNM1M2	2.0 ± 0.05	0.5 ± 0.05	0.32 ± 0.05	0.32 ± 0.05	GNM212	2.0 ± 0.05	0.6 ± 0.05	0.5 ± 0.05	0.5 ± 0.05	GNM214	2.0 ± 0.05	0.7 ± 0.05	0.3 ± 0.05	0.2 ± 0.05	GNM314	2.5 ± 0.05	0.8 ± 0.05	0.4 ± 0.05	0.4 ± 0.05
		Type	a	b	c	d																									
GNM1M2		2.0 ± 0.05	0.5 ± 0.05	0.32 ± 0.05	0.32 ± 0.05																										
GNM212	2.0 ± 0.05	0.6 ± 0.05	0.5 ± 0.05	0.5 ± 0.05																											
GNM214	2.0 ± 0.05	0.7 ± 0.05	0.3 ± 0.05	0.2 ± 0.05																											
GNM314	2.5 ± 0.05	0.8 ± 0.05	0.4 ± 0.05	0.4 ± 0.05																											
(in mm)																															
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.				Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2 ± 0.5 seconds at $230 \pm 5^\circ\text{C}$ or Sn-3.0Ag-0.5Cu solder solution for 2 ± 0.5 seconds at $245 \pm 5^\circ\text{C}$.																									
14	Resistance to Soldering Heat	The measured and observed characteristics should satisfy the specifications in the following table.				Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at $270 \pm 5^\circ\text{C}$ for 10 ± 0.5 seconds. Let sit at room temperature for 24 ± 2 hours, then measure. • Initial measurement for high dielectric constant type Perform a heat treatment at $150+0/-10^\circ\text{C}$ for one hour and then let sit for 24 ± 2 hours at room temperature. Perform the initial measurement.																									
	Appearance	No marking defects																													
	Capacitance Change	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ (whichever is larger)		R7, R6, C7: Within $\pm 7.5\%$																											
	Q/D.F.	30pF min.: $Q \geq 1000$ 30pF max.: $Q \geq 400+20C$ C: Nominal Capacitance (pF)	Char.	25V min.	16V		10V	6.3V																							
			R7, R6, C7	0.025 max.	0.035 max.		0.035 max.	0.05 max.																							
I.R.	More than $10,000\text{M}\Omega$ or $500\Omega \cdot \text{F}$ (whichever is smaller)																														
Dielectric Strength	No failure																														

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GNM Series Specifications and Test Methods (1)

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When no "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).

No.	Item	Specifications				Test Method															
		Temperature Compensating Type	High Dielectric Type																		
15	Temperature Cycle	The measured and observed characteristics should satisfy the specifications in the following table.				Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours (temperature compensating type) or 48±4 hours (high dielectric constant type) at room temperature, then measure. <table border="1" style="margin-top: 10px;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table> <ul style="list-style-type: none"> • Initial measurement for high dielectric constant type Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. 	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3
	Step	1	2	3	4																
	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.																
	Time (min.)	30±3	2 to 3	30±3	2 to 3																
	Appearance	No marking defects																			
	Capacitance Change	Within ±2.5% or ±0.25pF (whichever is larger)	R7, R6, C7: Within ±7.5%																		
Q/D.F.	30pF min.: Q≥1000 30pF max.: Q≥400+20C C: Nominal Capacitance (pF)	<table border="1" style="font-size: small;"> <thead> <tr> <th>Char.</th> <th>25V min.</th> <th>16V</th> <th>10V</th> <th>6.3V</th> </tr> </thead> <tbody> <tr> <td>R7, R6, C7</td> <td>0.025 max.</td> <td>0.035 max.</td> <td>0.035 max.</td> <td>0.05 max.</td> </tr> </tbody> </table>	Char.	25V min.	16V	10V	6.3V	R7, R6, C7	0.025 max.	0.035 max.	0.035 max.	0.05 max.									
Char.	25V min.	16V	10V	6.3V																	
R7, R6, C7	0.025 max.	0.035 max.	0.035 max.	0.05 max.																	
I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																				
	Dielectric Strength	No failure																			
16	Humidity Steady State	The measured and observed characteristics should satisfy the specifications in the following table.				Set the capacitor at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure.															
	Appearance	No marking defects																			
	Capacitance Change	Within ±5% or ±0.5pF (whichever is larger)	R7, R6, C7: Within ±12.5%																		
	Q/D.F.	30pF and over: Q≥350 10pF and over, 30pF and below: Q≥275+5C/2 10pF and below: Q≥200+10C C: Nominal Capacitance (pF)	<table border="1" style="font-size: small;"> <thead> <tr> <th>Char.</th> <th>25V min.</th> <th>16V</th> <th>10V/6.3V</th> </tr> </thead> <tbody> <tr> <td>R7, R6, C7</td> <td>0.05 max.</td> <td>0.05 max.</td> <td>0.05 max.</td> </tr> </tbody> </table>	Char.	25V min.		16V	10V/6.3V	R7, R6, C7	0.05 max.	0.05 max.	0.05 max.									
	Char.	25V min.	16V	10V/6.3V																	
R7, R6, C7	0.05 max.	0.05 max.	0.05 max.																		
I.R.	More than 1,000MΩ or 50Ω · F (whichever is smaller)																				
17	Humidity Load	The measured and observed characteristics should satisfy the specifications in the following table.				Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.															
	Appearance	No marking defects																			
	Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)	R7, R6, C7: Within ±12.5%																		
	Q/D.F.	30pF and over: Q≥200 30pF and below: Q≥100+10C/3 C: Nominal Capacitance (pF)	<table border="1" style="font-size: small;"> <thead> <tr> <th>Char.</th> <th>25V min.</th> <th>16V</th> <th>10V/6.3V</th> </tr> </thead> <tbody> <tr> <td>R7, R6, C7</td> <td>0.05 max.</td> <td>0.05 max.</td> <td>0.05 max.</td> </tr> </tbody> </table>	Char.	25V min.		16V	10V/6.3V	R7, R6, C7	0.05 max.	0.05 max.	0.05 max.									
	Char.	25V min.	16V	10V/6.3V																	
R7, R6, C7	0.05 max.	0.05 max.	0.05 max.																		
I.R.	More than 500MΩ or 25Ω · F (whichever is smaller)																				

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GNM Series Specifications and Test Methods (1)

☐ Continued from the preceding page.

**When no "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).**

No.	Item	Specifications				Test Method								
		Temperature Compensating Type	High Dielectric Type											
18	High Temperature Load	The measured and observed characteristics should satisfy the specifications in the following table.				Apply 200% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. • Initial measurement for high dielectric constant type. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 24±2 hours at room temperature. Perform initial measurement.								
	Appearance	No marking defects												
	Capacitance Change	Within ±3% or ±0.3pF (whichever is larger)	R7, R6, C7: Within ±12.5%											
	Q/D.F.	30pF and over: $Q \geq 350$ 10pF and over, 30pF and below: $Q \geq 275 + 5C/2$ 10pF and below: $Q \geq 200 + 10C$ C: Nominal Capacitance (pF)	<table border="1" style="font-size: small;"> <thead> <tr> <th>Char.</th> <th>25V min.</th> <th>16V</th> <th>10V/6.3V</th> </tr> </thead> <tbody> <tr> <td>R7, R6, C7</td> <td>0.04 max.</td> <td>0.05 max.</td> <td>0.05 max.</td> </tr> </tbody> </table>	Char.	25V min.		16V	10V/6.3V	R7, R6, C7	0.04 max.	0.05 max.	0.05 max.		
	Char.	25V min.	16V	10V/6.3V										
R7, R6, C7	0.04 max.	0.05 max.	0.05 max.											
I.R.	More than 1,000MΩ or 50Ω · F (whichever is smaller)													

Table A

Char.	Nominal Values (ppm/°C) *1	Capacitance Change from 25°C (%)					
		-55°C		-30°C		-10°C	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

*1: Nominal values denote the temperature coefficient within a range of 25 to 125°C.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

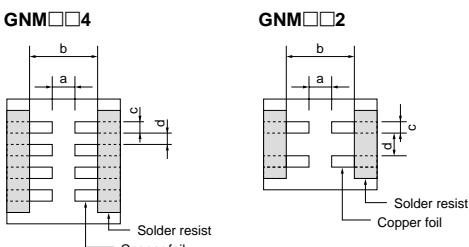
Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GNM Series Specifications and Test Methods (2)

When no "***" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method																														
1	Operating Temperature Range	R6: -55°C to +85°C																															
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.																														
3	Appearance	No defects or abnormalities	Visual inspection																														
4	Dimensions	Within the specified dimension	Using calipers																														
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.																														
6	Insulation Resistance	50Ω · F min.	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 1 minute of charging.																														
7	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at 25°C at the frequency and voltage shown in the table. <table border="1"> <thead> <tr> <th>Nominal Capacitance</th> <th>Measuring Frequency</th> <th>Measuring Voltage</th> </tr> </thead> <tbody> <tr> <td>$C \leq 10\mu\text{F}^{*1}$ (10V min.)</td> <td>1±0.1kHz</td> <td>1.0±0.2Vrms</td> </tr> <tr> <td>$C \leq 10\mu\text{F}^{*2}$ (6.3V max.)</td> <td>1±0.1kHz</td> <td>0.5±0.1Vrms</td> </tr> <tr> <td>^{*1}For items in Table1</td> <td>1±0.1kHz</td> <td>0.5±0.1Vrms</td> </tr> <tr> <td>^{*2}For items in Table2</td> <td>1±0.1kHz</td> <td>1.0±0.1Vrms</td> </tr> </tbody> </table>	Nominal Capacitance	Measuring Frequency	Measuring Voltage	$C \leq 10\mu\text{F}^{*1}$ (10V min.)	1±0.1kHz	1.0±0.2Vrms	$C \leq 10\mu\text{F}^{*2}$ (6.3V max.)	1±0.1kHz	0.5±0.1Vrms	^{*1} For items in Table1	1±0.1kHz	0.5±0.1Vrms	^{*2} For items in Table2	1±0.1kHz	1.0±0.1Vrms															
Nominal Capacitance	Measuring Frequency	Measuring Voltage																															
$C \leq 10\mu\text{F}^{*1}$ (10V min.)	1±0.1kHz	1.0±0.2Vrms																															
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^{*1} For items in Table1	1±0.1kHz	0.5±0.1Vrms																															
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8	Dissipation Factor (D.F.)	0.1 max. ^{*3} <table border="1"> <caption>Table 3</caption> <thead> <tr> <th>GNM0M2 R6</th> <th>103/223/473/104</th> </tr> </thead> <tbody> <tr> <td>GNM1M2 R6</td> <td>0J 105/225</td> </tr> <tr> <td>GNM1M2 R6</td> <td>1A 105MEA4</td> </tr> <tr> <td>GNM1M2 R6</td> <td>1A 225</td> </tr> <tr> <td>GNM212 R6</td> <td>0J 225</td> </tr> <tr> <td>GNM212 R6</td> <td>1A 225</td> </tr> <tr> <td>GNM214 R6</td> <td>0J 225</td> </tr> </tbody> </table> ^{*3} However 0.125 max. for Table 3 items.	GNM0M2 R6	103/223/473/104	GNM1M2 R6	0J 105/225	GNM1M2 R6	1A 105MEA4	GNM1M2 R6	1A 225	GNM212 R6	0J 225	GNM212 R6	1A 225	GNM214 R6	0J 225	<table border="1"> <caption>Table 1</caption> <thead> <tr> <th>GNM0M2 R6</th> <th>1A 104</th> </tr> </thead> <tbody> <tr> <td>GNM0M2 R6</td> <td>1C 104</td> </tr> <tr> <td>GNM1M2 R6</td> <td>1A 105/225</td> </tr> <tr> <td>GNM1M2 R6</td> <td>1C 224/105</td> </tr> </tbody> </table> <table border="1"> <caption>Table 2</caption> <thead> <tr> <th>GNM0M2 R6</th> <th>0J 103/223/473</th> </tr> </thead> <tbody> <tr> <td>GNM212 R6</td> <td>0J 225</td> </tr> <tr> <td>GNM214 R6</td> <td>0J 105</td> </tr> </tbody> </table>	GNM0M2 R6	1A 104	GNM0M2 R6	1C 104	GNM1M2 R6	1A 105/225	GNM1M2 R6	1C 224/105	GNM0M2 R6	0J 103/223/473	GNM212 R6	0J 225	GNM214 R6	0J 105		
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9	Capacitance Temperature Characteristics	<table border="1"> <thead> <tr> <th>Char.</th> <th>Temp. Range</th> <th>Reference Temp.</th> <th>Cap. Change</th> </tr> </thead> <tbody> <tr> <td>R6</td> <td>-55 to +85°C</td> <td>25°C</td> <td>Within ±15%</td> </tr> </tbody> </table>	Char.	Temp. Range	Reference Temp.	Cap. Change	R6	-55 to +85°C	25°C	Within ±15%	The capacitance change should be measured after 5 min. at each specified temperature stage. <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>85±3</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> The ranges of capacitance change compared with the 25°C value over the temperature ranges shown in the table should be within the specified ranges. • Initial measurement for high dielectric constant type. Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.	Step	Temperature (°C)	1	25±2	2	-55±3	3	25±2	4	85±3	5	25±2										
Char.	Temp. Range	Reference Temp.	Cap. Change																														
R6	-55 to +85°C	25°C	Within ±15%																														
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4	85±3																																
5	25±2																																
10	Adhesive Strength of Termination	No removal of the terminations or other defects should occur. 	Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply 5N (GNM0M2: 2N) force in parallel with the test jig for 10±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. <table border="1"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>GNM0M2</td> <td>0.2</td> <td>0.96</td> <td>0.25</td> <td>0.2</td> </tr> <tr> <td>GNM1M2</td> <td>0.5</td> <td>1.6</td> <td>0.32</td> <td>0.32</td> </tr> <tr> <td>GNM212</td> <td>0.6</td> <td>1.8</td> <td>0.5</td> <td>0.5</td> </tr> <tr> <td>GNM214</td> <td>0.6</td> <td>2.0</td> <td>0.25</td> <td>0.25</td> </tr> <tr> <td>GNM314</td> <td>0.8</td> <td>2.5</td> <td>0.4</td> <td>0.4</td> </tr> </tbody> </table> (in mm)	Type	a	b	c	d	GNM0M2	0.2	0.96	0.25	0.2	GNM1M2	0.5	1.6	0.32	0.32	GNM212	0.6	1.8	0.5	0.5	GNM214	0.6	2.0	0.25	0.25	GNM314	0.8	2.5	0.4	0.4
Type	a	b	c	d																													
GNM0M2	0.2	0.96	0.25	0.2																													
GNM1M2	0.5	1.6	0.32	0.32																													
GNM212	0.6	1.8	0.5	0.5																													
GNM214	0.6	2.0	0.25	0.25																													
GNM314	0.8	2.5	0.4	0.4																													
11	Vibration	Appearance: No defects or abnormalities Capacitance: Within the specified tolerance D.F.: 0.1 max. ^{*3} ^{*3} However 0.125 max. for Table 3 items.	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																														

Continued on the following page. 

GNM Series Specifications and Test Methods (2)

Continued from the preceding page.

When no "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GNM Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method																														
12	Appearance	No marking defects	Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																														
	Capacitance Change	Within $\pm 10\%$																															
	Deflection	<div style="text-align: center;"> </div> <table border="1" style="margin: 10px auto; border-collapse: collapse; text-align: center;"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>GNM0M2</td> <td>2.0\pm0.05</td> <td>0.2\pm0.05</td> <td>0.2\pm0.05</td> <td>0.25\pm0.05</td> </tr> <tr> <td>GNM1M2</td> <td>2.0\pm0.05</td> <td>0.5\pm0.05</td> <td>0.32\pm0.05</td> <td>0.32\pm0.05</td> </tr> <tr> <td>GNM212</td> <td>2.0\pm0.05</td> <td>0.6\pm0.05</td> <td>0.5\pm0.05</td> <td>0.5\pm0.05</td> </tr> <tr> <td>GNM214</td> <td>2.0\pm0.05</td> <td>0.7\pm0.05</td> <td>0.3\pm0.05</td> <td>0.2\pm0.05</td> </tr> <tr> <td>GNM314</td> <td>2.5\pm0.05</td> <td>0.8\pm0.05</td> <td>0.4\pm0.05</td> <td>0.4\pm0.05</td> </tr> </tbody> </table> <p style="text-align: center;">(in mm)</p>	Type	a	b	c	d	GNM0M2	2.0 \pm 0.05	0.2 \pm 0.05	0.2 \pm 0.05	0.25 \pm 0.05	GNM1M2	2.0 \pm 0.05	0.5 \pm 0.05	0.32 \pm 0.05	0.32 \pm 0.05	GNM212	2.0 \pm 0.05	0.6 \pm 0.05	0.5 \pm 0.05	0.5 \pm 0.05	GNM214	2.0 \pm 0.05	0.7 \pm 0.05	0.3 \pm 0.05	0.2 \pm 0.05	GNM314	2.5 \pm 0.05	0.8 \pm 0.05	0.4 \pm 0.05	0.4 \pm 0.05	<div style="text-align: center;"> </div> <p style="text-align: center;">Flexure : ≤ 1</p>
Type	a	b	c	d																													
GNM0M2	2.0 \pm 0.05	0.2 \pm 0.05	0.2 \pm 0.05	0.25 \pm 0.05																													
GNM1M2	2.0 \pm 0.05	0.5 \pm 0.05	0.32 \pm 0.05	0.32 \pm 0.05																													
GNM212	2.0 \pm 0.05	0.6 \pm 0.05	0.5 \pm 0.05	0.5 \pm 0.05																													
GNM214	2.0 \pm 0.05	0.7 \pm 0.05	0.3 \pm 0.05	0.2 \pm 0.05																													
GNM314	2.5 \pm 0.05	0.8 \pm 0.05	0.4 \pm 0.05	0.4 \pm 0.05																													
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2 \pm 0.5 seconds at 230 \pm 5°C or Sn-3.0Ag-0.5Cu solder solution for 2 \pm 0.5 seconds at 245 \pm 5°C.																														
14	Resistance to Soldering Heat	Appearance	No marking defects																														
		Capacitance Change	R6*: Within $\pm 7.5\%$ ** GNM0M2R60G105: Within +15/-7.5%																														
		D.F.	0.1 max. * ³ * ³ However 0.125 max. for Table 3 items.																														
		I.R.	50 Ω · F min.																														
		Dielectric Strength	No failure																														
15	Temperature Cycle	Appearance	No marking defects																														
		Capacitance Change	R6* ⁵ : Within $\pm 12.5\%$ * ⁵ GNM0M2R60G105, GNM0M2R60J103/223/473/104, GNM0M2R61A103/223/473/104, GNM0M2R61C103/223/473/104, GNM1M2R61A105: Within $\pm 15\%$																														
		D.F.	0.1 max. * ³ * ³ However 0.125 max. for Table 3 items.																														
		I.R.	50 Ω · F min.																														
		Dielectric Strength	No failure																														
16	High Temperature High Humidity (Steady)	Appearance	No marking defects																														
		Capacitance Change	R6: Within $\pm 12.5\%$																														
		D.F.	0.2 max.																														
		I.R.	12.5 Ω · F min.																														
17	Durability	Appearance	No marking defects																														
		Capacitance Change	R6: Within $\pm 12.5\%$																														
		D.F.	0.2 max.																														
		I.R.	25 Ω · F min.																														

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



Low ESL LLL/LLR/LLA/LLM Series

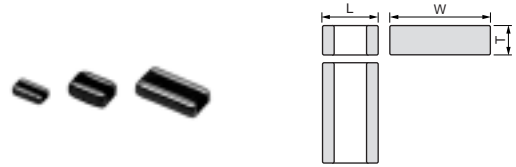
Reversed Geometry Low ESL Type

■ Features

1. Low ESL, good for noise reduction for high frequency
2. Small, high cap

■ Applications

Decoupling solution for "chip sets", such as Mobile/FPD TV



Part Number	Dimensions (mm)		
	L	W	T
LLL153	0.5 ±0.05	1.0 ±0.05	0.3 ±0.05
LLL185	0.8 ±0.1	1.6 ±0.1	0.6 max.
LLL215	1.25 ±0.1	2.0 ±0.1	0.5 +0/-0.15
LLL216			0.6 ±0.1
LLL219	1.6 ±0.15	3.2 ±0.15	0.85 ±0.1
LLL315			0.5 +0/-0.15
LLL317			0.7 ±0.1
LLL31M	0.8 ±0.15	1.6 ±0.15	1.15 ±0.1
LLR185			0.5 +0.05/-0.1

Controlled ESR Low ESL Type

■ Features

1. Good solution for anti resonance reduction with Controlled ESR.
2. Suitable for high speed IC decoupling due to low inductance type.
3. 4 types of ESR are available.

■ Applications

1. All kind of IC package (network processor, media processor, etc)
2. Circuit that has anti-resonance

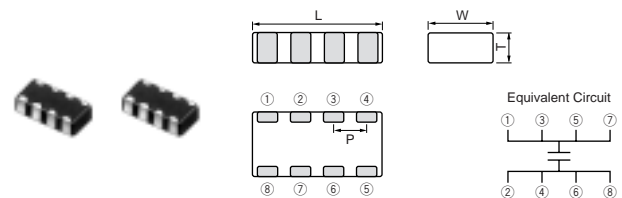
Eight Terminals Low ESL Type

■ Features

1. Low ESL (100pH), suitable to decoupling capacitor for 1GHz clock speed IC.
2. Small, high cap

■ Applications

High speed IC package (FPGA, network processor, etc)



Part Number	Dimensions (mm)			
	L	W	T	P
LLA185	1.6 ±0.1	0.8 ±0.1	0.5 +0.05/-0.1	0.4 ±0.1
LLA215	2.0 ±0.1	1.25 ±0.1	0.5 +0.05/-0.1	0.5 ±0.05
LLA219	2.0 ±0.1	1.25 ±0.1	0.85 ±0.1	0.5 ±0.05
LLA315	3.2 ±0.15	1.6 ±0.15	0.5 +0.05/-0.1	0.8 ±0.1
LLA319	3.2 ±0.15	1.6 ±0.15	0.85 ±0.1	0.8 ±0.1
LLA31M	3.2 ±0.15	1.6 ±0.15	1.15 ±0.1	0.8 ±0.1

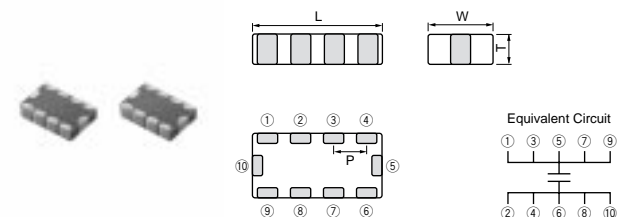
Ten Terminals Low ESL Type

■ Features

1. Low ESL (45pH), suitable to decoupling capacitor for 2GHz clock speed IC.
2. Small, high cap

■ Applications

High speed IC package (FPGA, network processor, etc)



Part Number	Dimensions (mm)			
	L	W	T	P
LLM215	2.0 ±0.1	1.25 ±0.1	0.5 +0.05/-0.1	0.5 ±0.05
LLM315	3.2 ±0.15	1.6 ±0.15	0.5 +0.05/-0.1	0.8 ±0.1

For General GRM Series

Array GNM Series

Low ESL LLL Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Capacitance Table

Reversed Geometry Low ESL Type X7R(R7)/X7S(C7)/X6S(C8)/X5R(R6) Characteristics

		5 ex.5: T Dimension [mm]		0.5x1.0 (15) <0204>					0.8x1.6 (18) <0306>					1.25x2.0 (21) <0508>					1.6x3.2 (31) <0612>				
Capacitance	LxW [mm]	6.3 (0J)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)					
	Rated Voltage [Vdc]																						
2200pF(222)				5																			
4700pF(472)				5																			
10000pF(103)					5				6									7					
22000pF(223)					5				6									7					
47000pF(473)						5				6								7					
0.10μF(104)		3					5			6				M	7								
0.22μF(224)		3					5				9	6			M	7							
0.47μF(474)			3					5				9			M	7							
1.0μF(105)								5				9				M	7						
2.2μF(225)								5					9				M	7					
4.7μF(475)																		M					
10μF(106)																			M				

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

Reversed Geometry Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

		5 ex.5: T Dimension [mm]		0.8x1.6 (18) <0306>				1.25x2.0 (21) <0508>				1.6x3.2 (31) <0612>			
Capacitance	LxW [mm]	25 (1E)	16 (1C)	10 (1A)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)	6.3 (0J)	4 (0G)	50 (1H)	25 (1E)	16 (1C)	10 (1A)
	Rated Voltage [Vdc]														
10000pF(103)		5				5						5			
22000pF(223)			5				5					5			
47000pF(473)			5					5				5			
0.10μF(104)				5				5				5			
0.22μF(224)					5				5				5		
0.47μF(474)										5				5	
1.0μF(105)											5				

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

Controlled ESR Low ESL Type X7S(C7) Characteristics

		5 ex.5: T Dimension [mm]		0.8x1.6 (18) <0306>			
Capacitance	LxW [mm]						
	Rated Voltage [Vdc]	4 (0G)					
Capacitance	ESR [mΩ]	100 (E01)	220 (E03)	470 (E05)	1000 (E07)		
	1.0μF(105)		5	5	5	5	

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Capacitance Table

For General
GRM Series

Eight Terminals Low ESL Type X7S(C7)/X7R(R7) Characteristics

		5 ex.5: T Dimension [mm]									
		1.6x0.8 (18) <0603>			2.0x1.25 (21) <0805>				3.2x1.6 (31) <1206>		
Rated Voltage [Vdc]		4	25	16	10	6.3	4	16	10	4	
Capacitance		(0G)	(1E)	(1C)	(1A)	(0J)	(0G)	(1C)	(1A)	(0G)	
10000pF(103)			9								
22000pF(223)			9								
47000pF(473)			9								
0.10μF(104)		5		9				9			
0.22μF(224)		5		9				9			
0.47μF(474)		5			9			9			
1.0μF(105)		5				9		M	9		
2.2μF(225)		5					9		M	9	
4.7μF(475)							9				

The part number code is shown in () and Unit is shown in []. <->: EIA [inch] Code

Array
GMM Series

Low ESL
LL□ Series

Eight Terminals Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

		5 ex.5: T Dimension [mm]									
		2.0x1.25 (21) <0805>					3.2x1.6 (31) <1206>				
Rated Voltage [Vdc]		25	16	10	6.3	4	16	10	6.3		
Capacitance		(1E)	(1C)	(1A)	(0J)	(0G)	(1C)	(1A)	(0J)		
10000pF(103)		5									
22000pF(223)		5									
47000pF(473)			5								
0.10μF(104)			5								
0.22μF(224)				5			5				
0.47μF(474)					5			5			
1.0μF(105)						5			5		
2.2μF(225)							5		5		
4.7μF(475)							5				

The part number code is shown in () and Unit is shown in []. <->: EIA [inch] Code

High-Q
GJM Series

High Frequency
GOM Series

Ten Terminals Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

		5 ex.5: T Dimension [mm]									
		2.0x1.25 (21) <0805>					3.2x1.6 (31) <1206>				
Rated Voltage [Vdc]		25	16	6.3	4	16	10	6.3			
Capacitance		(1E)	(1C)	(0J)	(0G)	(1C)	(1A)	(0J)			
10000pF(103)		5									
22000pF(223)		5									
47000pF(473)			5								
0.10μF(104)			5			5					
0.22μF(224)				5		5					
0.47μF(474)					5		5				
1.0μF(105)						5					
2.2μF(225)								5			

The part number code is shown in () and Unit is shown in []. <->: EIA [inch] Code

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Reversed Geometry Low ESL Type X7R(R7)/X7S(C7)/X6S(C8) Characteristics

LxW [mm]		0.5x1.0(15)<0204>	
Rated Volt. [Vdc]		6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number	
0.10μF(104)	±20%(M)	LLL153C80J104ME01E*	
0.22μF(224)	±20%(M)	LLL153C80J224ME14E*	
0.47μF(474)	±20%(M)	LLL153C70G474ME17E*	

LLL153 Series 4V/0.47μF(L: 0.5+0.07/-0.03mm)

LxW [mm]		0.8x1.6(18)<0306>			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
2200pF(222)	±20%(M)	LLL185R71H222MA01L			
4700pF(472)	±20%(M)	LLL185R71H472MA01L			
10000pF(103)	±20%(M)	LLL185R71E103MA01L			
22000pF(223)	±20%(M)	LLL185R71E223MA01L			
47000pF(473)	±20%(M)	LLL185R71C473MA01L			
0.10μF(104)	±20%(M)	LLL185R71A104MA01L			
0.22μF(224)	±20%(M)	LLL185R71A224MA01L			

LxW [mm]		0.8x1.6(18)<0306>	
Rated Volt. [Vdc]		4(0G)	
Capacitance	Tolerance	Part Number	
0.47μF(474)	±20%(M)	LLL185C70G474MA01L	
1.0μF(105)	±20%(M)	LLL185C70G105ME02L*	
2.2μF(225)	±20%(M)	LLL185C70G225ME01L*	

LxW [mm]		1.25x2.0(21)<0508>			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLL216R71H103MA01L			
22000pF(223)	±20%(M)	LLL216R71H223MA01L			
47000pF(473)	±20%(M)	LLL216R71E473MA01L			
0.10μF(104)	±20%(M)	LLL216R71E104MA01L			
0.22μF(224)	±20%(M)	LLL219R71C224MA01L			
0.47μF(474)	±20%(M)	LLL219R71A474MA01L			
1.0μF(105)	±20%(M)	LLL219R71A105MA01L			

LxW [mm]		1.25x2.0(21)<0508>	
Rated Volt. [Vdc]		4(0G)	
Capacitance	Tolerance	Part Number	
2.2μF(225)	±20%(M)	LLL219C70G225MA01L	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code
 * Please refer to LLL/LLR/LLA/LLM Series Specifications and Test Method (2).

(Part Number) LL L 15 3 C8 0J 104 M E01 E

1 2 3 4 5 6 7 8 9 10

1 Product ID 2 Series 3 Dimensions (LxW) 4 Dimension (T)
5 Temperature Characteristics 6 Rated Voltage 7 Capacitance
8 Capacitance Tolerance 9 Individual Specification Code 10 Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

For General GRM Series
 Array GNM Series
 Low ESL LLM Series
 High-Q GJM Series
 High Frequency GQM Series
 Monolithic Microchip GMA Series
 For Bonding GMD Series
 Product Information

Reversed Geometry Low ESL Type X7R(R7)/X5R(R6) Characteristics

LxW [mm]		1.6x3.2(31)<0612>			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLL317R71H103MA01L			
22000pF(223)	±20%(M)	LLL317R71H223MA01L			
47000pF(473)	±20%(M)	LLL317R71H473MA01L			
0.10μF(104)	±20%(M)	LLL31MR71H104MA01L	LLL317R71E104MA01L		
0.22μF(224)	±20%(M)		LLL31MR71E224MA01L	LLL317R71C224MA01L	
0.47μF(474)	±20%(M)		LLL31MR71E474MA01L	LLL317R71C474MA01L	
1.0μF(105)	±20%(M)			LLL31MR71C105MA01L	LLL317R71A105MA01L
2.2μF(225)	±20%(M)				LLL31MR71A225MA01L

LxW [mm]		1.6x3.2(31)<0612>	
Rated Volt. [Vdc]		6.3(0J)	
Capacitance	Tolerance	Part Number	
2.2μF(225)	±20%(M)	LLL317R70J225MA01L	
4.7μF(475)	±20%(M)	LLL31MR70J475MA01L	
10μF(106)	±20%(M)	LLL31MR60J106ME01L*	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code
 * Please refer to LLL/LLR/LLA/LLM Series Specifications and Test Method (2).

Reversed Geometry Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

LxW [mm]		0.8x1.6(18)<0306>			
Rated Volt. [Vdc]		25(1E)	16(1C)	10(1A)	4(0G)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLL185R71E103MA11L			
22000pF(223)	±20%(M)		LLL185R71C223MA11L		
47000pF(473)	±20%(M)		LLL185R71C473MA11L		
0.10μF(104)	±20%(M)			LLL185R71A104MA11L	
0.22μF(224)	±20%(M)				LLL185C70G224MA11L

LxW [mm]		1.25x2.0(21)<0508>			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLL215R71H103MA11L			
22000pF(223)	±20%(M)		LLL215R71E223MA11L		
47000pF(473)	±20%(M)			LLL215R71C473MA11L	
0.10μF(104)	±20%(M)			LLL215R71C104MA11L	
0.22μF(224)	±20%(M)				LLL215R71A224MA11L

LxW [mm]		1.25x2.0(21)<0508>	
Rated Volt. [Vdc]		6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number	
0.47μF(474)	±20%(M)	LLL215R70J474MA11L	
1.0μF(105)	±20%(M)	LLL215C70G105MA11L	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

- (Part Number) **LL** **L** **31** **7** **R7** **1H** **103** **M** **A01** **L** ①Product ID ②Series ③Dimensions (LxW) ④Dimension (T)
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

Reversed Geometry Low ESL Type X7R(R7) Characteristics-Low Profile

LxW [mm]		1.6x3.2(31)<0612>			
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)	10(1A)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLL315R71H103MA11L			
22000pF(223)	±20%(M)	LLL315R71H223MA11L			
47000pF(473)	±20%(M)		LLL315R71E473MA11L		
0.10μF(104)	±20%(M)		LLL315R71E104MA11L		
0.22μF(224)	±20%(M)			LLL315R71C224MA11L	
0.47μF(474)	±20%(M)				LLL315R71A474MA11L

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

Controlled ESR Low ESL Type X7S(C7) Characteristics

LxW [mm]		0.8x1.6(18)<0306>			
Rated Volt. [Vdc]		4(0G)			
ESR [mΩ]		100(E01)	220(E03)	470(E05)	1000(E07)
Capacitance	Tolerance	Part Number			
1.0μF(105)	±20%(M)	LLR185C70G105ME01L*	LLR185C70G105ME03L*	LLR185C70G105ME05L*	LLR185C70G105ME07L*

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

* Please refer to LLL/LLR/LLA/LLM Series Specifications and Test Method (2).

Eight Terminals Low ESL Type X7R(R7)/X7S(C7) Characteristics

LxW [mm]		1.6x0.8(18)<0603>
Rated Volt. [Vdc]		4(0G)
Capacitance	Tolerance	Part Number
0.10μF(104)	±20%(M)	LLA185C70G104MA01L
0.22μF(224)	±20%(M)	LLA185C70G224MA01L
0.47μF(474)	±20%(M)	LLA185C70G474MA01L
1.0μF(105)	±20%(M)	LLA185C70G105ME01L*
2.2μF(225)	±20%(M)	LLA185C70G225ME16L*

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		25(1E)	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLA219R71E103MA01L			
22000pF(223)	±20%(M)	LLA219R71E223MA01L			
47000pF(473)	±20%(M)	LLA219R71E473MA01L			
0.10μF(104)	±20%(M)		LLA219R71C104MA01L		
0.22μF(224)	±20%(M)		LLA219R71C224MA01L		
0.47μF(474)	±20%(M)			LLA219R71A474MA01L	
1.0μF(105)	±20%(M)				LLA219R70J105MA01L

LxW [mm]		2.0x1.25(21)<0805>
Rated Volt. [Vdc]		4(0G)
Capacitance	Tolerance	Part Number
2.2μF(225)	±20%(M)	LLA219C70G225MA01L
4.7μF(475)	±20%(M)	LLA219C70G475ME01L*

The part number code is shown in () and Unit is shown in []. <>: EIA [inch] Code

* Please refer to LLL/LLR/LLA/LLM Series Specifications and Test Method (2).

For General GRM Series

Array GNM Series

Low ESL LLL Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Eight Terminals Low ESL Type X7R(R7) Characteristics

LxW [mm]		3.2x1.6(31)<1206>		
Rated Volt. [Vdc]		16(1C)	10(1A)	4(0G)
Capacitance	Tolerance	Part Number		
0.10μF(104)	±20%(M)	LLA319R71C104MA01L		
0.22μF(224)	±20%(M)	LLA319R71C224MA01L		
0.47μF(474)	±20%(M)	LLA319R71C474MA01L		
1.0μF(105)	±20%(M)	LLA31MR71C105MA01L	LLA319R71A105MA01L	
2.2μF(225)	±20%(M)		LLA31MR71A225MA01L	LLA319R70G225MA01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Eight Terminals Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		25(1E)	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLA215R71E103MA14L			
22000pF(223)	±20%(M)	LLA215R71E223MA14L			
47000pF(473)	±20%(M)		LLA215R71C473MA14L		
0.10μF(104)	±20%(M)		LLA215R71C104MA14L		
0.22μF(224)	±20%(M)			LLA215R71A224MA14L	
0.47μF(474)	±20%(M)				LLA215R70J474MA14L

LxW [mm]		2.0x1.25(21)<0805>	3.2x1.6(31)<1206>		
Rated Volt. [Vdc]		4(0G)	16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
0.22μF(224)	±20%(M)		LLA315R71C224MA14L		
0.47μF(474)	±20%(M)			LLA315R71A474MA14L	
1.0μF(105)	±20%(M)	LLA215C70G105MA14L			LLA315R70J105MA14L
2.2μF(225)	±20%(M)	LLA215C70G225ME11L*			LLA315R70J225MA14L
4.7μF(475)	±20%(M)	LLA215C70G475ME19L*			

Ten Terminals Low ESL Type X7R(R7)/X7S(C7) Characteristics-Low Profile

LxW [mm]		2.0x1.25(21)<0805>			
Rated Volt. [Vdc]		25(1E)	16(1C)	6.3(0J)	4(0G)
Capacitance	Tolerance	Part Number			
10000pF(103)	±20%(M)	LLM215R71E103MA11L			
22000pF(223)	±20%(M)	LLM215R71E223MA11L			
47000pF(473)	±20%(M)		LLM215R71C473MA11L		
0.10μF(104)	±20%(M)		LLM215R71C104MA11L		
0.22μF(224)	±20%(M)			LLM215R70J224MA11L	
0.47μF(474)	±20%(M)			LLM215R70J474MA11L	
1.0μF(105)	±20%(M)				LLM215C70G105MA11L
2.2μF(225)	±20%(M)				LLM215C70G225ME11L*

LxW [mm]		3.2x1.6(31)<1206>		
Rated Volt. [Vdc]		16(1C)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number		
0.10μF(104)	±20%(M)	LLM315R71C104MA11L		
0.22μF(224)	±20%(M)	LLM315R71C224MA11L		
0.47μF(474)	±20%(M)		LLM315R71A474MA11L	
2.2μF(225)	±20%(M)			LLM315R70J225MA11L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to LLL/LLR/LLA/LLM Series Specifications and Test Method (2).

- (Part Number) **LL** **A** **31** **9** **R7** **1C** **104** **M** **A01** **L**
- ① Product ID
 - ② Series
 - ③ Dimensions (LxW)
 - ④ Dimension (T)
 - ⑤ Temperature Characteristics
 - ⑥ Rated Voltage
 - ⑦ Capacitance
 - ⑧ Capacitance Tolerance
 - ⑨ Individual Specification Code
 - ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

LLL/LLR/LLA/LLM Series Specifications and Test Methods (1)

When no "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method																								
1	Operating Temperature Range	R7, C7: -55 to +125°C																									
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.																								
3	Appearance	No defects or abnormalities	Visual inspection																								
4	Dimensions	Within the specified dimension	Using calipers																								
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.																								
6	Insulation Resistance	$C \leq 0.047\mu\text{F}$: More than 10,000MΩ $C > 0.047\mu\text{F}$: More than $500\Omega \cdot \text{F}$ C: Normal Capacitance	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging.																								
7	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at 25°C at the frequency and voltage shown in the table. Frequency: $1 \pm 0.1\text{kHz}$ Voltage: $1 \pm 0.2\text{Vrms}$ *For LLA185C70G474, the capacitance should be measured using a voltage of $0.5 \pm 0.1\text{Vrms}$.																								
8	Dissipation Factor (D.F.)	W.V.: 25V min.; 0.025 max. W.V.: 16V/10V max.; 0.035 max. W.V.: 6.3V max.; 0.05 max.																									
9	Capacitance Temperature Characteristics	<table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Char.</th> <th>Temp. Range (°C)</th> <th>Reference Temp.</th> <th>Cap.Change</th> </tr> </thead> <tbody> <tr> <td>R7</td> <td>-55 to +125</td> <td>25°C</td> <td>Within $\pm 15\%$</td> </tr> <tr> <td>C7</td> <td>-55 to +125</td> <td>25°C</td> <td>Within $\pm 22\%$</td> </tr> </tbody> </table>	Char.	Temp. Range (°C)	Reference Temp.	Cap.Change	R7	-55 to +125	25°C	Within $\pm 15\%$	C7	-55 to +125	25°C	Within $\pm 22\%$	<p>The capacitance change should be measured after 5 min. at each specified temperature stage.</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>The ranges of capacitance change compared with the 25°C value over the temperature ranges shown in the table should be within the specified ranges.</p> <ul style="list-style-type: none"> Initial measurement. <p>Perform a heat treatment at $150 \pm 0/-10^\circ\text{C}$ for one hour and then set for 24 ± 2 hours at room temperature. Perform the initial measurement.</p>	Step	Temperature (°C)	1	25±2	2	-55±3	3	25±2	4	125±3	5	25±2
Char.	Temp. Range (°C)	Reference Temp.	Cap.Change																								
R7	-55 to +125	25°C	Within $\pm 15\%$																								
C7	-55 to +125	25°C	Within $\pm 22\%$																								
Step	Temperature (°C)																										
1	25±2																										
2	-55±3																										
3	25±2																										
4	125±3																										
5	25±2																										
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	Solder the capacitor to the test jig (glass epoxy board) using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10 ± 1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *5N (LLL18 and LLA/LLM Series)																								
11	Vibration Resistance	Appearance	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																								
		Capacitance																									
		D.F.																									
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2 ± 0.5 seconds at $230 \pm 5^\circ\text{C}$, or Sn-3.0Ag-0.5Cu solder solution for 2 ± 0.5 seconds at $245 \pm 5^\circ\text{C}$.																								
13	Resistance to Soldering Heat	Appearance	Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at $270 \pm 5^\circ\text{C}$ for 10 ± 0.5 seconds. Let sit at room temperature for 24 ± 2 hours, then measure.																								
		Capacitance Change																									
		D.F.																									
		I.R.																									
		Dielectric Strength																									

Continued on the following page.

LLL/LLR/LLA/LLM Series Specifications and Test Methods (1)

Continued from the preceding page. **When no "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (1). When "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (2).**

No.	Item	Specifications	Test Method															
14	Temperature Cycle	Appearance	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure. <table border="1" style="margin-top: 10px;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3
		Step		1	2	3	4											
		Temp. (°C)		Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.											
		Time (min.)		30±3	2 to 3	30±3	2 to 3											
		Capacitance Change		Within ±7.5%														
D.F.	W.V.: 25V min.; 0.025 max. W.V.: 16V/10V max.; 0.035 max. W.V.: 6.3V max.; 0.05 max.																	
I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)																	
	Dielectric Strength	No failure																
15	Humidity (Steady State)	Appearance	Set the capacitor at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure.															
		Capacitance Change		Within ±12.5%														
		D.F.		W.V.: 10V min.; 0.05 max. W.V.: 6.3V max.; 0.075 max.														
		I.R.		More than 1,000MΩ or 50Ω · F (whichever is smaller)														
16	Humidity Load	Appearance	Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.															
		Capacitance Change		Within ±12.5%														
		D.F.		W.V.: 10V min.; 0.05 max. W.V.: 6.3V max.; 0.075 max.														
		I.R.		More than 500MΩ or 25Ω · F (whichever is smaller)														
17	High Temperature Load	Appearance	Apply 200% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. <p>•Initial measurement. Apply 200% of the rated DC voltage for one hour at the maximum operating temperature ±3°C. Remove and let sit for 24±2 hours at room temperature. Perform initial measurement.</p>															
		Capacitance Change		Within ±12.5%														
		D.F.		W.V.: 10V min.; 0.05 max. W.V.: 6.3V max.; 0.075 max.														
		I.R.		More than 1,000MΩ or 50Ω · F (whichever is smaller)														

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series


For Bonding GMD Series

Product Information

LLL/LLR/LLA/LLM Series Specifications and Test Methods (2)

When no "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method																	
1	Operating Temperature Range	R6: -55 to +85°C R7, C7: -55 to +125°C C8: -55 to +105°C																		
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{0-P} , whichever is larger, should be maintained within the rated voltage range.																	
3	Appearance	No defects or abnormalities	Visual inspection																	
4	Dimensions	Within the specified dimension	Using calipers																	
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.																	
6	Insulation Resistance	50Ω · F min.	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 1 minute of charging.																	
7	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at 25°C at the frequency and voltage shown in the table.																	
8	Dissipation Factor (D.F.)	R6, R7, C7, C8: 0.120 max.	<table border="1"> <thead> <tr> <th>Capacitance</th> <th>Frequency</th> <th>Voltage</th> </tr> </thead> <tbody> <tr> <td>C ≤ 10μF (10V min.)</td> <td>1 ± 0.1kHz</td> <td>1.0 ± 0.2Vrms</td> </tr> <tr> <td>C ≤ 10μF (6.3V max.)</td> <td>1 ± 0.1kHz</td> <td>0.5 ± 0.1Vrms</td> </tr> <tr> <td>C > 10μF</td> <td>120 ± 24Hz</td> <td>0.5 ± 0.1Vrms</td> </tr> </tbody> </table>	Capacitance	Frequency	Voltage	C ≤ 10μF (10V min.)	1 ± 0.1kHz	1.0 ± 0.2Vrms	C ≤ 10μF (6.3V max.)	1 ± 0.1kHz	0.5 ± 0.1Vrms	C > 10μF	120 ± 24Hz	0.5 ± 0.1Vrms					
Capacitance	Frequency	Voltage																		
C ≤ 10μF (10V min.)	1 ± 0.1kHz	1.0 ± 0.2Vrms																		
C ≤ 10μF (6.3V max.)	1 ± 0.1kHz	0.5 ± 0.1Vrms																		
C > 10μF	120 ± 24Hz	0.5 ± 0.1Vrms																		
9	Capacitance Temperature Characteristics	<table border="1"> <thead> <tr> <th>Char.</th> <th>Temp. Range (°C)</th> <th>Reference Temp.</th> <th>Cap. Change</th> </tr> </thead> <tbody> <tr> <td>R6</td> <td>-55 to +85</td> <td rowspan="4">25°C</td> <td>Within ±15%</td> </tr> <tr> <td>R7</td> <td>-55 to +125</td> <td>Within ±15%</td> </tr> <tr> <td>C7</td> <td>-55 to +125</td> <td>Within ±22%</td> </tr> <tr> <td>C8</td> <td>-55 to +105</td> <td>Within ±22%</td> </tr> </tbody> </table>	Char.	Temp. Range (°C)	Reference Temp.	Cap. Change	R6	-55 to +85	25°C	Within ±15%	R7	-55 to +125	Within ±15%	C7	-55 to +125	Within ±22%	C8	-55 to +105	Within ±22%	<p>The capacitance change should be measured after 5 min. at each specified temperature stage. The ranges of capacitance change compared with the 25°C value over the temperature ranges shown in the table should be within the specified ranges.</p> <p>• Initial measurement. Perform a heat treatment at 150+0/-10°C for one hour and then set for 24±2 hours at room temperature. Perform the initial measurement.</p>
Char.	Temp. Range (°C)	Reference Temp.	Cap. Change																	
R6	-55 to +85	25°C	Within ±15%																	
R7	-55 to +125		Within ±15%																	
C7	-55 to +125		Within ±22%																	
C8	-55 to +105		Within ±22%																	
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	Solder the capacitor to the test jig (glass epoxy board) using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *5N (LLL15, LLL18, LLR18, LLA, LLM Series)																	
11	Vibration	Appearance	Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).																	
Capacitance		Within the specified tolerance																		
D.F.		R6, R7, C7, C8: 0.120 max.																		
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2±0.5 seconds at 230±5°C, or Sn-3.0Ag-0.5Cu solder solution for 2±0.5 seconds at 245±5°C.																	
13	Resistance to Soldering Heat	Appearance	Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at 270±5°C for 10±0.5 seconds. Let sit at room temperature for 24±2 hours, then measure. • Initial measurement. Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement.																	
Capacitance Change		R6, R7, C7, C8: Within ±7.5%																		
D.F.		R6, R7, C7, C8: 0.120 max.																		
I.R.		50Ω · F min.																		
Dielectric Strength		No failure																		

Continued on the following page. 

For General GRM Series

Array GNM Series

Low ESL LLL Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

LLL/LLR/LLA/LLM Series Specifications and Test Methods (2)

☐ Continued from the preceding page. **When no "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to LLL/LLR/LLA/LLM Series Specifications and Test Methods (2).**

No.	Item	Specifications	Test Method															
14	Appearance	No marking defects	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24±2 hours at room temperature, then measure. <table border="1" style="margin-top: 10px;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table> <ul style="list-style-type: none"> • Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. 	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Min. Operating Temp. +0/-3	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3
	Step	1		2	3	4												
	Temp. (°C)	Min. Operating Temp. +0/-3		Room Temp.	Min. Operating Temp. +0/-3	Room Temp.												
	Time (min.)	30±3		2 to 3	30±3	2 to 3												
	Capacitance Change	R6, R7, C7, C8: Within ±12.5%																
D.F.	R6, R7, C7, C8: 0.120 max.																	
I.R.	50Ω · F min.																	
Dielectric Strength	No failure																	
15	Appearance	No marking defects	Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. The charge/discharge current is less than 50mA. Apply the rated DC voltage. <ul style="list-style-type: none"> • Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure. 															
	Capacitance Change	R6, R7, C7, C8: Within ±12.5%																
	D.F.	R6, R7, C7, C8: 0.2 max.																
	I.R.	12.5Ω · F min.																
16	Appearance	No marking defects	Apply 150% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. The charge/discharge current is less than 50mA. <ul style="list-style-type: none"> • Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure. 															
	Capacitance Change	R6, R7, C7, C8: Within ±12.5% * LLL153C70G474: Within ±20%																
	D.F.	R6, R7, C7, C8: 0.2 max.																
	I.R.	25Ω · F min.																
*	ESR	Within below ESR value at Frequency: 10±0.1MHz 100mΩ: Within 70 to 130mΩ 220mΩ: Within 154 to 286mΩ 470mΩ: Within 329 to 611mΩ 1000mΩ: Within 700 to 1300mΩ	The ESR should be measured at room temperature with the Equivalent of HP4294A.															

* LLR: This specification is only for LLR Type

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



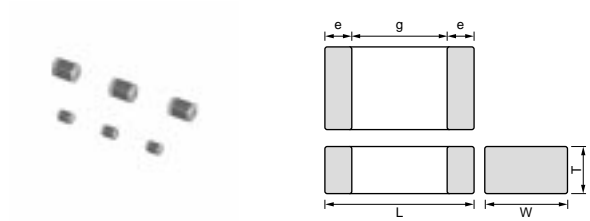
High-Q Type GJM Series

■ Features

1. Mobile Telecommunication and RF module, mainly
2. Improvement of telephone call quality, Low power Consumption, yield ratio improvement.

■ Applications

VCO, PA, Mobile Telecommunication



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GJM03	0.6 ±0.03	0.3 ±0.03	0.3 ±0.03	0.1 to 0.2	0.2
GJM15	1.0 ±0.05	0.5 ±0.05	0.5 ±0.05	0.15 to 0.35	0.3

For General
GRM Series

Array
GNM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Capacitance Table

Temperature Compensating Type C0G(5C)/C0H(6C) Characteristics

		3 ex.3: T Dimension [mm]												
Capacitance	LxW [mm]	0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>	Capacitance	LxW [mm]	0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>	Capacitance	LxW [mm]	0.6x0.3 (03) <0201>		1.0x0.5 (15) <0402>
		Rated Voltage [Vdc]	25 (1E)	6.3 (0J)			50 (1H)	Rated Voltage [Vdc]	25 (1E)			6.3 (0J)	50 (1H)	Rated Voltage [Vdc]
0.1pF(R10)				5	5.0pF(5R0)		3		5	9.9pF(9R9)		3		5
0.2pF(R20)	3			5	5.1pF(5R1)	3			5	10pF(100)	3			5
0.3pF(R30)	3			5	5.2pF(5R2)	3			5	11pF(110)	3			5
0.4pF(R40)	3			5	5.3pF(5R3)	3			5	12pF(120)	3			5
0.5pF(R50)	3			5	5.4pF(5R4)	3			5	13pF(130)	3			5
0.6pF(R60)	3			5	5.5pF(5R5)	3			5	15pF(150)	3			5
0.7pF(R70)	3			5	5.6pF(5R6)	3			5	16pF(160)	3			5
0.8pF(R80)	3			5	5.7pF(5R7)	3			5	18pF(180)	3			5
0.9pF(R90)	3			5	5.8pF(5R8)	3			5	20pF(200)	3			5
1.0pF(1R0)	3			5	5.9pF(5R9)	3			5	22pF(220)		3		
1.1pF(1R1)	3			5	6.0pF(6R0)	3			5	24pF(240)		3		
1.2pF(1R2)	3			5	6.1pF(6R1)	3			5	27pF(270)		3		
1.3pF(1R3)	3			5	6.2pF(6R2)	3			5	30pF(300)		3		
1.4pF(1R4)	3			5	6.3pF(6R3)	3			5	33pF(330)		3		
1.5pF(1R5)	3			5	6.4pF(6R4)	3			5					
1.6pF(1R6)	3			5	6.5pF(6R5)	3			5					
1.7pF(1R7)	3			5	6.6pF(6R6)	3			5					
1.8pF(1R8)	3			5	6.7pF(6R7)	3			5					
1.9pF(1R9)	3			5	6.8pF(6R8)	3			5					
2.0pF(2R0)	3			5	6.9pF(6R9)	3			5					
2.1pF(2R1)	3			5	7.0pF(7R0)	3			5					
2.2pF(2R2)	3			5	7.1pF(7R1)	3			5					
2.3pF(2R3)	3			5	7.2pF(7R2)	3			5					
2.4pF(2R4)	3			5	7.3pF(7R3)	3			5					
2.5pF(2R5)	3			5	7.4pF(7R4)	3			5					
2.6pF(2R6)	3			5	7.5pF(7R5)	3			5					
2.7pF(2R7)	3			5	7.6pF(7R6)	3			5					
2.8pF(2R8)	3			5	7.7pF(7R7)	3			5					
2.9pF(2R9)	3			5	7.8pF(7R8)	3			5					
3.0pF(3R0)	3			5	7.9pF(7R9)	3			5					
3.1pF(3R1)	3			5	8.0pF(8R0)	3			5					
3.2pF(3R2)	3			5	8.1pF(8R1)	3			5					
3.3pF(3R3)	3			5	8.2pF(8R2)	3			5					
3.4pF(3R4)	3			5	8.3pF(8R3)	3			5					
3.5pF(3R5)	3			5	8.4pF(8R4)	3			5					
3.6pF(3R6)	3			5	8.5pF(8R5)	3			5					
3.7pF(3R7)	3			5	8.6pF(8R6)	3			5					
3.8pF(3R8)	3			5	8.7pF(8R7)	3			5					
3.9pF(3R9)	3			5	8.8pF(8R8)	3			5					
4.0pF(4R0)	3			5	8.9pF(8R9)	3			5					
4.1pF(4R1)	3			5	9.0pF(9R0)	3			5					
4.2pF(4R2)	3			5	9.1pF(9R1)	3			5					
4.3pF(4R3)	3			5	9.2pF(9R2)	3			5					
4.4pF(4R4)	3			5	9.3pF(9R3)	3			5					
4.5pF(4R5)	3			5	9.4pF(9R4)	3			5					
4.6pF(4R6)	3			5	9.5pF(9R5)	3			5					
4.7pF(4R7)	3			5	9.6pF(9R6)	3			5					
4.8pF(4R8)	3			5	9.7pF(9R7)	3			5					
4.9pF(4R9)	3			5	9.8pF(9R8)	3			5					

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	50(1H)
Capacitance	Tolerance	Part Number	
2.0pF(2R0)	±0.05pF(W)	GJM0335C1E2R0WB01D	GJM1555C1H2R0WB01D
	±0.1pF(B)	GJM0335C1E2R0BB01D	GJM1555C1H2R0BB01D
	±0.25pF(C)	GJM0335C1E2R0CB01D	GJM1555C1H2R0CB01D
2.1pF(2R1)	±0.05pF(W)	GJM0335C1E2R1WB01D	GJM1555C1H2R1WB01D
	±0.1pF(B)	GJM0335C1E2R1BB01D	GJM1555C1H2R1BB01D
	±0.25pF(C)	GJM0335C1E2R1CB01D	GJM1555C1H2R1CB01D
2.2pF(2R2)	±0.05pF(W)	GJM0335C1E2R2WB01D	GJM1555C1H2R2WB01D
	±0.1pF(B)	GJM0335C1E2R2BB01D	GJM1555C1H2R2BB01D
	±0.25pF(C)	GJM0335C1E2R2CB01D	GJM1555C1H2R2CB01D
2.3pF(2R3)	±0.05pF(W)	GJM0335C1E2R3WB01D	GJM1555C1H2R3WB01D
	±0.1pF(B)	GJM0335C1E2R3BB01D	GJM1555C1H2R3BB01D
	±0.25pF(C)	GJM0335C1E2R3CB01D	GJM1555C1H2R3CB01D
2.4pF(2R4)	±0.05pF(W)	GJM0335C1E2R4WB01D	GJM1555C1H2R4WB01D
	±0.1pF(B)	GJM0335C1E2R4BB01D	GJM1555C1H2R4BB01D
	±0.25pF(C)	GJM0335C1E2R4CB01D	GJM1555C1H2R4CB01D
2.5pF(2R5)	±0.05pF(W)	GJM0335C1E2R5WB01D	GJM1555C1H2R5WB01D
	±0.1pF(B)	GJM0335C1E2R5BB01D	GJM1555C1H2R5BB01D
	±0.25pF(C)	GJM0335C1E2R5CB01D	GJM1555C1H2R5CB01D
2.6pF(2R6)	±0.05pF(W)	GJM0335C1E2R6WB01D	GJM1555C1H2R6WB01D
	±0.1pF(B)	GJM0335C1E2R6BB01D	GJM1555C1H2R6BB01D
	±0.25pF(C)	GJM0335C1E2R6CB01D	GJM1555C1H2R6CB01D
2.7pF(2R7)	±0.05pF(W)	GJM0335C1E2R7WB01D	GJM1555C1H2R7WB01D
	±0.1pF(B)	GJM0335C1E2R7BB01D	GJM1555C1H2R7BB01D
	±0.25pF(C)	GJM0335C1E2R7CB01D	GJM1555C1H2R7CB01D
2.8pF(2R8)	±0.05pF(W)	GJM0335C1E2R8WB01D	GJM1555C1H2R8WB01D
	±0.1pF(B)	GJM0335C1E2R8BB01D	GJM1555C1H2R8BB01D
	±0.25pF(C)	GJM0335C1E2R8CB01D	GJM1555C1H2R8CB01D
2.9pF(2R9)	±0.05pF(W)	GJM0335C1E2R9WB01D	GJM1555C1H2R9WB01D
	±0.1pF(B)	GJM0335C1E2R9BB01D	GJM1555C1H2R9BB01D
	±0.25pF(C)	GJM0335C1E2R9CB01D	GJM1555C1H2R9CB01D
3.0pF(3R0)	±0.05pF(W)	GJM0335C1E3R0WB01D	GJM1555C1H3R0WB01D
	±0.1pF(B)	GJM0335C1E3R0BB01D	GJM1555C1H3R0BB01D
	±0.25pF(C)	GJM0335C1E3R0CB01D	GJM1555C1H3R0CB01D
3.1pF(3R1)	±0.05pF(W)	GJM0335C1E3R1WB01D	GJM1555C1H3R1WB01D
	±0.1pF(B)	GJM0335C1E3R1BB01D	GJM1555C1H3R1BB01D
	±0.25pF(C)	GJM0335C1E3R1CB01D	GJM1555C1H3R1CB01D
3.2pF(3R2)	±0.05pF(W)	GJM0335C1E3R2WB01D	GJM1555C1H3R2WB01D
	±0.1pF(B)	GJM0335C1E3R2BB01D	GJM1555C1H3R2BB01D
	±0.25pF(C)	GJM0335C1E3R2CB01D	GJM1555C1H3R2CB01D
3.3pF(3R3)	±0.05pF(W)	GJM0335C1E3R3WB01D	GJM1555C1H3R3WB01D
	±0.1pF(B)	GJM0335C1E3R3BB01D	GJM1555C1H3R3BB01D
	±0.25pF(C)	GJM0335C1E3R3CB01D	GJM1555C1H3R3CB01D
3.4pF(3R4)	±0.05pF(W)	GJM0335C1E3R4WB01D	GJM1555C1H3R4WB01D
	±0.1pF(B)	GJM0335C1E3R4BB01D	GJM1555C1H3R4BB01D
	±0.25pF(C)	GJM0335C1E3R4CB01D	GJM1555C1H3R4CB01D
3.5pF(3R5)	±0.05pF(W)	GJM0335C1E3R5WB01D	GJM1555C1H3R5WB01D
	±0.1pF(B)	GJM0335C1E3R5BB01D	GJM1555C1H3R5BB01D
	±0.25pF(C)	GJM0335C1E3R5CB01D	GJM1555C1H3R5CB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

- | | | | | |
|---------------|--|--|--|---|
| (Part Number) | G J M 03 3 5C 1E 2R0 W B01 D | ① Product ID ② Series
⑤ Temperature Characteristics
⑧ Capacitance Tolerance | ③ Dimensions (LxW)
⑥ Rated Voltage
⑨ Individual Specification Code | ④ Dimension (T)
⑦ Capacitance
⑩ Packaging |
|---------------|--|--|--|---|

Packaging Code in Part Number shows STD 180mm Reel Taping.

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	50(1H)
Capacitance	Tolerance	Part Number	
3.6pF(3R6)	±0.05pF(W)	GJM0335C1E3R6WB01D	GJM1555C1H3R6WB01D
	±0.1pF(B)	GJM0335C1E3R6BB01D	GJM1555C1H3R6BB01D
	±0.25pF(C)	GJM0335C1E3R6CB01D	GJM1555C1H3R6CB01D
3.7pF(3R7)	±0.05pF(W)	GJM0335C1E3R7WB01D	GJM1555C1H3R7WB01D
	±0.1pF(B)	GJM0335C1E3R7BB01D	GJM1555C1H3R7BB01D
	±0.25pF(C)	GJM0335C1E3R7CB01D	GJM1555C1H3R7CB01D
3.8pF(3R8)	±0.05pF(W)	GJM0335C1E3R8WB01D	GJM1555C1H3R8WB01D
	±0.1pF(B)	GJM0335C1E3R8BB01D	GJM1555C1H3R8BB01D
	±0.25pF(C)	GJM0335C1E3R8CB01D	GJM1555C1H3R8CB01D
3.9pF(3R9)	±0.05pF(W)	GJM0335C1E3R9WB01D	GJM1555C1H3R9WB01D
	±0.1pF(B)	GJM0335C1E3R9BB01D	GJM1555C1H3R9BB01D
	±0.25pF(C)	GJM0335C1E3R9CB01D	GJM1555C1H3R9CB01D
4.0pF(4R0)	±0.05pF(W)	GJM0335C1E4R0WB01D	GJM1555C1H4R0WB01D
	±0.1pF(B)	GJM0335C1E4R0BB01D	GJM1555C1H4R0BB01D
	±0.25pF(C)	GJM0335C1E4R0CB01D	GJM1555C1H4R0CB01D
4.1pF(4R1)	±0.05pF(W)	GJM0335C1E4R1WB01D	GJM1555C1H4R1WB01D
	±0.1pF(B)	GJM0335C1E4R1BB01D	GJM1555C1H4R1BB01D
	±0.25pF(C)	GJM0335C1E4R1CB01D	GJM1555C1H4R1CB01D
4.2pF(4R2)	±0.05pF(W)	GJM0335C1E4R2WB01D	GJM1555C1H4R2WB01D
	±0.1pF(B)	GJM0335C1E4R2BB01D	GJM1555C1H4R2BB01D
	±0.25pF(C)	GJM0335C1E4R2CB01D	GJM1555C1H4R2CB01D
4.3pF(4R3)	±0.05pF(W)	GJM0335C1E4R3WB01D	GJM1555C1H4R3WB01D
	±0.1pF(B)	GJM0335C1E4R3BB01D	GJM1555C1H4R3BB01D
	±0.25pF(C)	GJM0335C1E4R3CB01D	GJM1555C1H4R3CB01D
4.4pF(4R4)	±0.05pF(W)	GJM0335C1E4R4WB01D	GJM1555C1H4R4WB01D
	±0.1pF(B)	GJM0335C1E4R4BB01D	GJM1555C1H4R4BB01D
	±0.25pF(C)	GJM0335C1E4R4CB01D	GJM1555C1H4R4CB01D
4.5pF(4R5)	±0.05pF(W)	GJM0335C1E4R5WB01D	GJM1555C1H4R5WB01D
	±0.1pF(B)	GJM0335C1E4R5BB01D	GJM1555C1H4R5BB01D
	±0.25pF(C)	GJM0335C1E4R5CB01D	GJM1555C1H4R5CB01D
4.6pF(4R6)	±0.05pF(W)	GJM0335C1E4R6WB01D	GJM1555C1H4R6WB01D
	±0.1pF(B)	GJM0335C1E4R6BB01D	GJM1555C1H4R6BB01D
	±0.25pF(C)	GJM0335C1E4R6CB01D	GJM1555C1H4R6CB01D
4.7pF(4R7)	±0.05pF(W)	GJM0335C1E4R7WB01D	GJM1555C1H4R7WB01D
	±0.1pF(B)	GJM0335C1E4R7BB01D	GJM1555C1H4R7BB01D
	±0.25pF(C)	GJM0335C1E4R7CB01D	GJM1555C1H4R7CB01D
4.8pF(4R8)	±0.05pF(W)	GJM0335C1E4R8WB01D	GJM1555C1H4R8WB01D
	±0.1pF(B)	GJM0335C1E4R8BB01D	GJM1555C1H4R8BB01D
	±0.25pF(C)	GJM0335C1E4R8CB01D	GJM1555C1H4R8CB01D
4.9pF(4R9)	±0.05pF(W)	GJM0335C1E4R9WB01D	GJM1555C1H4R9WB01D
	±0.1pF(B)	GJM0335C1E4R9BB01D	GJM1555C1H4R9BB01D
	±0.25pF(C)	GJM0335C1E4R9CB01D	GJM1555C1H4R9CB01D
5.0pF(5R0)	±0.05pF(W)	GJM0335C1E5R0WB01D	GJM1555C1H5R0WB01D
	±0.1pF(B)	GJM0335C1E5R0BB01D	GJM1555C1H5R0BB01D
	±0.25pF(C)	GJM0335C1E5R0CB01D	GJM1555C1H5R0CB01D
5.1pF(5R1)	±0.05pF(W)	GJM0335C1E5R1WB01D	GJM1555C1H5R1WB01D
	±0.1pF(B)	GJM0335C1E5R1BB01D	GJM1555C1H5R1BB01D
	±0.25pF(C)	GJM0335C1E5R1CB01D	GJM1555C1H5R1CB01D
	±0.5pF(D)	GJM0335C1E5R1DB01D	GJM1555C1H5R1DB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C)/C0H(6C) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	50(1H)
Capacitance	Tolerance	Part Number	
6.4pF(6R4)	±0.05pF(W)	GJM0335C1E6R4WB01D	GJM1555C1H6R4WB01D
	±0.1pF(B)	GJM0335C1E6R4BB01D	GJM1555C1H6R4BB01D
	±0.25pF(C)	GJM0335C1E6R4CB01D	GJM1555C1H6R4CB01D
	±0.5pF(D)	GJM0335C1E6R4DB01D	GJM1555C1H6R4DB01D
6.5pF(6R5)	±0.05pF(W)	GJM0335C1E6R5WB01D	GJM1555C1H6R5WB01D
	±0.1pF(B)	GJM0335C1E6R5BB01D	GJM1555C1H6R5BB01D
	±0.25pF(C)	GJM0335C1E6R5CB01D	GJM1555C1H6R5CB01D
	±0.5pF(D)	GJM0335C1E6R5DB01D	GJM1555C1H6R5DB01D
6.6pF(6R6)	±0.05pF(W)	GJM0335C1E6R6WB01D	GJM1555C1H6R6WB01D
	±0.1pF(B)	GJM0335C1E6R6BB01D	GJM1555C1H6R6BB01D
	±0.25pF(C)	GJM0335C1E6R6CB01D	GJM1555C1H6R6CB01D
	±0.5pF(D)	GJM0335C1E6R6DB01D	GJM1555C1H6R6DB01D
6.7pF(6R7)	±0.05pF(W)	GJM0335C1E6R7WB01D	GJM1555C1H6R7WB01D
	±0.1pF(B)	GJM0335C1E6R7BB01D	GJM1555C1H6R7BB01D
	±0.25pF(C)	GJM0335C1E6R7CB01D	GJM1555C1H6R7CB01D
	±0.5pF(D)	GJM0335C1E6R7DB01D	GJM1555C1H6R7DB01D
6.8pF(6R8)	±0.05pF(W)	GJM0335C1E6R8WB01D	GJM1555C1H6R8WB01D
	±0.1pF(B)	GJM0335C1E6R8BB01D	GJM1555C1H6R8BB01D
	±0.25pF(C)	GJM0335C1E6R8CB01D	GJM1555C1H6R8CB01D
	±0.5pF(D)	GJM0335C1E6R8DB01D	GJM1555C1H6R8DB01D
6.9pF(6R9)	±0.05pF(W)	GJM0336C1E6R9WB01D	GJM1555C1H6R9WB01D
	±0.1pF(B)	GJM0336C1E6R9BB01D	GJM1555C1H6R9BB01D
	±0.25pF(C)	GJM0336C1E6R9CB01D	GJM1555C1H6R9CB01D
	±0.5pF(D)	GJM0336C1E6R9DB01D	GJM1555C1H6R9DB01D
7.0pF(7R0)	±0.05pF(W)	GJM0336C1E7R0WB01D	GJM1555C1H7R0WB01D
	±0.1pF(B)	GJM0336C1E7R0BB01D	GJM1555C1H7R0BB01D
	±0.25pF(C)	GJM0336C1E7R0CB01D	GJM1555C1H7R0CB01D
	±0.5pF(D)	GJM0336C1E7R0DB01D	GJM1555C1H7R0DB01D
7.1pF(7R1)	±0.05pF(W)	GJM0336C1E7R1WB01D	GJM1555C1H7R1WB01D
	±0.1pF(B)	GJM0336C1E7R1BB01D	GJM1555C1H7R1BB01D
	±0.25pF(C)	GJM0336C1E7R1CB01D	GJM1555C1H7R1CB01D
	±0.5pF(D)	GJM0336C1E7R1DB01D	GJM1555C1H7R1DB01D
7.2pF(7R2)	±0.05pF(W)	GJM0336C1E7R2WB01D	GJM1555C1H7R2WB01D
	±0.1pF(B)	GJM0336C1E7R2BB01D	GJM1555C1H7R2BB01D
	±0.25pF(C)	GJM0336C1E7R2CB01D	GJM1555C1H7R2CB01D
	±0.5pF(D)	GJM0336C1E7R2DB01D	GJM1555C1H7R2DB01D
7.3pF(7R3)	±0.05pF(W)	GJM0336C1E7R3WB01D	GJM1555C1H7R3WB01D
	±0.1pF(B)	GJM0336C1E7R3BB01D	GJM1555C1H7R3BB01D
	±0.25pF(C)	GJM0336C1E7R3CB01D	GJM1555C1H7R3CB01D
	±0.5pF(D)	GJM0336C1E7R3DB01D	GJM1555C1H7R3DB01D
7.4pF(7R4)	±0.05pF(W)	GJM0336C1E7R4WB01D	GJM1555C1H7R4WB01D
	±0.1pF(B)	GJM0336C1E7R4BB01D	GJM1555C1H7R4BB01D
	±0.25pF(C)	GJM0336C1E7R4CB01D	GJM1555C1H7R4CB01D
	±0.5pF(D)	GJM0336C1E7R4DB01D	GJM1555C1H7R4DB01D
7.5pF(7R5)	±0.05pF(W)	GJM0336C1E7R5WB01D	GJM1555C1H7R5WB01D
	±0.1pF(B)	GJM0336C1E7R5BB01D	GJM1555C1H7R5BB01D
	±0.25pF(C)	GJM0336C1E7R5CB01D	GJM1555C1H7R5CB01D
	±0.5pF(D)	GJM0336C1E7R5DB01D	GJM1555C1H7R5DB01D
7.6pF(7R6)	±0.05pF(W)	GJM0336C1E7R6WB01D	GJM1555C1H7R6WB01D
	±0.1pF(B)	GJM0336C1E7R6BB01D	GJM1555C1H7R6BB01D
	±0.25pF(C)	GJM0336C1E7R6CB01D	GJM1555C1H7R6CB01D
	±0.5pF(D)	GJM0336C1E7R6DB01D	GJM1555C1H7R6DB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Temperature Compensating Type C0G(5C)/C0H(6C) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	50(1H)
Capacitance	Tolerance	Part Number	
8.9pF(8R9)	±0.05pF(W)	GJM0336C1E8R9WB01D	GJM1555C1H8R9WB01D
	±0.1pF(B)	GJM0336C1E8R9BB01D	GJM1555C1H8R9BB01D
	±0.25pF(C)	GJM0336C1E8R9CB01D	GJM1555C1H8R9CB01D
	±0.5pF(D)	GJM0336C1E8R9DB01D	GJM1555C1H8R9DB01D
9.0pF(9R0)	±0.05pF(W)	GJM0336C1E9R0WB01D	GJM1555C1H9R0WB01D
	±0.1pF(B)	GJM0336C1E9R0BB01D	GJM1555C1H9R0BB01D
	±0.25pF(C)	GJM0336C1E9R0CB01D	GJM1555C1H9R0CB01D
	±0.5pF(D)	GJM0336C1E9R0DB01D	GJM1555C1H9R0DB01D
9.1pF(9R1)	±0.05pF(W)	GJM0336C1E9R1WB01D	GJM1555C1H9R1WB01D
	±0.1pF(B)	GJM0336C1E9R1BB01D	GJM1555C1H9R1BB01D
	±0.25pF(C)	GJM0336C1E9R1CB01D	GJM1555C1H9R1CB01D
	±0.5pF(D)	GJM0336C1E9R1DB01D	GJM1555C1H9R1DB01D
9.2pF(9R2)	±0.05pF(W)	GJM0336C1E9R2WB01D	GJM1555C1H9R2WB01D
	±0.1pF(B)	GJM0336C1E9R2BB01D	GJM1555C1H9R2BB01D
	±0.25pF(C)	GJM0336C1E9R2CB01D	GJM1555C1H9R2CB01D
	±0.5pF(D)	GJM0336C1E9R2DB01D	GJM1555C1H9R2DB01D
9.3pF(9R3)	±0.05pF(W)	GJM0336C1E9R3WB01D	GJM1555C1H9R3WB01D
	±0.1pF(B)	GJM0336C1E9R3BB01D	GJM1555C1H9R3BB01D
	±0.25pF(C)	GJM0336C1E9R3CB01D	GJM1555C1H9R3CB01D
	±0.5pF(D)	GJM0336C1E9R3DB01D	GJM1555C1H9R3DB01D
9.4pF(9R4)	±0.05pF(W)	GJM0336C1E9R4WB01D	GJM1555C1H9R4WB01D
	±0.1pF(B)	GJM0336C1E9R4BB01D	GJM1555C1H9R4BB01D
	±0.25pF(C)	GJM0336C1E9R4CB01D	GJM1555C1H9R4CB01D
	±0.5pF(D)	GJM0336C1E9R4DB01D	GJM1555C1H9R4DB01D
9.5pF(9R5)	±0.05pF(W)	GJM0336C1E9R5WB01D	GJM1555C1H9R5WB01D
	±0.1pF(B)	GJM0336C1E9R5BB01D	GJM1555C1H9R5BB01D
	±0.25pF(C)	GJM0336C1E9R5CB01D	GJM1555C1H9R5CB01D
	±0.5pF(D)	GJM0336C1E9R5DB01D	GJM1555C1H9R5DB01D
9.6pF(9R6)	±0.05pF(W)	GJM0336C1E9R6WB01D	GJM1555C1H9R6WB01D
	±0.1pF(B)	GJM0336C1E9R6BB01D	GJM1555C1H9R6BB01D
	±0.25pF(C)	GJM0336C1E9R6CB01D	GJM1555C1H9R6CB01D
	±0.5pF(D)	GJM0336C1E9R6DB01D	GJM1555C1H9R6DB01D
9.7pF(9R7)	±0.05pF(W)	GJM0336C1E9R7WB01D	GJM1555C1H9R7WB01D
	±0.1pF(B)	GJM0336C1E9R7BB01D	GJM1555C1H9R7BB01D
	±0.25pF(C)	GJM0336C1E9R7CB01D	GJM1555C1H9R7CB01D
	±0.5pF(D)	GJM0336C1E9R7DB01D	GJM1555C1H9R7DB01D
9.8pF(9R8)	±0.05pF(W)	GJM0336C1E9R8WB01D	GJM1555C1H9R8WB01D
	±0.1pF(B)	GJM0336C1E9R8BB01D	GJM1555C1H9R8BB01D
	±0.25pF(C)	GJM0336C1E9R8CB01D	GJM1555C1H9R8CB01D
	±0.5pF(D)	GJM0336C1E9R8DB01D	GJM1555C1H9R8DB01D
9.9pF(9R9)	±0.05pF(W)	GJM0336C1E9R9WB01D	GJM1555C1H9R9WB01D
	±0.1pF(B)	GJM0336C1E9R9BB01D	GJM1555C1H9R9BB01D
	±0.25pF(C)	GJM0336C1E9R9CB01D	GJM1555C1H9R9CB01D
	±0.5pF(D)	GJM0336C1E9R9DB01D	GJM1555C1H9R9DB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C)/C0H(6C) Characteristics

LxW [mm]		0.6x0.3(03)<0201>		1.0x0.5(15)<0402>
Rated Volt. [Vdc]		25(1E)	6.3(0J)	50(1H)
Capacitance	Tolerance	Part Number		
10pF(100)	±2%(G)	GJM0336C1E100GB01D		GJM1555C1H100GB01D
	±5%(J)	GJM0336C1E100JB01D		GJM1555C1H100JB01D
11pF(110)	±2%(G)	GJM0336C1E110GB01D		GJM1555C1H110GB01D
	±5%(J)	GJM0336C1E110JB01D		GJM1555C1H110JB01D
12pF(120)	±2%(G)	GJM0336C1E120GB01D		GJM1555C1H120GB01D
	±5%(J)	GJM0336C1E120JB01D		GJM1555C1H120JB01D
13pF(130)	±2%(G)	GJM0336C1E130GB01D		GJM1555C1H130GB01D
	±5%(J)	GJM0336C1E130JB01D		GJM1555C1H130JB01D
15pF(150)	±2%(G)	GJM0336C1E150GB01D		GJM1555C1H150GB01D
	±5%(J)	GJM0336C1E150JB01D		GJM1555C1H150JB01D
16pF(160)	±2%(G)	GJM0336C1E160GB01D		GJM1555C1H160GB01D
	±5%(J)	GJM0336C1E160JB01D		GJM1555C1H160JB01D
18pF(180)	±2%(G)	GJM0336C1E180GB01D		GJM1555C1H180GB01D
	±5%(J)	GJM0336C1E180JB01D		GJM1555C1H180JB01D
20pF(200)	±2%(G)	GJM0336C1E200GB01D		GJM1555C1H200GB01D
	±5%(J)	GJM0336C1E200JB01D		GJM1555C1H200JB01D
22pF(220)	±2%(G)		GJM0335C0J220GB01D	
	±5%(J)		GJM0335C0J220JB01D	
24pF(240)	±2%(G)		GJM0335C0J240GB01D	
	±5%(J)		GJM0335C0J240JB01D	
27pF(270)	±2%(G)		GJM0335C0J270GB01D	
	±5%(J)		GJM0335C0J270JB01D	
30pF(300)	±2%(G)		GJM0335C0J300GB01D	
	±5%(J)		GJM0335C0J300JB01D	
33pF(330)	±2%(G)		GJM0335C0J330GB01D	
	±5%(J)		GJM0335C0J330JB01D	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series
Array GNM Series
Low ESL LL□ Series
High-Q GJM Series
High Frequency GQM Series
Monolithic Microchip GMA Series
For Bonding GMD Series
Product Information

(Part Number) **GJ M 03 3 6C 1E 100 G B01 D**
 ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩

- ① Product ID
- ② Series
- ③ Dimensions (LxW)
- ④ Dimension (T)
- ⑤ Temperature Characteristics
- ⑥ Rated Voltage
- ⑦ Capacitance
- ⑧ Capacitance Tolerance
- ⑨ Individual Specification Code
- ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.



GJM Series Specifications and Test Methods

No.	Item	Specifications		Test Method				
		Temperature Compensating Type						
1	Operating Temperature Range	-55 to +125°C		Reference Temperature: 25°C (2C, 3C, 4C: 20°C)				
2	Rated Voltage	See the previous pages.		The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.				
3	Appearance	No defects or abnormalities		Visual inspection				
4	Dimensions	Within the specified dimensions		Using calipers				
5	Dielectric Strength	No defects or abnormalities		No failure should be observed when 300% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.				
6	Insulation Resistance (I.R.)	10,000MΩ min. or 500Ω · F min. (whichever is smaller)		The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging.				
7	Capacitance	Within the specified tolerance		The capacitance/Q should be measured at 25°C at the frequency and voltage shown in the table.				
8	Q	30pF and over: $Q \geq 1000$ 30pF and below: $Q \geq 400 + 20C$ C: Nominal Capacitance (pF)		<table border="1" style="margin-left: auto; margin-right: auto;"> <tr> <td>Frequency</td> <td>1±0.1MHz</td> </tr> <tr> <td>Voltage</td> <td>0.5 to 5Vrms</td> </tr> </table>	Frequency	1±0.1MHz	Voltage	0.5 to 5Vrms
Frequency	1±0.1MHz							
Voltage	0.5 to 5Vrms							
9	Capacitance Temperature Characteristics	Temperature Coefficient	Within the specified tolerance (Table A)	The capacitance change should be measured after 5 min. at each specified temperature stage. Temperature Compensating Type The temperature coefficient is determined using the capacitance measured in step 3 as a reference. When cycling the temperature sequentially from step 1 through 5, (5C: +25 to 125°C: other temp. coeffs.: +20 to 125°C) the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in steps 1, 3 and 5 by the capacitance value in step 3.				
		Capacitance Drift	Within ±0.2% or ±0.05pF (whichever is larger.)					
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.		Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply a 5N* force in parallel with the test jig for 10±1 sec. The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock. *2N (GJM03)				

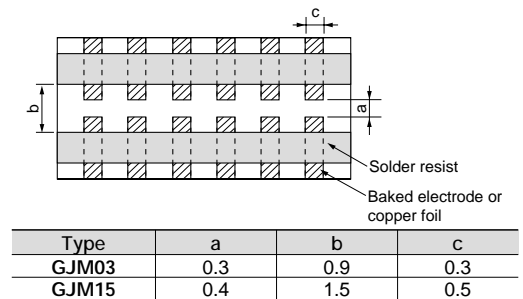


Fig. 1

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

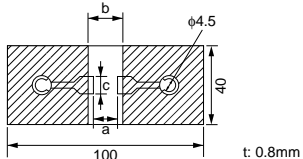
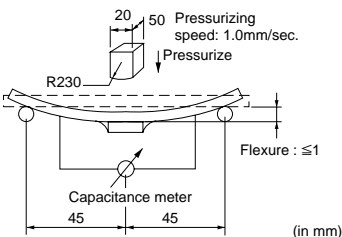
Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GJM Series Specifications and Test Methods

☐ Continued from the preceding page.

No.	Item	Specifications		Test Method									
		Temperature Compensating Type											
11	Vibration Resistance	Appearance	No defects or abnormalities		Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute. This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).								
		Capacitance	Within the specified tolerance										
		Q	30pF and over: $Q \geq 1000$ 30pF and below: $Q \geq 400+20C$ C: Nominal Capacitance (pF)										
12	Deflection	Appearance	No marking defects		Solder the capacitor to the test jig (glass epoxy boards) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.								
		Capacitance Change	Within $\pm 5\%$ or $\pm 0.5\text{pF}$ (whichever is larger)										
		 <table border="1" data-bbox="375 862 885 929"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GJM03</td> <td>0.3</td> <td>0.9</td> <td>0.3</td> </tr> <tr> <td>GJM15</td> <td>0.4</td> <td>1.5</td> <td>0.5</td> </tr> </tbody> </table> <p style="text-align: center;">(in mm)</p>		Type		a	b	c	GJM03	0.3	0.9	0.3	GJM15
Type	a	b	c										
GJM03	0.3	0.9	0.3										
GJM15	0.4	1.5	0.5										
 <p style="text-align: center;">(in mm)</p>													
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.		Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2 ± 0.5 seconds at $230 \pm 5^\circ\text{C}$ or Sn-3.0Ag-0.5Cu solder solution for 2 ± 0.5 seconds at $245 \pm 5^\circ\text{C}$.									
14	Resistance to Soldering Heat	The measured and observed characteristics should satisfy the specifications in the following table.		Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at $270 \pm 5^\circ\text{C}$ for 10 ± 0.5 seconds. Let sit at room temperature for 24 ± 2 hours.									
		Appearance	No marking defects										
		Capacitance Change	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ (whichever is larger)										
		Q	30pF and over: $Q \geq 1000$ 30pF and below: $Q \geq 400+20C$ C: Nominal Capacitance (pF)										
		I.R.	More than 10,000M Ω or 500 $\Omega \cdot \text{F}$ (whichever is smaller)										
15	Temperature Cycle	The measured and observed characteristics should satisfy the specifications in the following table.		Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24 ± 2 hours at room temperature, then measure.									
		Appearance	No marking defects										
		Capacitance Change	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ (whichever is larger)										
		Q	30pF and over: $Q \geq 1000$ 30pF and below: $Q \geq 400+20C$ C: Nominal Capacitance (pF)										
		I.R.	More than 10,000M Ω or 500 $\Omega \cdot \text{F}$ (whichever is smaller)										
16	Humidity, Steady State	The measured and observed characteristics should satisfy the specifications in the following table.		Let the capacitor sit at $40 \pm 2^\circ\text{C}$ and 90 to 95% humidity for 500 ± 12 hours. Remove and let sit for 24 ± 2 hours (temperature compensating type) at room temperature, then measure.									
		Appearance	No marking defects										
		Capacitance Change	Within $\pm 5\%$ or $\pm 0.5\text{pF}$ (whichever is larger)										
		Q	30pF and below: $Q \geq 350$ 10pF and over, 30pF and below: $Q \geq 275 + \frac{5}{C}$ 10pF and below: $Q \geq 200+10C$ C: Nominal Capacitance (pF)										
		I.R.	More than 10,000M Ω or 500 $\Omega \cdot \text{F}$ (whichever is smaller)										

Continued on the following page. ↗

GJM Series Specifications and Test Methods

☐ Continued from the preceding page.

No.	Item	Specifications		Test Method
		Temperature Compensating Type		
17	Humidity Load	The measured and observed characteristics should satisfy the specifications in the following table.		Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects	
		Capacitance Change	Within ±7.5% or ±0.75pF (whichever is larger)	
		Q	30pF and over: Q≥200 30pF and below: Q≥100+ $\frac{1}{Q}$ C C: Nominal Capacitance (pF)	
		I.R.	More than 500MΩ or 25Ω · F (whichever is smaller)	
18	High Temperature Load	The measured and observed characteristics should satisfy the specifications in the following table.		Apply 200% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours (temperature compensating type) at room temperature, then measure. The charge/discharge current is less than 50mA.
		Appearance	No marking defects	
		Capacitance Change	Within ±3% or ±0.3pF (whichever is larger)	
		Q	30pF and over: Q≥350 10pF and over, 30pF and below: Q≥275+ $\frac{1}{Q}$ C 10pF and below: Q≥200+10C C: Nominal Capacitance (pF)	
		I.R.	More than 1,000MΩ or 50Ω · F (whichever is smaller)	
19	ESR	0.1pF<C≤1pF: 350mΩ · pF below 1pF<C≤5pF: 300mΩ below 5pF<C≤10pF: 250mΩ below		The ESR should be measured at room temperature, and frequency 1±0.2GHz with the equivalent of BOONTON Model 34A.
		10pF<C≤33pF: 400mΩ below		The ESR should be measured at room temperature, and frequency 500±50MHz with the equivalent of HP8753B.

Table A
(1)

Char. Code	Temp. Coeff. (ppm/°C) *1	Capacitance Change from 25°C Value (%)					
		-55°C		-30°C		-10°C	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11
6C	0±60	0.87	-0.48	0.60	-0.33	0.38	-0.21

*1: Nominal values denote the temperature coefficient within a range of 25 to 125°C.

(2)

Char.	Nominal Values (ppm/°C) *2	Capacitance Change from 20°C Value (%)					
		-55°C		-25°C		-10°C	
		Max.	Min.	Max.	Min.	Max.	Min.
2C	0±60	0.82	-0.45	0.49	-0.27	0.33	-0.18
3C	0±120	1.37	-0.90	0.82	-0.54	0.55	-0.36
4C	0±250	2.56	-1.88	1.54	-1.13	1.02	-0.75

*2: Nominal values denote the temperature coefficient within a range of 20 to 125°C.

For General GRM Series

Array GJM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



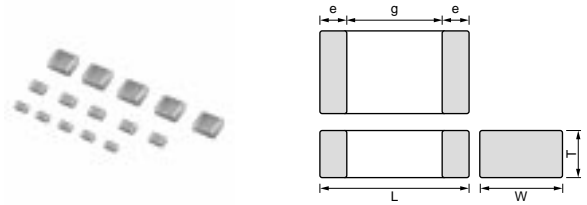
High Frequency GQM Series

■ Features

1. HiQ and low ESR at VHF, UHF, Microwave
2. Feature improvement, low power consumption for mobile telecommunication. (Base station, terminal, etc.)

■ Applications

High frequency circuit (Mobile telecommunication, etc.)



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GQM187	1.6 ±0.15	0.8 ±0.15	0.7 ±0.1	0.2 to 0.5	0.5
GQM188	1.6 ±0.1	0.8 ±0.1	0.8 ±0.1	0.2 to 0.5	0.5
GQM219 (50,100V)	2.0 ±0.1	1.25 ±0.1	0.85 ±0.1	0.2 to 0.7	0.7
GQM219 (250V)	2.0 ±0.15	1.25 ±0.15	0.85 ±0.15	0.2 to 0.7	0.7
GQM22M	2.8 ±0.5	2.8 ±0.4	1.15 ±0.2	0.3 min.	1.0

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GQM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Capacitance Table

Temperature Compensating Type C0G(5C) Characteristics

7		ex.7: T Dimension [mm]						
Capacitance	LxW [mm]	1.6x0.8 (18) <0603>			2.0x1.25 (21) <0805>			2.8x2.8 (22) <1111>
		250 (2E)	100 (2A)	50 (1H)	250 (2E)	100 (2A)	50 (1H)	500 (2H)
0.10pF(R10)	7							
0.20pF(R20)	7							
0.30pF(R30)	7							
0.40pF(R40)	7							
0.50pF(R50)	7	8			9	9		M
0.75pF(R75)	7	8			9	9		M
1.0pF(1R0)	7	8			9	9		M
1.1pF(1R1)	7	8			9	9		M
1.2pF(1R2)	7	8			9	9		M
1.3pF(1R3)	7	8			9	9		M
1.5pF(1R5)	7	8			9	9		M
1.6pF(1R6)	7	8			9	9		M
1.8pF(1R8)	7	8			9	9		M
2.0pF(2R0)	7	8			9	9		M
2.2pF(2R2)	7	8			9	9		M
2.4pF(2R4)	7	8			9	9		M
2.7pF(2R7)	7	8			9	9		M
3.0pF(3R0)	7	8			9	9		M
3.3pF(3R3)	7	8			9	9		M
3.6pF(3R6)	7	8			9	9		M
3.9pF(3R9)	7	8			9	9		M
4.0pF(4R0)	7	8			9	9		M
4.3pF(4R3)	7	8			9	9		M
4.7pF(4R7)	7	8			9	9		M
5.0pF(5R0)	7	8			9	9		M
5.1pF(5R1)	7	8			9	9		M
5.6pF(5R6)	7	8			9	9		M
6.0pF(6R0)	7	8			9	9		M
6.2pF(6R2)	7	8			9	9		M
6.8pF(6R8)	7	8			9	9		M
7.0pF(7R0)	7		8	9	9			M
7.5pF(7R5)	7		8	9	9			M
8.0pF(8R0)	7		8	9	9			M
8.2pF(8R2)	7		8	9	9			M
9.0pF(9R0)	7		8	9	9			M
9.1pF(9R1)	7		8	9	9			M
10pF(100)	7		8	9	9			M
11pF(110)	7		8	9	9			M
12pF(120)	7		8	9	9			M
13pF(130)	7		8	9	9			M
15pF(150)	7		8	9	9			M
16pF(160)	7		8	9	9			M
18pF(180)	7		8	9	9			M
20pF(200)	7		8	9		9		M
22pF(220)	7		8	9		9		M
24pF(240)	7		8	9		9		M
27pF(270)	7		8	9		9		M
30pF(300)	7		8	9		9		M
33pF(330)	7		8	9		9		M

Capacitance	LxW [mm]	1.6x0.8 (18) <0603>			2.0x1.25 (21) <0805>			2.8x2.8 (22) <1111>	
		250 (2E)	100 (2A)	50 (1H)	250 (2E)	100 (2A)	50 (1H)	500 (2H)	
36pF(360)	7			8	9			9	M
39pF(390)	7			8	9			9	M
43pF(430)	7			8	9			9	M
47pF(470)	7			8	9			9	M
51pF(510)				8	9			9	M
56pF(560)				8	9			9	M
62pF(620)				8	9			9	M
68pF(680)				8	9			9	M
75pF(750)				8	9			9	M
82pF(820)				8	9			9	M
91pF(910)				8	9			9	M
100pF(101)				8	9			9	M

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		250(2E)	100(2A)
Capacitance	Tolerance	Part Number	
0.10pF(R10)	±0.1pF(B)	GQM1875C2ER10BB12D	
0.20pF(R20)	±0.1pF(B)	GQM1875C2ER20BB12D	
0.30pF(R30)	±0.1pF(B)	GQM1875C2ER30BB12D	
	±0.25pF(C)	GQM1875C2ER30CB12D	
0.40pF(R40)	±0.1pF(B)	GQM1875C2ER40BB12D	
	±0.25pF(C)	GQM1875C2ER40CB12D	
0.50pF(R50)	±0.1pF(B)	GQM1875C2ER50BB12D	GQM1885C2AR50BB01D
	±0.25pF(C)	GQM1875C2ER50CB12D	GQM1885C2AR50CB01D
0.75pF(R75)	±0.1pF(B)	GQM1875C2ER75BB12D	GQM1885C2AR75BB01D
	±0.25pF(C)	GQM1875C2ER75CB12D	GQM1885C2AR75CB01D
1.0pF(1R0)	±0.1pF(B)	GQM1875C2E1R0BB12D	GQM1885C2A1R0BB01D
	±0.25pF(C)	GQM1875C2E1R0CB12D	GQM1885C2A1R0CB01D
1.1pF(1R1)	±0.1pF(B)	GQM1875C2E1R1BB12D	GQM1885C2A1R1BB01D
	±0.25pF(C)	GQM1875C2E1R1CB12D	GQM1885C2A1R1CB01D
1.2pF(1R2)	±0.1pF(B)	GQM1875C2E1R2BB12D	GQM1885C2A1R2BB01D
	±0.25pF(C)	GQM1875C2E1R2CB12D	GQM1885C2A1R2CB01D
1.3pF(1R3)	±0.1pF(B)	GQM1875C2E1R3BB12D	GQM1885C2A1R3BB01D
	±0.25pF(C)	GQM1875C2E1R3CB12D	GQM1885C2A1R3CB01D
1.5pF(1R5)	±0.1pF(B)	GQM1875C2E1R5BB12D	GQM1885C2A1R5BB01D
	±0.25pF(C)	GQM1875C2E1R5CB12D	GQM1885C2A1R5CB01D
1.6pF(1R6)	±0.1pF(B)	GQM1875C2E1R6BB12D	GQM1885C2A1R6BB01D
	±0.25pF(C)	GQM1875C2E1R6CB12D	GQM1885C2A1R6CB01D
1.8pF(1R8)	±0.1pF(B)	GQM1875C2E1R8BB12D	GQM1885C2A1R8BB01D
	±0.25pF(C)	GQM1875C2E1R8CB12D	GQM1885C2A1R8CB01D
2.0pF(2R0)	±0.1pF(B)	GQM1875C2E2R0BB12D	GQM1885C2A2R0BB01D
	±0.25pF(C)	GQM1875C2E2R0CB12D	GQM1885C2A2R0CB01D
2.2pF(2R2)	±0.1pF(B)	GQM1875C2E2R2BB12D	GQM1885C2A2R2BB01D
	±0.25pF(C)	GQM1875C2E2R2CB12D	GQM1885C2A2R2CB01D
2.4pF(2R4)	±0.1pF(B)	GQM1875C2E2R4BB12D	GQM1885C2A2R4BB01D
	±0.25pF(C)	GQM1875C2E2R4CB12D	GQM1885C2A2R4CB01D
2.7pF(2R7)	±0.1pF(B)	GQM1875C2E2R7BB12D	GQM1885C2A2R7BB01D
	±0.25pF(C)	GQM1875C2E2R7CB12D	GQM1885C2A2R7CB01D
3.0pF(3R0)	±0.1pF(B)	GQM1875C2E3R0BB12D	GQM1885C2A3R0BB01D
	±0.25pF(C)	GQM1875C2E3R0CB12D	GQM1885C2A3R0CB01D
3.3pF(3R3)	±0.1pF(B)	GQM1875C2E3R3BB12D	GQM1885C2A3R3BB01D
	±0.25pF(C)	GQM1875C2E3R3CB12D	GQM1885C2A3R3CB01D
3.6pF(3R6)	±0.1pF(B)	GQM1875C2E3R6BB12D	GQM1885C2A3R6BB01D
	±0.25pF(C)	GQM1875C2E3R6CB12D	GQM1885C2A3R6CB01D
3.9pF(3R9)	±0.1pF(B)	GQM1875C2E3R9BB12D	GQM1885C2A3R9BB01D
	±0.25pF(C)	GQM1875C2E3R9CB12D	GQM1885C2A3R9CB01D
4.0pF(4R0)	±0.1pF(B)	GQM1875C2E4R0BB12D	GQM1885C2A4R0BB01D
	±0.25pF(C)	GQM1875C2E4R0CB12D	GQM1885C2A4R0CB01D
4.3pF(4R3)	±0.1pF(B)	GQM1875C2E4R3BB12D	GQM1885C2A4R3BB01D
	±0.25pF(C)	GQM1875C2E4R3CB12D	GQM1885C2A4R3CB01D
4.7pF(4R7)	±0.1pF(B)	GQM1875C2E4R7BB12D	GQM1885C2A4R7BB01D
	±0.25pF(C)	GQM1875C2E4R7CB12D	GQM1885C2A4R7CB01D
5.0pF(5R0)	±0.1pF(B)	GQM1875C2E5R0BB12D	GQM1885C2A5R0BB01D
	±0.25pF(C)	GQM1875C2E5R0CB12D	GQM1885C2A5R0CB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

- | | | | | |
|---------------|---|--|--|---|
| (Part Number) | G Q M 1 8 7 5 C 2 E R 1 0 B B 1 2 D | ① Product ID
⑤ Temperature Characteristics
⑧ Capacitance Tolerance | ② Series
⑥ Rated Voltage
⑨ Individual Specification Code | ③ Dimensions (LxW)
④ Dimension (T)
⑦ Capacitance
⑩ Packaging |
|---------------|---|--|--|---|

Packaging Code in Part Number shows STD 180mm Reel Taping.

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		1.6x0.8(18)<0603>		
Rated Volt. [Vdc]		250(2E)	100(2A)	50(1H)
Capacitance	Tolerance	Part Number		
5.1pF(5R1)	±0.25pF(C)	GQM1875C2E5R1CB12D	GQM1885C2A5R1CB01D	
	±0.5pF(D)	GQM1875C2E5R1DB12D	GQM1885C2A5R1DB01D	
5.6pF(5R6)	±0.25pF(C)	GQM1875C2E5R6CB12D	GQM1885C2A5R6CB01D	
	±0.5pF(D)	GQM1875C2E5R6DB12D	GQM1885C2A5R6DB01D	
6.0pF(6R0)	±0.25pF(C)	GQM1875C2E6R0CB12D	GQM1885C2A6R0CB01D	
	±0.5pF(D)	GQM1875C2E6R0DB12D	GQM1885C2A6R0DB01D	
6.2pF(6R2)	±0.25pF(C)	GQM1875C2E6R2CB12D	GQM1885C2A6R2CB01D	
	±0.5pF(D)	GQM1875C2E6R2DB12D	GQM1885C2A6R2DB01D	
6.8pF(6R8)	±0.25pF(C)	GQM1875C2E6R8CB12D	GQM1885C2A6R8CB01D	
	±0.5pF(D)	GQM1875C2E6R8DB12D	GQM1885C2A6R8DB01D	
7.0pF(7R0)	±0.25pF(C)	GQM1875C2E7R0CB12D		GQM1885C1H7R0CB01D
	±0.5pF(D)	GQM1875C2E7R0DB12D		GQM1885C1H7R0DB01D
7.5pF(7R5)	±0.25pF(C)	GQM1875C2E7R5CB12D		GQM1885C1H7R5CB01D
	±0.5pF(D)	GQM1875C2E7R5DB12D		GQM1885C1H7R5DB01D
8.0pF(8R0)	±0.25pF(C)	GQM1875C2E8R0CB12D		GQM1885C1H8R0CB01D
	±0.5pF(D)	GQM1875C2E8R0DB12D		GQM1885C1H8R0DB01D
8.2pF(8R2)	±0.25pF(C)	GQM1875C2E8R2CB12D		GQM1885C1H8R2CB01D
	±0.5pF(D)	GQM1875C2E8R2DB12D		GQM1885C1H8R2DB01D
9.0pF(9R0)	±0.25pF(C)	GQM1875C2E9R0CB12D		GQM1885C1H9R0CB01D
	±0.5pF(D)	GQM1875C2E9R0DB12D		GQM1885C1H9R0DB01D
9.1pF(9R1)	±0.25pF(C)	GQM1875C2E9R1CB12D		GQM1885C1H9R1CB01D
	±0.5pF(D)	GQM1875C2E9R1DB12D		GQM1885C1H9R1DB01D
10pF(100)	±2%(G)	GQM1875C2E100GB12D		GQM1885C1H100GB01D
	±5%(J)	GQM1875C2E100JB12D		GQM1885C1H100JB01D
11pF(110)	±2%(G)	GQM1875C2E110GB12D		GQM1885C1H110GB01D
	±5%(J)	GQM1875C2E110JB12D		GQM1885C1H110JB01D
12pF(120)	±2%(G)	GQM1875C2E120GB12D		GQM1885C1H120GB01D
	±5%(J)	GQM1875C2E120JB12D		GQM1885C1H120JB01D
13pF(130)	±2%(G)	GQM1875C2E130GB12D		GQM1885C1H130GB01D
	±5%(J)	GQM1875C2E130JB12D		GQM1885C1H130JB01D
15pF(150)	±2%(G)	GQM1875C2E150GB12D		GQM1885C1H150GB01D
	±5%(J)	GQM1875C2E150JB12D		GQM1885C1H150JB01D
16pF(160)	±2%(G)	GQM1875C2E160GB12D		GQM1885C1H160GB01D
	±5%(J)	GQM1875C2E160JB12D		GQM1885C1H160JB01D
18pF(180)	±2%(G)	GQM1875C2E180GB12D		GQM1885C1H180GB01D
	±5%(J)	GQM1875C2E180JB12D		GQM1885C1H180JB01D
20pF(200)	±2%(G)	GQM1875C2E200GB12D		GQM1885C1H200GB01D
	±5%(J)	GQM1875C2E200JB12D		GQM1885C1H200JB01D
22pF(220)	±2%(G)	GQM1875C2E220GB12D		GQM1885C1H220GB01D
	±5%(J)	GQM1875C2E220JB12D		GQM1885C1H220JB01D
24pF(240)	±2%(G)	GQM1875C2E240GB12D		GQM1885C1H240GB01D
	±5%(J)	GQM1875C2E240JB12D		GQM1885C1H240JB01D
27pF(270)	±2%(G)	GQM1875C2E270GB12D		GQM1885C1H270GB01D
	±5%(J)	GQM1875C2E270JB12D		GQM1885C1H270JB01D
30pF(300)	±2%(G)	GQM1875C2E300GB12D		GQM1885C1H300GB01D
	±5%(J)	GQM1875C2E300JB12D		GQM1885C1H300JB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		1.6x0.8(18)<0603>	
Rated Volt. [Vdc]		250(2E)	50(1H)
Capacitance	Tolerance	Part Number	
33pF(330)	±2%(G)	GQM1875C2E330GB12D	GQM1885C1H330GB01D
	±5%(J)	GQM1875C2E330JB12D	GQM1885C1H330JB01D
36pF(360)	±2%(G)	GQM1875C2E360GB12D	GQM1885C1H360GB01D
	±5%(J)	GQM1875C2E360JB12D	GQM1885C1H360JB01D
39pF(390)	±2%(G)	GQM1875C2E390GB12D	GQM1885C1H390GB01D
	±5%(J)	GQM1875C2E390JB12D	GQM1885C1H390JB01D
43pF(430)	±2%(G)	GQM1875C2E430GB12D	GQM1885C1H430GB01D
	±5%(J)	GQM1875C2E430JB12D	GQM1885C1H430JB01D
47pF(470)	±2%(G)	GQM1875C2E470GB12D	GQM1885C1H470GB01D
	±5%(J)	GQM1875C2E470JB12D	GQM1885C1H470JB01D
51pF(510)	±2%(G)		GQM1885C1H510GB01D
	±5%(J)		GQM1885C1H510JB01D
56pF(560)	±2%(G)		GQM1885C1H560GB01D
	±5%(J)		GQM1885C1H560JB01D
62pF(620)	±2%(G)		GQM1885C1H620GB01D
	±5%(J)		GQM1885C1H620JB01D
68pF(680)	±2%(G)		GQM1885C1H680GB01D
	±5%(J)		GQM1885C1H680JB01D
75pF(750)	±2%(G)		GQM1885C1H750GB01D
	±5%(J)		GQM1885C1H750JB01D
82pF(820)	±2%(G)		GQM1885C1H820GB01D
	±5%(J)		GQM1885C1H820JB01D
91pF(910)	±2%(G)		GQM1885C1H910GB01D
	±5%(J)		GQM1885C1H910JB01D
100pF(101)	±2%(G)		GQM1885C1H101GB01D
	±5%(J)		GQM1885C1H101JB01D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

(Part Number) **GQ** **M** **18** **7** **5C** **2E** **330** **G** **B12** **D** ①Product ID ②Series ③Dimensions (LxW) ④Dimension (T)
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		2.0x1.25(21)<0805>		2.8x2.8(22)<1111>
Rated Volt. [Vdc]		250(2E)	100(2A)	500(2H)
Capacitance	Tolerance	Part Number		
0.50pF(50)	±0.1pF(B)	GQM2195C2ER50BB12D	GQM2195C2AR50BB01D	GQM22M5C2HR50BB01L
	±0.25pF(C)	GQM2195C2ER50CB12D	GQM2195C2AR50CB01D	GQM22M5C2HR50CB01L
0.75pF(75)	±0.1pF(B)	GQM2195C2ER75BB12D	GQM2195C2AR75BB01D	GQM22M5C2HR75BB01L
	±0.25pF(C)	GQM2195C2ER75CB12D	GQM2195C2AR75CB01D	GQM22M5C2HR75CB01L
1.0pF(10)	±0.1pF(B)	GQM2195C2E1R0BB12D	GQM2195C2A1R0BB01D	GQM22M5C2H1R0BB01L
	±0.25pF(C)	GQM2195C2E1R0CB12D	GQM2195C2A1R0CB01D	GQM22M5C2H1R0CB01L
1.1pF(11)	±0.1pF(B)	GQM2195C2E1R1BB12D	GQM2195C2A1R1BB01D	GQM22M5C2H1R1BB01L
	±0.25pF(C)	GQM2195C2E1R1CB12D	GQM2195C2A1R1CB01D	GQM22M5C2H1R1CB01L
1.2pF(12)	±0.1pF(B)	GQM2195C2E1R2BB12D	GQM2195C2A1R2BB01D	GQM22M5C2H1R2BB01L
	±0.25pF(C)	GQM2195C2E1R2CB12D	GQM2195C2A1R2CB01D	GQM22M5C2H1R2CB01L
1.3pF(13)	±0.1pF(B)	GQM2195C2E1R3BB12D	GQM2195C2A1R3BB01D	GQM22M5C2H1R3BB01L
	±0.25pF(C)	GQM2195C2E1R3CB12D	GQM2195C2A1R3CB01D	GQM22M5C2H1R3CB01L
1.5pF(15)	±0.1pF(B)	GQM2195C2E1R5BB12D	GQM2195C2A1R5BB01D	GQM22M5C2H1R5BB01L
	±0.25pF(C)	GQM2195C2E1R5CB12D	GQM2195C2A1R5CB01D	GQM22M5C2H1R5CB01L
1.6pF(16)	±0.1pF(B)	GQM2195C2E1R6BB12D	GQM2195C2A1R6BB01D	GQM22M5C2H1R6BB01L
	±0.25pF(C)	GQM2195C2E1R6CB12D	GQM2195C2A1R6CB01D	GQM22M5C2H1R6CB01L
1.8pF(18)	±0.1pF(B)	GQM2195C2E1R8BB12D	GQM2195C2A1R8BB01D	GQM22M5C2H1R8BB01L
	±0.25pF(C)	GQM2195C2E1R8CB12D	GQM2195C2A1R8CB01D	GQM22M5C2H1R8CB01L
2.0pF(20)	±0.1pF(B)	GQM2195C2E2R0BB12D	GQM2195C2A2R0BB01D	GQM22M5C2H2R0BB01L
	±0.25pF(C)	GQM2195C2E2R0CB12D	GQM2195C2A2R0CB01D	GQM22M5C2H2R0CB01L
2.2pF(22)	±0.1pF(B)	GQM2195C2E2R2BB12D	GQM2195C2A2R2BB01D	GQM22M5C2H2R2BB01L
	±0.25pF(C)	GQM2195C2E2R2CB12D	GQM2195C2A2R2CB01D	GQM22M5C2H2R2CB01L
2.4pF(24)	±0.1pF(B)	GQM2195C2E2R4BB12D	GQM2195C2A2R4BB01D	GQM22M5C2H2R4BB01L
	±0.25pF(C)	GQM2195C2E2R4CB12D	GQM2195C2A2R4CB01D	GQM22M5C2H2R4CB01L
2.7pF(27)	±0.1pF(B)	GQM2195C2E2R7BB12D	GQM2195C2A2R7BB01D	GQM22M5C2H2R7BB01L
	±0.25pF(C)	GQM2195C2E2R7CB12D	GQM2195C2A2R7CB01D	GQM22M5C2H2R7CB01L
3.0pF(30)	±0.1pF(B)	GQM2195C2E3R0BB12D	GQM2195C2A3R0BB01D	GQM22M5C2H3R0BB01L
	±0.25pF(C)	GQM2195C2E3R0CB12D	GQM2195C2A3R0CB01D	GQM22M5C2H3R0CB01L
3.3pF(33)	±0.1pF(B)	GQM2195C2E3R3BB12D	GQM2195C2A3R3BB01D	GQM22M5C2H3R3BB01L
	±0.25pF(C)	GQM2195C2E3R3CB12D	GQM2195C2A3R3CB01D	GQM22M5C2H3R3CB01L
3.6pF(36)	±0.1pF(B)	GQM2195C2E3R6BB12D	GQM2195C2A3R6BB01D	GQM22M5C2H3R6BB01L
	±0.25pF(C)	GQM2195C2E3R6CB12D	GQM2195C2A3R6CB01D	GQM22M5C2H3R6CB01L
3.9pF(39)	±0.1pF(B)	GQM2195C2E3R9BB12D	GQM2195C2A3R9BB01D	GQM22M5C2H3R9BB01L
	±0.25pF(C)	GQM2195C2E3R9CB12D	GQM2195C2A3R9CB01D	GQM22M5C2H3R9CB01L
4.0pF(40)	±0.1pF(B)	GQM2195C2E4R0BB12D	GQM2195C2A4R0BB01D	GQM22M5C2H4R0BB01L
	±0.25pF(C)	GQM2195C2E4R0CB12D	GQM2195C2A4R0CB01D	GQM22M5C2H4R0CB01L
4.3pF(43)	±0.1pF(B)	GQM2195C2E4R3BB12D	GQM2195C2A4R3BB01D	GQM22M5C2H4R3BB01L
	±0.25pF(C)	GQM2195C2E4R3CB12D	GQM2195C2A4R3CB01D	GQM22M5C2H4R3CB01L
4.7pF(47)	±0.1pF(B)	GQM2195C2E4R7BB12D	GQM2195C2A4R7BB01D	GQM22M5C2H4R7BB01L
	±0.25pF(C)	GQM2195C2E4R7CB12D	GQM2195C2A4R7CB01D	GQM22M5C2H4R7CB01L
5.0pF(50)	±0.1pF(B)	GQM2195C2E5R0BB12D	GQM2195C2A5R0BB01D	GQM22M5C2H5R0BB01L
	±0.25pF(C)	GQM2195C2E5R0CB12D	GQM2195C2A5R0CB01D	GQM22M5C2H5R0CB01L
5.1pF(51)	±0.25pF(C)	GQM2195C2E5R1CB12D	GQM2195C2A5R1CB01D	GQM22M5C2H5R1CB01L
	±0.5pF(D)	GQM2195C2E5R1DB12D	GQM2195C2A5R1DB01D	GQM22M5C2H5R1DB01L
5.6pF(56)	±0.25pF(C)	GQM2195C2E5R6CB12D	GQM2195C2A5R6CB01D	GQM22M5C2H5R6CB01L
	±0.5pF(D)	GQM2195C2E5R6DB12D	GQM2195C2A5R6DB01D	GQM22M5C2H5R6DB01L
6.0pF(60)	±0.25pF(C)	GQM2195C2E6R0CB12D	GQM2195C2A6R0CB01D	GQM22M5C2H6R0CB01L
	±0.5pF(D)	GQM2195C2E6R0DB12D	GQM2195C2A6R0DB01D	GQM22M5C2H6R0DB01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		2.0x1.25(21)<0805>			2.8x2.8(22)<1111>
Rated Volt. [Vdc]		250(2E)	100(2A)	50(1H)	500(2H)
Capacitance	Tolerance	Part Number			
6.2pF(6R2)	±0.25pF(C)	GQM2195C2E6R2CB12D	GQM2195C2A6R2CB01D		GQM22M5C2H6R2CB01L
	±0.5pF(D)	GQM2195C2E6R2DB12D	GQM2195C2A6R2DB01D		GQM22M5C2H6R2DB01L
6.8pF(6R8)	±0.25pF(C)	GQM2195C2E6R8CB12D	GQM2195C2A6R8CB01D		GQM22M5C2H6R8CB01L
	±0.5pF(D)	GQM2195C2E6R8DB12D	GQM2195C2A6R8DB01D		GQM22M5C2H6R8DB01L
7.0pF(7R0)	±0.25pF(C)	GQM2195C2E7R0CB12D	GQM2195C2A7R0CB01D		GQM22M5C2H7R0CB01L
	±0.5pF(D)	GQM2195C2E7R0DB12D	GQM2195C2A7R0DB01D		GQM22M5C2H7R0DB01L
7.5pF(7R5)	±0.25pF(C)	GQM2195C2E7R5CB12D	GQM2195C2A7R5CB01D		GQM22M5C2H7R5CB01L
	±0.5pF(D)	GQM2195C2E7R5DB12D	GQM2195C2A7R5DB01D		GQM22M5C2H7R5DB01L
8.0pF(8R0)	±0.25pF(C)	GQM2195C2E8R0CB12D	GQM2195C2A8R0CB01D		GQM22M5C2H8R0CB01L
	±0.5pF(D)	GQM2195C2E8R0DB12D	GQM2195C2A8R0DB01D		GQM22M5C2H8R0DB01L
8.2pF(8R2)	±0.25pF(C)	GQM2195C2E8R2CB12D	GQM2195C2A8R2CB01D		GQM22M5C2H8R2CB01L
	±0.5pF(D)	GQM2195C2E8R2DB12D	GQM2195C2A8R2DB01D		GQM22M5C2H8R2DB01L
9.0pF(9R0)	±0.25pF(C)	GQM2195C2E9R0CB12D	GQM2195C2A9R0CB01D		GQM22M5C2H9R0CB01L
	±0.5pF(D)	GQM2195C2E9R0DB12D	GQM2195C2A9R0DB01D		GQM22M5C2H9R0DB01L
9.1pF(9R1)	±0.25pF(C)	GQM2195C2E9R1CB12D	GQM2195C2A9R1CB01D		GQM22M5C2H9R1CB01L
	±0.5pF(D)	GQM2195C2E9R1DB12D	GQM2195C2A9R1DB01D		GQM22M5C2H9R1DB01L
10pF(100)	±2%(G)	GQM2195C2E100GB12D	GQM2195C2A100GB01D		GQM22M5C2H100GB01L
	±5%(J)	GQM2195C2E100JB12D	GQM2195C2A100JB01D		GQM22M5C2H100JB01L
11pF(110)	±2%(G)	GQM2195C2E110GB12D	GQM2195C2A110GB01D		GQM22M5C2H110GB01L
	±5%(J)	GQM2195C2E110JB12D	GQM2195C2A110JB01D		GQM22M5C2H110JB01L
12pF(120)	±2%(G)	GQM2195C2E120GB12D	GQM2195C2A120GB01D		GQM22M5C2H120GB01L
	±5%(J)	GQM2195C2E120JB12D	GQM2195C2A120JB01D		GQM22M5C2H120JB01L
13pF(130)	±2%(G)	GQM2195C2E130GB12D	GQM2195C2A130GB01D		GQM22M5C2H130GB01L
	±5%(J)	GQM2195C2E130JB12D	GQM2195C2A130JB01D		GQM22M5C2H130JB01L
15pF(150)	±2%(G)	GQM2195C2E150GB12D	GQM2195C2A150GB01D		GQM22M5C2H150GB01L
	±5%(J)	GQM2195C2E150JB12D	GQM2195C2A150JB01D		GQM22M5C2H150JB01L
16pF(160)	±2%(G)	GQM2195C2E160GB12D	GQM2195C2A160GB01D		GQM22M5C2H160GB01L
	±5%(J)	GQM2195C2E160JB12D	GQM2195C2A160JB01D		GQM22M5C2H160JB01L
18pF(180)	±2%(G)	GQM2195C2E180GB12D	GQM2195C2A180GB01D		GQM22M5C2H180GB01L
	±5%(J)	GQM2195C2E180JB12D	GQM2195C2A180JB01D		GQM22M5C2H180JB01L
20pF(200)	±2%(G)	GQM2195C2E200GB12D		GQM2195C1H200GB01D	GQM22M5C2H200GB01L
	±5%(J)	GQM2195C2E200JB12D		GQM2195C1H200JB01D	GQM22M5C2H200JB01L
22pF(220)	±2%(G)	GQM2195C2E220GB12D		GQM2195C1H220GB01D	GQM22M5C2H220GB01L
	±5%(J)	GQM2195C2E220JB12D		GQM2195C1H220JB01D	GQM22M5C2H220JB01L
24pF(240)	±2%(G)	GQM2195C2E240GB12D		GQM2195C1H240GB01D	GQM22M5C2H240GB01L
	±5%(J)	GQM2195C2E240JB12D		GQM2195C1H240JB01D	GQM22M5C2H240JB01L
27pF(270)	±2%(G)	GQM2195C2E270GB12D		GQM2195C1H270GB01D	GQM22M5C2H270GB01L
	±5%(J)	GQM2195C2E270JB12D		GQM2195C1H270JB01D	GQM22M5C2H270JB01L
30pF(300)	±2%(G)	GQM2195C2E300GB12D		GQM2195C1H300GB01D	GQM22M5C2H300GB01L
	±5%(J)	GQM2195C2E300JB12D		GQM2195C1H300JB01D	GQM22M5C2H300JB01L
33pF(330)	±2%(G)	GQM2195C2E330GB12D		GQM2195C1H330GB01D	GQM22M5C2H330GB01L
	±5%(J)	GQM2195C2E330JB12D		GQM2195C1H330JB01D	GQM22M5C2H330JB01L
36pF(360)	±2%(G)	GQM2195C2E360GB12D		GQM2195C1H360GB01D	GQM22M5C2H360GB01L
	±5%(J)	GQM2195C2E360JB12D		GQM2195C1H360JB01D	GQM22M5C2H360JB01L
39pF(390)	±2%(G)	GQM2195C2E390GB12D		GQM2195C1H390GB01D	GQM22M5C2H390GB01L
	±5%(J)	GQM2195C2E390JB12D		GQM2195C1H390JB01D	GQM22M5C2H390JB01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

(Part Number) **GQ** **M** **21** **9** **5C** **2E** **6R2** **C** **B12** **D** **1** **2** **3** **4** **5** **6** **7** **8** **9** **10** **1** **2** **3** **4** **5** **6** **7** **8** **9** **10**

① Product ID ② Series ③ Dimensions (LxW) ④ Dimension (T)
 ⑤ Temperature Characteristics ⑥ Rated Voltage ⑦ Capacitance
 ⑧ Capacitance Tolerance ⑨ Individual Specification Code ⑩ Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

Temperature Compensating Type C0G(5C) Characteristics

LxW [mm]		2.0x1.25(21)<0805>		2.8x2.8(22)<1111>
Rated Volt. [Vdc]		250(2E)	50(1H)	500(2H)
Capacitance	Tolerance	Part Number		
43pF(430)	±2%(G)	GQM2195C2E430GB12D	GQM2195C1H430GB01D	GQM22M5C2H430GB01L
	±5%(J)	GQM2195C2E430JB12D	GQM2195C1H430JB01D	GQM22M5C2H430JB01L
47pF(470)	±2%(G)	GQM2195C2E470GB12D	GQM2195C1H470GB01D	GQM22M5C2H470GB01L
	±5%(J)	GQM2195C2E470JB12D	GQM2195C1H470JB01D	GQM22M5C2H470JB01L
51pF(510)	±2%(G)	GQM2195C2E510GB12D	GQM2195C1H510GB01D	GQM22M5C2H510GB01L
	±5%(J)	GQM2195C2E510JB12D	GQM2195C1H510JB01D	GQM22M5C2H510JB01L
56pF(560)	±2%(G)	GQM2195C2E560GB12D	GQM2195C1H560GB01D	GQM22M5C2H560GB01L
	±5%(J)	GQM2195C2E560JB12D	GQM2195C1H560JB01D	GQM22M5C2H560JB01L
62pF(620)	±2%(G)	GQM2195C2E620GB12D	GQM2195C1H620GB01D	GQM22M5C2H620GB01L
	±5%(J)	GQM2195C2E620JB12D	GQM2195C1H620JB01D	GQM22M5C2H620JB01L
68pF(680)	±2%(G)	GQM2195C2E680GB12D	GQM2195C1H680GB01D	GQM22M5C2H680GB01L
	±5%(J)	GQM2195C2E680JB12D	GQM2195C1H680JB01D	GQM22M5C2H680JB01L
75pF(750)	±2%(G)	GQM2195C2E750GB12D	GQM2195C1H750GB01D	GQM22M5C2H750GB01L
	±5%(J)	GQM2195C2E750JB12D	GQM2195C1H750JB01D	GQM22M5C2H750JB01L
82pF(820)	±2%(G)	GQM2195C2E820GB12D	GQM2195C1H820GB01D	GQM22M5C2H820GB01L
	±5%(J)	GQM2195C2E820JB12D	GQM2195C1H820JB01D	GQM22M5C2H820JB01L
91pF(910)	±2%(G)	GQM2195C2E910GB12D	GQM2195C1H910GB01D	GQM22M5C2H910GB01L
	±5%(J)	GQM2195C2E910JB12D	GQM2195C1H910JB01D	GQM22M5C2H910JB01L
100pF(101)	±2%(G)	GQM2195C2E101GB12D	GQM2195C1H101GB01D	GQM22M5C2H101GB01L
	±5%(J)	GQM2195C2E101JB12D	GQM2195C1H101JB01D	GQM22M5C2H101JB01L

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

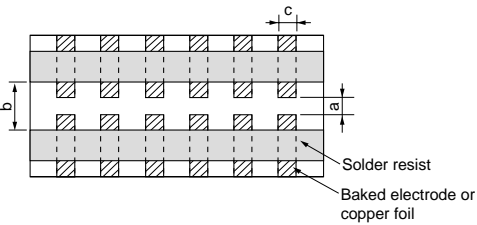
High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

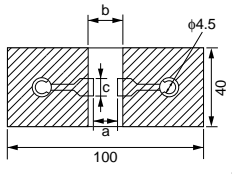
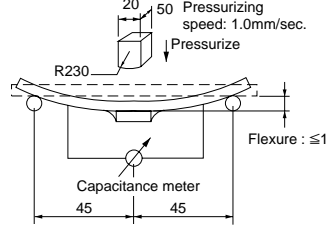
QGM Series Specifications and Test Methods

No.	Item	Specifications	Test Method																
1	Operating Temperature	-55 to 125°C	Reference Temperature: 25°C																
2	Rated Voltage	See the previous page.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V^{P-P} or V^{O-P} , whichever is larger, should be maintained within the rated voltage range.																
3	Appearance	No defects or abnormalities	Visual inspection																
4	Dimension	Within the specified dimensions	Using calipers																
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when 300%* of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA. *GQM187, GQM219(250V), GQM22: 250% of the rated voltage																
6	Insulation Resistance	More than 10,000MΩ	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at 25°C and 75%RH max. and within 2 minutes of charging, provided the charge/discharge current is less than 50mA.																
7	Capacitance	Within the specified tolerance	The capacitance/Q should be measured at 25°C at the frequency and voltage shown in the table.																
8	Q	30pF and over: $Q \geq 1400$ 30pF and below: $Q \geq 800+20C$ C: Nominal Capacitance (pF)																	
9	Capacitance Temperature Characteristics	Temperature Coefficient	Within the specified tolerance (Table A)																
		Capacitance Drift	Within $\pm 0.2\%$ or $\pm 0.05\text{pF}$ (whichever is larger)																
			<p>The capacitance change should be measured after 5 min. at each specified temp. stage.</p> <p>The temperature coefficient is determined using the capacitance measured in step 3 as a reference.</p> <p>When cycling the temperature sequentially from steps 1 through 5 the capacitance should be within the specified tolerance for the temperature coefficient and capacitance change as in Table A. The capacitance drift is calculated by dividing the differences between the maximum and minimum measured values in the steps 1, 3 and 5 by the capacitance value in step 3.</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Reference Temp. ± 2</td> </tr> <tr> <td>2</td> <td>-55± 3</td> </tr> <tr> <td>3</td> <td>Reference Temp. ± 2</td> </tr> <tr> <td>4</td> <td>125± 3</td> </tr> <tr> <td>5</td> <td>Reference Temp. ± 2</td> </tr> </tbody> </table>	Step	Temperature (°C)	1	Reference Temp. ± 2	2	-55 ± 3	3	Reference Temp. ± 2	4	125 ± 3	5	Reference Temp. ± 2				
Step	Temperature (°C)																		
1	Reference Temp. ± 2																		
2	-55 ± 3																		
3	Reference Temp. ± 2																		
4	125 ± 3																		
5	Reference Temp. ± 2																		
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	<p>Solder the capacitor to the test jig (glass epoxy board) shown in Fig. 1 using a eutectic solder. Then apply 10N* force in parallel with the test jig for 10\pm1 sec.</p> <p>The soldering should be done either with an iron or using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p> <p style="text-align: right;">*5N (GQM188)</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GQM18</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> </tr> <tr> <td>GQM21</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>GQM22</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> </tbody> </table> <p style="text-align: right;">(in mm)</p>	Type	a	b	c	GQM18	1.0	3.0	1.2	GQM21	1.2	4.0	1.65	GQM22	2.2	5.0	2.9
		Type		a	b	c													
GQM18	1.0	3.0	1.2																
GQM21	1.2	4.0	1.65																
GQM22	2.2	5.0	2.9																
		<p>Fig. 1</p>																	
11	Vibration Resistance	Appearance	No defects or abnormalities																
		Capacitance	Within the specified tolerance																
			<p>Solder the capacitor to the test jig (glass epoxy board) in the same manner and under the same conditions as (10). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 minute.</p> <p>This motion should be applied for a period of 2 hours in each of 3 mutually perpendicular directions (total of 6 hours).</p>																
		Q	<p>30pF and over: $Q \geq 1400$ 30pF and below: $Q \geq 800+20C$ C: Nominal Capacitance (pF)</p>																

Continued on the following page. ↗

GQM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																
12	Appearance	No defects or abnormalities.	Solder the capacitor on the test jig (glass epoxy board) shown in Fig. 2 using a eutectic solder. Then apply a force in the direction shown in Fig. 3. The soldering should be done by the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																
	Capacitance Change	Within $\pm 5\%$ or $\pm 0.5\text{pF}$ (whichever is larger)																	
	Deflection	 <table border="1" style="margin: 10px auto; text-align: center;"> <thead> <tr> <th>Type</th> <th>a</th> <th>b</th> <th>c</th> </tr> </thead> <tbody> <tr> <td>GQM18</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> </tr> <tr> <td>GQM21</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>GQM22</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> </tbody> </table> <p style="text-align: center;">(in mm)</p>	Type	a	b	c	GQM18	1.0	3.0	1.2	GQM21	1.2	4.0	1.65	GQM22	2.2	5.0	2.9	
Type	a	b	c																
GQM18	1.0	3.0	1.2																
GQM21	1.2	4.0	1.65																
GQM22	2.2	5.0	2.9																
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Preheat at 80 to 120°C for 10 to 30 seconds. After preheating, immerse in eutectic solder solution for 2 ± 0.5 seconds at $230\pm 5^\circ\text{C}$ or Sn-3.0Ag-0.5Cu solder solution for 2 ± 0.5 seconds at $245\pm 5^\circ\text{C}$.																
14	Resistance to Soldering Heat	The measured and observed characteristics should satisfy the specifications in the following table.																	
		Appearance	No defects or abnormalities.																
		Capacitance Change	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ (whichever is larger)																
		Q	30pF and over: $Q \geq 1400$ 30pF and below: $Q \geq 800 + 20C$ C: Nominal Capacitance (pF)																
		I.R.	More than 10,000MΩ																
	Dielectric Strength	No defects.	Preheat the capacitor at 120 to 150°C for 1 minute. Immerse the capacitor in a eutectic solder or Sn-3.0Ag-0.5Cu solder solution at $270\pm 5^\circ\text{C}$ for 10 ± 0.5 seconds. Let sit at room temperature for 24 ± 2 hours, then measure.																
15	Temperature Cycle	The measured and observed characteristics should satisfy the specifications in the following table.																	
		Appearance	No defects or abnormalities.																
		Capacitance Change	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$ (whichever is larger)																
		Q	30pF and over: $Q \geq 1400$ 30pF and below: $Q \geq 800 + 20C$ C: Nominal Capacitance (pF)																
		I.R.	More than 10,000MΩ																
	Dielectric Strength	No defects.	Fix the capacitor to the supporting jig in the same manner and under the same conditions as (10). Perform the five cycles according to the four heat treatments listed in the following table. Let sit for 24 ± 2 hours at room temperature, then measure.																
			<table border="1" style="margin: 10px auto; text-align: center;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3	
Step	1	2	3	4															
Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.															
Time (min.)	30±3	2 to 3	30±3	2 to 3															
16	Humidity Steady State	The measured and observed characteristics should satisfy the specifications in the following table.																	
		Appearance	No defects or abnormalities.																
		Capacitance Change	Within $\pm 5\%$ or $\pm 0.5\text{pF}$ (whichever is larger)																
		Q	30pF and over: $Q \geq 350$ 10pF and over, 30pF and below: $Q \geq 275 + 5C/2$ 10pF and below: $Q \geq 200 + 10C$ C: Nominal Capacitance (pF)																
	I.R.	More than 1,000MΩ	Set the capacitor at $40\pm 2^\circ\text{C}$ and in 90 to 95% humidity for 500 ± 12 hours. Remove and set for 24 ± 2 hours at room temperature, then measure.																

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GQM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method	
17	Humidity Load	The measured and observed characteristics should satisfy the specifications in the following table.	Apply the rated voltage at 40±2°C and 90 to 95% humidity for 500±12 hours. Remove and let sit for 24±2 hours at room temperature then measure. The charge/discharge current is less than 50mA.	
		Appearance		No defects or abnormalities.
		Capacitance Change		Within ±7.5% or ±0.75pF (whichever is larger)
		Q		30pF and over: $Q \geq 200$ 30pF and below: $Q \geq 100 + 10C/3$ C: Nominal Capacitance (pF)
	I.R.	More than 500MΩ		
18	High Temperature Load	The measured and observed characteristics should satisfy the specifications in the following table.	Apply 200%* of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Set for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. *GQM22: 150% of the rated voltage	
		Appearance		No defects or abnormalities.
		Capacitance Change		Within ±3% or ±0.3pF (whichever is larger)
		Q		30pF and over: $Q \geq 350$ 10pF and over, 30pF and below: $Q \geq 275 + 5C/2$ 10pF and below: $Q \geq 200 + 10C$ C: Nominal Capacitance (pF)
	I.R.	More than 1,000MΩ		

Table A

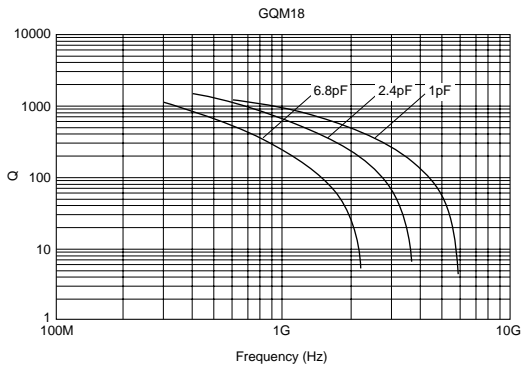
Char.	Nominal Values (ppm/°C) *1	Capacitance Change from 25°C (%)					
		-55°C		-30°C		-10°C	
		Max.	Min.	Max.	Min.	Max.	Min.
5C	0±30	0.58	-0.24	0.40	-0.17	0.25	-0.11

*1: Nominal values denote the temperature coefficient within a range of 25 to 125°C.

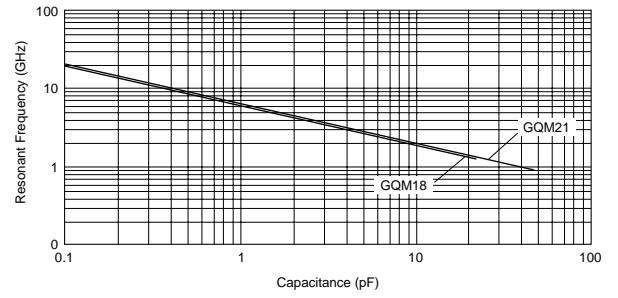
For General GRM Series
Array GNM Series
Low ESL LL□ Series
High-Q GJM Series
High Frequency GOM Series
Monolithic Microchip GMA Series
For Bonding GMD Series
Product Information

GQM Series Data

■ Q - Frequency Characteristics



■ Resonant Frequency - Capacitance



For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



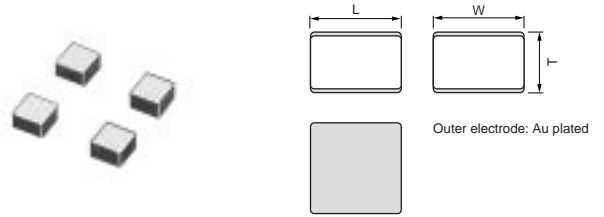
Monolithic Microchip GMA Series

■ Features

1. Better microwave characteristics
2. Suitable for by passing
3. High density mounting

■ Applications

1. Optical device for telecommunication
2. IC, built-in IC packaging
3. Measuring equipment



Part Number	Dimensions (mm)		
	L	W	T
GMA0D3	0.38 ±0.05	0.38 ±0.05	0.3 ±0.05
GMA05X	0.5 ±0.05	0.5 ±0.05	0.35 ±0.05
GMA085	0.8 ±0.05	0.8 ±0.05	0.5 ±0.1

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Capacitance Table

High Dielectric Constant Type X7R(R7)/X5R(R6) Characteristics

X		ex.X: T Dimension [mm]												
Capacitance	LxW [mm]	0.38x0.38 (0D) <015015>		0.5x0.5 (05) <0202>					0.8x0.8 (08) <0303>					
		Rated Voltage [Vdc]	10 (1A)	100 (2A)	25 (1E)	10 (1A)	6.3 (0J)	100 (2A)	25 (1E)	10 (1A)	6.3 (0J)			
100pF(101)			X											
150pF(151)			X											
220pF(221)			X											
330pF(331)			X											
470pF(471)			X											
680pF(681)			X											
1000pF(102)			X											
1500pF(152)					X			5						
2200pF(222)					X			5						
3300pF(332)					X			5						
4700pF(472)					X			5						
6800pF(682)						X		5						
10000pF(103)	3					X			5					
15000pF(153)						X			5					
22000pF(223)						X			5					
33000pF(333)										5				
47000pF(473)										5				
68000pF(683)										5				
0.10μF(104)							X			5				
0.47μF(474)													5	

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

High Dielectric Constant Type X7R(R7)/X5R(R6) Characteristics

LxW [mm]		0.38x0.38(0D)<015015>
Rated Volt. [Vdc]		10(1A)
Capacitance	Tolerance	Part Number
10000pF(103)	±20%(M)	GMA0D3R71A103MA01T

LxW [mm]		0.5x0.5(05)<0202>			
Rated Volt. [Vdc]		100(2A)	25(1E)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
100pF(101)	±20%(M)	GMA05XR72A101MA01T			
150pF(151)	±20%(M)	GMA05XR72A151MA01T			
220pF(221)	±20%(M)	GMA05XR72A221MA01T			
330pF(331)	±20%(M)	GMA05XR72A331MA01T			
470pF(471)	±20%(M)	GMA05XR72A471MA01T			
680pF(681)	±20%(M)	GMA05XR72A681MA01T			
1000pF(102)	±20%(M)	GMA05XR72A102MA01T			
1500pF(152)	±20%(M)		GMA05XR71E152MA11T		
2200pF(222)	±20%(M)		GMA05XR71E222MA11T		
3300pF(332)	±20%(M)		GMA05XR71E332MA11T		
4700pF(472)	±20%(M)		GMA05XR71E472MA11T		
6800pF(682)	±20%(M)			GMA05XR71A682MA01T	
10000pF(103)	±20%(M)			GMA05XR71A103MA01T	
15000pF(153)	±20%(M)			GMA05XR71A153MA01T	
22000pF(223)	±20%(M)			GMA05XR71A223MA01T	
33000pF(333)	±20%(M)				
47000pF(473)	±20%(M)				
68000pF(683)	±20%(M)				
0.10μF(104)	±20%(M)				GMA05XR60J104ME12T*

LxW [mm]		0.8x0.8(08)<0303>			
Rated Volt. [Vdc]		100(2A)	25(1E)	10(1A)	6.3(0J)
Capacitance	Tolerance	Part Number			
1500pF(152)	±20%(M)	GMA085R72A152MA01T			
2200pF(222)	±20%(M)	GMA085R72A222MA01T			
3300pF(332)	±20%(M)	GMA085R72A332MA01T			
4700pF(472)	±20%(M)	GMA085R72A472MA01T			
6800pF(682)	±20%(M)	GMA085R72A682MA01T			
10000pF(103)	±20%(M)		GMA085R71E103MA11T		
15000pF(153)	±20%(M)		GMA085R71E153MA11T		
22000pF(223)	±20%(M)		GMA085R71E223MA11T		
33000pF(333)	±20%(M)			GMA085R71A333MA01T	
47000pF(473)	±20%(M)			GMA085R71A473MA01T	
68000pF(683)	±20%(M)			GMA085R71A683MA01T	
0.10μF(104)	±20%(M)			GMA085R71A104MA01T	
0.47μF(474)	±20%(M)				GMA085R60J474ME12T*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GMA series Specifications and Test Method (2).

(Part Number) **GM** **A** **0D** **3** **R7** **1A** **103** **M** **A01** **T**
 ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨ ⑩

- ① Product ID
- ② Series
- ③ Dimensions (LxW)
- ④ Dimension (T)
- ⑤ Temperature Characteristics
- ⑥ Rated Voltage
- ⑦ Capacitance
- ⑧ Capacitance Tolerance
- ⑨ Individual Specification Code
- ⑩ Packaging

Packaging Code in Part Number shows STD Tray.

GMA Series Specifications and Test Methods (1)

When no "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method															
1	Operating Temperature Range	R7: -55 to +125°C	Reference Temperature: 25°C															
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.															
3	Appearance	No defects or abnormalities	Visual inspection															
4	Dimensions	Within the specified dimensions	Using calipers															
5	Dielectric Strength	No defects or abnormalities	No failure should be observed when a voltage of 250% of the rated voltage is applied between the both terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.															
6	Insulation Resistance	More than 10,000MΩ or 500ΩF (whichever is smaller)	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 2 minutes of charging.															
7	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at reference temperature at the frequency and voltage shown in the table.															
8	Dissipation Factor (D.F.)	R7: W.V.: 25V min.; 0.025 max. W.V.: 16V/10V; 0.035 max.	<table border="1" style="margin-left: auto; margin-right: auto;"> <tr> <td>Frequency</td> <td>1±0.1kHz</td> </tr> <tr> <td>Voltage</td> <td>1±0.2Vrms</td> </tr> </table>	Frequency	1±0.1kHz	Voltage	1±0.2Vrms											
Frequency	1±0.1kHz																	
Voltage	1±0.2Vrms																	
9	Capacitance Temperature Characteristics	No bias R7: Within +/-15% (-55 to +125°C)	The capacitance change should be measured after 5 min. at each specified temp. stage. •The ranges of capacitance change compared with the Reference Temperature value over the temperature ranges shown in the table should be within the specified ranges.* <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3</td> </tr> </tbody> </table> *Initial measurement for high dielectric constant type Perform a heat treatment at 150 +0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement.	Step	Temperature (°C)	1	25±2	2	-55±3	3	25±2	4	125±3					
Step	Temperature (°C)																	
1	25±2																	
2	-55±3																	
3	25±2																	
4	125±3																	
10	Mechanical Strength	Bond Strength	Pull force: 0.03N min. MIL-STD-883 Method 2011 Condition D Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20) and bond a 25μm (0.001 inch) gold wire to the capacitor terminal using an ultrasonic ball bond. Then, pull wire.															
		Die Shear Strength	Die Shear force: 2N min. MIL-STD-883 Method 2019 Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20). Apply the force parallel to the substrate.															
11	Vibration Resistance	Appearance	No defects or abnormalities															
		Capacitance	Within the specified tolerance															
		D.F.	R7: W.V.: 25V min.; 0.025 max. W.V.: 16V/10V; 0.035 max. Ramp frequency from 10 to 55Hz then return to 10Hz all within 1 minute. Amplitude: 1.5 mm (0.06 inch) max. total excursion. Apply this motion for a period of 2 hours in each of 3 mutually perpendicular directions (total 6 hours).															
12	Temperature Cycle	Appearance	No defects or abnormalities															
		Capacitance Change	R7: Within ±7.5%															
		D.F.	R7: W.V.: 25V min.; 0.025 max. W.V.: 16V/10V; 0.035 max.															
		I.R.	More than 10,000MΩ or 500ΩF (whichever is smaller)															
		Dielectric Strength	No defects															
			The capacitor should be set for 24±2 hours at room temperature after one hour of heat treatment at 150+0/-10°C, then measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11) and conduct the five cycles according to the temperatures and time shown in the following table. Set it for 24±2 hours at room temperature, then measure. <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30±3</td> <td>2 to 3</td> <td>30±3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30±3	2 to 3	30±3	2 to 3
Step	1	2	3	4														
Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.														
Time (min.)	30±3	2 to 3	30±3	2 to 3														

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding and wire bonding when tests No. 11 to 15 are performed.

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

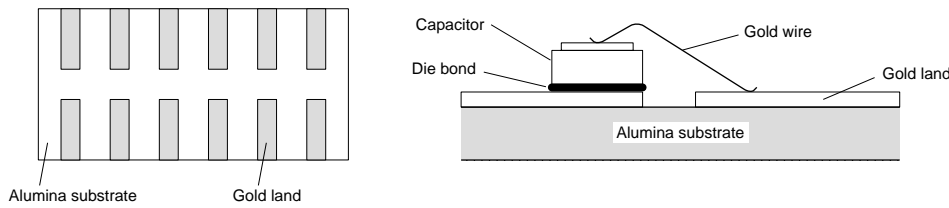
GMA Series Specifications and Test Methods (1)

Continued from the preceding page.

When no "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method
13	Humidity (Steady State)	Appearance	No defects or abnormalities
		Capacitance Change	R7: Within $\pm 12.5\%$
		D.F.	R7: W.V.: 10V min.; 0.05 max.
		I.R.	More than 1,000M Ω or 50 Ω F (whichever is smaller)
14	Humidity Load	Appearance	No defects or abnormalities
		Capacitance Change	R7: Within $\pm 12.5\%$
		D.F.	R7: W.V.: 10V min.; 0.05 max.
		I.R.	More than 500M Ω or 25 Ω F (whichever is smaller)
15	High Temperature Load	Appearance	No defects or abnormalities
		Capacitance Change	R7: Within $\pm 12.5\%$
		D.F.	R7: W.V.: 10V min.; 0.05 max.
		I.R.	More than 1,000M Ω or 50 Ω F (whichever is smaller)
			Set the capacitor for 500 ± 12 hours at 40 $\pm 2^\circ$ C, in 90 to 95% humidity. Take it out and set it for 24 ± 2 hours at room temperature, then measure.
			Apply the rated voltage for 500 ± 12 hours at 40 $\pm 2^\circ$ C, in 90 to 95% humidity and set it for 24 ± 2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
			A voltage treatment should be given to the capacitor, in which a DC voltage of 200% the rated voltage is applied for one hour at the maximum operating temperature; $\pm 3^\circ$ C then it should be set for 24 ± 2 hours at room temperature and the initial measurement should be conducted. Then apply the above mentioned voltage continuously for 1000 ± 12 hours at the same temperature, remove it from the bath, and set it for 24 ± 2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding and wire bonding when tests No. 11 to 15 are performed.



For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

GMA Series Specifications and Test Methods (2)

When no "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GMA Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method															
1	Operating Temperature Range	R6 : -55°C to 85°C	Reference Temperature : 25°C															
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.															
3	Appearance	No defects or abnormalities.	Visual inspection.															
4	Dimensions	Within the specified dimensions.	Using calipers.															
5	Dielectric Strength	No defects or abnormalities.	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.															
6	Insulation Resistance	More than 50Ω · F	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 1 minutes of charging.															
7	Capacitance	Within the specified tolerance.	The capacitance/D.F. should be measured at reference temperature at the frequency and voltage shown in the table.															
8	Dissipation Factor (D.F.)	R6 : 0.1 max.	<table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Capacitance</th> <th>Frequency</th> <th>Voltage</th> </tr> </thead> <tbody> <tr> <td>C ≤ 10μF (6.3Vmax.)</td> <td>1 ± 0.1kHz</td> <td>0.5 ± 0.1Vrms</td> </tr> </tbody> </table>	Capacitance	Frequency	Voltage	C ≤ 10μF (6.3Vmax.)	1 ± 0.1kHz	0.5 ± 0.1Vrms									
Capacitance	Frequency	Voltage																
C ≤ 10μF (6.3Vmax.)	1 ± 0.1kHz	0.5 ± 0.1Vrms																
9	Capacitance Temperature Characteristics	No bias R6 : Within ±15% (-55°C to +85°C)	<p>The capacitance change should be measured after 5 min. at each specified temp. stage.</p> <p>The ranges of capacitance change compared with the Reference Temperature value over the temperature ranges shown in the table should be within the specified ranges.*</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25 ± 2</td> </tr> <tr> <td>2</td> <td>-55 ± 3</td> </tr> <tr> <td>3</td> <td>25 ± 2</td> </tr> <tr> <td>4</td> <td>85 ± 3</td> </tr> </tbody> </table> <p>*Initial measurement for high dielectric constant type Perform a heat treatment at 150 +0/-10°C for one hour and then let sit for 24 ± 2 hours at room temperature. Perform the initial measurement.</p>	Step	Temperature (°C)	1	25 ± 2	2	-55 ± 3	3	25 ± 2	4	85 ± 3					
Step	Temperature (°C)																	
1	25 ± 2																	
2	-55 ± 3																	
3	25 ± 2																	
4	85 ± 3																	
10	Mechanical Strength	Bond Strength	Pull force : 0.03N min. MIL-STD-883 Method 2011 Condition D Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20) and bond a 25μm (0.001 inch) gold wire to the capacitor terminal using an ultrasonic ball bond. Then, pull wire.															
		Die Shear Strength	Die Shear force : 2N min. MIL-STD-883 Method 2019 Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20). Apply the force parallel to the substrate.															
11	Vibration Resistance	Appearance	No defects or abnormalities.															
		Capacitance	Within the specified tolerance.															
		D.F.	R6 : 0.1 max. Ramp frequency from 10 to 55Hz then return to 10Hz all within 1 minute. Amplitude: 1.5 mm (0.06 inch) max. total excursion. Apply this motion for a period of 2 hours in each of 3 mutually perpendicular directions (total 6 hours).															
12	Temperature Sudden Change	Appearance	No defects or abnormalities.															
		Capacitance Change	R6 : Within ±7.5%															
		D.F.	R6 : 0.1 max.															
		I.R.	More than 50Ω · F															
		Dielectric Strength	No defects															
			<p>The capacitor should be set for 24 ± 2 hours at room temperature after one hour of heat treatment at 150 +0/-10°C, then measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11) and conduct the five cycles according to the temperatures and time shown in the following table. Set it for 48 ± 4 hours at room temperature, then measure.</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30 ± 3</td> <td>2 to 3</td> <td>30 ± 3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30 ± 3	2 to 3	30 ± 3	2 to 3
Step	1	2	3	4														
Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.														
Time (min.)	30 ± 3	2 to 3	30 ± 3	2 to 3														

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding and wire bonding when tests No. 11 to 14 are performed.

Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

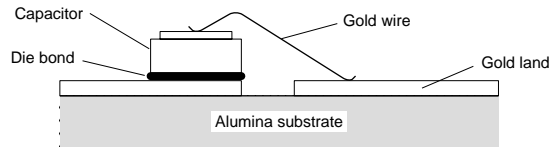
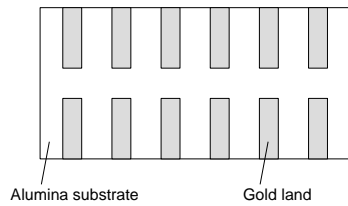
GMA Series Specifications and Test Methods (2)

Continued from the preceding page.

When no "***" is added in PNs table, please refer to GMA Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GMA Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method
13	Appearance	No defects or abnormalities.	Apply the rated voltage for 500±12 hours at 40±2°C, in 90 to 95% humidity and set it for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. • Initial measurement Perform a heat treatment at 150+0/−10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/−10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.
	Capacitance Change	R6 : Within ±12.5%	
	D.F.	R6 : 0.2 max.	
	High Temperature High Humidity (Steady) I.R.	More than 12.5Ω · F	
14	Appearance	No defects or abnormalities.	Apply 150% of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours at room temperature, then measure. The charge/ discharge current is less than 50mA. • Initial measurement Perform a heat treatment at 150+0/−10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/−10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.
	Capacitance Change	R6 : Within ±12.5%	
	D.F.	R6 : 0.2 max.	
	Durability I.R.	More than 25Ω · F	

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding and wire bonding when tests No. 11 to 14 are performed.



For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Chip Monolithic Ceramic Capacitors



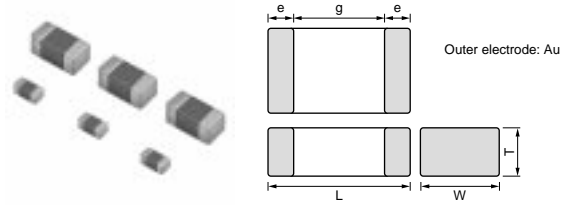
for Bonding GMD Series

■ Features

1. Small chip size (LxWxT: 0.6x0.3x0.3, 1.0x0.5x0.5mm)
2. Available for Wire/Die bonding due to Gold termination.
3. Suitable for Optical device for telecommunication, built-in IC packaging.

■ Applications

1. Optical device for telecommunication
2. IC, built-in IC packaging



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GMD033	0.6±0.03	0.3±0.03	0.3±0.03	0.12 to 0.22	0.16
GMD155	1.0±0.05	0.5±0.05	0.5±0.05	0.15 to 0.35	0.3

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information

Capacitance Table

High Dielectric Constant Type X7R(R7)/X5R(R6) Characteristics

		3 ex.3: T Dimension [mm]							
Capacitance	LxW [mm]	0.6x0.3 (03) <0201>			1.0x0.5 (15) <0402>			0.6x0.3 (03) <0201>	1.0x0.5 (15) <0402>
	Rated Voltage [Vdc]	25 (1E)	16 (1C)	10 (1A)	50 (1H)	25 (1E)	16 (1C)	6.3 (0J)	10 (1A)
100pF(101)	3								
120pF(121)	3								
150pF(151)	3								
180pF(181)	3								
220pF(221)	3				5				
270pF(271)	3				5				
330pF(331)	3				5				
390pF(391)	3				5				
470pF(471)	3				5				
560pF(561)	3				5				
680pF(681)	3				5				
820pF(821)	3				5				
1000pF(102)	3				5				
1200pF(122)	3				5				
1500pF(152)	3				5				
1800pF(182)		3			5				
2200pF(222)		3			5				
2700pF(272)		3			5				
3300pF(332)		3			5				
3900pF(392)			3		5				
4700pF(472)			3		5				
5600pF(562)			3			5			
6800pF(682)			3			5			
8200pF(822)			3			5			
10000pF(103)			3			5			
12000pF(123)						5			
15000pF(153)						5			
18000pF(183)						5			
22000pF(223)						5			
27000pF(273)						5			
33000pF(333)						5			
39000pF(393)						5			
47000pF(473)						5			
56000pF(563)							5	3	
68000pF(683)							5	3	
82000pF(823)							5	3	
0.10μF(104)							5	3	
0.12μF(124)									5
0.15μF(154)									5
0.18μF(184)									5
0.22μF(224)									5
0.27μF(274)									5
0.33μF(334)									5
0.39μF(394)									5
0.47μF(474)									5

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

High Dielectric Constant Type X7R(R7) Characteristics

LxW [mm]		1.0x0.5(15)<0402>		
Rated Volt. [Vdc]		50(1H)	25(1E)	16(1C)
Capacitance	Tolerance	Part Number		
220pF(221)	±10%(K)	GMD155R71H221KA01D		
270pF(271)	±10%(K)	GMD155R71H271KA01D		
330pF(331)	±10%(K)	GMD155R71H331KA01D		
390pF(391)	±10%(K)	GMD155R71H391KA01D		
470pF(471)	±10%(K)	GMD155R71H471KA01D		
560pF(561)	±10%(K)	GMD155R71H561KA01D		
680pF(681)	±10%(K)	GMD155R71H681KA01D		
820pF(821)	±10%(K)	GMD155R71H821KA01D		
1000pF(102)	±10%(K)	GMD155R71H102KA01D		
1200pF(122)	±10%(K)	GMD155R71H122KA01D		
1500pF(152)	±10%(K)	GMD155R71H152KA01D		
1800pF(182)	±10%(K)	GMD155R71H182KA01D		
2200pF(222)	±10%(K)	GMD155R71H222KA01D		
2700pF(272)	±10%(K)	GMD155R71H272KA01D		
3300pF(332)	±10%(K)	GMD155R71H332KA01D		
3900pF(392)	±10%(K)	GMD155R71H392KA01D		
4700pF(472)	±10%(K)	GMD155R71H472KA01D		
5600pF(562)	±10%(K)		GMD155R71E562KA01D	
6800pF(682)	±10%(K)		GMD155R71E682KA01D	
8200pF(822)	±10%(K)		GMD155R71E822KA01D	
10000pF(103)	±10%(K)		GMD155R71E103KA01D	
12000pF(123)	±10%(K)		GMD155R71E123KA01D	
15000pF(153)	±10%(K)		GMD155R71E153KA01D	
18000pF(183)	±10%(K)		GMD155R71E183KA01D	
22000pF(223)	±10%(K)		GMD155R71E223KA01D	
27000pF(273)	±10%(K)		GMD155R71E273KA11D	
33000pF(333)	±10%(K)		GMD155R71E333KA11D	
39000pF(393)	±10%(K)		GMD155R71E393KA11D	
47000pF(473)	±10%(K)		GMD155R71E473KA11D	
56000pF(563)	±10%(K)			GMD155R71C563KA11D
68000pF(683)	±10%(K)			GMD155R71C683KA11D
82000pF(823)	±10%(K)			GMD155R71C823KA11D
0.10μF(104)	±10%(K)			GMD155R71C104KA11D

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

(Part Number) **GM** **D** **15** **5** **R7** **1H** **221** **K** **A01** **D** ①Product ID ②Series ③Dimensions (LxW) ④Dimension (T)
 ⑤Temperature Characteristics ⑥Rated Voltage ⑦Capacitance
 ⑧Capacitance Tolerance ⑨Individual Specification Code ⑩Packaging

Packaging Code in Part Number shows STD 180mm Reel Taping.

High Dielectric Constant Type X5R(R6) Characteristics

LxW [mm]		0.6x0.3(03)<0201>	1.0x0.5(15)<0402>
Rated Volt. [Vdc]		6.3(0J)	10(1A)
Capacitance	Tolerance	Part Number	
56000pF(563)	±10%(K)	GMD033R60J563KE11D*	
68000pF(683)	±10%(K)	GMD033R60J683KE11D*	
82000pF(823)	±10%(K)	GMD033R60J823KE11D*	
0.10μF(104)	±10%(K)	GMD033R60J104KE11D*	
0.12μF(124)	±10%(K)		GMD155R61A124KE12D*
0.15μF(154)	±10%(K)		GMD155R61A154KE12D*
0.18μF(184)	±10%(K)		GMD155R61A184KE12D*
0.22μF(224)	±10%(K)		GMD155R61A224KE12D*
0.27μF(274)	±10%(K)		GMD155R61A274KE11D*
0.33μF(334)	±10%(K)		GMD155R61A334KE11D*
0.39μF(394)	±10%(K)		GMD155R61A394KE11D*
0.47μF(474)	±10%(K)		GMD155R61A474KE11D*

The part number code is shown in () and Unit is shown in []. < >: EIA [inch] Code

* Please refer to GMD series Specifications and Test Method (2).

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series


Product Information

GMD Series Specifications and Test Methods (1)

When no "***" is added in PNs table, please refer to GMD Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GMD Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method															
1	Operating Temperature Range	R7 : -55°C to 125°C	Reference Temperature : 25°C															
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.															
3	Appearance	No defects or abnormalities.	Visual inspection.															
4	Dimensions	Within the specified dimensions.	Using calipers.															
5	Dielectric Strength	No defects or abnormality.	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.															
6	Insulation Resistance	More than 10,000MΩ or 500Ω · F (whichever is smaller)	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 2 minutes of charging.															
7	Capacitance	Within the specified tolerance.	The capacitance/D.F. should be measured at reference temperature at the frequency and voltage shown in the table.															
8	Dissipation Factor (D.F.)	R7 : W.V. 25Vmin. : 0.025 max. W.V. 16/10V : 0.035 max.	<table border="1"> <tr> <td>Frequency</td> <td>1±0.1kHz</td> </tr> <tr> <td>Voltage</td> <td>1±0.2Vrms</td> </tr> </table>	Frequency	1±0.1kHz	Voltage	1±0.2Vrms											
Frequency	1±0.1kHz																	
Voltage	1±0.2Vrms																	
9	Capacitance Temperature Characteristics	No bias R7 : Within ±15% (-55°C to +125°C)	<p>The capacitance change should be measured after 5 min. at each specified temp. stage.</p> <p>The ranges of capacitance change compared with the Reference Temperature value over the temperature ranges shown in the table should be within the specified ranges.*</p> <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>-55±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>125±3</td> </tr> </tbody> </table> <p>*Initial measurement for high dielectric constant type Perform a heat treatment at 150 +0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement.</p>	Step	Temperature (°C)	1	25±2	2	-55±3	3	25±2	4	125±3					
Step	Temperature (°C)																	
1	25±2																	
2	-55±3																	
3	25±2																	
4	125±3																	
10	Mechanical Strength	Bond Strength Pull force : 0.03N min.	MIL-STD-883 Method 2011 Condition D Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20) and bond a 25mm (0.001 inch) gold wire to the capacitor terminal using an ultrasonic ball bond. Then, pull wire.															
		Die Shear Strength Die Shear force : 2N min.	MIL-STD-883 Method 2019 Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20). Apply the force parallel to the substrate.															
11	Vibration Resistance	Appearance	No defects or abnormalities.															
		Capacitance	Within the specified tolerance.															
		D.F.	R7 : W.V. 25Vmin. : 0.025 max. W.V. 16/10V : 0.035 max.															
12	Temperature Cycle	Appearance	No defects or abnormalities.															
		Capacitance Change	R7 : Within ±7.5%															
		D.F.	R7 : W.V. 25Vmin. : 0.025 max. W.V. 16/10V : 0.035 max.															
		I.R.	More than 10,000MΩ or 500Ω · F (whichever is smaller)															
		Dielectric Strength	No defects															
			<p>The capacitor should be set for 24±2 hours at room temperature after one hour of heat treatment at 150+0/-10°C, then measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11) and conduct the five cycles according to the temperatures and time shown in the following table. Set it for 24±2 hours at room temperature, then measure.</p> <table border="1"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp.+0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp.+3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30+/-3</td> <td>2 to 3</td> <td>30+/-3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.	Time (min.)	30+/-3	2 to 3	30+/-3	2 to 3
Step	1	2	3	4														
Temp. (°C)	Min. Operating Temp.+0/-3	Room Temp.	Max. Operating Temp.+3/-0	Room Temp.														
Time (min.)	30+/-3	2 to 3	30+/-3	2 to 3														

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding. when tests No. 11 to 15 are performed.

Continued on the following page. 

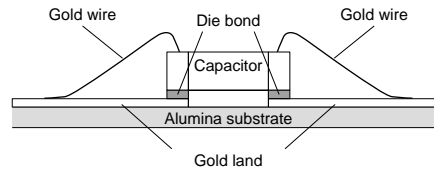
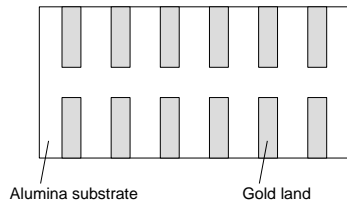
GMD Series Specifications and Test Methods (1)

Continued from the preceding page.

When no "*" is added in PNs table, please refer to GMD Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GMD Series Specifications and Test Methods (2).**

No.	Item	Specifications	Test Method
13	Humidity (Steady State)	Appearance	Set the capacitor for 500±12 hours at 40±2°C, in 90 to 95% humidity. Take it out and set it for 24±2 hours at room temperature, then measure.
		Capacitance Change	
		D.F.	
		I.R.	
14	Humidity Load	Appearance	Apply the rated voltage for 500±12 hours at 40±2°C, in 90 to 95% humidity and set it for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	
		D.F.	
		I.R.	
15	High Temperature Load	Appearance	A voltage treatment should be given to the capacitor, in which a DC voltage of 200% the rated voltage is applied for one hour at the maximum operating temperature; ±3°C then it should be set for 24±2 hours at room temperature and the initial measurement should be conducted. Then apply the above-mentioned voltage continuously for 1000±12 hours at the same temperature, remove it from the bath, and set it for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA.
		Capacitance Change	
		D.F.	
		I.R.	

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding. when tests No. 11 to 15 are performed.



For General GRM Series

Array GMM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series


Product Information

GMD Series Specifications and Test Methods (2)

When no "*" is added in PNs table, please refer to GMD Series Specifications and Test Methods (1).
 When "*" is added in PNs table, please refer to GMD Series Specifications and Test Methods (2).

No.	Item	Specifications	Test Method															
1	Operating Temperature Range	R6 : -55°C to 85°C	Reference Temperature : 25°C															
2	Rated Voltage	See the previous pages.	The rated voltage is defined as the maximum voltage that may be applied continuously to the capacitor. When AC voltage is superimposed on DC voltage, V ^{P-P} or V ^{O-P} , whichever is larger, should be maintained within the rated voltage range.															
3	Appearance	No defects or abnormalities.	Visual inspection.															
4	Dimensions	Within the specified dimensions.	Using calipers.															
5	Dielectric Strength	No defects or abnormalities.	No failure should be observed when 250% of the rated voltage is applied between the terminations for 1 to 5 seconds, provided the charge/discharge current is less than 50mA.															
6	Insulation Resistance	More than 50Ω · F	The insulation resistance should be measured with a DC voltage not exceeding the rated voltage at normal temperature and humidity and within 1 minutes of charging.															
7	Capacitance	Within the specified tolerance.	The capacitance/D.F. should be measured at reference temperature at the frequency and voltage shown in the table.															
8	Dissipation Factor (D.F.)	R6 : 0.1 max.	<table border="1"> <thead> <tr> <th>Capacitance</th> <th>Frequency</th> <th>Voltage</th> </tr> </thead> <tbody> <tr> <td>C ≤ 10μF (10Vmin.)*1</td> <td>1 ± 0.1kHz</td> <td>1.0 ± 0.2Vrms</td> </tr> <tr> <td>C ≤ 10μF (6.3Vmax.)</td> <td>1 ± 0.1kHz</td> <td>0.5 ± 0.1Vrms</td> </tr> </tbody> </table>	Capacitance	Frequency	Voltage	C ≤ 10μF (10Vmin.)*1	1 ± 0.1kHz	1.0 ± 0.2Vrms	C ≤ 10μF (6.3Vmax.)	1 ± 0.1kHz	0.5 ± 0.1Vrms						
			Capacitance	Frequency	Voltage													
C ≤ 10μF (10Vmin.)*1	1 ± 0.1kHz	1.0 ± 0.2Vrms																
C ≤ 10μF (6.3Vmax.)	1 ± 0.1kHz	0.5 ± 0.1Vrms																
			*1 GMD155 R6 1A 124 to 224 are applied to 0.5 ± 0.1 Vrms.															
9	Capacitance Temperature Characteristics	No bias	R6 : Within ±15% (-55°C to +85°C) The capacitance change should be measured after 5 min. at each specified temp. stage. The ranges of capacitance change compared with the Reference Temperature value over the temperature ranges shown in the table should be within the specified ranges.*															
				<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25 ± 2</td> </tr> <tr> <td>2</td> <td>-55 ± 3</td> </tr> <tr> <td>3</td> <td>25 ± 2</td> </tr> <tr> <td>4</td> <td>85 ± 3</td> </tr> </tbody> </table>	Step	Temperature (°C)	1	25 ± 2	2	-55 ± 3	3	25 ± 2	4	85 ± 3				
Step	Temperature (°C)																	
1	25 ± 2																	
2	-55 ± 3																	
3	25 ± 2																	
4	85 ± 3																	
10	Mechanical Strength	Bond Strength	Pull force : 0.03N min. MIL-STD-883 Method 2011 Condition D Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20) and bond a 25μm (0.001 inch) gold wire to the capacitor terminal using an ultrasonic ball bond. Then, pull wire.															
		Die Shear Strength	Die Shear force : 2N min. MIL-STD-883 Method 2019 Mount the capacitor on a gold metallized alumina substrate with Au-Sn (80/20). Apply the force parallel to the substrate.															
11	Vibration Resistance	Appearance	No defects or abnormalities.															
		Capacitance	Within the specified tolerance.															
		D.F.	R6 : 0.1 max.															
12	Temperature Sudden Change	Appearance	No defects or abnormalities.															
		Capacitance Change	R6 : Within ±7.5%															
		D.F.	R6 : 0.1 max.															
		I.R.	More than 50Ω · F															
		Dielectric Strength	No defects															
			The capacitor should be set for 24 ± 2 hours at room temperature after one hour of heat treatment at 150 + 0/-10°C, then measure for the initial measurement. Fix the capacitor to the supporting jig in the same manner and under the same conditions as (11) and conduct the five cycles according to the temperatures and time shown in the following table. Set it for 24 ± 2 hours at room temperature, then measure.															
			<table border="1"> <thead> <tr> <th>Step</th> <th>1</th> <th>2</th> <th>3</th> <th>4</th> </tr> </thead> <tbody> <tr> <td>Temp. (°C)</td> <td>Min. Operating Temp. +0/-3</td> <td>Room Temp.</td> <td>Max. Operating Temp. +3/-0</td> <td>Room Temp.</td> </tr> <tr> <td>Time (min.)</td> <td>30 ± 3</td> <td>2 to 3</td> <td>30 ± 3</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	1	2	3	4	Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.	Time (min.)	30 ± 3	2 to 3	30 ± 3	2 to 3
Step	1	2	3	4														
Temp. (°C)	Min. Operating Temp. +0/-3	Room Temp.	Max. Operating Temp. +3/-0	Room Temp.														
Time (min.)	30 ± 3	2 to 3	30 ± 3	2 to 3														

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding. when tests No. 11 to 14 are performed.

Continued on the following page. 

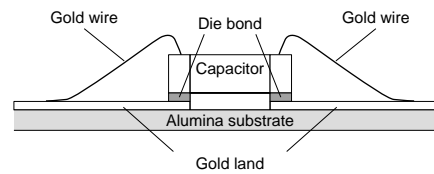
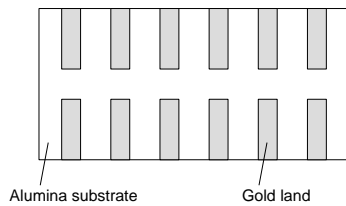
GMD Series Specifications and Test Methods (2)

☐ Continued from the preceding page.

When no "*" is added in PNs table, please refer to GMD Series Specifications and Test Methods (1).
 When "***" is added in PNs table, please refer to GMD Series Specifications and Test Methods (2).**

No.	Item	Specifications	Test Method	
13	High Temperature High Humidity (Steady)	Appearance	Apply the rated voltage for 500±12 hours at 40±2°C, in 90 to 95% humidity and set it for 24±2 hours at room temperature, then measure. The charge/discharge current is less than 50mA. • Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.	
		Capacitance Change		R6 : Within ±12.5%
		D.F.		R6 : 0.2 max.
		I.R.		More than 12.5Ω · F
14	Durability	Appearance	Apply 150%*2 of the rated voltage for 1000±12 hours at the maximum operating temperature ±3°C. Let sit for 24±2 hours at room temperature, then measure. The charge/ discharge current is less than 50mA. *2 GMD155 R6 1A 274 to 474 are applied to 120%. • Initial measurement Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature. Perform the initial measurement. • Measurement after test Perform a heat treatment at 150+0/-10°C for one hour and then let sit for 24±2 hours at room temperature, then measure.	
		Capacitance Change		R6 : Within ±12.5%
		D.F.		R6 : 0.2 max.
		I.R.		More than 25Ω · F

Mounting for testing: The capacitors should be mounted on the substrate as shown below using die bonding. when tests No. 11 to 14 are performed.



For General GRM Series

Array GMM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Package

Minimum Quantity Guide

Part Number	Dimensions (mm)			Quantity (pcs.)						
	L	W	T	ø180mm Reel		ø330mm Reel		Bulk Case	Bulk Bag	
Packaging Code				Paper Tape	Embossed Tape	Paper Tape	Embossed Tape	C	Bulk : B Tray : T	
For General Purpose	GRM02	0.4	0.2	0.2	-	40,000 ¹⁾	-	-	-	1,000
	GRM03	0.6	0.3	0.3	15,000	-	50,000	-	-	1,000
	GRM15	1.0	0.5	0.25/0.3	10,000	-	50,000	-	-	1,000
				0.5	10,000	-	50,000	-	50,000 ²⁾	1,000
	GRM18	1.6	0.8	0.5	4,000	-	10,000	-	-	1,000
				0.8	4,000	-	10,000	-	15,000 ²⁾	1,000
	GRM21	2.0	1.25	0.6	4,000	-	10,000	-	10,000	1,000
				0.85	4,000	-	10,000	-	-	1,000
	GRM31	3.2	1.6	1.0/1.25	-	3,000	-	10,000	5,000 ²⁾	1,000
				0.6/0.85	4,000	-	10,000	-	-	1,000
				1.15	-	3,000	-	10,000	-	1,000
	GRM32	3.2	2.5	1.6	-	2,000	-	6,000	-	1,000
				0.85	4,000	-	10,000	-	-	1,000
				1.15	-	3,000	-	10,000	-	1,000
				1.35	-	2,000	-	8,000	-	1,000
	GRM43	4.5	3.2	1.6	-	2,000	-	6,000	-	1,000
				1.8/2.0	-	1,000	-	4,000	-	1,000
				2.5	-	1,000	-	4,000	-	1,000
	GRM55	5.7	5.0	1.15	-	1,000	-	5,000	-	1,000
				1.35/1.6	-	1,000	-	4,000	-	1,000
1.8/2.0				-	500	-	2,000	-	500	
High Power Type	0.6	0.3	0.3	15,000	-	50,000	-	-	1,000	
			0.5	10,000	-	50,000	-	50,000	1,000	
			0.5	10,000	-	50,000	-	-	1,000	
High Frequency	QGM18	1.6	0.8	0.7/0.8	4,000	-	10,000	-	1,000	
	QGM21	2.0	1.25	0.85	4,000	-	10,000	-	1,000	
Microchip	QGM22	2.8	2.8	1.15	-	1,000	-	4,000	-	1,000
	GMA0D	0.38	0.38	0.3	-	-	-	-	400 ³⁾	
	GMA05	0.5	0.5	0.35	-	-	-	-	400 ³⁾	
	GMA08	0.8	0.8	0.5	-	-	-	-	400 ³⁾	
	GMD03	0.6	0.3	0.3	15,000	-	50,000	-	1,000	
Array	GMD15	1.0	0.5	0.5	10,000	-	50,000	-	1,000	
	GNM0M	0.9	0.6	0.45	10,000	-	50,000	-	1,000	
	GNM1M	1.37	1.0	0.5/0.6/0.8	4,000	-	10,000	-	1,000	
	GNM21	2.0	1.25	0.5/0.6/0.85	4,000	-	10,000	-	1,000	
Low ESL	LLL15	0.5	1.0	0.3	10,000 ⁴⁾	-	50,000 ⁴⁾	-	-	1,000
				0.3	-	4,000	-	10,000	-	1,000
	LLL18/LLR18	0.8	1.6	0.5	-	4,000	-	10,000	-	1,000
				0.5/0.6	-	4,000	-	10,000	-	1,000
	LLL21	1.25	2.0	0.85	-	3,000	-	10,000	-	1,000
				0.5/0.7	-	4,000	-	10,000	-	1,000
	LLL31	1.6	3.2	1.15	-	3,000	-	10,000	-	1,000
				0.5	-	4,000	-	10,000	-	1,000
	LLA18	1.6	0.8	0.5	-	4,000	-	10,000	-	1,000
				0.5	-	4,000	-	10,000	-	1,000
LLA21	2.0	1.25	0.85	-	3,000	-	10,000	-	1,000	
			0.5	-	4,000	-	10,000	-	1,000	
LLA31	3.2	1.6	0.85	-	3,000	-	10,000	-	1,000	
			1.15	-	3,000	-	10,000	-	1,000	
			0.5	-	4,000	-	10,000	-	1,000	
LLM21	2.0	1.25	0.5	-	4,000	-	10,000	-	1,000	
LLM31	3.2	1.6	0.5	-	4,000	-	10,000	-	1,000	

- 1) 4mm width, 1mm pitch Embossed Taping.
- 2) There are parts without bulk case packaging.
- 3) Tray
- 4) LLL15: ø180mm Reel Paper Taping Packaging Code: E, ø330mm Reel Paper Taping Packaging Code: F

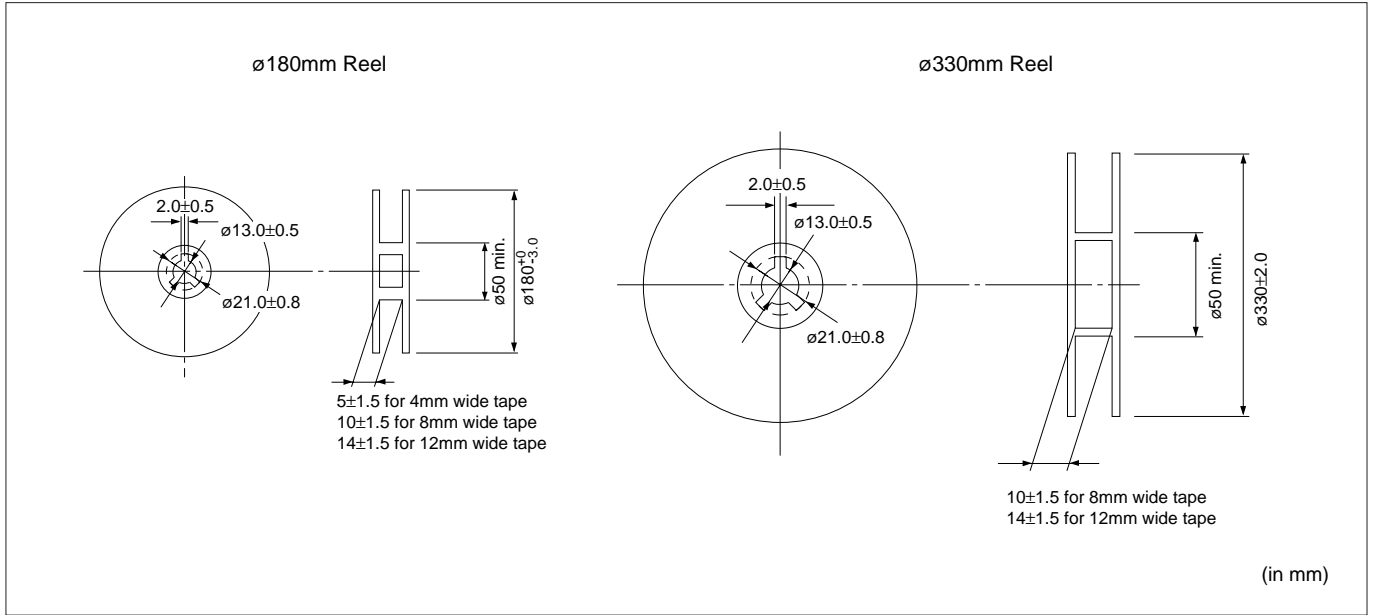
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Package

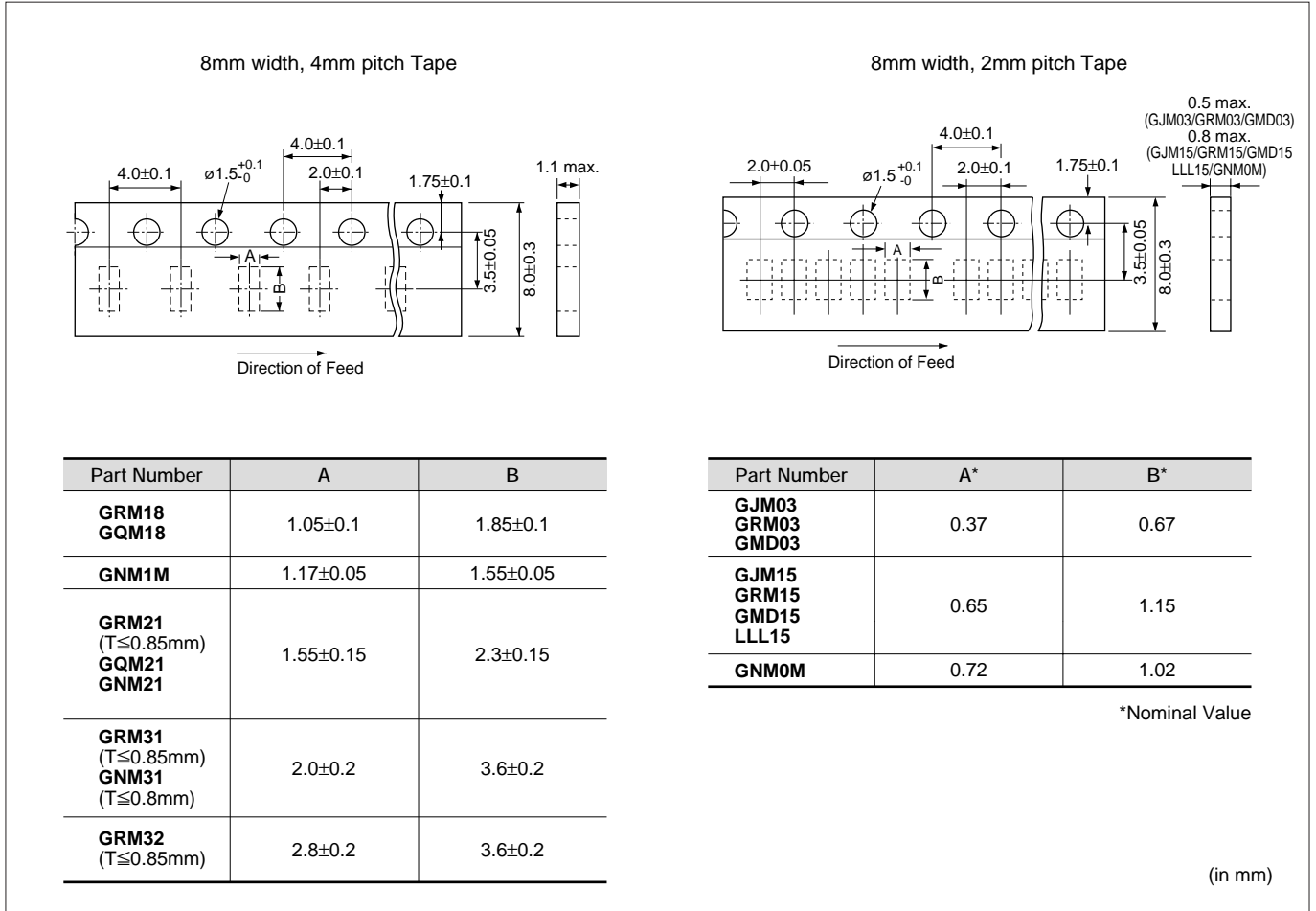
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■ Tape Carrier Packaging

(1) Dimensions of Reel



(2) Dimensions of Paper Tape



Continued on the following page. ↗

For General
GRM Series

Array
GNM Series

Low ESL
LLL Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

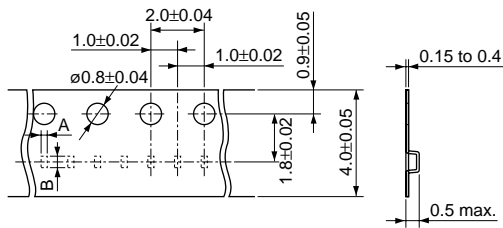
Product Information
Package

Package

Continued from the preceding page.

(3) Dimensions of Embossed Tape

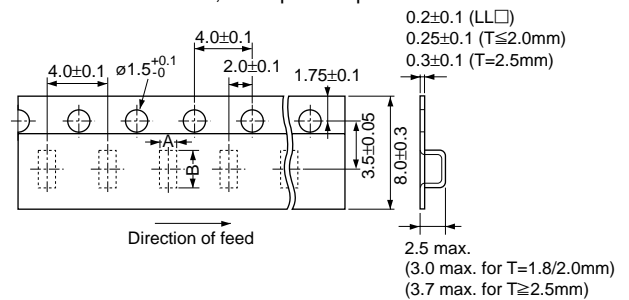
4mm width, 1mm pitch Tape



Part Number	A*	B*
GRM02	0.23	0.43

*Nominal Value

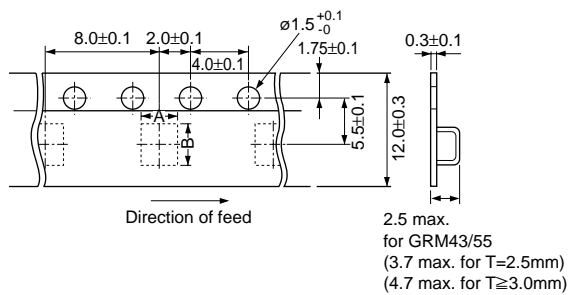
8mm width, 4mm pitch Tape



Part Number	A	B
LLL18, LLR18 LLA18	1.05±0.1	1.85±0.1
GRM21 (T≥1.0mm) LLL21 LLA21, LLM21	1.45±0.2	2.25±0.2
GRM31 (T≥1.15mm) LLL31 LLA31, LLM31 GJM31 (T≥1.0mm)	1.9±0.2	3.5±0.2
GRM32 (T≥1.0mm)	2.8±0.2	3.5±0.2
GQM22	2.8*	3.5*

*Nominal Value

12mm width, 8mm pitch Tape



Part Number	A*	B*
GRM43	3.6	4.9
GRM55	5.2	6.1

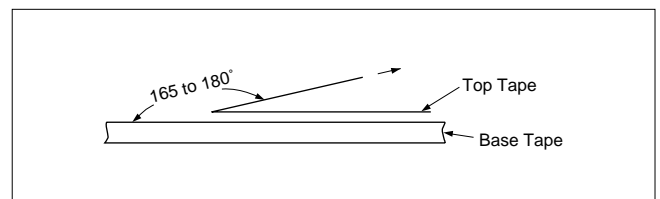
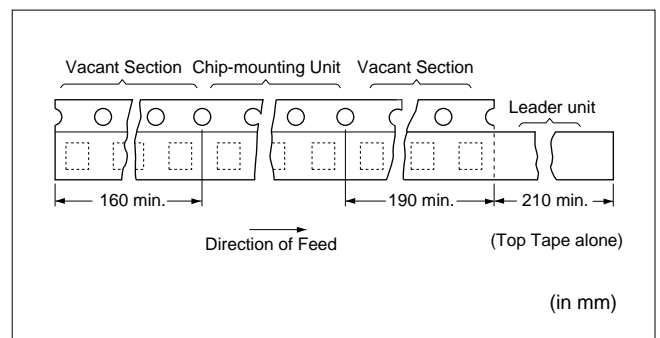
*Nominal Value

(in mm)

(4) Taping Method

- Tapes for capacitors are wound clockwise. The sprocket holes are to the right as the tape is pulled toward the user.
- Part of the leader and part of the empty tape should be attached to the end of the tape as follows.
- The top tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
- Missing capacitors number within 0.1% of the number per reel or 1 pc, whichever is greater, and are not continuous.
- The top tape and bottom tape should not protrude beyond the edges of the tape and should not cover sprocket holes.
- Cumulative tolerance of sprocket holes, 10 pitches: ±0.3mm.
- Peeling off force: 0.1 to 0.6N* in the direction shown at right.

*GRM02
GRM03
GJM03
GMD03
: 0.05 to 0.5N



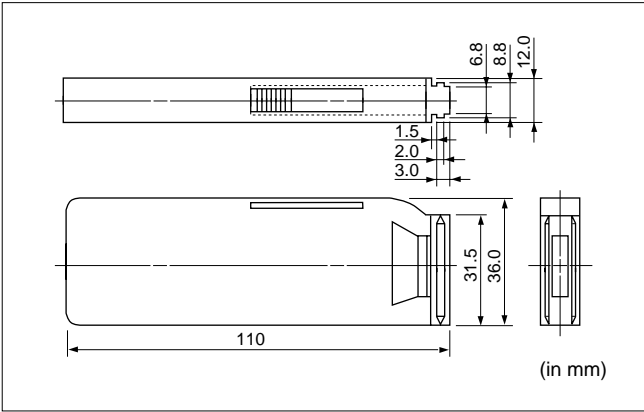
Continued on the following page.

Package

☐ Continued from the preceding page.

■ Dimensions of Bulk Case Packaging

The bulk case uses antistatic materials. Please contact Murata for details.



For General GRM Series
Array GNM Series
Low ESL LL□ Series
High-Q GJM Series
High Frequency GOM Series
Monolithic Microchip GMA Series
For Bonding GMD Series
Product Information Package

⚠Caution

■ Storage and Operation conditions

1. The performance of chip monolithic ceramic capacitors may be affected by the storage conditions.

1-1. Store capacitors in the following conditions:

Temperature of +5°C to +40°C and a Relative Humidity of 20% to 70%.

- (1) Sunlight, dust, rapid temperature changes, corrosive gas atmosphere or high temperature and humidity conditions during storage may affect the solderability and the packaging performance. Please use product within six months of receipt.
- (2) Please confirm solderability before using after six months. Store the capacitors without opening the original bag. Even if the storage period is short, do not exceed the specified atmospheric conditions.

- 1-2. Corrosive gas can react with the termination (external) electrodes or lead wires of capacitors, and result in poor solderability. Do not store the capacitors in an atmosphere consisting of corrosive gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas, etc.).
- 1-3. Due to moisture condensation caused by rapid humidity changes, or the photochemical change caused by direct sunlight on the terminal electrodes and/or the resin/epoxy coatings, the solderability and electrical performance may deteriorate. Do not store capacitors under direct sunlight or in high humidity conditions.

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information
⚠Caution



Rating

1. Temperature Dependent Characteristics

1. The electrical characteristics of the capacitor can change with temperature.

1-1. For capacitors having larger temperature dependency, the capacitance may change with temperature changes.

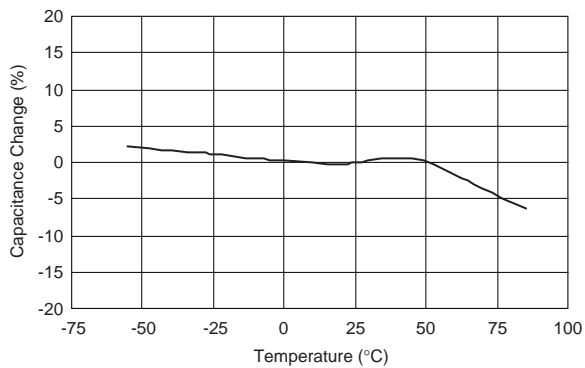
The following actions are recommended in order to ensure suitable capacitance values.

(1) Select a suitable capacitance for the operating temperature range.

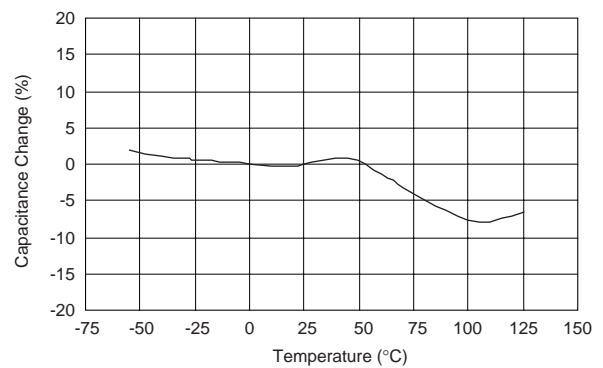
(2) The capacitance may change within the rated temperature.

When you use a high dielectric constant type capacitor in a circuit that needs a tight (narrow) capacitance tolerance. (e. g., a time constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. And check capacitors using your actual appliances at the intended environment and operating conditions.

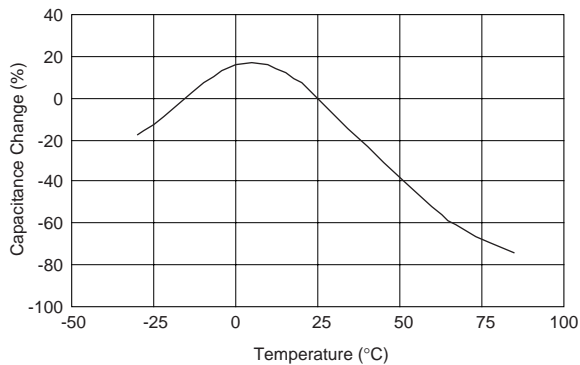
Typical Temperature Characteristics R6(X5R)



Typical Temperature Characteristics R7(X7R)



Typical Temperature Characteristics F5(Y5V)



2. Measurement of Capacitance

1. Measure capacitance with the voltage and the frequency specified in the product specifications.

1-1. The output voltage of the measuring equipment may decrease occasionally when capacitance is high. Please confirm whether a prescribed measured voltage is impressed to the capacitor.

1-2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in an AC circuit.

Continued on the following page.

⚠ Caution

☐ Continued from the preceding page.

3. Applied Voltage

1. Do not apply a voltage to the capacitor that exceeds the rated voltage as called out in the specifications.

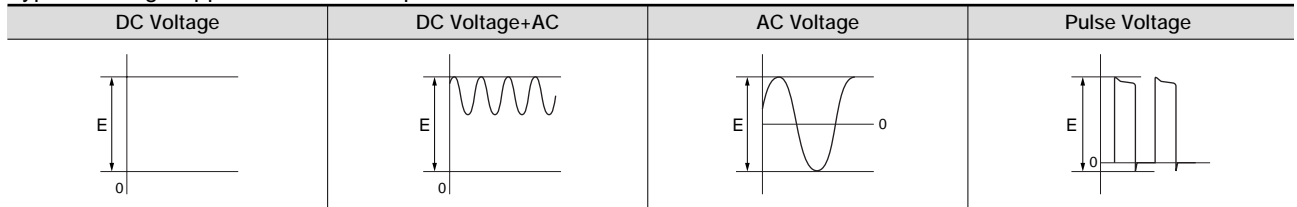
1-1. Applied voltage between the terminals of a capacitor shall be less than or equal to the rated voltage.

(1) When AC voltage is superimposed on DC voltage, the zero-to-peak voltage shall not exceed the rated DC voltage.

When AC voltage or pulse voltage is applied, the peak-to-peak voltage shall not exceed the rated DC voltage.

(2) Abnormal voltages (surge voltage, static electricity, pulse voltage, etc.) shall not exceed the rated DC voltage.

Typical Voltage Applied to the DC Capacitor



(E: Maximum possible applied voltage.)

1-2. Influence of overvoltage

Overvoltage that is applied to the capacitor may result in an electrical short circuit caused by the breakdown of the internal dielectric layers.

The time duration until breakdown depends on the applied voltage and the ambient temperature.

4. Applied Voltage and Self-heating Temperature

1. When the capacitor is used in a high-frequency voltage, pulse voltage, application, be sure to take into account self-heating may be caused by resistant factors of the capacitor.

1-1. The load should be contained to the level such that when measuring at atmospheric temperature of 25°C, the product's self-heating remains below 20°C and surface temperature of the capacitor in the actual circuit remains within the maximum operating temperature.

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5. DC Voltage and AC Voltage Characteristics

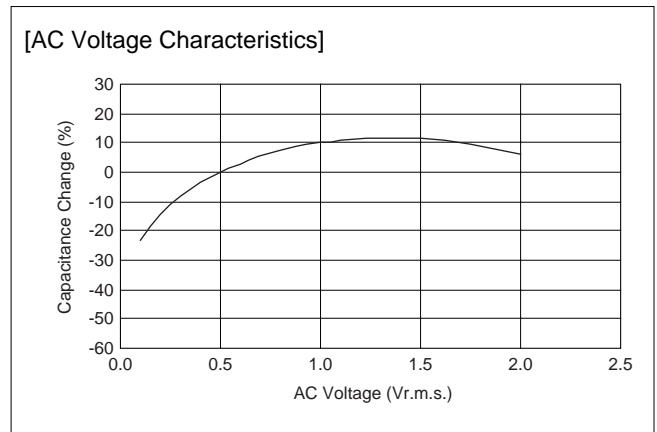
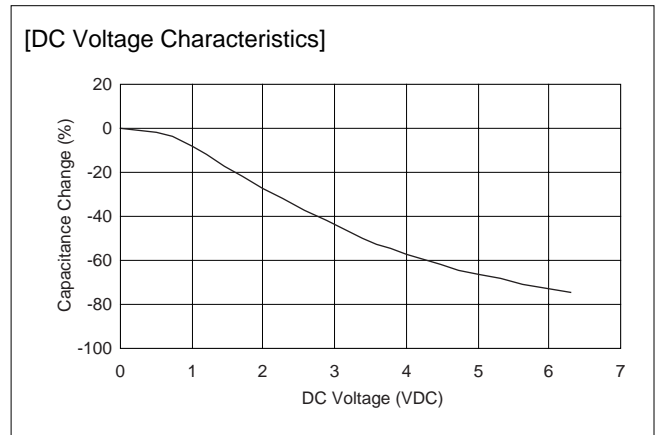
1. The capacitance value of a high dielectric constant type capacitor changes depending on the DC voltage applied. Please consider the DC voltage characteristics when a capacitor is selected for use in a DC circuit.

1-1. The capacitance of ceramic capacitors may change sharply depending on the applied voltage (see figure).

Please confirm the following in order to secure the capacitance.

- (1) Whether the capacitance change caused by the applied voltage is within the range allowed or not.
- (2) In the DC voltage characteristics, the rate of capacitance change becomes larger as voltage increases, even if the applied voltage is below the rated voltage. When a high dielectric constant type capacitor is in a circuit that needs a tight (narrow) capacitance tolerance (e. g., a time constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. In addition, check capacitors using your actual appliances at the intended environment and operating conditions.

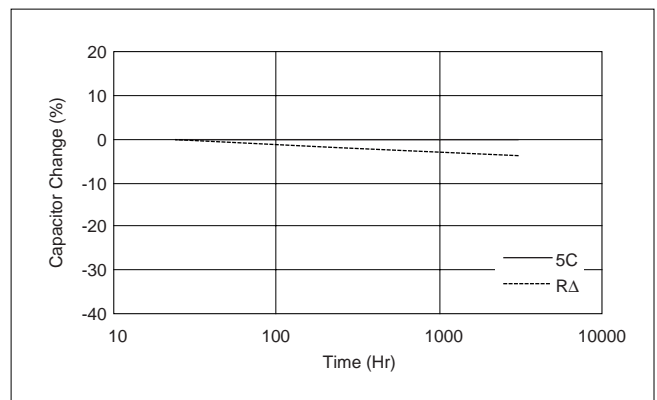
2. The capacitance values of high dielectric constant type capacitors change depending on the AC voltage applied. Please consider the AC voltage characteristics when selecting a capacitor to be used in an AC circuit.



6. Capacitance Aging

1. The high dielectric constant type capacitors have the characteristic in which the capacitance value decreases with passage of time.

When you use a high dielectric constant type capacitors in a circuit that needs a tight (narrow) capacitance tolerance (e. g., a time constant circuit), please carefully consider the characteristics of these capacitors, such as their aging, voltage, and temperature characteristics. In addition, check capacitors using your actual appliances at the intended environment and operating conditions.



Continued on the following page. ↗

For General GRM Series

Array GNM Series

Low ESL LL Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

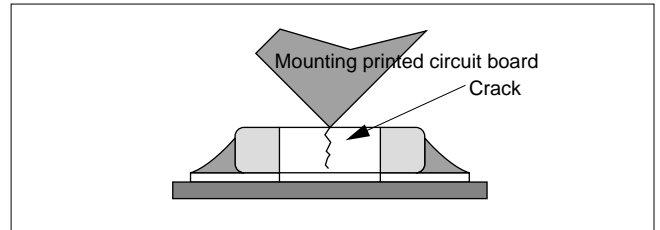
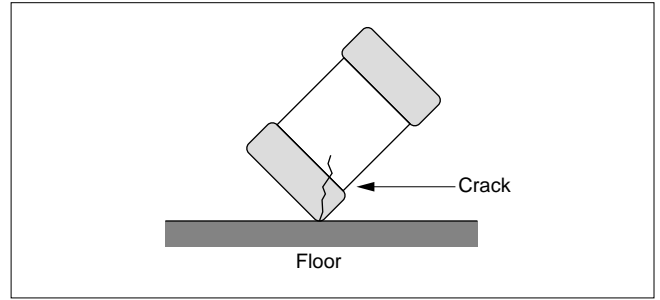
Product Information △Caution

⚠ Caution

☑ Continued from the preceding page.

7. Vibration and Shock

1. The capacitor's mechanical stress (vibration and shock) shall be specified for the use environment.
Please confirm the kind of vibration and/or shock, its condition, and any generation of resonance.
Please mount the capacitor so as not to generate resonance, and do not allow any impact on the terminals.
2. Mechanical shock due to being dropped may cause damage or a crack in the dielectric material of the capacitor.
Do not use a dropped capacitor because the quality and reliability may be deteriorated.
3. When printed circuit boards are piled up or handled, the corners of another printed circuit board should not be allowed to hit the capacitor, in order to avoid a crack or other damage to the capacitor.



For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

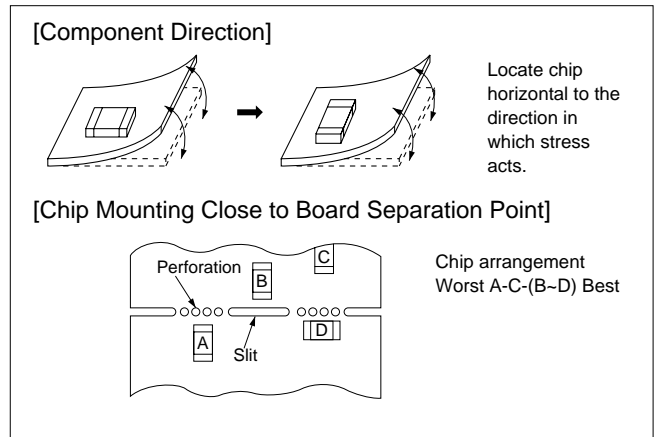
Product Information
⚠ Caution

Caution

Soldering and Mounting

1. Mounting Position

1. Confirm the best mounting position and direction that minimizes the stress imposed on the capacitor during flexing or bending the printed circuit board.
 - 1-1. Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.



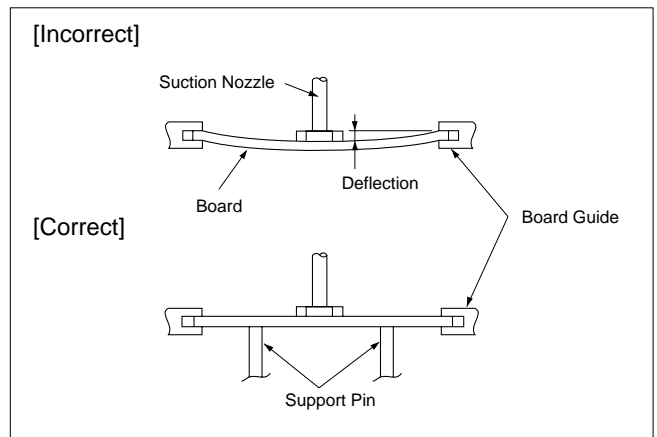
2. Information before Mounting

1. Do not reuse capacitors that were removed from the equipment.
2. Confirm capacitance characteristics under actual applied voltage.
3. Confirm the mechanical stress under actual process and equipment use.
4. Confirm the rated capacitance, rated voltage and other electrical characteristics before assembly.

5. Prior to use, confirm the solderability of capacitors that were in long-term storage.
6. Prior to measuring capacitance, carry out a heat treatment for capacitors that were in long-term storage.
7. The use of Sn-Zn based solder will deteriorate the reliability of the MLCC. Please contact our sales representative or product engineers on the use of Sn-Zn based solder in advance.

3. Maintenance of the Mounting (pick and place) Machine

1. Make sure that the following excessive forces are not applied to the capacitors.
 - 1-1. In mounting the capacitors on the printed circuit board, any bending force against them shall be kept to a minimum to prevent them from any bending damage or cracking. Please take into account the following precautions and recommendations for use in your process.
 - (1) Adjust the lowest position of the pickup nozzle so as not to bend the printed circuit board.
 - (2) Adjust the nozzle pressure within a static load of 1N to 3N during mounting.
2. Dirt particles and dust accumulated between the suction nozzle and the cylinder inner wall prevent the nozzle from moving smoothly. This imposes greater force upon the chip during mounting, causing cracked chips. Also the locating claw, when worn out, imposes uneven forces on the chip when positioning, causing cracked chips. The suction nozzle and the locating claw must be maintained, checked and replaced periodically.



Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

Caution

Continued from the preceding page.

4-1. Reflow Soldering

- When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB board. Preheating conditions are shown in table 1. It is required to keep the temperature differential between the solder and the component's surface (ΔT) as small as possible.
- Solderability of Tin plating termination chips might be deteriorated when a low temperature soldering profile where the peak solder temperature is below the melting point of Tin is used. Please confirm the Solderability of Tin plated termination chips before use.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and the solvent within the range shown in the table 1.

Table 1

Part Number	Temperature Differential
GRM02/03/15/18/21/31 GJM03/15 LLL15/18/21/31 LLR18 GQM18/21	$\Delta T \leq 190^\circ\text{C}$
GRM32/43/55 LLA18/21/31 LLM21/31 GNM GQM22	$\Delta T \leq 130^\circ\text{C}$

Recommended Conditions

	Pb-Sn Solder		Lead Free Solder
	Infrared Reflow	Vapor Reflow	
Peak Temperature	230 to 250°C	230 to 240°C	240 to 260°C
Atmosphere	Air	Air	Air or N ₂

Pb-Sn Solder: Sn-37Pb
 Lead Free Solder: Sn-3.0Ag-0.5Cu

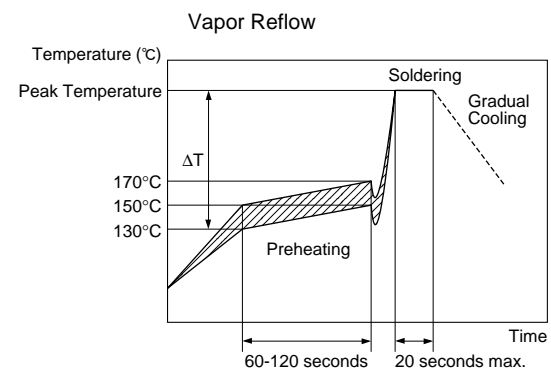
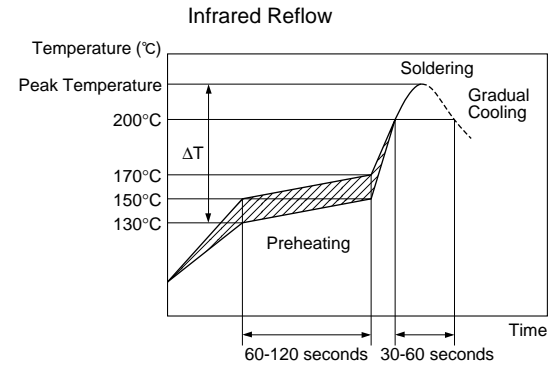
4. Optimum Solder Amount for Reflow Soldering

- Overly thick application of solder paste results in a excessive solder fillet height. This makes the chip more susceptible to mechanical and thermal stress on the board and may cause the chips to crack.
- Too little solder paste results in a lack of adhesive strength on the outer electrode, which may result in chips breaking loose from the PCB.
- Make sure the solder has been applied smoothly to the end surface to a height of 0.2mm* min.

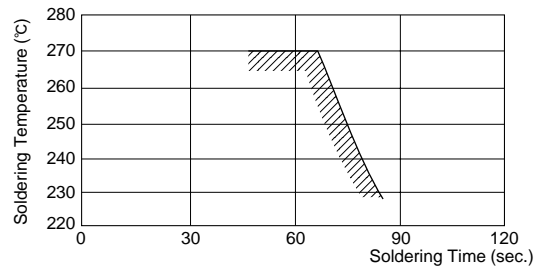
Inverting the PCB

Make sure not to impose any abnormal mechanical shocks to the PCB.

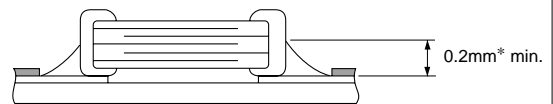
[Standard Conditions for Reflow Soldering]



[Allowable Reflow Soldering Temperature and Time]



In a case of repeated soldering, the accumulated soldering time must be within the range shown above.



* GRM02/03: 1/3 of Chip Thickness min.

in section

Caution

Continued from the preceding page.

4-2. Flow Soldering

- When sudden heat is applied to the components, the mechanical strength of the components will decrease because a sudden temperature change causes deformation inside the components. In order to prevent mechanical damage in the components, preheating should be required for both of the components and the PCB board.
Preheating conditions are shown in table 2. It is required to keep the temperature differential between the solder and the component's surface (ΔT) as small as possible.
- Excessively long soldering time or high soldering temperature can result in leaching of the outer electrodes, causing poor adhesion or a reduction in capacitance value due to loss of contact between electrodes and end termination.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and solvent within the range shown in the table 2.
- Do not apply flow soldering to chips not listed in table 2.

Table 2

Part Number	Temperature Differential
GRM18/21/31	$\Delta T \leq 150^\circ\text{C}$
LLL21/31	
GQM18/21	

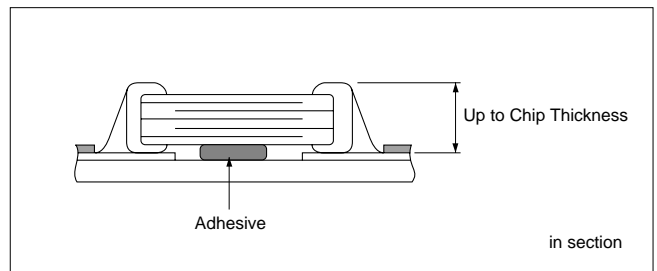
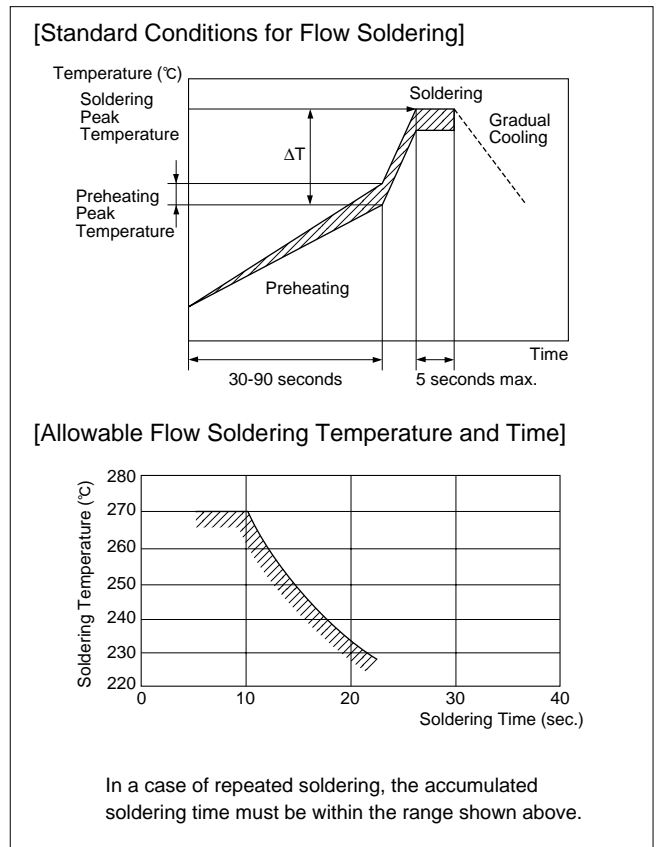
Recommended Conditions

	Pb-Sn Solder	Lead Free Solder
Preheating Peak Temperature	90 to 110°C	100 to 120°C
Soldering Peak Temperature	240 to 250°C	250 to 260°C
Atmosphere	Air	N ₂

Pb-Sn Solder: Sn-37Pb
Lead Free Solder: Sn-3.0Ag-0.5Cu

5. Optimum Solder Amount for Flow Soldering

- The top of the solder fillet should be lower than the thickness of components. If the solder amount is excessive, the risk of cracking is higher during board bending or any other stressful condition.



Continued on the following page.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information

⚠ Caution

☐ Continued from the preceding page.

4-3. Correction with a Soldering Iron

1. When sudden heat is applied to the components when using a soldering iron, the mechanical strength of the components will decrease because the extreme temperature change can cause deformations inside the components. In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB board. Preheating conditions, (The "Temperature of the Soldering Iron Tip", "Preheating Temperature", "Temperature Differential" between the iron tip and the components and the PCB), should be within the conditions of table 3. It is required to keep the temperature differential between the soldering iron and the component surfaces (ΔT) as small as possible.
2. After soldering, do not allow the component/PCB to rapidly cool down.
3. The operating time for the re-working should be as short as possible. When re-working time is too long, it may cause solder leaching, in turn causing a reduction in the adhesive strength of the terminations.
4. Optimum Solder amount when re-working with a Soldering Iron
 - 4-1. For sizes smaller than 0603, (GRM03/15/18, GJM03/15, GQM18), the top of the solder fillet should be lower than 2/3's of the thickness of the component or 0.5mm whichever is smaller. For 0805 and larger sizes, (GRM21/31/32/43/55, GQM21/22), the top of the solder fillet should be lower than 2/3's of the thickness of the component. If the solder amount is excessive, the risk of cracking is higher during board bending or under any other stressful condition.
 - 4-2. A soldering iron with a tip of $\phi 3\text{mm}$ or smaller should be used. It is also necessary to keep the soldering iron from touching the components during the re-work.
 - 4-3. Solder wire with $\phi 0.5\text{mm}$ or smaller is required for soldering.

4-4. Leaded Component Insertion

1. If the PCB is flexed when leaded components (such as transformers and ICs) are being mounted, chips may crack and solder joints may break.
Before mounting leaded components, support the PCB using backup pins or special jigs to prevent warping.

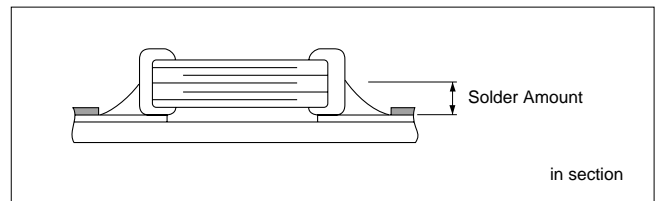
5. Washing

Excessive ultrasonic oscillation during cleaning can cause the PCBs to resonate, resulting in cracked chips or broken solder joints. Take note not to vibrate PCBs.

Table 3

Part Number	Temperature of Soldering Iron Tip	Preheating Temperature	Temperature Differential (ΔT)	Atmosphere
GRM03/15/18/21/31 GJM03/15 GQM18/21	350°C max.	150°C min.	$\Delta T \leq 190^\circ\text{C}$	Air
GRM32/43/55 GQM22	280°C max.	150°C min.	$\Delta T \leq 130^\circ\text{C}$	Air

*Applicable for both Pb-Sn and Lead Free Solder.
 Pb-Sn Solder: Sn-37Pb
 Lead Free Solder: Sn-3.0Ag-0.5Cu



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Caution

☐ Continued from the preceding page.

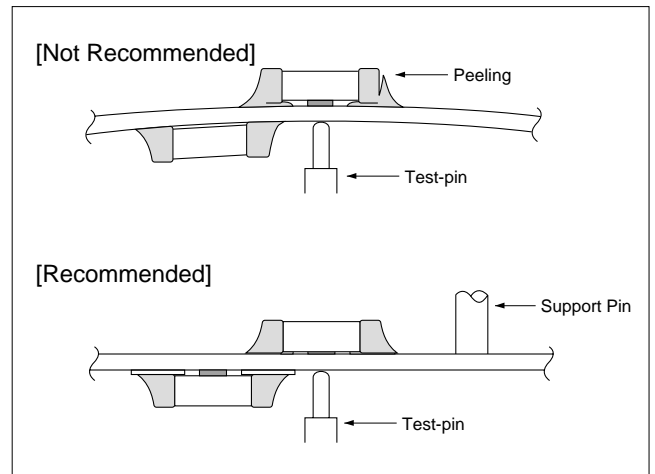
6. Electrical Test on Printed Circuit Board

1. Confirm position of the support pin or specific jig, when inspecting the electrical performance of a capacitor after mounting on the printed circuit board.

1-1. Avoid bending printed circuit board by the pressure of a test pin, etc.

The thrusting force of the test probe can flex the PCB, resulting in cracked chips or open solder joints. Provide support pins on the back side of the PCB to prevent warping or flexing.

1-2. Avoid vibration of the board by shock when a test pin contacts a printed circuit board.

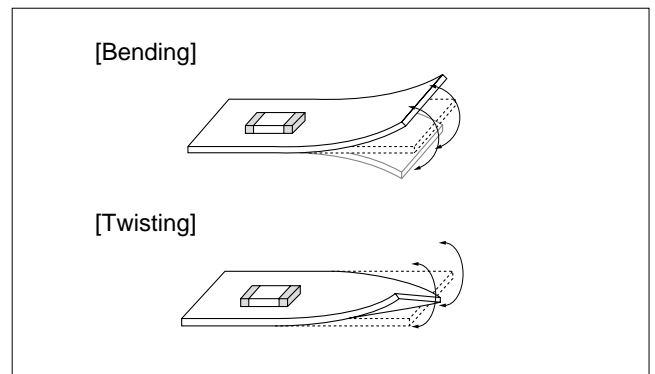


7. Printed Circuit Board Cropping

1. After mounting a capacitor on a printed circuit board, do not apply any stress to the capacitor that is caused by bending or twisting the board.

1-1. In cropping the board, the stress as shown right may cause the capacitor to crack.

Try not to apply this type of stress to a capacitor.



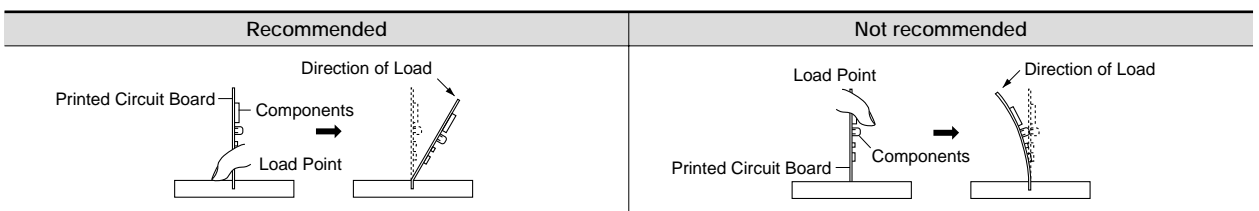
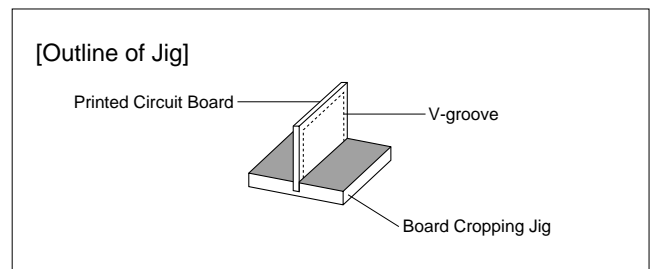
2. Ascertain of the cropping method for the printed circuit board in advance.

2-1. Printed circuit board cropping shall be carried out by using a jig or an apparatus to prevent the mechanical stress that can occur to the board.

(1) Example of a suitable jig

Recommended example: the board should be pushed as close to the cropping jig as possible and from the back side of board in order to minimize the compressive stress applied to capacitor.

Not recommended example: when the board is pushed at a point far from the cropping jig and from the front side of board as below, the capacitor may form a crack caused by the tensile stress applied to capacitor.



Continued on the following page. ☐

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information
△Caution

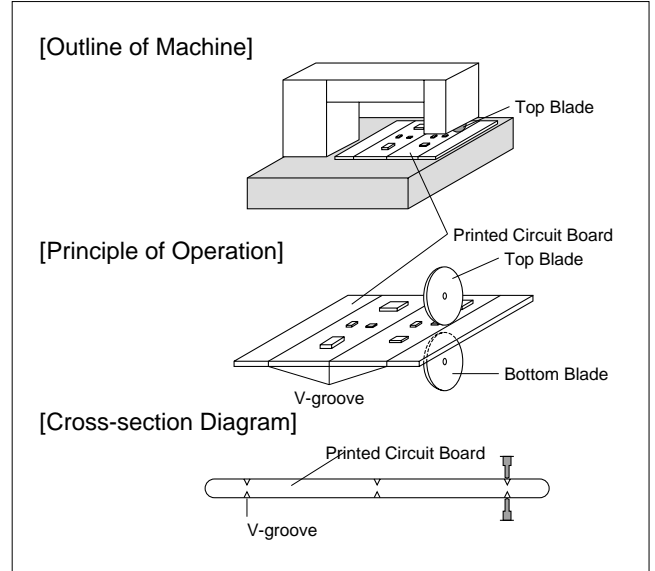
Caution

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(2) Example of a suitable machine

An outline of a printed circuit board cropping machine is shown as follows. Along the lines with the V-grooves on the printed circuit board, the top and bottom blades are aligned to one another when cropping the board.

The misalignment of the position between top and bottom blades may cause the capacitor to crack.



Recommended	Not Recommended		
	Top-bottom Misalignment	Left-right Misalignment	Front-rear Misalignment
<p>Top Blade</p> <p>Bottom Blade</p>	<p>Top Blade</p> <p>Bottom Blade</p>	<p>Top Blade</p> <p>Bottom Blade</p>	<p>Top Blade</p> <p>Bottom Blade</p>

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GQM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information
△Caution



■ Others

1. Under Operation of Equipment

- 1-1. Do not touch a capacitor directly with bare hands during operation in order to avoid the danger of an electric shock.
- 1-2. Do not allow the terminals of a capacitor to come in contact with any conductive objects (short-circuit). Do not expose a capacitor to a conductive liquid, including any acid or alkali solutions.
- 1-3. Confirm the environment in which the equipment will operate is under the specified conditions. Do not use the equipment under the following environments.
 - (1) Being splattered with water or oil.
 - (2) Being exposed to direct sunlight.
 - (3) Being exposed to Ozone, ultraviolet rays or radiation.
 - (4) Being exposed to toxic gas (e.g., hydrogen sulfide, sulfur dioxide, chlorine, ammonia gas, etc.)
 - (5) Any vibrations or mechanical shocks exceeding the specified limits.
 - (6) Moisture condensing environments.
- 1-4. Use damp proof countermeasures if using under any conditions that can cause condensation.

2. Others

- 2-1. In an Emergency
 - (1) If the equipment should generate smoke, fire or smell, immediately turn off or unplug the equipment.

If the equipment is not turned off or unplugged, the hazards may be worsened by supplying continuous power.

- (2) In this type of situation, do not allow face and hands to come in contact with the capacitor or burns may be caused by the capacitor's high temperature.

2-2. Disposal of Waste

When capacitors are disposed, they must be burned or buried by an industrial waste vendor with the appropriate licenses.

2-3. Circuit Design

GRM, GCM, GMA/D, LLL/A/M, GQM, GJM, GNM Series capacitors in this catalog are not safety certified products.

2-4. Remarks

Failure to follow the cautions may result, worst case, in a short circuit and smoking when the product is used.
 The above notices are for standard applications and conditions. Contact us when the products are used in special mounting conditions.
 Select optimum conditions for operation as they determine the reliability of the product after assembly.
 The data herein are given in typical values, not guaranteed ratings.

For General GRM Series

Array GNM Series

Low ESL LL□ Series

High-Q GJM Series

High Frequency GOM Series

Monolithic Microchip GMA Series

For Bonding GMD Series

Product Information
△Caution

Notice

■ Rating

1. Operating Temperature

1. The operating temperature limit depends on the capacitor.

- 1-1. Do not apply temperatures exceeding the upper operating temperature.

It is necessary to select a capacitor with a suitable rated temperature that will cover the operating temperature range.

Also it is necessary to consider the temperature distribution in equipment and the seasonal temperature variable factor.

- 1-2. Consider the self-heating of the capacitor.

The surface temperature of the capacitor shall be the upper operating temperature or less when including the self-heating factors.

2. Atmosphere Surroundings (gaseous and liquid)

1. Restriction on the operating environment of capacitors.

- 1-1. Capacitors, when used in the above, unsuitable, operating environments may deteriorate due to the corrosion of the terminations and the penetration of moisture into the capacitor.

- 1-2. The same phenomenon as the above may occur when the electrodes or terminals of the capacitor are subject to moisture condensation.

- 1-3. The deterioration of characteristics and insulation resistance due to the oxidization or corrosion of terminal electrodes may result in breakdown when the capacitor is exposed to corrosive or volatile gases or solvents for long periods of time.

3. Piezo-electric Phenomenon

1. When using high dielectric constant type capacitors in AC or pulse circuits, the capacitor itself vibrates at specific frequencies and noise may be generated. Moreover, when the mechanical vibration or shock is added to the capacitor, noise may occur.

Notice

■ Soldering and Mounting

1. PCB Design

1. Notice for Pattern Forms

- 1-1. Unlike leaded components, chip components are susceptible to flexing stresses since they are mounted directly on the substrate. They are also more sensitive to mechanical and thermal stresses than leaded components. Excess solder fillet height can multiply these stresses and cause chip cracking. When designing substrates, take land patterns and dimensions into consideration to eliminate the possibility of excess solder fillet height.
- 1-2. It is possible for the chip to crack by the expansion and shrinkage of a metal board. Please contact us if you want to use our ceramic capacitors on a metal board such as Aluminum.

Pattern Forms

	Prohibited	Correct
Placing Close to Chassis		
Placing of Chip Components and Leaded Components		
Placing of Leaded Components after Chip Component		
Lateral Mounting		

Continued on the following page.

For General GRM Series

Array GNM Series

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Product Information Notice

Notice

☐ Continued from the preceding page.

2. Land Dimensions

2-1. A chip capacitor can be cracked due to the stress of PCB bending / etc if the land area is larger than needed and has an excess amount of solder. Please refer to the land dimensions in table 1 for flow soldering, table 2 for reflow soldering, table 3 for GNM & LLA, and table 4 for LLM. Please confirm the suitable land dimension by evaluating the actual SET / PCB.

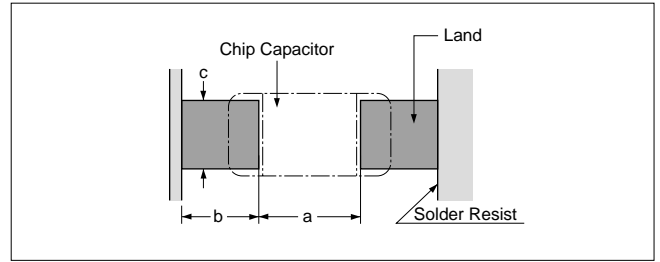


Table 1 Flow Soldering Method

Part Number	Dimensions	Chip (L×W)	a	b	c
GRM18 GQM18		1.6×0.8	0.6 to 1.0	0.8 to 0.9	0.6 to 0.8
GRM21 GQM21		2.0×1.25	1.0 to 1.2	0.9 to 1.0	0.8 to 1.1
GRM31		3.2×1.6	2.2 to 2.6	1.0 to 1.1	1.0 to 1.4
LLL21		1.25×2.0	0.4 to 0.7	0.5 to 0.7	1.4 to 1.8
LLL31		1.6×3.2	0.6 to 1.0	0.8 to 0.9	2.6 to 2.8

(in mm)

Table 2 Reflow Soldering Method

Part Number	Dimensions	Chip (L×W)	a	b	c
GRM02		0.4×0.2	0.16 to 0.2	0.12 to 0.18	0.2 to 0.23
GRM03 GJM03		0.6×0.3	0.2 to 0.3	0.2 to 0.35	0.2 to 0.4
GRM15 GJM15		1.0×0.5	0.3 to 0.5	0.35 to 0.45	0.4 to 0.6
GRM18 GQM18		1.6×0.8	0.6 to 0.8	0.6 to 0.7	0.6 to 0.8
GRM21 GQM21		2.0×1.25	1.0 to 1.2	0.6 to 0.7	0.8 to 1.1
GRM31		3.2×1.6	2.2 to 2.4	0.8 to 0.9	1.0 to 1.4
GRM32		3.2×2.5	2.0 to 2.4	1.0 to 1.2	1.8 to 2.3
GRM43		4.5×3.2	3.0 to 3.5	1.2 to 1.4	2.3 to 3.0
GRM55		5.7×5.0	4.0 to 4.6	1.4 to 1.6	3.5 to 4.8
LLL15		0.5×1.0	0.15 to 0.2	0.2 to 0.25	0.7 to 1.0
LLL18 LLR18		0.8×1.6	0.2 to 0.3	0.3 to 0.4	1.4 to 1.6
LLL21		1.25×2.0	0.4 to 0.6	0.4 to 0.5	1.4 to 1.8
LLL31		1.6×3.2	0.6 to 0.8	0.6 to 0.7	2.6 to 2.8
GQM22		3.2×2.5	2.2 to 2.5	0.8 to 1.0	1.9 to 2.3

(in mm)

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Notice

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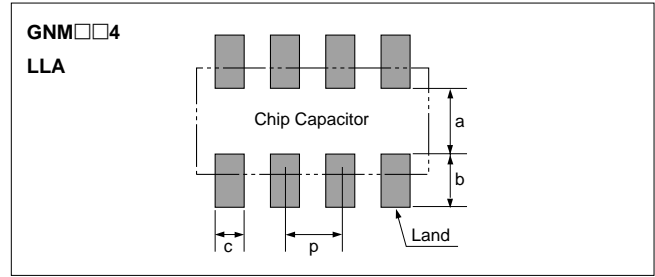
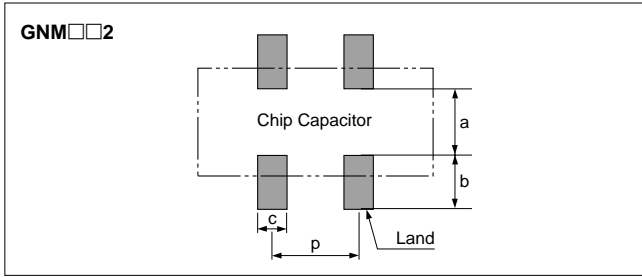


Table 3 GNM, LLA Series for Reflow Soldering Land Dimensions

Part Number	Dimensions (mm)					
	L	W	a	b	c	p
GNM0M2	0.9	0.6	0.12 to 0.20*	0.35 to 0.40*	0.3	0.45
GNM1M2	1.37	1.0	0.4 to 0.5	0.35 to 0.45	0.3 to 0.35	0.64
GNM212	2.0	1.25	0.6 to 0.7	0.5 to 0.7	0.4 to 0.5	1.0
GNM214	2.0	1.25	0.6 to 0.7	0.5 to 0.7	0.25 to 0.35	0.5
GNM314	3.2	1.6	0.8 to 1.0	0.7 to 0.9	0.3 to 0.4	0.8
LLA18	1.6	0.8	0.3 to 0.4	0.25 to 0.35	0.15 to 0.25	0.4
LLA21	2.0	1.25	0.5 to 0.7	0.35 to 0.6	0.2 to 0.3	0.5
LLA31	3.2	1.6	0.7 to 0.9	0.4 to 0.7	0.3 to 0.4	0.8

* $0.82 \leq a+2b \leq 1.00$

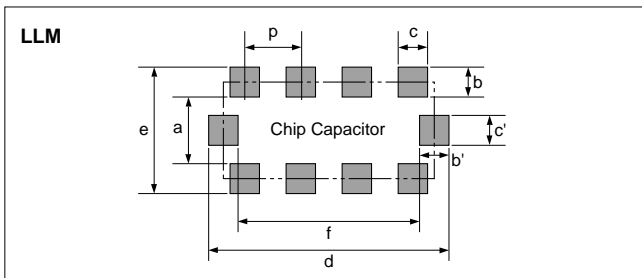


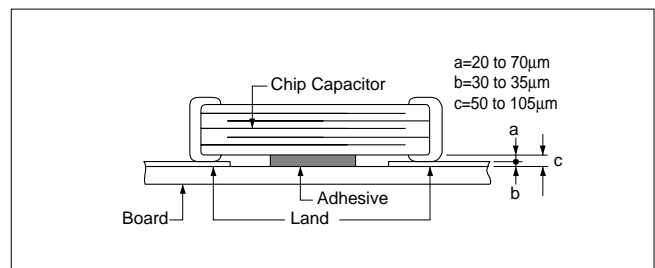
Table 4 LLM Series for Reflow Soldering Land Dimensions

Part Number	Dimensions (mm)						
	a	b, b'	c, c'	d	e	f	p
LLM21	0.6 to 0.8	(0.3 to 0.5)	0.3	2.0 to 2.6	1.3 to 1.8	1.4 to 1.6	0.5
LLM31	1.0	(0.3 to 0.5)	0.4	3.2 to 3.6	1.6 to 2.0	2.6	0.8

$b=(c-e)/2, b'=(d-f)/2$

2. Adhesive Application

- Thin or insufficient adhesive can cause the chips to loosen or become disconnected during flow soldering. The amount of adhesive must be more than dimension c, shown in the drawing at right, to obtain the correct bonding strength. The chip's electrode thickness and land thickness must also be taken into consideration.
- Low viscosity adhesive can cause chips to slip after mounting. The adhesive must have a viscosity of 5000Pa · s (500ps) min. (at 25°C).



3. Adhesive Coverage

Part Number	Adhesive Coverage*
GRM18, GQM18	0.05mg min.
GRM21, LLL21, GQM21	0.1mg min.
GRM31, LLL31	0.15mg min.

*Nominal Value

Continued on the following page.

Notice

☐ Continued from the preceding page.

3. Adhesive Curing

1. Insufficient curing of the adhesive can cause chips to disconnect during flow soldering and deterioration in the insulation resistance between the outer electrodes due to moisture absorption.

Control curing temperature and time in order to prevent insufficient hardening.

4. Flux Application

1. An excessive amount of flux generates a large quantity of flux gas, which can cause a deterioration of Solderability. Therefore apply flux thinly and evenly throughout. (A foaming system is generally used for flow soldering.)
2. Flux containing too high a percentage of halide may cause corrosion of the outer electrodes unless there is sufficient cleaning. Use flux with a halide content of 0.2% max.

3. Do not use strong acidic flux.

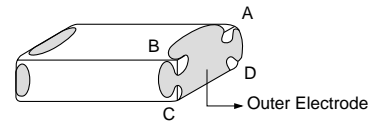
4. Do not use water-soluble *flux.

(*Water-soluble flux can be defined as non rosin type flux including wash-type flux and non-wash-type flux.)

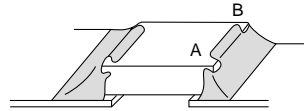
5. Flow Soldering

- Set temperature and time to ensure that leaching of the outer electrode does not exceed 25% of the chip end area as a single chip (full length of the edge A-B-C-D shown right) and 25% of the length A-B shown below as mounted on substrate.

[As a Single Chip]



[As Mounted on Substrate]



6. Washing

1. Please evaluate a capacitor by actual cleaning equipment and conditions to confirm the quality and select the applicable solvent.
2. Unsuitable cleaning solvent may leave residual flux or other foreign substances, causing deterioration of electrical characteristics and the reliability of the

capacitors.

3. Select the proper cleaning conditions.

- 3-1. Improper cleaning conditions (excessive or insufficient) may result in the deterioration of the performance of the capacitors.

Continued on the following page. ☐

Notice

☐ Continued from the preceding page.

7. Coating

1. A crack may be caused in the capacitor due to the stress of the thermal contraction of the resin during curing process.

The stress is affected by the amount of resin and curing contraction.

Select a resin with small curing contraction.

The difference in the thermal expansion coefficient between a coating resin or a molding resin and the capacitor may cause the destruction and deterioration of the capacitor such as a crack or peeling, and lead to the deterioration of insulation resistance or dielectric breakdown.

Select a resin for which the thermal expansion coefficient is as close to that of capacitor as possible.

A silicone resin can be used as an under-coating to buffer against the stress.

2. Select a resin that is less hygroscopic.

Using hygroscopic resins under high humidity conditions may cause the deterioration of the insulation resistance of a capacitor.

An epoxy resin can be used as a less hygroscopic resin.

8. Die Bonding/Wire Bonding (GMA or GMD Series)

1. Die Bonding of Capacitors

- Use the following materials for the Brazing alloys:
Au-Sn (80/20) 300 to 320 °C in N₂ atmosphere

- Mounting

- (1) Control the temperature of the substrate so it matches the temperature of the brazing alloy.
- (2) Place the brazing alloy on the substrate and place the capacitor on the alloy. Hold the capacitor and gently apply the load. Be sure to complete the operation within 1 minute.

2. Wire Bonding

- Wire

Gold wire: 25 micro m (0.001 inch) diameter

- Bonding

- (1) Thermo compression, ultrasonic ball bonding.
- (2) Required stage temperature: 150 to 200 °C
- (3) Required wedge or capillary weight: 0.2N to 0.5N
- (4) Bond the capacitor and base substrate or other devices with gold wire.

For General
GRM Series

Array
GNM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information
Notice

Notice

■ Others

1. Transportation

1. The performance of a capacitor may be affected by the conditions during transportation.

1-1. The capacitors shall be protected against excessive temperature, humidity and mechanical force during transportation.

(1) Climatic condition

- low air temperature: -40°C
- change of temperature air/air: -25°C/+25°C
- low air pressure: 30 kPa
- change of air pressure: 6 kPa/min.

(2) Mechanical condition

Transportation shall be done in such a way that the boxes are not deformed and forces are not directly passed on to the inner packaging.

1-2. Do not apply excessive vibration, shock, and pressure to the capacitor.

- (1) When excessive mechanical shock or pressure is applied to a capacitor, chipping or cracking may occur in the ceramic body of the capacitor.
- (2) When the sharp edge of an air driver, a soldering iron, tweezers, a chassis, etc. impacts strongly on the surface of capacitor, the capacitor may crack and short-circuit.

1-3. Do not use a capacitor to which excessive shock was applied by dropping, etc.

The capacitor dropped accidentally during processing may be damaged.

Reference Data

1. Solderability

(1) Test Method

Subject the chip capacitor to the following conditions.
 Then apply flux (an ethanol solution of 25% rosin) to the chip and dip it in 230°C eutectic solder for 2 seconds.

Conditions:

Expose prepared at room temperature (for 6 months and 12 months, respectively)

Prepared at high temperature (for 100 hours at 85°C)

Prepared left at high humidity (for 100 hours under 90%RH to 95%RH at 40°C)

(2) Test Samples

GRM21 : Products for flow/reflow soldering.

(3) Acceptance Criteria

With a 60-power optical microscope, measure the surface area of the outer electrode that is covered with solder.

(4) Results

Refer to Table 1.

Table 1

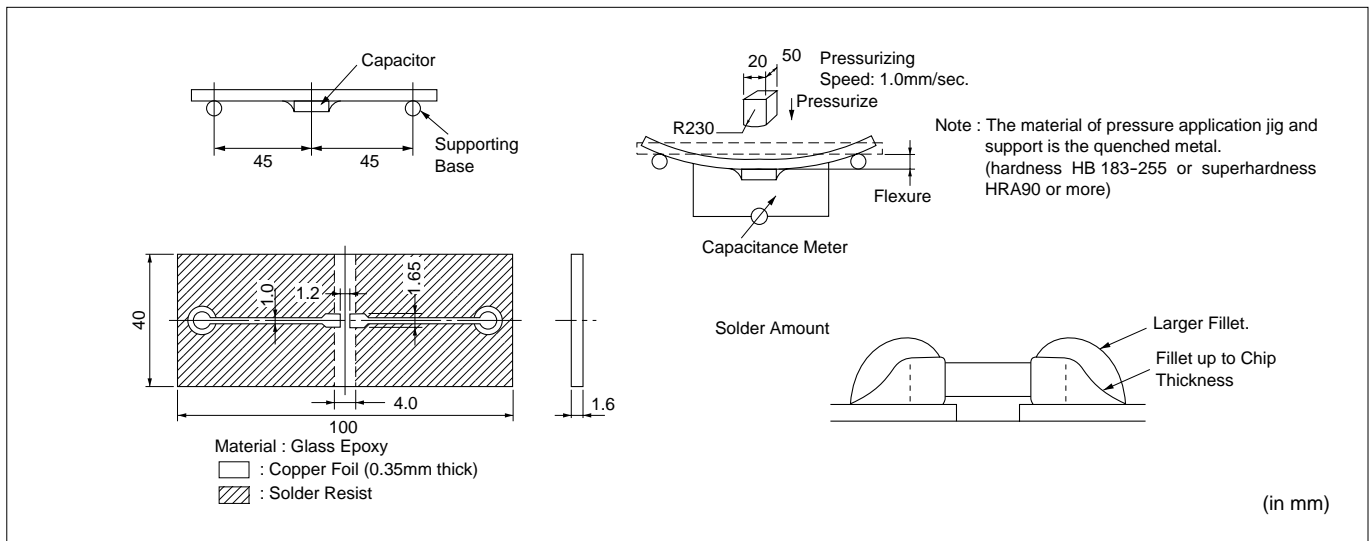
Sample	Initial State	Prepared at Room Temperature		Prepared at High Temperature for 100 Hours at 85°C	Prepared at High Humidity for 100 Hours at 90 to 95% RH and 40°C
		6 months	12 months		
GRM21 for flow/reflow soldering	95 to 100%	95 to 100%	95%	90 to 95%	95%

2. Board Bending Strength for Solder Fillet Height

(1) Test Method

Solder the chip capacitor to the test PCB with the amount of solder paste necessary to achieve the fillet heights.

Then bend the PCB using the method illustrated and measure capacitance.



(2) Test Samples

GRM21: 5C/R7/F5 Characteristics T=0.6mm

(3) Acceptance Criteria

Products should be determined to be defective if the change in capacitance has exceeded the values specified in Table 2.

Table 2

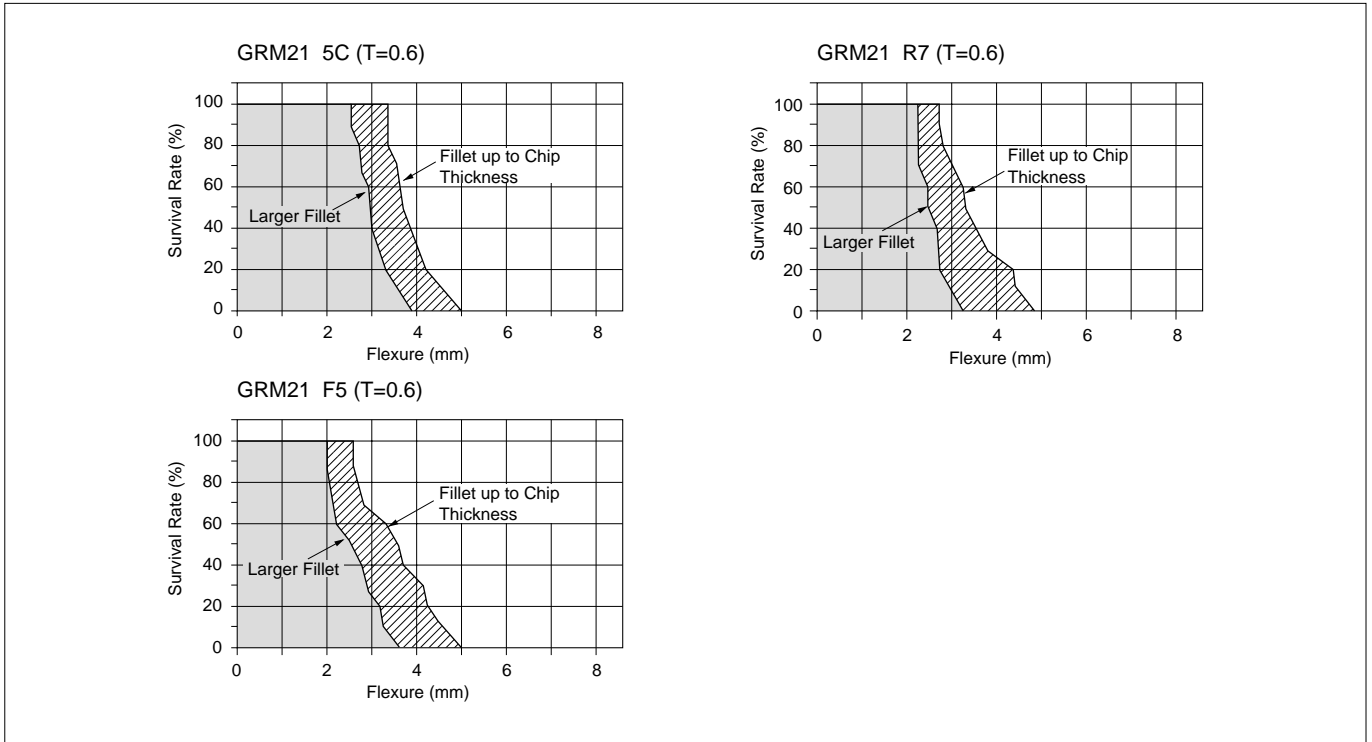
Characteristics	Change in Capacitance
5C	Within $\pm 5\%$ or $\pm 0.5\text{pF}$, whichever is greater
R7	Within $\pm 12.5\%$
F5	Within $\pm 20\%$

Continued on the following page. ↗

Reference Data

☐ Continued from the preceding page.

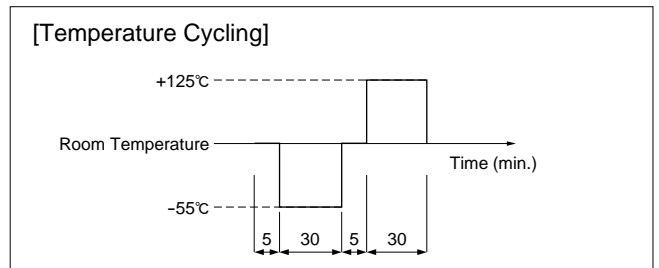
(4) Results



3. Temperature Cycling for Solder Fillet Height

(1) Test Method

Solder the chips to the substrate of various test fixtures using sufficient amounts of solder to achieve the required fillet height. Then subject the fixtures to the cycle illustrated at right 200 times.



① Solder Amount

Alumina substrates are typically designed for reflow soldering.

Glass epoxy or paper phenol substrates are typically used for flow soldering.

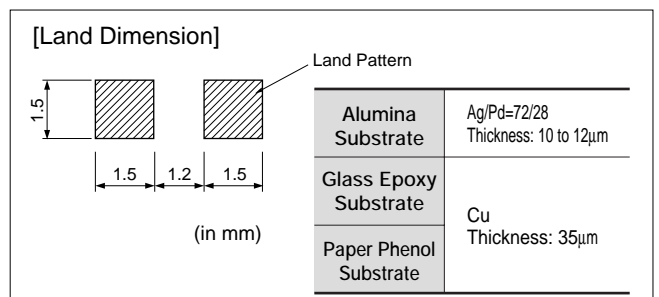
② Material

Alumina (Thickness: 0.64mm)
 Glass epoxy (Thickness: 1.64mm)
 Paper phenol (Thickness: 1.64mm)

[Solder Amount]

Substrate		Alumina	Glass Epoxy or Paper Phenol
Solder Amount	①		
	②		
	③		
Solder to be used		6X4 Eutectic solder	

③ Land Dimension



Continued on the following page. ↗

Reference Data

Continued from the preceding page.

(2) Test Samples

GRM21 5C/R7/F5 Characteristics T=0.6mm

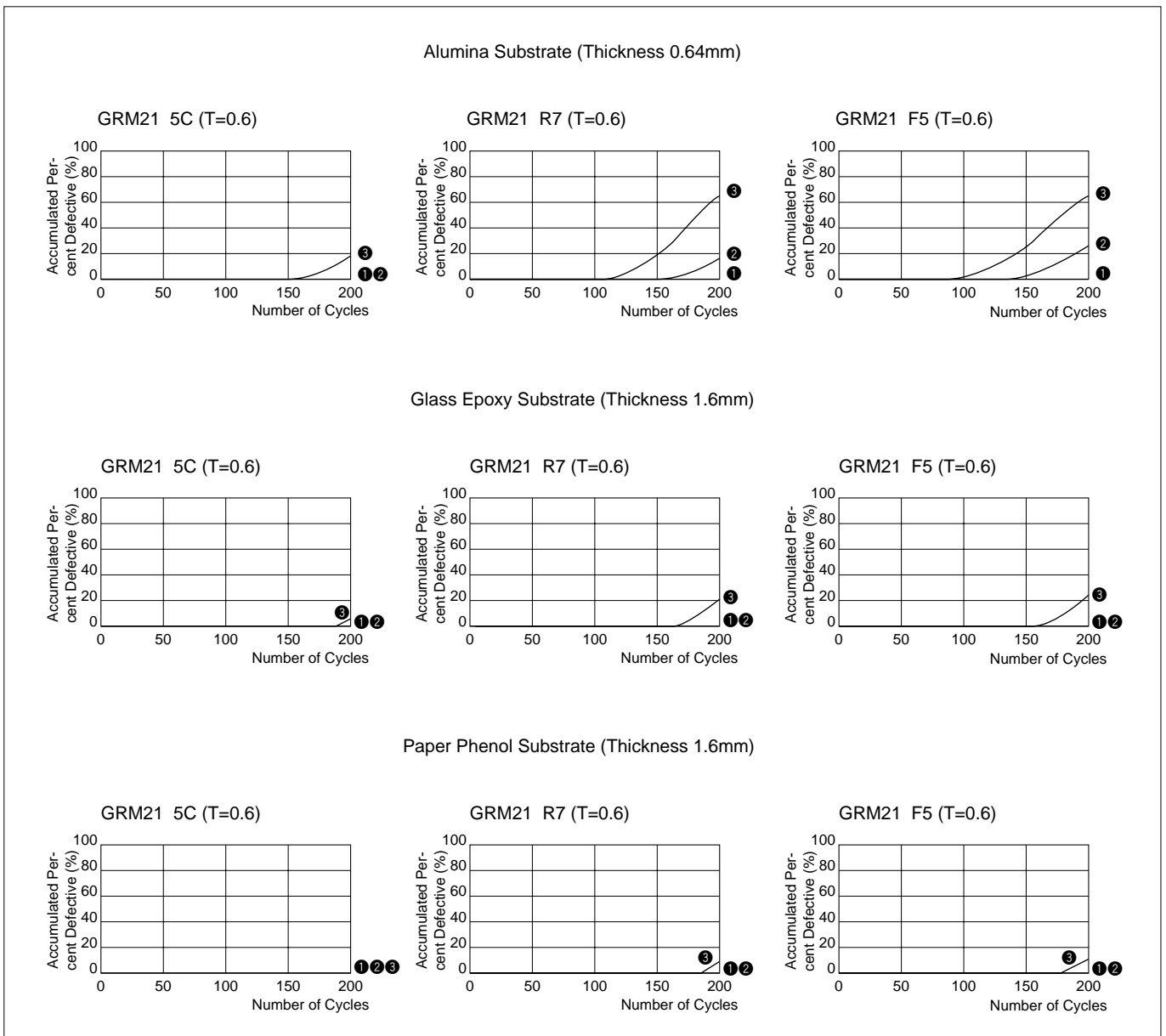
(3) Acceptance Criteria

Products are determined to be defective if the change in capacitance has exceeded the values specified in Table 3.

Table 3

Characteristics	Change in Capacitance
5C	Within $\pm 2.5\%$ or $\pm 0.25\text{pF}$, whichever is greater
R7	Within $\pm 7.5\%$
F5	Within $\pm 20\%$

(4) Results



Continued on the following page.

For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information
Reference Data

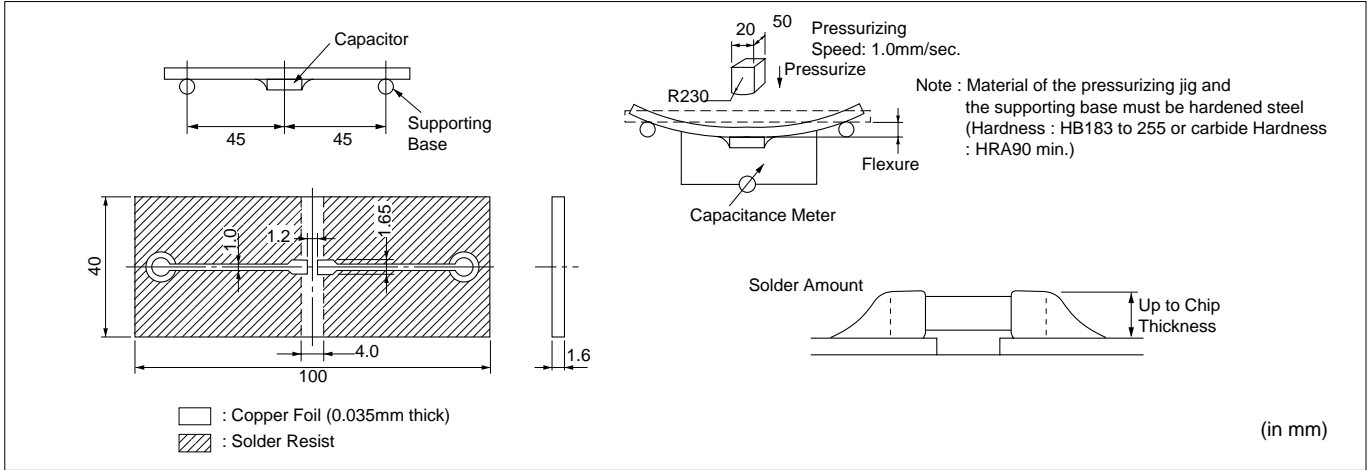
Reference Data

☐ Continued from the preceding page.

4. Board Bending Strength for Board Material

(1) Test Method

Solder the chip to the test board. Then bend the board using the method illustrated below, to measure capacitance.



(2) Test Samples

GRM21 5C/R7/F5 Characteristics T=0.6mm typical

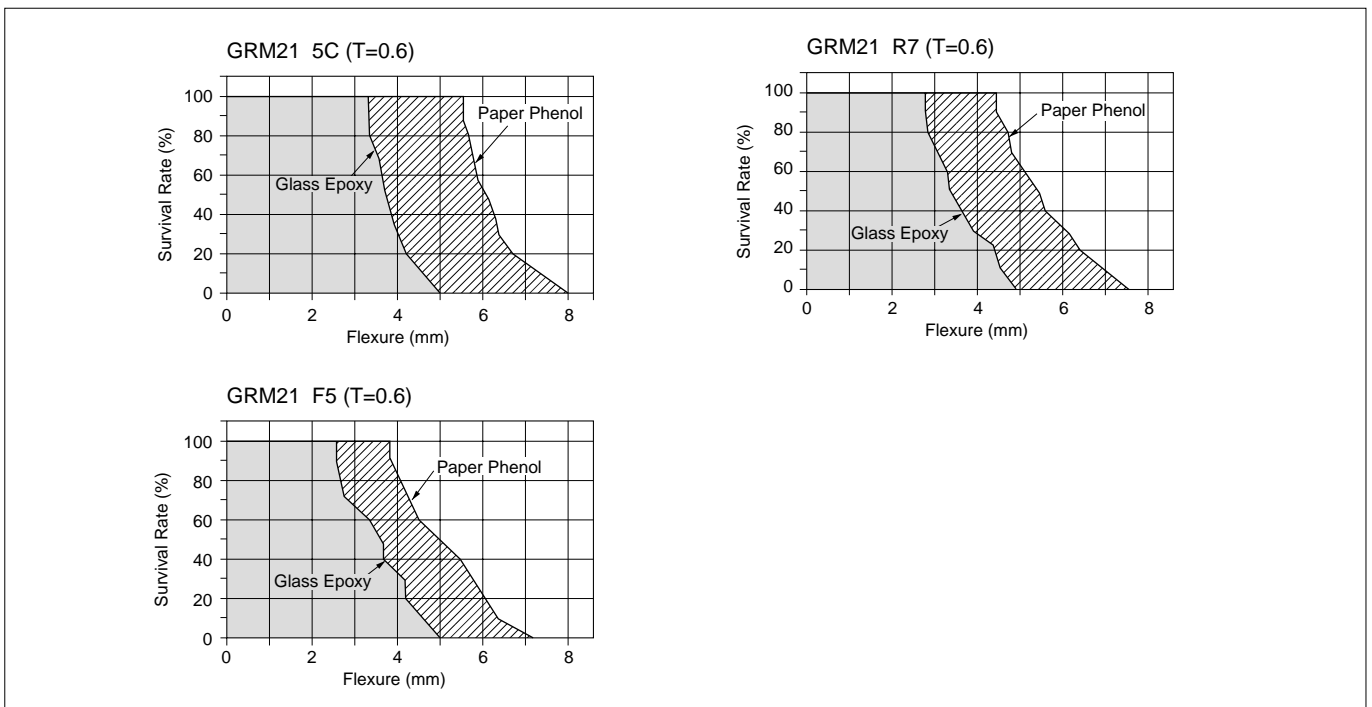
(3) Acceptance Criteria

Products should be determined to be defective if the change in capacitance has exceeded the values specified in Table 4.

Table 4

Characteristics	Change in Capacitance
5C	Within $\pm 5\%$ or $\pm 0.5\text{pF}$, whichever is greater
R7	Within $\pm 12.5\%$
F5	Within $\pm 20\%$

(4) Results



Continued on the following page. ↗

Reference Data

☐ Continued from the preceding page.

5. Break Strength

(1) Test Method

Place the chip on a steel plate as illustrated on the right. Increase load applied to a point near the center of the test sample.

(2) Test Samples

GRM21 5C/R7/F5 Characteristics
GRM31 5C/R7/F5 Characteristics

(3) Acceptance Criteria

Define the load that has caused the chip to break or crack, as the bending force.

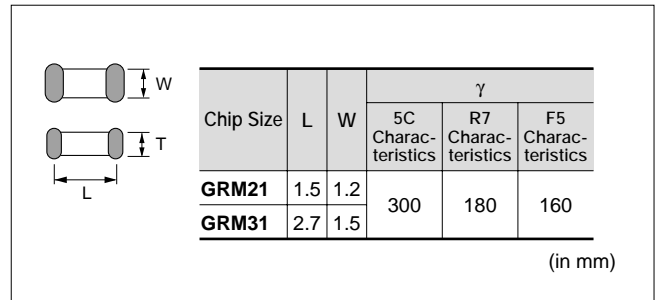
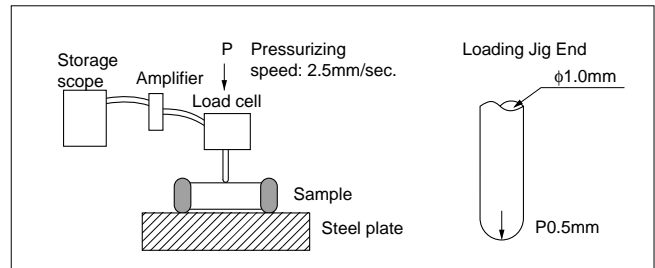
(4) Explanation

Break strength, P, is proportionate to the square of the thickness of the ceramic element and is expressed as a curve of secondary degree.

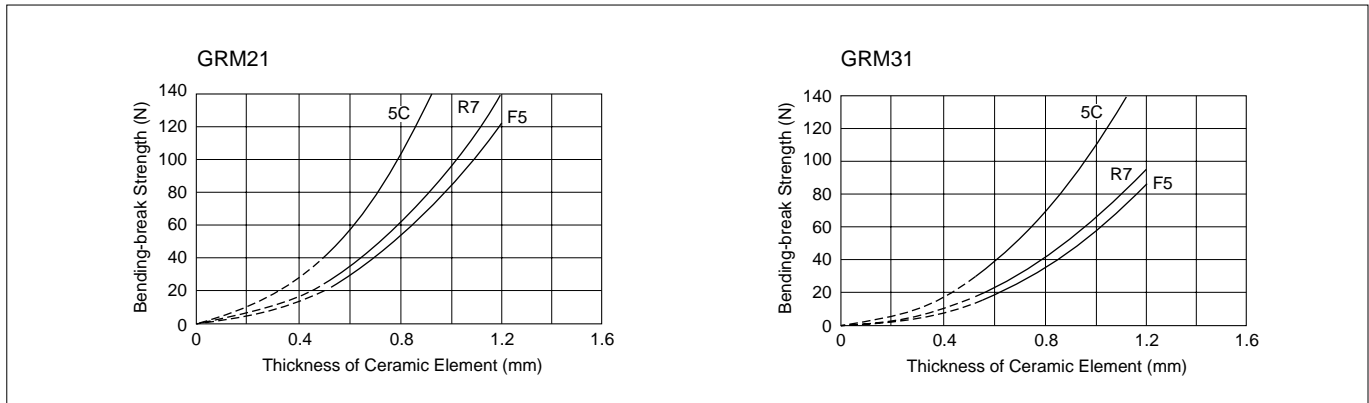
The formula is:

$$P = \frac{2\gamma WT^2}{3L} \quad (\text{N})$$

- W : Width of ceramic element (mm)
- T : Thickness of element (mm)
- L : Distance between fulcrums (mm)
- γ : Bending stress (N/mm²)



(5) Results



6. Thermal Shock

(1) Test method

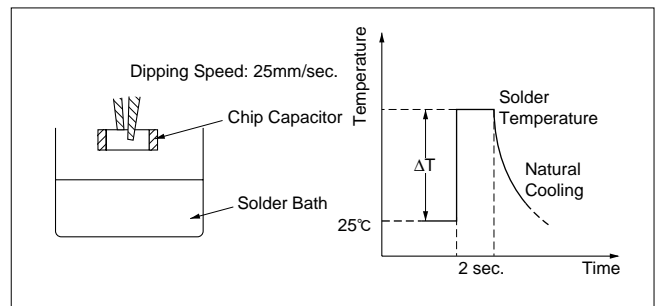
After applying flux (an ethanol solution of 25% rosin), dip the chip in a solder bath (6X4 eutectic solder) in accordance with the following conditions:

(2) Test samples

GRM21 5C/R7/F5 Characteristics T=0.6mm typical

(3) Acceptance criteria

Visually inspect the test sample with a 60-power optical microscope. Chips exhibiting breaks or cracks should be determined to be defective.

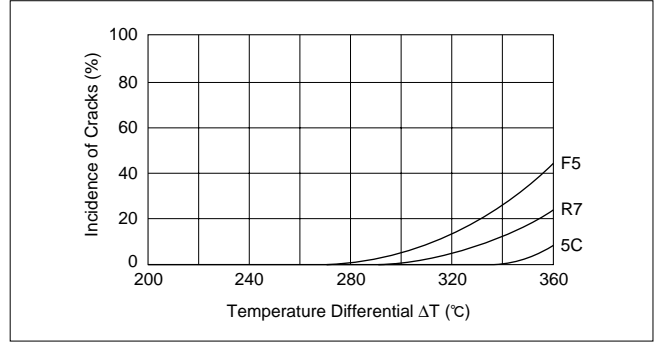


Continued on the following page. ☐

Reference Data

☐ Continued from the preceding page.

(4) Results



7. Solder Heat Resistance

(1) Test Method

① Reflow soldering:

Apply about 300 μm of solder paste over the alumina substrate. After reflow soldering, remove the chip and check for leaching that may have occurred on the outer electrode.

② Flow soldering:

After dipping the test sample with a pair of tweezers in wave solder (eutectic solder), check for leaching that may have occurred on the outer electrode.

③ Dip soldering:

After dipping the test sample with a pair of tweezers in static solder (eutectic solder), check for leaching that may have occurred on the outer electrode.

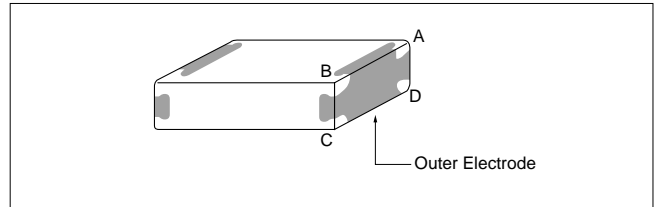
④ Flux to be used: An ethanol solution of 25% rosin.

(2) Test samples

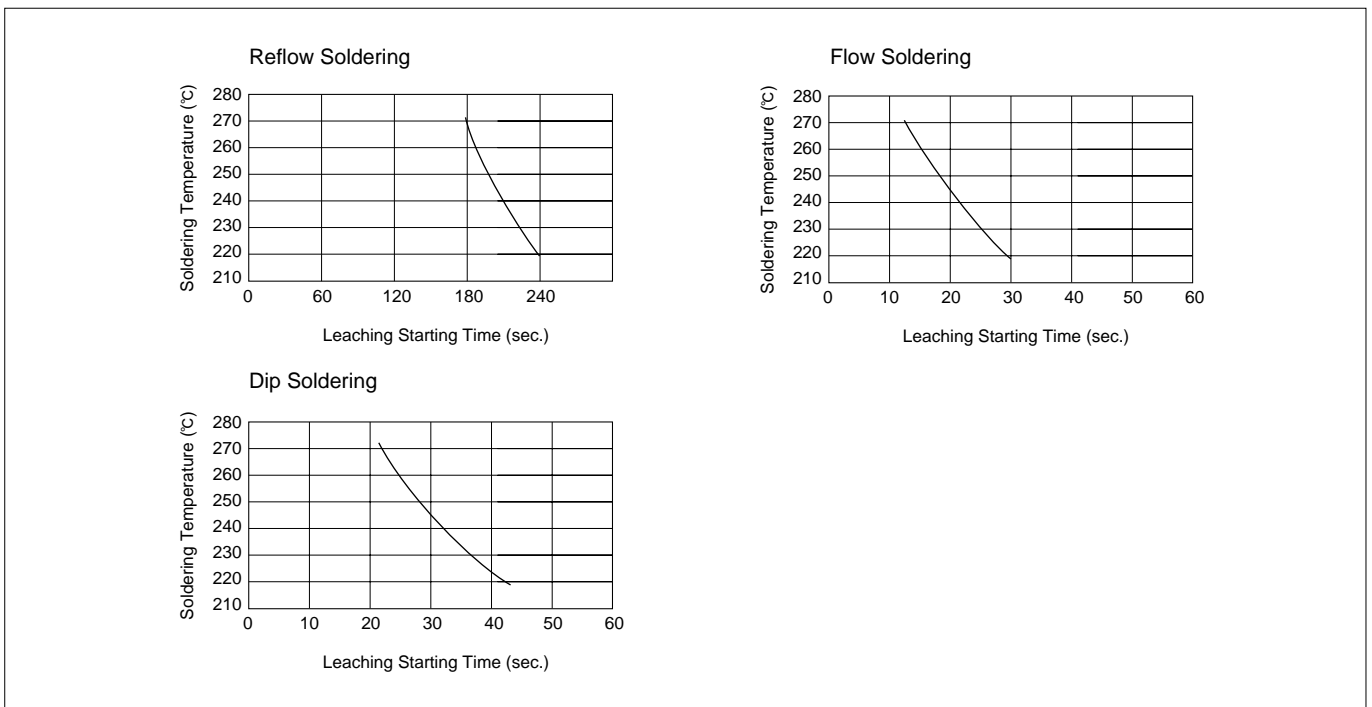
GRM21: For flow/reflow soldering T=0.6mm

(3) Acceptance criteria

The starting time of leaching should be defined as the time when the outer electrode has lost 25% of the total edge length of A-B-C-D as illustrated:



(4) Results



Continued on the following page. ↗

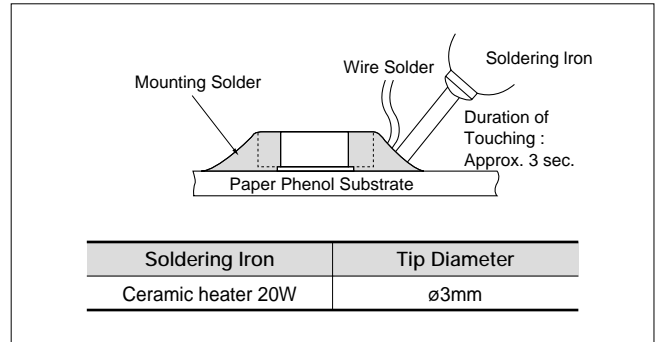
Reference Data

☐ Continued from the preceding page.

8. Thermal Shock when Making Corrections with a Soldering Iron

(1) Test Method

Apply a soldering iron meeting the conditions below to the soldered joint of a chip that has been soldered to a paper phenol board, while supplying wire solder. (Note: the soldering iron tip should not directly touch the ceramic element of the chip.)



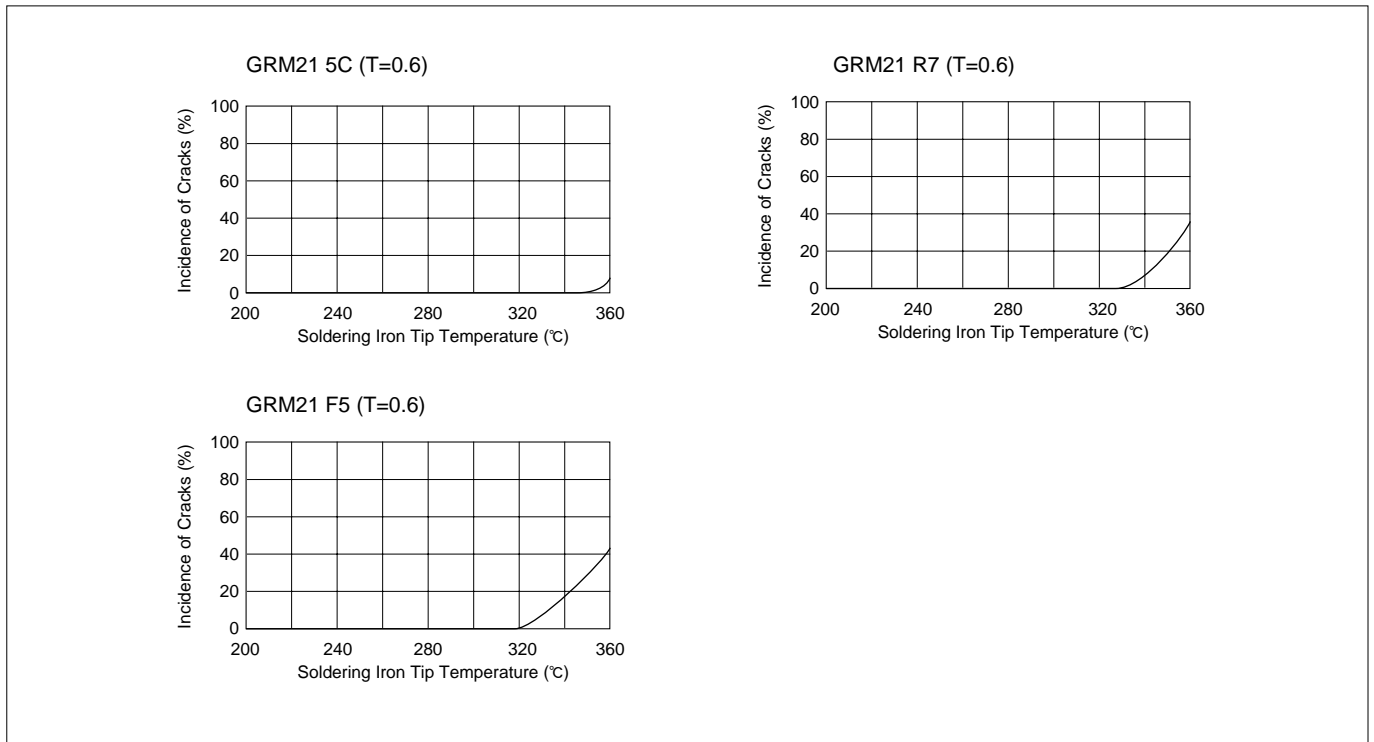
(2) Test Samples

GRM21 5C/R7/F5 Characteristics T=0.6mm

(3) Acceptance Criteria for Defects

Observe the appearance of the test sample with a 60-power optical microscope. Those units displaying any breaks or cracks are determined to be defective.

(4) Results



For General
GRM Series

Array
GMM Series

Low ESL
LL□ Series

High-Q
GJM Series

High Frequency
GOM Series

Monolithic Microchip
GMA Series

For Bonding
GMD Series

Product Information
Reference Data

Chip Monolithic Ceramic Capacitors (Medium Voltage)

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For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

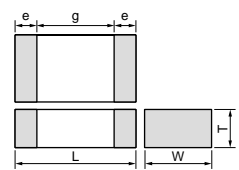
Chip Monolithic Ceramic Capacitors (Medium Voltage)



Low Dissipation Factor GRM Series

■ Features

1. Low-loss and suitable for high frequency circuits
2. Murata's original internal electrode structure provides high flash-over voltage.
3. A new monolithic structure for small, surface-mountable devices capable of operating at high voltage levels
4. Sn-plated external electrodes provides good solderability.
5. Use the GRM21/31 type with flow or reflow soldering, and other types with reflow soldering only.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GRM21A	2.0 ±0.2	1.25 ±0.2	1.0 +0, -0.3	0.3	0.7
GRM21B			1.25 ±0.2		
GRM31A	3.2 ±0.2	1.6 ±0.2	1.0 +0, -0.3		1.5*
GRM31B			1.25 +0, -0.3		
GRM32A	3.2 ±0.2	2.5 ±0.2	1.0 +0, -0.3		
GRM32B			1.25 +0, -0.3		
GRM42A	4.5 ±0.3	2.0 ±0.2	1.0 +0, -0.3	2.9	

* GRM31A7U3D, GRM32A7U3D, GRM32B7U3D: 1.8mm min.

■ Applications

Ideal for use on high frequency pulse circuits such as snubber circuits for switching power supplies, DC-DC converters, ballasts (inverter fluorescent lamps), etc.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.

C0G Characteristics

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM21A5C2E100JW01D	DC250	C0G (EIA)	10 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E120JW01D	DC250	C0G (EIA)	12 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E150JW01D	DC250	C0G (EIA)	15 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E180JW01D	DC250	C0G (EIA)	18 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E220JW01D	DC250	C0G (EIA)	22 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E270JW01D	DC250	C0G (EIA)	27 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E330JW01D	DC250	C0G (EIA)	33 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E390JW01D	DC250	C0G (EIA)	39 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E470JW01D	DC250	C0G (EIA)	47 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E560JW01D	DC250	C0G (EIA)	56 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E680JW01D	DC250	C0G (EIA)	68 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E820JW01D	DC250	C0G (EIA)	82 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A5C2E101JW01D	DC250	C0G (EIA)	100 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM31A5C2J100JW01D	DC630	C0G (EIA)	10 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J120JW01D	DC630	C0G (EIA)	12 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J150JW01D	DC630	C0G (EIA)	15 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J180JW01D	DC630	C0G (EIA)	18 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J220JW01D	DC630	C0G (EIA)	22 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J270JW01D	DC630	C0G (EIA)	27 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J330JW01D	DC630	C0G (EIA)	33 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J390JW01D	DC630	C0G (EIA)	39 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J470JW01D	DC630	C0G (EIA)	47 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J560JW01D	DC630	C0G (EIA)	56 ±5%	3.2	1.6	1.0	1.5	0.3 min.

Continued on the following page.



Continued from the preceding page.

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM31A5C2J680JW01D	DC630	C0G (EIA)	68 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J820JW01D	DC630	C0G (EIA)	82 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J101JW01D	DC630	C0G (EIA)	100 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J121JW01D	DC630	C0G (EIA)	120 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J151JW01D	DC630	C0G (EIA)	150 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J181JW01D	DC630	C0G (EIA)	180 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J221JW01D	DC630	C0G (EIA)	220 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J271JW01D	DC630	C0G (EIA)	270 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J331JW01D	DC630	C0G (EIA)	330 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J391JW01D	DC630	C0G (EIA)	390 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J471JW01D	DC630	C0G (EIA)	470 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C2J561JW01D	DC630	C0G (EIA)	560 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31B5C2J681JW01L	DC630	C0G (EIA)	680 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31B5C2J821JW01L	DC630	C0G (EIA)	820 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31B5C2J102JW01L	DC630	C0G (EIA)	1000 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31A5C3A100JW01D	DC1000	C0G (EIA)	10 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A120JW01D	DC1000	C0G (EIA)	12 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A150JW01D	DC1000	C0G (EIA)	15 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A180JW01D	DC1000	C0G (EIA)	18 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A220JW01D	DC1000	C0G (EIA)	22 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A270JW01D	DC1000	C0G (EIA)	27 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A330JW01D	DC1000	C0G (EIA)	33 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A390JW01D	DC1000	C0G (EIA)	39 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A470JW01D	DC1000	C0G (EIA)	47 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A560JW01D	DC1000	C0G (EIA)	56 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A680JW01D	DC1000	C0G (EIA)	68 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A820JW01D	DC1000	C0G (EIA)	82 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A5C3A101JW01D	DC1000	C0G (EIA)	100 ±5%	3.2	1.6	1.0	1.5	0.3 min.

U2J Characteristics

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM21A7U2E101JW31D	DC250	U2J (EIA)	100 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E121JW31D	DC250	U2J (EIA)	120 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E151JW31D	DC250	U2J (EIA)	150 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E181JW31D	DC250	U2J (EIA)	180 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E221JW31D	DC250	U2J (EIA)	220 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E271JW31D	DC250	U2J (EIA)	270 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E331JW31D	DC250	U2J (EIA)	330 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E391JW31D	DC250	U2J (EIA)	390 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E471JW31D	DC250	U2J (EIA)	470 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E561JW31D	DC250	U2J (EIA)	560 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E681JW31D	DC250	U2J (EIA)	680 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E821JW31D	DC250	U2J (EIA)	820 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E102JW31D	DC250	U2J (EIA)	1000 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E122JW31D	DC250	U2J (EIA)	1200 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E152JW31D	DC250	U2J (EIA)	1500 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E182JW31D	DC250	U2J (EIA)	1800 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21A7U2E222JW31D	DC250	U2J (EIA)	2200 ±5%	2.0	1.25	1.0	0.7	0.3 min.
GRM21B7U2E272JW32L	DC250	U2J (EIA)	2700 ±5%	2.0	1.25	1.25	0.7	0.3 min.
GRM31A7U2E272JW31D	DC250	U2J (EIA)	2700 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM21B7U2E332JW32L	DC250	U2J (EIA)	3300 ±5%	2.0	1.25	1.25	0.7	0.3 min.
GRM31A7U2E332JW31D	DC250	U2J (EIA)	3300 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM21B7U2E392JW32L	DC250	U2J (EIA)	3900 ±5%	2.0	1.25	1.25	0.7	0.3 min.
GRM31A7U2E392JW31D	DC250	U2J (EIA)	3900 ±5%	3.2	1.6	1.0	1.5	0.3 min.

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Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM21B7U2E472JW32L	DC250	U2J (EIA)	4700 ±5%	2.0	1.25	1.25	0.7	0.3 min.
GRM31A7U2E472JW31D	DC250	U2J (EIA)	4700 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM21B7U2E562JW32L	DC250	U2J (EIA)	5600 ±5%	2.0	1.25	1.25	0.7	0.3 min.
GRM31A7U2E562JW31D	DC250	U2J (EIA)	5600 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31B7U2E682JW31L	DC250	U2J (EIA)	6800 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31B7U2E822JW31L	DC250	U2J (EIA)	8200 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31B7U2E103JW31L	DC250	U2J (EIA)	10000 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31A7U2J100JW31D	DC630	U2J (EIA)	10 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J120JW31D	DC630	U2J (EIA)	12 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J150JW31D	DC630	U2J (EIA)	15 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J180JW31D	DC630	U2J (EIA)	18 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J220JW31D	DC630	U2J (EIA)	22 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J270JW31D	DC630	U2J (EIA)	27 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J330JW31D	DC630	U2J (EIA)	33 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J390JW31D	DC630	U2J (EIA)	39 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J470JW31D	DC630	U2J (EIA)	47 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J560JW31D	DC630	U2J (EIA)	56 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J680JW31D	DC630	U2J (EIA)	68 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J820JW31D	DC630	U2J (EIA)	82 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J101JW31D	DC630	U2J (EIA)	100 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J121JW31D	DC630	U2J (EIA)	120 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J151JW31D	DC630	U2J (EIA)	150 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J181JW31D	DC630	U2J (EIA)	180 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J221JW31D	DC630	U2J (EIA)	220 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J271JW31D	DC630	U2J (EIA)	270 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J331JW31D	DC630	U2J (EIA)	330 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J391JW31D	DC630	U2J (EIA)	390 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J471JW31D	DC630	U2J (EIA)	470 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J561JW31D	DC630	U2J (EIA)	560 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J681JW31D	DC630	U2J (EIA)	680 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J821JW31D	DC630	U2J (EIA)	820 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U2J102JW31D	DC630	U2J (EIA)	1000 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM32A7U2J122JW31D	DC630	U2J (EIA)	1200 ±5%	3.2	2.5	1.0	1.5	0.3 min.
GRM32A7U2J152JW31D	DC630	U2J (EIA)	1500 ±5%	3.2	2.5	1.0	1.5	0.3 min.
GRM32A7U2J182JW31D	DC630	U2J (EIA)	1800 ±5%	3.2	2.5	1.0	1.5	0.3 min.
GRM32A7U2J222JW31D	DC630	U2J (EIA)	2200 ±5%	3.2	2.5	1.0	1.5	0.3 min.
GRM31A7U3A100JW31D	DC1000	U2J (EIA)	10 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A120JW31D	DC1000	U2J (EIA)	12 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A150JW31D	DC1000	U2J (EIA)	15 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A180JW31D	DC1000	U2J (EIA)	18 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A220JW31D	DC1000	U2J (EIA)	22 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A270JW31D	DC1000	U2J (EIA)	27 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A330JW31D	DC1000	U2J (EIA)	33 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A390JW31D	DC1000	U2J (EIA)	39 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A470JW31D	DC1000	U2J (EIA)	47 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A560JW31D	DC1000	U2J (EIA)	56 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A680JW31D	DC1000	U2J (EIA)	68 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A820JW31D	DC1000	U2J (EIA)	82 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A101JW31D	DC1000	U2J (EIA)	100 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A121JW31D	DC1000	U2J (EIA)	120 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A151JW31D	DC1000	U2J (EIA)	150 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A181JW31D	DC1000	U2J (EIA)	180 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A221JW31D	DC1000	U2J (EIA)	220 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A271JW31D	DC1000	U2J (EIA)	270 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31A7U3A331JW31D	DC1000	U2J (EIA)	330 ±5%	3.2	1.6	1.0	1.5	0.3 min.
GRM31B7U3A391JW31L	DC1000	U2J (EIA)	390 ±5%	3.2	1.6	1.25	1.5	0.3 min.
GRM31B7U3A471JW31L	DC1000	U2J (EIA)	470 ±5%	3.2	1.6	1.25	1.5	0.3 min.

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Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM31A7U3D100JW31D	DC2000	U2J (EIA)	10 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D120JW31D	DC2000	U2J (EIA)	12 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D150JW31D	DC2000	U2J (EIA)	15 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D180JW31D	DC2000	U2J (EIA)	18 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D220JW31D	DC2000	U2J (EIA)	22 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D270JW31D	DC2000	U2J (EIA)	27 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D330JW31D	DC2000	U2J (EIA)	33 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D390JW31D	DC2000	U2J (EIA)	39 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D470JW31D	DC2000	U2J (EIA)	47 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D560JW31D	DC2000	U2J (EIA)	56 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM31A7U3D680JW31D	DC2000	U2J (EIA)	68 ±5%	3.2	1.6	1.0	1.8	0.3 min.
GRM32A7U3D820JW31D	DC2000	U2J (EIA)	82 ±5%	3.2	2.5	1.0	1.8	0.3 min.
GRM32A7U3D101JW31D	DC2000	U2J (EIA)	100 ±5%	3.2	2.5	1.0	1.8	0.3 min.
GRM32A7U3D121JW31D	DC2000	U2J (EIA)	120 ±5%	3.2	2.5	1.0	1.8	0.3 min.
GRM32A7U3D151JW31D	DC2000	U2J (EIA)	150 ±5%	3.2	2.5	1.0	1.8	0.3 min.
GRM32B7U3D181JW31L	DC2000	U2J (EIA)	180 ±5%	3.2	2.5	1.25	1.8	0.3 min.
GRM32B7U3D221JW31L	DC2000	U2J (EIA)	220 ±5%	3.2	2.5	1.25	1.8	0.3 min.
GRM42A7U3F270JW31L	DC3150	U2J (EIA)	27 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F330JW31L	DC3150	U2J (EIA)	33 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F390JW31L	DC3150	U2J (EIA)	39 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F470JW31L	DC3150	U2J (EIA)	47 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F560JW31L	DC3150	U2J (EIA)	56 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F680JW31L	DC3150	U2J (EIA)	68 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F820JW31L	DC3150	U2J (EIA)	82 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A7U3F101JW31L	DC3150	U2J (EIA)	100 ±5%	4.5	2.0	1.0	2.9	0.3 min.

For General Purpose
GRM/GRJ Series

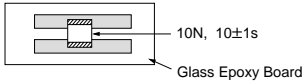
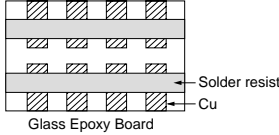
Only for Applications


AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

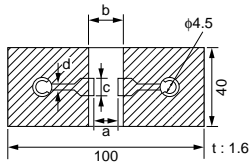
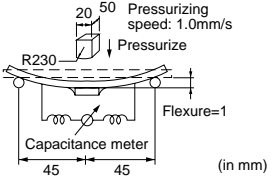
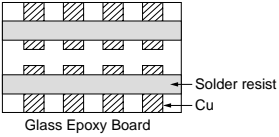
GRM Series Specifications and Test Methods

No.	Item	Specifications	Test Method												
1	Operating Temperature Range	-55 to +125°C	-												
2	Appearance	No defects or abnormalities	Visual inspection												
3	Dimensions	Within the specified dimension	Using calipers and micrometers												
4	Dielectric Strength	No defects or abnormalities	<p>No failure should be observed when voltage in the Table is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.</p> <table border="1"> <thead> <tr> <th>Rated Voltage</th> <th>Test Voltage</th> </tr> </thead> <tbody> <tr> <td>DC250V</td> <td>200% of the rated voltage</td> </tr> <tr> <td>DC630V</td> <td>150% of the rated voltage</td> </tr> <tr> <td>DC1kV, DC2kV, DC3.15kV</td> <td>130% of the rated voltage</td> </tr> </tbody> </table>	Rated Voltage	Test Voltage	DC250V	200% of the rated voltage	DC630V	150% of the rated voltage	DC1kV, DC2kV, DC3.15kV	130% of the rated voltage				
Rated Voltage	Test Voltage														
DC250V	200% of the rated voltage														
DC630V	150% of the rated voltage														
DC1kV, DC2kV, DC3.15kV	130% of the rated voltage														
5	Insulation Resistance (I.R.)	More than 10,000MΩ	The insulation resistance should be measured with DC500±50V (DC250±25V in case of rated voltage: DC250V) and within 60±5 sec. of charging.												
6	Capacitance	Within the specified tolerance	The capacitance/Q should be measured at the frequency and voltage shown as follows.												
7	Q	1,000 min.	<table border="1"> <thead> <tr> <th>Capacitance</th> <th>Frequency</th> <th>Voltage</th> </tr> </thead> <tbody> <tr> <td>C < 1,000pF</td> <td>1±0.2MHz</td> <td>AC0.5 to 5V(r.m.s.)</td> </tr> <tr> <td>C ≥ 1,000pF</td> <td>1±0.2kHz</td> <td>AC1±0.2V(r.m.s.)</td> </tr> </tbody> </table>	Capacitance	Frequency	Voltage	C < 1,000pF	1±0.2MHz	AC0.5 to 5V(r.m.s.)	C ≥ 1,000pF	1±0.2kHz	AC1±0.2V(r.m.s.)			
Capacitance	Frequency	Voltage													
C < 1,000pF	1±0.2MHz	AC0.5 to 5V(r.m.s.)													
C ≥ 1,000pF	1±0.2kHz	AC1±0.2V(r.m.s.)													
8	Capacitance Temperature Characteristics	Temp. Coefficient C0G char. : 0±30ppm/°C (Temp. Range : +25 to +125°C) 0+30, -72ppm/°C (Temp. Range : -55 to +25°C) U2J char. : -750±120ppm/°C (Temp. Range : +25 to +125°C) -750+120, -347ppm/°C (Temp. Range : -55 to +25°C)	The capacitance measurement should be made at each step specified in the Table. <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4	Max. Operating Temp.±2	5	25±2
Step	Temperature (°C)														
1	25±2														
2	Min. Operating Temp.±3														
3	25±2														
4	Max. Operating Temp.±2														
5	25±2														
9	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.  <p style="text-align: center;">Fig. 1</p>												
10	Appearance	No defects or abnormalities	Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.). 												
	Capacitance	Within the specified tolerance													
	Q	1,000 min.													

Continued on the following page. 

GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																							
11	Deflection	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																							
		 <p>Fig. 2</p> <table border="1"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>2.0×1.25</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> <td rowspan="4">1.0</td> </tr> <tr> <td>3.2×1.6</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>3.2×2.5</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>4.5×2.0</td> <td>3.5</td> <td>7.0</td> <td>2.4</td> </tr> </tbody> </table>		L×W (mm)	Dimension (mm)				a	b	c	d	2.0×1.25	1.2	4.0	1.65	1.0	3.2×1.6	2.2	5.0	2.0	3.2×2.5	2.2	5.0	2.9	4.5×2.0
L×W (mm)	Dimension (mm)																									
	a	b	c	d																						
2.0×1.25	1.2	4.0	1.65	1.0																						
3.2×1.6	2.2	5.0	2.0																							
3.2×2.5	2.2	5.0	2.9																							
4.5×2.0	3.5	7.0	2.4																							
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder																							
		 <p>Fig. 3</p>																								
13	Resistance to Soldering Heat	Appearance	No marking defects																							
		Capacitance Change	Within ±2.5%																							
		Q	1,000 min.																							
		I.R.	More than 10,000MΩ																							
		Dielectric Strength	In accordance with item No.4																							
			Preheat the capacitor at 120 to 150°C* for 1 min. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s *Preheating for more than 3.2×2.5mm																							
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.														
Step	Temperature	Time																								
1	100 to 120°C	1 min.																								
2	170 to 200°C	1 min.																								
14	Temperature Cycle	Appearance	No marking defects																							
		Capacitance Change	Within ±2.5%																							
		Q	500 min.																							
		I.R.	More than 10,000MΩ																							
		Dielectric Strength	In accordance with item No.4																							
			Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,* then measure.																							
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> <th>Time (min.)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min. Operating Temp.±3</td> <td>30±3</td> </tr> <tr> <td>2</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> <tr> <td>3</td> <td>Max. Operating Temp.±2</td> <td>30±3</td> </tr> <tr> <td>4</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> </tbody> </table>  <p>Fig. 4</p>	Step	Temperature (°C)	Time (min.)	1	Min. Operating Temp.±3	30±3	2	Room Temp.	2 to 3	3	Max. Operating Temp.±2	30±3	4	Room Temp.	2 to 3								
Step	Temperature (°C)	Time (min.)																								
1	Min. Operating Temp.±3	30±3																								
2	Room Temp.	2 to 3																								
3	Max. Operating Temp.±2	30±3																								
4	Room Temp.	2 to 3																								
15	Humidity (Steady State)	Appearance	No marking defects																							
		Capacitance Change	Within ±5.0%																							
		Q	350 min.																							
		I.R.	More than 1,000MΩ																							
		Dielectric Strength	In accordance with item No.4																							
			Let the capacitor sit at 40±2°C and relative humidity of 90 to 95% for 500±24 hrs. Remove and let sit for 24±2 hrs. at room condition,* then measure.																							
16	Life	Appearance	No marking defects																							
		Capacitance Change	Within ±3.0%																							
		Q	350 min.																							
		I.R.	More than 1,000MΩ																							
		Dielectric Strength	In accordance with item No.4																							
			Apply voltage as in Table for 1,000±4 hrs. at maximum operating temperature ±3°C. Remove and let sit for 24±2 hrs. at room condition,* then measure.																							
			<table border="1"> <thead> <tr> <th>Rated Voltage</th> <th>Applied Voltage</th> </tr> </thead> <tbody> <tr> <td>DC250V</td> <td>150% of the rated voltage</td> </tr> <tr> <td>DC630V, DC1kV, DC2kV, DC3.15kV</td> <td>120% of the rated voltage</td> </tr> </tbody> </table> The charge/discharge current is less than 50mA.	Rated Voltage	Applied Voltage	DC250V	150% of the rated voltage	DC630V, DC1kV, DC2kV, DC3.15kV	120% of the rated voltage																	
Rated Voltage	Applied Voltage																									
DC250V	150% of the rated voltage																									
DC630V, DC1kV, DC2kV, DC3.15kV	120% of the rated voltage																									

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

Chip Monolithic Ceramic Capacitors (Medium Voltage)



High Capacitance for General Use GRM Series

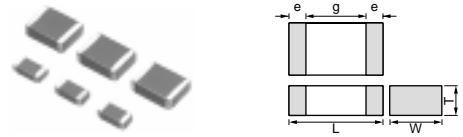
■ Features

1. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
2. Sn-plated external electrodes provide good solderability.
3. Use the GRM18/21/31 types with flow or reflow soldering, and other types with reflow soldering only.

■ Applications

1. Ideal for use on diode-snubber circuits for switching power supplies.
2. Ideal for use as primary-secondary coupling for DC-DC converters.
3. Ideal for use on line filters and ringer detectors for telephones, facsimiles and modems.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)					
	L	W	T	e	g min.	
GRM188	1.6 ±0.1	0.8 ±0.1	0.8 ±0.1	0.2 to 0.5	0.4	
GRM21A	2.0 ±0.2	1.25 ±0.2	1.0 +0,-0.3			
GRM21B			1.25 ±0.2			
GRM31B	3.2 ±0.2	1.6 ±0.2	1.25 +0,-0.3	0.3 min.	1.2	
GRM31C			1.6 ±0.2			
GRM32Q			1.5 +0,-0.3			
GRM32D	2.0 +0,-0.3					
GRM43Q	4.5 ±0.4	3.2 ±0.3	1.5 +0,-0.3			2.2
GRM43D			2.0 +0,-0.3			
GRM55D	5.7 ±0.4	5.0 ±0.4	2.0 +0,-0.3	3.2		

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM188R72E221KW07D	DC250	X7R (EIA)	220pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM188R72E331KW07D	DC250	X7R (EIA)	330pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM188R72E471KW07D	DC250	X7R (EIA)	470pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM188R72E681KW07D	DC250	X7R (EIA)	680pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM188R72E102KW07D	DC250	X7R (EIA)	1000pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM21AR72E102KW01D	DC250	X7R (EIA)	1000pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM188R72E152KW07D	DC250	X7R (EIA)	1500pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM21AR72E152KW01D	DC250	X7R (EIA)	1500pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM188R72E222KW07D	DC250	X7R (EIA)	2200pF ±10%	1.6	0.8	0.8	0.4	0.2 to 0.5
GRM21AR72E222KW01D	DC250	X7R (EIA)	2200pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM21AR72E332KW01D	DC250	X7R (EIA)	3300pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM21AR72E472KW01D	DC250	X7R (EIA)	4700pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM21AR72E682KW01D	DC250	X7R (EIA)	6800pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRM21BR72E103KW03L	DC250	X7R (EIA)	10000pF ±10%	2.0	1.25	1.25	0.7	0.3 min.
GRM31BR72E153KW01L	DC250	X7R (EIA)	15000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72E223KW01L	DC250	X7R (EIA)	22000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31CR72E333KW03L	DC250	X7R (EIA)	33000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRM31CR72E473KW03L	DC250	X7R (EIA)	47000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRM31BR72E683KW01L	DC250	X7R (EIA)	68000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM32QR72E683KW01L	DC250	X7R (EIA)	68000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRM31CR72E104KW03L	DC250	X7R (EIA)	0.10μF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRM32DR72E104KW01L	DC250	X7R (EIA)	0.10μF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRM32QR72E154KW01L	DC250	X7R (EIA)	0.15μF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRM43QR72E154KW01L	DC250	X7R (EIA)	0.15μF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRM32DR72E224KW01L	DC250	X7R (EIA)	0.22μF ±10%	3.2	2.5	2.0	1.2	0.3 min.

Continued on the following page. ↗



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Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM43DR72E224KW01L	DC250	X7R (EIA)	0.22μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM43DR72E334KW01L	DC250	X7R (EIA)	0.33μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM55DR72E334KW01L	DC250	X7R (EIA)	0.33μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRM43DR72E474KW01L	DC250	X7R (EIA)	0.47μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM55DR72E474KW01L	DC250	X7R (EIA)	0.47μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRM55DR72E105KW01L	DC250	X7R (EIA)	1.0μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRM31BR72J102KW01L	DC630	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J152KW01L	DC630	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J222KW01L	DC630	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J332KW01L	DC630	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J472KW01L	DC630	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J682KW01L	DC630	X7R (EIA)	6800pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR72J103KW01L	DC630	X7R (EIA)	10000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31CR72J153KW03L	DC630	X7R (EIA)	15000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRM32QR72J223KW01L	DC630	X7R (EIA)	22000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRM32DR72J333KW01L	DC630	X7R (EIA)	33000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRM32DR72J473KW01L	DC630	X7R (EIA)	47000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRM43QR72J683KW01L	DC630	X7R (EIA)	68000pF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRM43DR72J104KW01L	DC630	X7R (EIA)	0.10μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM55DR72J154KW01L	DC630	X7R (EIA)	0.15μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRM55DR72J224KW01L	DC630	X7R (EIA)	0.22μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRM31BR73A471KW01L	DC1000	X7R (EIA)	470pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR73A102KW01L	DC1000	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR73A152KW01L	DC1000	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR73A222KW01L	DC1000	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR73A332KW01L	DC1000	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM31BR73A472KW01L	DC1000	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRM32QR73A682KW01L	DC1000	X7R (EIA)	6800pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRM32QR73A103KW01L	DC1000	X7R (EIA)	10000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRM32DR73A153KW01L	DC1000	X7R (EIA)	15000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRM32DR73A223KW01L	DC1000	X7R (EIA)	22000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRM43DR73A333KW01L	DC1000	X7R (EIA)	33000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM43DR73A473KW01L	DC1000	X7R (EIA)	47000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRM55DR73A104KW01L	DC1000	X7R (EIA)	0.10μF ±10%	5.7	5.0	2.0	3.2	0.3 min.

For General Purpose
GRM/GRJ Series

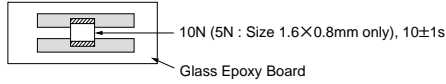
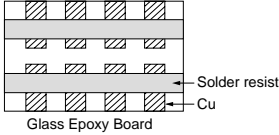
Only for Applications

AC250V Type
GA2 Series


Safety Standard
Certified GA3 Series

Product Information

GRM Series Specifications and Test Methods

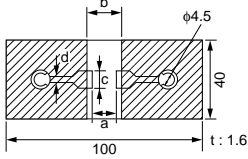
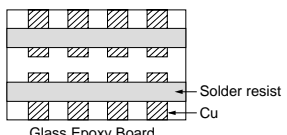
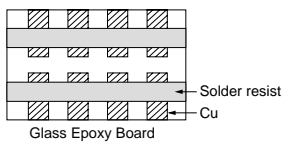
No.	Item	Specifications	Test Method									
1	Operating Temperature Range	-55 to +125°C	-									
2	Appearance	No defects or abnormalities	Visual inspection									
3	Dimensions	Within the specified dimensions	Using calipers and micrometers									
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when 150% of the rated voltage (200% of the rated voltage in case of rated voltage: DC250V, 120% of the rated voltage in case of rated voltage: DC1kV) is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.									
5	Insulation Resistance (I.R.)	C ≥ 0.01μF: More than 100MΩ • μF C < 0.01μF: More than 10,000MΩ	The insulation resistance should be measured with DC500±50V (DC250±25V in case of rated voltage: DC250V) and within 60±5 sec. of charging.									
6	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V(r.m.s.)									
7	Dissipation Factor (D.F.)	0.025 max.										
8	Capacitance Temperature Characteristics	Cap. Change Within ±15% (Temp. Range: -55 to +125°C)	The capacitance measurement should be made at each step specified in the Table.									
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±9°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4
Step	Temperature (°C)											
1	25±2											
2	Min. Operating Temp.±3											
3	25±2											
4	Max. Operating Temp.±2											
5	25±2											
9	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p>  <p>10N (5N : Size 1.6×0.8mm only), 10±1s Glass Epoxy Board</p> <p>Fig. 1</p>									
10	Vibration Resistance	Appearance	No defects or abnormalities									
		Capacitance	Within the specified tolerance									
		D.F.	0.025 max.									
			<p>Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).</p>  <p>Solder resist Cu Glass Epoxy Board</p>									

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. 

GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																															
11	Deflection	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																															
		 <p style="text-align: center;">Fig. 2</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>1.6×0.8</td> <td>1.0</td> <td>3.0</td> <td>1.2</td> <td rowspan="6" style="text-align: center;">1.0</td> </tr> <tr> <td>2.0×1.25</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> </tr> <tr> <td>3.2×1.6</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>3.2×2.5</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>4.5×3.2</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>5.7×5.0</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table>		L×W (mm)	Dimension (mm)				a	b	c	d	1.6×0.8	1.0	3.0	1.2	1.0	2.0×1.25	1.2	4.0	1.65	3.2×1.6	2.2	5.0	2.0	3.2×2.5	2.2	5.0	2.9	4.5×3.2	3.5	7.0	3.7	5.7×5.0
L×W (mm)	Dimension (mm)																																	
	a	b	c	d																														
1.6×0.8	1.0	3.0	1.2	1.0																														
2.0×1.25	1.2	4.0	1.65																															
3.2×1.6	2.2	5.0	2.0																															
3.2×2.5	2.2	5.0	2.9																															
4.5×3.2	3.5	7.0	3.7																															
5.7×5.0	4.5	8.0	5.6																															
			 <p style="text-align: center;">Fig. 3 (in mm)</p>																															
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder																															
13	Resistance to Soldering Heat	Appearance	No marking defects																															
		Capacitance Change	Within ±10%																															
		D.F.	0.025 max.																															
		I.R.	$C \geq 0.01\mu\text{F}$: More than 100MΩ • μF $C < 0.01\mu\text{F}$: More than 10,000MΩ																															
		Dielectric Strength	In accordance with item No.4																															
			Preheat the capacitor at 120 to 150°C* for 1 min. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s •Pretreatment Perform a heat treatment at 150±18°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*																															
			*Preheating for more than 3.2×2.5mm																															
			<table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.																						
Step	Temperature	Time																																
1	100 to 120°C	1 min.																																
2	170 to 200°C	1 min.																																
14	Temperature Cycle	Appearance	No marking defects																															
		Capacitance Change	Within ±7.5%																															
		D.F.	0.025 max.																															
		I.R.	$C \geq 0.01\mu\text{F}$: More than 100MΩ • μF $C < 0.01\mu\text{F}$: More than 10,000MΩ																															
		Dielectric Strength	In accordance with item No.4																															
			Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,* then measure.																															
			<table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> <th>Time (min.)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min. Operating Temp.±3</td> <td>30±3</td> </tr> <tr> <td>2</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> <tr> <td>3</td> <td>Max. Operating Temp.±2</td> <td>30±3</td> </tr> <tr> <td>4</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	Temperature (°C)	Time (min.)	1	Min. Operating Temp.±3	30±3	2	Room Temp.	2 to 3	3	Max. Operating Temp.±2	30±3	4	Room Temp.	2 to 3																
Step	Temperature (°C)	Time (min.)																																
1	Min. Operating Temp.±3	30±3																																
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4	Room Temp.	2 to 3																																
			•Pretreatment Perform a heat treatment at 150±18°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*																															
			 <p style="text-align: center;">Fig. 4</p>																															
15	Humidity (Steady State)	Appearance	No marking defects																															
		Capacitance Change	Within ±15%																															
		D.F.	0.05 max.																															
		I.R.	$C \geq 0.01\mu\text{F}$: More than 10MΩ • μF $C < 0.01\mu\text{F}$: More than 1,000MΩ																															
		Dielectric Strength	In accordance with item No.4																															
			Let the capacitor sit at 40±2°C and relative humidity of 90 to 95% for 500±24hrs. Remove and let sit for 24±2 hrs. at room condition,* then measure. •Pretreatment Perform a heat treatment at 150±18°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*																															

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page.

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GRM Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method	
16	Life	Appearance	Apply 120% of the rated voltage (150% of the rated voltage in case of rated voltage: DC250V, 110% of the rated voltage in case of rated voltage: DC1kV) for 1,000 ^{±4} hrs. at maximum operating temperature $\pm 3^{\circ}\text{C}$. Remove and let sit for 24 \pm 2hrs. at room condition,* then measure. The charge/discharge current is less than 50mA. •Pretreatment Apply test voltage for 60 \pm 5 min. at test temperature. Remove and let sit for 24 \pm 2 hrs. at room condition.*	
		Capacitance Change		Within $\pm 15\%$ (rated voltage: DC250V, DC630V) Within $\pm 20\%$ (rated voltage: DC1kV)
		D.F.		0.05 max.
		I.R.		$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than 1,000M Ω
		Dielectric Strength		In accordance with item No.4
17	Humidity Loading (Application: DC250V, DC630V item)	Appearance	Apply the rated voltage at 40 $\pm 2^{\circ}\text{C}$ and relative humidity of 90 to 95% for 500 ^{±2} hrs. Remove and let sit for 24 \pm 2 hrs. at room condition,* then measure. •Pretreatment Apply test voltage for 60 \pm 5 min. at test temperature. Remove and let sit for 24 \pm 2 hrs. at room condition.*	
		Capacitance Change		Within $\pm 15\%$
		D.F.		0.05 max.
		I.R.		$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than 1,000M Ω
		Dielectric Strength		In accordance with item No.4

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Chip Monolithic Ceramic Capacitors (Medium Voltage)



Soft Termination Type GRJ series

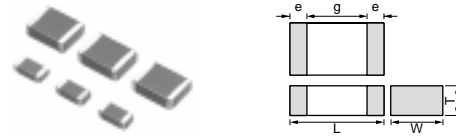
■ Features

1. Improves endurance against Board Bending Stress.
2. Reduces the board bending stress by the conductive polymer termination.
3. Use the GRJ21/31 types with flow or reflow soldering, and other types with reflow soldering only.

■ Applications

1. Ideal for use on diode-snubber circuits for switching power supplies.
2. Ideal for use as primary-secondary coupling for DC-DC converters.
3. Ideal for use on line filters and ringer detectors for telephones, facsimiles and modems.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)				
	L	W	T	e	g min.
GRJ21A	2.0 ±0.2	1.25 ±0.2	1.0 +0,-0.3	0.3 min.	0.7
GRJ21B			1.25 ±0.2		
GRJ31B	3.2 ±0.2	1.6 ±0.2	1.25 +0,-0.3		1.2
GRJ31C			1.6 ±0.2		
GRJ32Q	3.2 ±0.3	2.5 ±0.2	1.5 +0,-0.3		2.2
GRJ32D			2.0 +0,-0.3		
GRJ43Q	4.5 ±0.4	3.2 ±0.3	1.5 +0,-0.3		3.2
GRJ43D			2.0 +0,-0.3		
GRJ55D	5.7 ±0.4	5.0 ±0.4	2.0 +0,-0.3		

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRJ21AR72E102KWJ1D	DC250	X7R (EIA)	1000pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E152KWJ1D	DC250	X7R (EIA)	1500pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E222KWJ1D	DC250	X7R (EIA)	2200pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E332KWJ1D	DC250	X7R (EIA)	3300pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E472KWJ1D	DC250	X7R (EIA)	4700pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21AR72E682KWJ1D	DC250	X7R (EIA)	6800pF ±10%	2.0	1.25	1.0	0.7	0.3 min.
GRJ21BR72E103KWJ3L	DC250	X7R (EIA)	10000pF ±10%	2.0	1.25	1.25	0.7	0.3 min.
GRJ31BR72E153KWJ1L	DC250	X7R (EIA)	15000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72E223KWJ1L	DC250	X7R (EIA)	22000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31CR72E333KWJ3L	DC250	X7R (EIA)	33000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ31CR72E473KWJ3L	DC250	X7R (EIA)	47000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ31BR72E683KWJ1L	DC250	X7R (EIA)	68000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ32QR72E683KWJ1L	DC250	X7R (EIA)	68000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ31CR72E104KWJ3L	DC250	X7R (EIA)	0.10µF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ32DR72E104KWJ1L	DC250	X7R (EIA)	0.10µF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32QR72E154KWJ1L	DC250	X7R (EIA)	0.15µF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ43QR72E154KWJ1L	DC250	X7R (EIA)	0.15µF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRJ32DR72E224KWJ1L	DC250	X7R (EIA)	0.22µF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43DR72E224KWJ1L	DC250	X7R (EIA)	0.22µF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ43DR72E334KWJ1L	DC250	X7R (EIA)	0.33µF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72E334KWJ1L	DC250	X7R (EIA)	0.33µF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ43DR72E474KWJ1L	DC250	X7R (EIA)	0.47µF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72E474KWJ1L	DC250	X7R (EIA)	0.47µF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ55DR72E105KWJ1L	DC250	X7R (EIA)	1.0µF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ31BR72J102KWJ1L	DC630	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J152KWJ1L	DC630	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J222KWJ1L	DC630	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.

Continued on the following page.

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Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRJ31BR72J332KWJ1L	DC630	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J472KWJ1L	DC630	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J682KWJ1L	DC630	X7R (EIA)	6800pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR72J103KWJ1L	DC630	X7R (EIA)	10000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31CR72J153KWJ3L	DC630	X7R (EIA)	15000pF ±10%	3.2	1.6	1.6	1.2	0.3 min.
GRJ32QR72J223KWJ1L	DC630	X7R (EIA)	22000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32DR72J333KWJ1L	DC630	X7R (EIA)	33000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32DR72J473KWJ1L	DC630	X7R (EIA)	47000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43QR72J683KWJ1L	DC630	X7R (EIA)	68000pF ±10%	4.5	3.2	1.5	2.2	0.3 min.
GRJ43DR72J104KWJ1L	DC630	X7R (EIA)	0.10μF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR72J154KWJ1L	DC630	X7R (EIA)	0.15μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ55DR72J224KWJ1L	DC630	X7R (EIA)	0.22μF ±10%	5.7	5.0	2.0	3.2	0.3 min.
GRJ31BR73A471KWJ1L	DC1000	X7R (EIA)	470pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A102KWJ1L	DC1000	X7R (EIA)	1000pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A152KWJ1L	DC1000	X7R (EIA)	1500pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A222KWJ1L	DC1000	X7R (EIA)	2200pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A332KWJ1L	DC1000	X7R (EIA)	3300pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ31BR73A472KWJ1L	DC1000	X7R (EIA)	4700pF ±10%	3.2	1.6	1.25	1.2	0.3 min.
GRJ32QR73A682KWJ1L	DC1000	X7R (EIA)	6800pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32QR73A103KWJ1L	DC1000	X7R (EIA)	10000pF ±10%	3.2	2.5	1.5	1.2	0.3 min.
GRJ32DR73A153KWJ1L	DC1000	X7R (EIA)	15000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ32DR73A223KWJ1L	DC1000	X7R (EIA)	22000pF ±10%	3.2	2.5	2.0	1.2	0.3 min.
GRJ43DR73A333KWJ1L	DC1000	X7R (EIA)	33000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ43DR73A473KWJ1L	DC1000	X7R (EIA)	47000pF ±10%	4.5	3.2	2.0	2.2	0.3 min.
GRJ55DR73A104KWJ1L	DC1000	X7R (EIA)	0.10μF ±10%	5.7	5.0	2.0	3.2	0.3 min.

For General Purpose GRM/GRJ Series

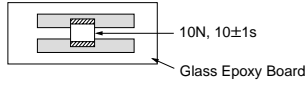
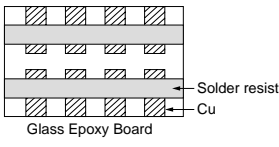
Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GRJ Series Specifications and Test Methods

No.	Item	Specifications	Test Method												
1	Operating Temperature Range	-55 to +125°C	-												
2	Appearance	No defects or abnormalities	Visual inspection												
3	Dimensions	Within the specified dimensions	Using calipers and micrometers												
4	Dielectric Strength	No defects or abnormalities	<p>No failure should be observed when voltage in the Table is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.</p> <table border="1" style="width: 100%;"> <thead> <tr> <th>Rated Voltage</th> <th>Test Voltage</th> </tr> </thead> <tbody> <tr> <td>DC250V</td> <td>200% of the rated voltage</td> </tr> <tr> <td>DC630V</td> <td>150% of the rated voltage</td> </tr> <tr> <td>DC1kV</td> <td>120% of the rated voltage</td> </tr> </tbody> </table>	Rated Voltage	Test Voltage	DC250V	200% of the rated voltage	DC630V	150% of the rated voltage	DC1kV	120% of the rated voltage				
Rated Voltage	Test Voltage														
DC250V	200% of the rated voltage														
DC630V	150% of the rated voltage														
DC1kV	120% of the rated voltage														
5	Insulation Resistance (I.R.)	C ≥ 0.01μF: More than 100MΩ • μF C < 0.01μF: More than 10,000MΩ	The insulation resistance should be measured with DC500±50V (DC250±25V in case of rated voltage: DC250V) and within 60±5 sec. of charging.												
6	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V(r.m.s.)												
7	Dissipation Factor (D.F.)	0.025 max.													
8	Capacitance Temperature Characteristics	Cap. Change Within ±15% (Temp. Range: -55 to +125°C)	<p>The capacitance measurement should be made at each step specified in the Table.</p> <table border="1" style="width: 100%;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±9°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4	Max. Operating Temp.±2	5	25±2
Step	Temperature (°C)														
1	25±2														
2	Min. Operating Temp.±3														
3	25±2														
4	Max. Operating Temp.±2														
5	25±2														
9	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p>  <p style="text-align: center;">Fig. 1</p>												
10	Vibration Resistance	Appearance	No defects or abnormalities												
		Capacitance	Within the specified tolerance												
	D.F.	0.025 max.	<p>Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).</p> 												

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page.

For General Purpose GRM/GRJ Series

Only for Applications

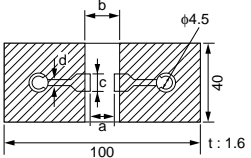
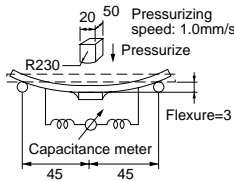
AC250V Type GA2 Series

Safety Standard Certified GA3 Series


Product Information

GRJ Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																														
11	Appearance	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																														
	Capacitance Change	Within $\pm 12.5\%$																															
11	Deflection	 <p>Fig. 2</p> <table border="1"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>2.0×1.25</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> <td rowspan="6">1.0</td> </tr> <tr> <td>3.2×1.6</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> <tr> <td>3.2×2.5</td> <td>2.2</td> <td>5.0</td> <td>2.9</td> </tr> <tr> <td>4.5×3.2</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>5.7×5.0</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table>	L×W (mm)	Dimension (mm)				a	b	c	d	2.0×1.25	1.2	4.0	1.65	1.0	3.2×1.6	2.2	5.0	2.0	3.2×2.5	2.2	5.0	2.9	4.5×3.2	3.5	7.0	3.7	5.7×5.0	4.5	8.0	5.6	 <p>Fig. 3 (in mm)</p>
				L×W (mm)	Dimension (mm)																												
			a		b	c	d																										
			2.0×1.25	1.2	4.0	1.65	1.0																										
			3.2×1.6	2.2	5.0	2.0																											
			3.2×2.5	2.2	5.0	2.9																											
4.5×3.2	3.5	7.0	3.7																														
5.7×5.0	4.5	8.0	5.6																														
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2 ± 0.5 sec. Immersing speed: 25 ± 2.5 mm/s Temp. of solder: $245\pm 5^\circ\text{C}$ Lead Free Solder (Sn-3.0Ag-0.5Cu) $235\pm 5^\circ\text{C}$ H60A or H63A Eutectic Solder																														
				13	Resistance to Soldering Heat	Appearance	No marking defects	Preheat the capacitor at 120 to 150°C^* for 1 min. Immerse the capacitor in solder solution at $260\pm 5^\circ\text{C}$ for 10 ± 1 sec. Let sit at room condition* for 24 ± 2 hrs., then measure. •Immersing speed: 25 ± 2.5 mm/s •Pretreatment Perform a heat treatment at $150\pm 1^\circ\text{C}$ for 60 ± 5 min. and then let sit for 24 ± 2 hrs. at room condition.*																									
						Capacitance Change	Within $\pm 10\%$																										
						D.F.	0.025 max.																										
						I.R.	$C \geq 0.01\mu\text{F}$: More than $100\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than $10,000\text{M}\Omega$																										
13	Dielectric Strength	In accordance with item No.4	<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.																					
				Step	Temperature	Time																											
1	100 to 120°C	1 min.																															
2	170 to 200°C	1 min.																															
14	Temperature Cycle	Appearance	No marking defects	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24 ± 2 hrs. at room condition,* then measure.																													
		Capacitance Change	Within $\pm 7.5\%$																														
		D.F.	0.025 max.																														
		I.R.	$C \geq 0.01\mu\text{F}$: More than $100\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than $10,000\text{M}\Omega$																														
		14	Dielectric Strength		In accordance with item No.4	<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature ($^\circ\text{C}$)</th> <th>Time (min.)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min. Operating Temp. ± 3</td> <td>30 ± 3</td> </tr> <tr> <td>2</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> <tr> <td>3</td> <td>Max. Operating Temp. ± 2</td> <td>30 ± 3</td> </tr> <tr> <td>4</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> </tbody> </table>	Step	Temperature ($^\circ\text{C}$)	Time (min.)	1	Min. Operating Temp. ± 3	30 ± 3	2	Room Temp.	2 to 3	3	Max. Operating Temp. ± 2	30 ± 3	4	Room Temp.	2 to 3												
							Step	Temperature ($^\circ\text{C}$)	Time (min.)																								
1	Min. Operating Temp. ± 3	30 ± 3																															
2	Room Temp.	2 to 3																															
3	Max. Operating Temp. ± 2	30 ± 3																															
4	Room Temp.	2 to 3																															
15	Humidity (Steady State)	Appearance	No marking defects	Let the capacitor sit at $40\pm 2^\circ\text{C}$ and relative humidity of 90 to 95% for 500 ± 2 hrs. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. •Pretreatment Perform a heat treatment at $150\pm 1^\circ\text{C}$ for 60 ± 5 min. and then let sit for 24 ± 2 hrs. at room condition.*																													
		Capacitance Change	Within $\pm 15\%$																														
		D.F.	0.05 max.																														
		I.R.	$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than $1,000\text{M}\Omega$																														
		Dielectric Strength	In accordance with item No.4																														

* "Room condition" Temperature: 15 to 35°C , Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. 

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GRJ Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method								
16	Life	Appearance	Apply voltage as in Table for 1,000 ^{±4} hrs. at maximum operating temperature $\pm 3^{\circ}\text{C}$. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. <table border="1" style="margin-left: 20px;"> <thead> <tr> <th>Rated Voltage</th> <th>Applied Voltage</th> </tr> </thead> <tbody> <tr> <td>DC250V</td> <td>150% of the rated voltage</td> </tr> <tr> <td>DC630V</td> <td>120% of the rated voltage</td> </tr> <tr> <td>DC1kV</td> <td>110% of the rated voltage</td> </tr> </tbody> </table>	Rated Voltage	Applied Voltage	DC250V	150% of the rated voltage	DC630V	120% of the rated voltage	DC1kV	110% of the rated voltage
		Rated Voltage		Applied Voltage							
		DC250V		150% of the rated voltage							
		DC630V		120% of the rated voltage							
		DC1kV		110% of the rated voltage							
Capacitance Change	Within $\pm 15\%$ (rated voltage: DC250V, DC630V) Within $\pm 20\%$ (rated voltage: DC1kV)										
D.F.	0.05 max.										
I.R.	$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than 1,000M Ω										
Dielectric Strength	In accordance with item No.4										
17	Humidity Loading (Application: DC250V, DC630V item)	Appearance	Apply the rated voltage at $40 \pm 2^{\circ}\text{C}$ and relative humidity of 90 to 95% for 500 ^{±2} hrs. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. •Pretreatment Apply test voltage for 60 ± 5 min. at test temperature. Remove and let sit for 24 ± 2 hrs. at room condition.*								
		Capacitance Change		Within $\pm 15\%$							
		D.F.		0.05 max.							
		I.R.		$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than 1,000M Ω							
		Dielectric Strength		In accordance with item No.4							

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

For General Purpose
GRM/GRJ Series

Only for Applications
GRM/DC3.15kV Series

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

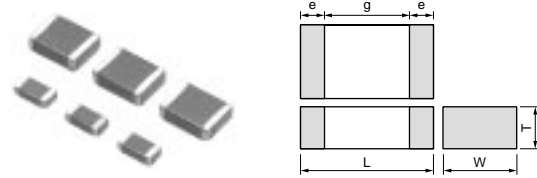
Chip Monolithic Ceramic Capacitors (Medium Voltage)



For LCD Backlight Inverter Circuit GRM/DC3.15kV Series

■ Features

1. Low-loss and suitable for high frequency circuits
2. Murata's original internal electrode structure realizes high flash-over voltage.
3. A new monolithic structure for small, surface-mountable devices capable of operating at high voltage levels.
4. Sn-plated external electrodes realize good solderability.
5. Only for reflow soldering
6. Capacitance values less than 22pF can be used in LCD backlight inverter circuits as long as the applied voltage, peak to peak, is less than 4.0kV at 100kHz or less.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GRM42A	4.5 ±0.3	2.0 ±0.2	1.0 +0, -0.3	0.3	2.9

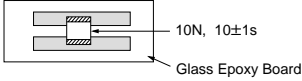
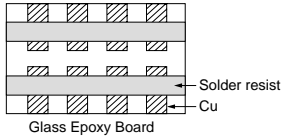
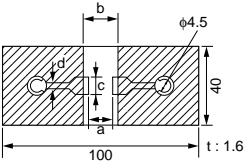
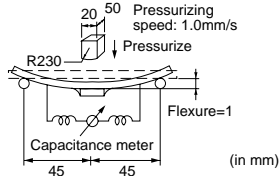
■ Applications

Ideal for use as the ballast in LCD backlight inverter.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GRM42A5C3F050DW01L	DC3150	COG (EIA)	5.0 ±0.5pF	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F100JW01L	DC3150	COG (EIA)	10 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F120JW01L	DC3150	COG (EIA)	12 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F150JW01L	DC3150	COG (EIA)	15 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F180JW01L	DC3150	COG (EIA)	18 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F220JW01L	DC3150	COG (EIA)	22 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F270JW01L	DC3150	COG (EIA)	27 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F330JW01L	DC3150	COG (EIA)	33 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F390JW01L	DC3150	COG (EIA)	39 ±5%	4.5	2.0	1.0	2.9	0.3 min.
GRM42A5C3F470JW01L	DC3150	COG (EIA)	47 ±5%	4.5	2.0	1.0	2.9	0.3 min.

GRM/DC3.15kV Series Specifications and Test Methods

No.	Item	Specifications	Test Method														
1	Operating Temperature Range	-55 to +125°C	—														
2	Appearance	No defects or abnormalities	Visual inspection														
3	Dimensions	Within the specified dimension	Using calipers and micrometers														
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when DC4095V is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.														
5	Insulation Resistance (I.R.)	More than 10,000MΩ	The insulation resistance should be measured with DC500±50V and within 60±5 sec. of charging.														
6	Capacitance	Within the specified tolerance	The capacitance/Q should be measured at a frequency of 1±0.2MHz and a voltage of AC0.5 to 5V(r.m.s.)														
7	Q	1,000 min.															
8	Capacitance Temperature Characteristics	Temp. Coefficient 0±30ppm/°C (Temp. Range: +25 to +125°C) 0+30, -72ppm/°C (Temp. Range: -55 to +25°C)	The capacitance measurement should be made at each step specified in the Table.														
			<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="width: 20%;">Step</th> <th style="width: 80%;">Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4	Max. Operating Temp.±2	5	25±2		
Step	Temperature (°C)																
1	25±2																
2	Min. Operating Temp.±3																
3	25±2																
4	Max. Operating Temp.±2																
5	25±2																
9	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p> <div style="text-align: center;">  <p>10N, 10±1s Glass Epoxy Board</p> </div> <p style="text-align: center;">Fig. 1</p>														
10	Vibration Resistance	Appearance	No defects or abnormalities														
		Capacitance	Within the specified tolerance														
		Q	1,000 min.														
			<p>Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).</p> <div style="text-align: center;">  <p>Solder resist Cu Glass Epoxy Board</p> </div>														
11	Deflection	No marking defects	<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p> <div style="text-align: center;">  <p>Fig. 2</p> <table border="1" style="margin: 0 auto; border-collapse: collapse;"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>4.5×2.0</td> <td>3.5</td> <td>7.0</td> <td>2.4</td> <td>1.0</td> </tr> </tbody> </table> </div>	L×W (mm)	Dimension (mm)				a	b	c	d	4.5×2.0	3.5	7.0	2.4	1.0
		L×W (mm)			Dimension (mm)												
a	b		c	d													
4.5×2.0	3.5	7.0	2.4	1.0													
			<div style="text-align: center;">  <p>20 50 Pressurizing speed: 1.0mm/s Pressurize R230 Capacitance meter Flexure=1 (in mm)</p> </div> <p style="text-align: center;">Fig. 3</p>														

Continued on the following page.

For General Purpose GRM/GRJ Series

Only for Applications GRM/DC3.15kV Series

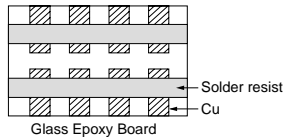
AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GRM/DC3.15kV Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method															
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder															
13	Resistance to Soldering Heat	Appearance	No marking defects															
		Capacitance Change	Within ±2.5%															
		Q	1,000 min.															
		I.R.	More than 10,000MΩ															
		Dielectric Strength	In accordance with item No.4															
			Preheat the capacitor as in table. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s															
			*Preheating															
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.						
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2	170 to 200°C	1 min.																
14	Temperature Cycle	Appearance	No marking defects															
		Capacitance Change	Within ±2.5%															
		Q	1,000 min.															
		I.R.	More than 10,000MΩ															
		Dielectric Strength	In accordance with item No.4															
			Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,* then measure.															
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Step	Temperature (°C)	Time (min.)																
1	Min. Operating Temp.±3	30±3																
2	Room Temp.	2 to 3																
3	Max. Operating Temp.±2	30±3																
4	Room Temp.	2 to 3																
			 <p style="text-align: center;">Fig. 4</p>															
15	Humidity (Steady State)	Appearance	No marking defects															
		Capacitance Change	Within ±5.0%															
		Q	350 min.															
		I.R.	More than 1,000MΩ															
		Dielectric Strength	In accordance with item No.4															
			Let the capacitor sit at 40±2°C and relative humidity of 90 to 95% for 500 ^{±2} hrs. Remove and let sit for 24±2 hrs. at room condition,* then measure.															
16	Life	Appearance	No marking defects															
		Capacitance Change	Within ±3.0%															
		Q	350 min.															
		I.R.	More than 1,000MΩ															
		Dielectric Strength	In accordance with item No.4															
			Apply 120% of the rated voltage for 1,000 ^{±4} hrs. at maximum operating temperature ±3°C. Remove and let sit for 24±2 hrs. at room condition,* then measure. The charge/discharge current is less than 50mA.															

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

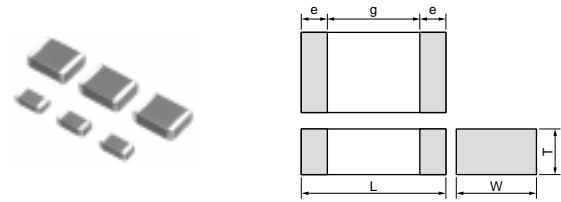
Chip Monolithic Ceramic Capacitors (Medium Voltage)



For Information Devices GR4 Series

■ Features

1. These items are designed specifically for telecommunications devices (IEEE802.3) in Ethernet LAN and primary-secondary coupling for DC-DC converters.
2. A new monolithic structure for small, high capacitance capable of operating at high voltage levels
3. Sn-plated external electrodes realize good solderability.
4. Only for reflow soldering



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GR442Q	4.5 ±0.3	2.0 ±0.2	1.5 +0, -0.3	0.3	2.5
GR443D	4.5 ±0.4	3.2 ±0.3	2.0 +0, -0.3		
GR443Q			1.5 +0, -0.3		
GR455D	5.7 ±0.4	5.0 ±0.4	2.0 +0, -0.3		3.2

■ Applications

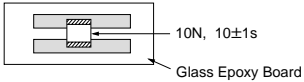
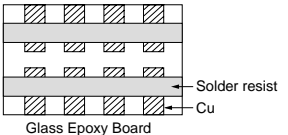
1. Ideal for use on telecommunications devices in Ethernet LAN
2. Ideal for use as primary-secondary coupling for DC-DC converters

Do not use these products in any Automotive Power train or Safety equipment including Battery charger for Electric Vehicles and Plug-in Hybrid. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.


Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GR442QR73D101KW01L	DC2000	X7R (EIA)	100 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D121KW01L	DC2000	X7R (EIA)	120 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D151KW01L	DC2000	X7R (EIA)	150 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D181KW01L	DC2000	X7R (EIA)	180 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D221KW01L	DC2000	X7R (EIA)	220 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D271KW01L	DC2000	X7R (EIA)	270 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D331KW01L	DC2000	X7R (EIA)	330 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D391KW01L	DC2000	X7R (EIA)	390 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D471KW01L	DC2000	X7R (EIA)	470 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D561KW01L	DC2000	X7R (EIA)	560 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D681KW01L	DC2000	X7R (EIA)	680 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D821KW01L	DC2000	X7R (EIA)	820 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D102KW01L	DC2000	X7R (EIA)	1000 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D122KW01L	DC2000	X7R (EIA)	1200 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR442QR73D152KW01L	DC2000	X7R (EIA)	1500 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GR443QR73D182KW01L	DC2000	X7R (EIA)	1800 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GR443QR73D222KW01L	DC2000	X7R (EIA)	2200 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GR443QR73D272KW01L	DC2000	X7R (EIA)	2700 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GR443QR73D332KW01L	DC2000	X7R (EIA)	3300 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GR443QR73D392KW01L	DC2000	X7R (EIA)	3900 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GR443DR73D472KW01L	DC2000	X7R (EIA)	4700 ±10%	4.5	3.2	2.0	2.5	0.3 min.
GR455DR73D103KW01L	DC2000	X7R (EIA)	10000 ±10%	5.7	5.0	2.0	3.2	0.3 min.

For General Purpose GRM/GRJ Series
 Only for Applications GR4 Series
 AC250V Type GA2 Series
 Safety Standard Certified GA3 Series
 Product Information

GR4 Series Specifications and Test Methods

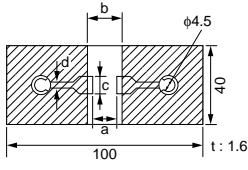
No.	Item	Specifications	Test Method												
1	Operating Temperature Range	-55 to +125°C	-												
2	Appearance	No defects or abnormalities	Visual inspection												
3	Dimensions	Within the specified dimensions	Using calipers and micrometers												
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when voltage in the table is applied between the terminations, provided the charge/discharge current is less than 50mA. <table border="1"> <thead> <tr> <th>Rated Voltage</th> <th>Test Voltage</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td rowspan="2">DC2kV</td> <td>120% of the rated voltage</td> <td>60±1 sec.</td> </tr> <tr> <td>AC1500V(r.m.s.)</td> <td>60±1 sec.</td> </tr> </tbody> </table>	Rated Voltage	Test Voltage	Time	DC2kV	120% of the rated voltage	60±1 sec.	AC1500V(r.m.s.)	60±1 sec.				
Rated Voltage	Test Voltage	Time													
DC2kV	120% of the rated voltage	60±1 sec.													
	AC1500V(r.m.s.)	60±1 sec.													
5	Pulse Voltage	No self healing breakdowns or flash-overs have taken place in the capacitor.	10 impulses of alternating polarity are subjected. (5 impulses for each polarity) The interval between impulses is 60 sec. Applied Pulse: 1.2/50µs Applied Voltage: 2.5kVo-p												
6	Insulation Resistance (I.R.)	More than 6,000MΩ	The insulation resistance should be measured with DC500±50V and within 60±5 sec. of charging.												
7	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V(r.m.s.)												
8	Dissipation Factor (D.F.)	0.025 max.													
9	Capacitance Temperature Characteristics	Cap. Change within ±15% (Temp. Range: -55 to +125°C)	The capacitance measurement should be made at each step specified in the Table. <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±10°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4	Max. Operating Temp.±2	5	25±2
Step	Temperature (°C)														
1	25±2														
2	Min. Operating Temp.±3														
3	25±2														
4	Max. Operating Temp.±2														
5	25±2														
10	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.  <p style="text-align: center;">Fig. 1</p>												
11	Vibration Resistance	Appearance	No defects or abnormalities												
		Capacitance	Within the specified tolerance												
	D.F.	0.025 max.	The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.). 												

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. 

GR4 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																			
12	Deflection	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																			
		 <p>Fig. 2</p> <table border="1"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>4.5×2.0</td> <td>3.5</td> <td>7.0</td> <td>2.4</td> <td rowspan="3">1.0</td> </tr> <tr> <td>4.5×3.2</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>5.7×5.0</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table>		L×W (mm)	Dimension (mm)				a	b	c	d	4.5×2.0	3.5	7.0	2.4	1.0	4.5×3.2	3.5	7.0	3.7	5.7×5.0
L×W (mm)	Dimension (mm)																					
	a	b	c	d																		
4.5×2.0	3.5	7.0	2.4	1.0																		
4.5×3.2	3.5	7.0	3.7																			
5.7×5.0	4.5	8.0	5.6																			
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder																			
14	Resistance to Soldering Heat	Appearance	No marking defects																			
		Capacitance Change	Within ±10%																			
		D.F.	0.025 max.																			
		I.R.	More than 1,000MΩ																			
		Dielectric Strength	In accordance with item No.4																			
15	Temperature Cycle	Appearance	No marking defects																			
		Capacitance Change	Within ±15%																			
		D.F.	0.05 max.																			
		I.R.	More than 3,000MΩ																			
		Dielectric Strength	In accordance with item No.4																			
16	Humidity (Steady State)	Appearance	No marking defects																			
		Capacitance Change	Within ±15%																			
		D.F.	0.05 max.																			
		I.R.	More than 1,000MΩ																			
		Dielectric Strength	In accordance with item No.4																			

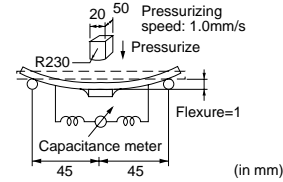


Fig. 3

Step	Temperature	Time
1	100 to 120°C	1 min.
2	170 to 200°C	1 min.

Step	Temperature (°C)	Time (min.)
1	Min. Operating Temp.±3	30±3
2	Room Temp.	2 to 3
3	Max. Operating Temp.±2	30±3
4	Room Temp.	2 to 3

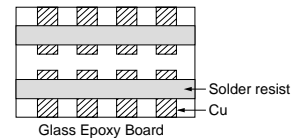


Fig. 4

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page.

For General Purpose
GRM/GRJ Series

Only for Applications
GR4 Series

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

GR4 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method
17	Life	Appearance	Apply 110% of the rated voltage for 1,000 ^{±48} hrs. at maximum operating temperature ±3°C. Remove and let sit for 24±2 hrs. at room condition,* then measure. The charge/discharge current is less than 50mA. •Pretreatment Apply test voltage for 60±5 min. at test temperature. Remove and let sit for 24±2 hrs. at room condition.*
		Capacitance Change	
		D.F.	
		I.R.	
		Dielectric Strength	
		No marking defects	
		Within ±20%	
		0.05 max.	
		More than 2,000MΩ	
		In accordance with item No.4	

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

For General Purpose
GRM/GRJ Series

Only for Applications
GR4 Series

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

Chip Monolithic Ceramic Capacitors (Medium Voltage)



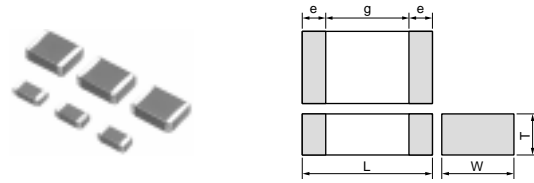
For Camera Flash Circuit GR7 Series

■ Features

1. Suitable for the trigger of the flash circuit, because real capacitance is stable during operating voltage.
2. The thin type fits thinner cameras.
3. Sn-plated external electrodes realize good solderability.
4. For flow and reflow soldering

■ Applications

For strobe circuit



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GR721A	2.0 ±0.2	1.25 ±0.2	1.0 +0, -0.3	0.3	0.7
GR721B			1.25 ±0.2		
GR731A	3.2 ±0.2	1.6 ±0.2	1.0 +0, -0.3		
GR731B			1.25 +0, -0.3		
GR731C			1.6 ±0.2		

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GR721AW0BB103KW01D	DC350	-	10000 ±10%	2.0	1.25	1.0	0.7	0.3 min.
GR731AW0BB103KW01D	DC350	-	10000 ±10%	3.2	1.6	1.0	1.2	0.3 min.
GR721AW0BB153KW01D	DC350	-	15000 ±10%	2.0	1.25	1.0	0.7	0.3 min.
GR731AW0BB153KW01D	DC350	-	15000 ±10%	3.2	1.6	1.0	1.2	0.3 min.
GR721BW0BB223KW03L	DC350	-	22000 ±10%	2.0	1.25	1.25	0.7	0.3 min.
GR731AW0BB223KW01D	DC350	-	22000 ±10%	3.2	1.6	1.0	1.2	0.3 min.
GR731BW0BB223KW01L	DC350	-	22000 ±10%	3.2	1.6	1.25	1.2	0.3 min.
GR721BW0BB273KW03L	DC350	-	27000 ±10%	2.0	1.25	1.25	0.7	0.3 min.
GR731AW0BB273KW01D	DC350	-	27000 ±10%	3.2	1.6	1.0	1.2	0.3 min.
GR731AW0BB333KW01D	DC350	-	33000 ±10%	3.2	1.6	1.0	1.2	0.3 min.
GR731BW0BB333KW01L	DC350	-	33000 ±10%	3.2	1.6	1.25	1.2	0.3 min.
GR731CW0BB473KW03L	DC350	-	47000 ±10%	3.2	1.6	1.6	1.2	0.3 min.

For General Purpose GRM/GRJ Series

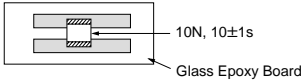
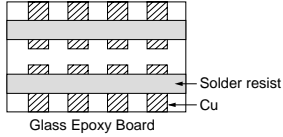
Only for Applications GR7 Series

AC250V Type GA2 Series


Safety Standard Certified GA3 Series

Product Information

GR7 Series Specifications and Test Methods

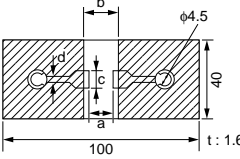
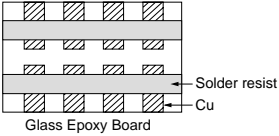
No.	Item	Specifications	Test Method									
1	Operating Temperature Range	-55 to +125°C	-									
2	Appearance	No defects or abnormalities	Visual inspection									
3	Dimensions	Within the specified dimensions	Using calipers and micrometers									
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when DC500V is applied between the terminations for 1 to 5 sec., provided the charge/discharge current is less than 50mA.									
5	Insulation Resistance (I.R.)	C ≥ 0.01μF: More than 100MΩ • μF C < 0.01μF: More than 10,000MΩ	The insulation resistance should be measured with DC250±50V and within 60±5 sec. of charging.									
6	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V(r.m.s.)									
7	Dissipation Factor (D.F.)	0.025 max.										
8	Capacitance Temperature Characteristics	Cap. Change Within ±10% (Apply DC350V bias) Within ±3% (No DC bias) (Temp. Range : -55 to +125°C)	The capacitance measurement should be made at each step specified in the Table.									
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±10°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4
Step	Temperature (°C)											
1	25±2											
2	Min. Operating Temp.±3											
3	25±2											
4	Max. Operating Temp.±2											
5	25±2											
9	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1.</p> <p>Then apply 10N force in the direction of the arrow.</p> <p>The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p>  <p>Fig. 1</p>									
10	Vibration Resistance	Appearance	No defects or abnormalities									
		Capacitance	Within the specified tolerance									
	D.F.	0.025 max.	<p>Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).</p> 									

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. 

GR7 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method															
11	Deflection	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.															
		 <p>Fig. 2</p> <table border="1"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>2.0×1.25</td> <td>1.2</td> <td>4.0</td> <td>1.65</td> <td rowspan="2">1.0</td> </tr> <tr> <td>3.2×1.6</td> <td>2.2</td> <td>5.0</td> <td>2.0</td> </tr> </tbody> </table>		L×W (mm)	Dimension (mm)				a	b	c	d	2.0×1.25	1.2	4.0	1.65	1.0	3.2×1.6
L×W (mm)	Dimension (mm)																	
	a	b	c	d														
2.0×1.25	1.2	4.0	1.65	1.0														
3.2×1.6	2.2	5.0	2.0															
12	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder															
13	Resistance to Soldering Heat	Appearance	No marking defects	Preheat the capacitor at 120 to 150°C for 1 min. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s •Pretreatment Perform a heat treatment at 150±1.8°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*														
		Capacitance Change	Within ±10%															
		D.F.	0.025 max.															
		I.R.	C≥0.01μF: More than 100MΩ • μF C<0.01μF: More than 10,000MΩ															
		Dielectric Strength	In accordance with item No.4															
14	Temperature Cycle	Appearance	No marking defects	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,* then measure.														
		Capacitance Change	Within ±7.5%															
		D.F.	0.025 max.															
		I.R.	C≥0.01μF: More than 100MΩ • μF C<0.01μF: More than 10,000MΩ															
		Dielectric Strength	In accordance with item No.4															
			<table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> <th>Time (min.)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min. Operating Temp.±3</td> <td>30±3</td> </tr> <tr> <td>2</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> <tr> <td>3</td> <td>Max. Operating Temp.±2</td> <td>30±3</td> </tr> <tr> <td>4</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±1.8°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>  <p>Fig. 4</p>	Step	Temperature (°C)	Time (min.)	1	Min. Operating Temp.±3	30±3	2	Room Temp.	2 to 3	3	Max. Operating Temp.±2	30±3	4	Room Temp.	2 to 3
Step	Temperature (°C)	Time (min.)																
1	Min. Operating Temp.±3	30±3																
2	Room Temp.	2 to 3																
3	Max. Operating Temp.±2	30±3																
4	Room Temp.	2 to 3																
15	Humidity (Steady State)	Appearance	No marking defects	Let the capacitor sit at 40±2°C and relative humidity of 90 to 95% for 500±24 hrs. Remove and let sit for 24±2 hrs. at room condition,* then measure. •Pretreatment Perform a heat treatment at 150±1.8°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*														
		Capacitance Change	Within ±15%															
		D.F.	0.05 max.															
		I.R.	C≥0.01μF: More than 10MΩ • μF C<0.01μF: More than 1,000MΩ															
		Dielectric Strength	In accordance with item No.4															

* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page.

For General Purpose
GRM/GRJ Series

Only for Applications
GR7 Series

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

GR7 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method
16	Life	Appearance	No marking defects
		Capacitance Change	Within $\pm 15\%$
		D.F.	0.05 max.
		I.R.	$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than $1,000\text{M}\Omega$
		Dielectric Strength	In accordance with item No.4
			Apply DC350V for $1,000^{+48}$ hrs. at maximum operating temperature $\pm 3^\circ\text{C}$. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. The charge/discharge current is less than 50mA. •Pretreatment Apply test voltage for 60 ± 5 min. at test temperature. Remove and let sit for 24 ± 2 hrs. at room condition.*
17	Humidity Loading	Appearance	No marking defects
		Capacitance Change	Within $\pm 15\%$
		D.F.	0.05 max.
		I.R.	$C \geq 0.01\mu\text{F}$: More than $10\text{M}\Omega \cdot \mu\text{F}$ $C < 0.01\mu\text{F}$: More than $1,000\text{M}\Omega$
		Dielectric Strength	In accordance with item No.4
			Apply the rated voltage at $40 \pm 2^\circ\text{C}$ and relative humidity of 90 to 95% for 500^{+24} hrs. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. •Pretreatment Apply test voltage for 60 ± 5 min. at test temperature. Remove and let sit for 24 ± 2 hrs. at room condition.*

* "Room condition" Temperature: 15 to 35°C , Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

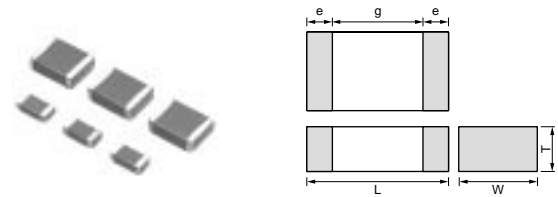
Chip Monolithic Ceramic Capacitors



AC250V Type (Which Meet Japanese Law) GA2 Series

■ Features

1. Chip monolithic ceramic capacitor for AC lines.
2. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
3. Sn-plated external electrodes realize good solderability.
4. Only for reflow soldering
5. Capacitance 0.01 to 0.1uF for connecting lines and 470 to 4700pF for connecting lines to earth.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GA242Q	4.5 ±0.3	2.0 ±0.2	1.5 +0, -0.3	0.3	2.5
GA243D	4.5 ±0.4	3.2 ±0.3	2.0 +0, -0.3		
GA243Q			1.5 +0, -0.3		
GA255D	5.7 ±0.4	5.0 ±0.4	2.0 +0, -0.3		3.2

■ Applications

Noise suppression filters for switching power supplies, telephones, facsimiles, modems.

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.

■ Reference Standard

GA2 series obtains no safety approval. This series is based on the standards of the electrical appliance and material safety law of Japan (separated table 4).

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA242QR7E2471MW01L	AC250 (r.m.s.)	X7R (EIA)	470pF ±20%	4.5	2.0	1.5	2.5	0.3 min.
GA242QR7E2102MW01L	AC250 (r.m.s.)	X7R (EIA)	1000pF ±20%	4.5	2.0	1.5	2.5	0.3 min.
GA243QR7E2222MW01L	AC250 (r.m.s.)	X7R (EIA)	2200pF ±20%	4.5	3.2	1.5	2.5	0.3 min.
GA243QR7E2332MW01L	AC250 (r.m.s.)	X7R (EIA)	3300pF ±20%	4.5	3.2	1.5	2.5	0.3 min.
GA243DR7E2472MW01L	AC250 (r.m.s.)	X7R (EIA)	4700pF ±20%	4.5	3.2	2.0	2.5	0.3 min.
GA243QR7E2103MW01L	AC250 (r.m.s.)	X7R (EIA)	10000pF ±20%	4.5	3.2	1.5	2.5	0.3 min.
GA243QR7E2223MW01L	AC250 (r.m.s.)	X7R (EIA)	22000pF ±20%	4.5	3.2	1.5	2.5	0.3 min.
GA243DR7E2473MW01L	AC250 (r.m.s.)	X7R (EIA)	47000pF ±20%	4.5	3.2	2.0	2.5	0.3 min.
GA255DR7E2104MW01L	AC250 (r.m.s.)	X7R (EIA)	0.10μF ±20%	5.7	5.0	2.0	3.2	0.3 min.

For General Purpose GRM/GRJ Series

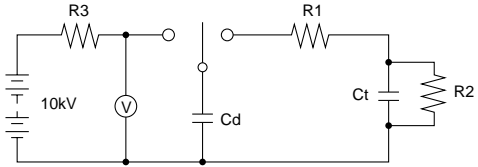
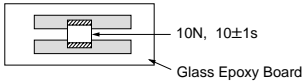
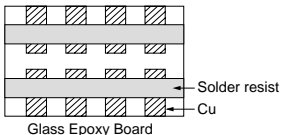
Only for Applications

AC250V Type GA2 Series


Safety Standard Certified GA3 Series

Product Information

GA2 Series Specifications and Test Methods

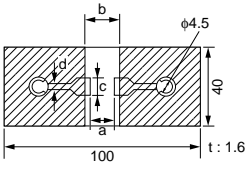
No.	Item	Specifications	Test Method												
1	Operating Temperature Range	-55 to +125°C	-												
2	Appearance	No defects or abnormalities	Visual inspection												
3	Dimensions	Within the specified dimensions	Using calipers and micrometers												
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when voltage in the table is applied between the terminations for 60±1 sec., provided the charge/discharge current is less than 50mA. <table border="1"> <thead> <tr> <th>Nominal Capacitance</th> <th>Test Voltage</th> </tr> </thead> <tbody> <tr> <td>C ≥ 10,000pF</td> <td>AC575V (r.m.s.)</td> </tr> <tr> <td>C < 10,000pF</td> <td>AC1500V (r.m.s.)</td> </tr> </tbody> </table>	Nominal Capacitance	Test Voltage	C ≥ 10,000pF	AC575V (r.m.s.)	C < 10,000pF	AC1500V (r.m.s.)						
Nominal Capacitance	Test Voltage														
C ≥ 10,000pF	AC575V (r.m.s.)														
C < 10,000pF	AC1500V (r.m.s.)														
5	Insulation Resistance (I.R.)	More than 2,000MΩ	The insulation resistance should be measured with DC500±50V and within 60±5 sec. of charging.												
6	Capacitance	Within the specified tolerance	The capacitance/D.F. should be measured at a frequency of 1±0.2kHz and a voltage of AC1±0.2V (r.m.s.)												
7	Dissipation Factor (D.F.)	0.025 max.													
8	Capacitance Temperature Characteristics	Cap. Change Within ±15% (Temp. Range: -55 to +125°C)	The capacitance measurement should be made at each step specified in the Table. <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2</td> </tr> </tbody> </table> <p>•Pretreatment Perform a heat treatment at 150±10°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*</p>	Step	Temperature (°C)	1	25±2	2	Min. Operating Temp.±3	3	25±2	4	Max. Operating Temp.±2	5	25±2
Step	Temperature (°C)														
1	25±2														
2	Min. Operating Temp.±3														
3	25±2														
4	Max. Operating Temp.±2														
5	25±2														
9	Discharge Test (Application: Nominal Capacitance C < 10,000pF)	Appearance	No defects or abnormalities <p>As in Fig., discharge is made 50 times at 5 sec. intervals from the capacitor (Cd) charged at DC voltage of specified.</p>  <p>Ct: Capacitor under test Cd: 0.001μF R1: 1,000Ω R2: 100MΩ R3: Surge resistance</p>												
10	Adhesive Strength of Termination	No removal of the terminations or other defects should occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.  <p>Fig. 1</p>												
11	Vibration Resistance	Appearance	No defects or abnormalities												
		Capacitance	Within the specified tolerance												
	D.F.	0.025 max.	The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).  <p>Glass Epoxy Board</p>												

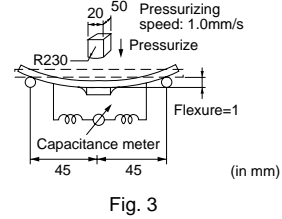
* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. 

GA2 Series Specifications and Test Methods

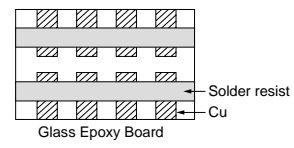
Continued from the preceding page.

No.	Item	Specifications	Test Method																			
12	Deflection	No marking defects	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2. Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.																			
		<div style="text-align: center;">  <p>Fig. 2</p> <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th rowspan="2">L×W (mm)</th> <th colspan="4">Dimension (mm)</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>4.5×2.0</td> <td>3.5</td> <td>7.0</td> <td>2.4</td> <td rowspan="3" style="text-align: center;">1.0</td> </tr> <tr> <td>4.5×3.2</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> </tr> <tr> <td>5.7×5.0</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> </tr> </tbody> </table> </div>		L×W (mm)	Dimension (mm)				a	b	c	d	4.5×2.0	3.5	7.0	2.4	1.0	4.5×3.2	3.5	7.0	3.7	5.7×5.0
L×W (mm)	Dimension (mm)																					
	a	b	c	d																		
4.5×2.0	3.5	7.0	2.4	1.0																		
4.5×3.2	3.5	7.0	3.7																			
5.7×5.0	4.5	8.0	5.6																			
13	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec. Immersing speed: 25±2.5mm/s Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder																			
14	Humidity Insulation	Appearance	The capacitor should be subjected to 40±2°C, relative humidity of 90 to 98% for 8 hrs., and then removed in room condition* for 16 hrs. until 5 cycles.																			
		Capacitance Change																				
		D.F.																				
		I.R.																				
		Dielectric Strength																				
15	Resistance to Soldering Heat	Appearance	Preheat the capacitor as in table. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition* for 24±2 hrs., then measure. •Immersing speed: 25±2.5mm/s •Pretreatment Perform a heat treatment at 150±10°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.* *Preheating																			
		Capacitance Change																				
		D.F.																				
		I.R.																				
		Dielectric Strength																				
16	Temperature Cycle	Appearance	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,* then measure.																			
		Capacitance Change																				
		D.F.																				
		I.R.																				
		Dielectric Strength																				



Step	Temperature	Time
1	100 to 120°C	1 min.
2	170 to 200°C	1 min.

Step	Temperature (°C)	Time (min.)
1	Min. Operating Temp.±3	30±3
2	Room Temp.	2 to 3
3	Max. Operating Temp.±2	30±3
4	Room Temp.	2 to 3



* "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Continued on the following page. ↗

For General Purpose GRM/GRJ Series
 Only for Applications
 AC250V Type GA2 Series
 Safety Standard Certified GA3 Series
 Product Information

GA2 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method									
17	Humidity (Steady State)	Appearance	No marking defects									
		Capacitance Change	Within $\pm 15\%$									
		D.F.	0.05 max.									
		I.R.	More than 1,000M Ω									
		Dielectric Strength	In accordance with item No.4									
			Let the capacitor sit at $40\pm 2^\circ\text{C}$ and relative humidity of 90 to 95% for 500^{+24}_{-8} hrs. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. •Pretreatment Perform a heat treatment at $150\pm 3^\circ\text{C}$ for 60 ± 5 min. and then let sit for 24 ± 2 hrs. at room condition.*									
18	Life	Appearance	No marking defects									
		Capacitance Change	Within $\pm 20\%$									
		D.F.	0.05 max.									
		I.R.	More than 1,000M Ω									
		Dielectric Strength	In accordance with item No.4									
			Apply voltage and time as in Table at maximum operating temperature $\pm 3^\circ\text{C}$. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. The charge / discharge current is less than 50mA. <table border="1" style="margin-left: auto; margin-right: auto;"> <thead> <tr> <th>Nominal Capacitance</th> <th>Test Time</th> <th>Test Voltage</th> </tr> </thead> <tbody> <tr> <td>$C \geq 10,000\text{pF}$</td> <td>$1,000^{+48}_{-8}$ hrs.</td> <td>AC300V (r.m.s.)</td> </tr> <tr> <td>$C < 10,000\text{pF}$</td> <td>$1,500^{+48}_{-8}$ hrs.</td> <td>AC500V (r.m.s.)*</td> </tr> </tbody> </table> * Except that once each hour the voltage is increased to AC1,000V (r.m.s.) for 0.1 sec. •Pretreatment Apply test voltage for 60 ± 5 min. at test temperature. Remove and let sit for 24 ± 2 hrs. at room condition.*	Nominal Capacitance	Test Time	Test Voltage	$C \geq 10,000\text{pF}$	$1,000^{+48}_{-8}$ hrs.	AC300V (r.m.s.)	$C < 10,000\text{pF}$	$1,500^{+48}_{-8}$ hrs.	AC500V (r.m.s.)*
Nominal Capacitance	Test Time	Test Voltage										
$C \geq 10,000\text{pF}$	$1,000^{+48}_{-8}$ hrs.	AC300V (r.m.s.)										
$C < 10,000\text{pF}$	$1,500^{+48}_{-8}$ hrs.	AC500V (r.m.s.)*										
19	Humidity Loading	Appearance	No marking defects									
		Capacitance Change	Within $\pm 15\%$									
		D.F.	0.05 max.									
		I.R.	More than 1,000M Ω									
		Dielectric Strength	In accordance with item No.4									
			Apply the rated voltage at $40\pm 2^\circ\text{C}$ and relative humidity of 90 to 95% for 500^{+24}_{-8} hrs. Remove and let sit for 24 ± 2 hrs. at room condition,* then measure. •Pretreatment Apply test voltage for 60 ± 5 min. at test temperature. Remove and let sit for 24 ± 2 hrs. at room condition.*									

* "Room condition" Temperature: 15 to 35 $^\circ\text{C}$, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

Chip Monolithic Ceramic Capacitors



Safety Standard Certified GA3 Series UL, IEC60384-14 Class X1/Y2 Type GC

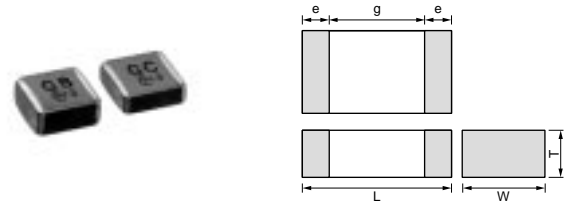
■ Features

1. Chip monolithic ceramic capacitor (certified as conforming to safety standards) for AC lines.
2. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
3. Compared to lead type capacitors, this new capacitor is greatly downsized and low-profiled to 1/10 or less in volume, and 1/4 or less in height.
4. Type GC can be used as an X1-class and Y2-class capacitor, line-by-pass capacitor of UL1414.
5. +125 degree C guaranteed
6. Only for reflow soldering

■ Applications

1. Ideal for use as Y capacitor or X capacitor for various switching power supplies
2. Ideal for modem applications

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GA355D	5.7 ±0.4	5.0 ±0.4	2.0 ±0.3	0.3	4.0

■ Standard Certification

	Standard No.	Class	Rated Voltage
UL	UL1414	Line By-pass	AC250V (r.m.s.)
VDE	IEC 60384-14 EN 60384-14	X1, Y2	
BSI	EN 60065 (14.2) IEC 60384-14 EN 60384-14		
SEMKO	IEC 60384-14 EN 60384-14		
ESTI	EN 60065 IEC 60384-14		

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA355DR7GC101KY02L	AC250 (r.m.s.)	X7R (EIA)	100 ±10%	5.7	5.0	2.0	4.0	0.3 min.
GA355DR7GC151KY02L	AC250 (r.m.s.)	X7R (EIA)	150 ±10%	5.7	5.0	2.0	4.0	0.3 min.
GA355DR7GC221KY02L	AC250 (r.m.s.)	X7R (EIA)	220 ±10%	5.7	5.0	2.0	4.0	0.3 min.
GA355DR7GC331KY02L	AC250 (r.m.s.)	X7R (EIA)	330 ±10%	5.7	5.0	2.0	4.0	0.3 min.

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

Chip Monolithic Ceramic Capacitors



Safety Standard Certified GA3 Series IEC60384-14 Class Y2, X1/Y2 Type GF

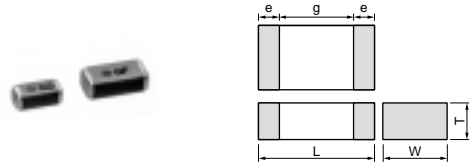
■ Features

1. Available for equipment based on IEC/EN60950 and UL1950. Besides, the GA352/355 types are available for equipment based on IEC/EN60065, UL1492, and UL6500.
2. Type GF can be used as a Y2-class capacitor.
3. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
4. +125 degree C guaranteed
5. Only for reflow soldering

■ Applications

1. Ideal for use on line filters and couplings for DAA modems without transformers
2. Ideal for use on line filters for information equipment
3. Ideal for use as Y capacitor or X capacitor for various switching power supplies (GA352/355 types only)

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)					
	L	W	T	e min.	g min.	
GA342A	4.5 ±0.3	2.0 ±0.2	1.0 +0, -0.3	0.3	2.5	
GA342D			2.0 ±0.2			
GA342Q			1.5 +0, -0.3			
GA352Q	5.7 ±0.4	2.8 ±0.3	1.5 +0, -0.3			4.0
GA355D			2.0 +0, -0.3			
GA355Q			1.5 +0, -0.3			

■ Standard Certification

	Standard No.	Class	Status of Certification		Rated Voltage
			Size : 4.5x2.0mm	Size : 5.7x2.8mm and over	
UL	UL1414	X1, Y2	—	⊙	AC250V (r.m.s.)
	UL 60950-1	—	⊙	—	
VDE	IEC 60384-14	X1, Y2	—	⊙	
SEMKO	EN 60384-14	Y2	⊙	⊙	

Applications

Size	Switching power supplies	Communication network devices such as a modem
4.5x2.0mm	—	⊙
5.7x2.8mm and over	⊙	⊙

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA342D1XGF100JY02L	AC250 (r.m.s.)	SL (JIS)	10 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGF120JY02L	AC250 (r.m.s.)	SL (JIS)	12 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGF150JY02L	AC250 (r.m.s.)	SL (JIS)	15 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGF180JY02L	AC250 (r.m.s.)	SL (JIS)	18 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGF220JY02L	AC250 (r.m.s.)	SL (JIS)	22 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342A1XGF270JW31L	AC250 (r.m.s.)	SL (JIS)	27 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF330JW31L	AC250 (r.m.s.)	SL (JIS)	33 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF390JW31L	AC250 (r.m.s.)	SL (JIS)	39 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF470JW31L	AC250 (r.m.s.)	SL (JIS)	47 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF560JW31L	AC250 (r.m.s.)	SL (JIS)	56 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF680JW31L	AC250 (r.m.s.)	SL (JIS)	68 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGF820JW31L	AC250 (r.m.s.)	SL (JIS)	82 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342QR7GF101KW01L	AC250 (r.m.s.)	X7R (EIA)	100 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GF151KW01L	AC250 (r.m.s.)	X7R (EIA)	150 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342DR7GF221KW02L	AC250 (r.m.s.)	X7R (EIA)	220 ±10%	4.5	2.0	2.0	2.5	0.3 min.
GA342DR7GF331KW02L	AC250 (r.m.s.)	X7R (EIA)	330 ±10%	4.5	2.0	2.0	2.5	0.3 min.
GA342QR7GF471KW01L	AC250 (r.m.s.)	X7R (EIA)	470 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA352QR7GF471KW01L	AC250 (r.m.s.)	X7R (EIA)	470 ±10%	5.7	2.8	1.5	4.0	0.3 min.
GA342QR7GF681KW01L	AC250 (r.m.s.)	X7R (EIA)	680 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA352QR7GF681KW01L	AC250 (r.m.s.)	X7R (EIA)	680 ±10%	5.7	2.8	1.5	4.0	0.3 min.
GA342DR7GF102KW02L	AC250 (r.m.s.)	X7R (EIA)	1000 ±10%	4.5	2.0	2.0	2.5	0.3 min.
GA352QR7GF102KW01L	AC250 (r.m.s.)	X7R (EIA)	1000 ±10%	5.7	2.8	1.5	4.0	0.3 min.

Continued on the following page. ↗

Continued from the preceding page.

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA352QR7GF152KW01L	AC250 (r.m.s.)	X7R (EIA)	1500 ±10%	5.7	2.8	1.5	4.0	0.3 min.
GA355QR7GF182KW01L	AC250 (r.m.s.)	X7R (EIA)	1800 ±10%	5.7	5.0	1.5	4.0	0.3 min.
GA355QR7GF222KW01L	AC250 (r.m.s.)	X7R (EIA)	2200 ±10%	5.7	5.0	1.5	4.0	0.3 min.
GA355QR7GF332KW01L	AC250 (r.m.s.)	X7R (EIA)	3300 ±10%	5.7	5.0	1.5	4.0	0.3 min.
GA355DR7GF472KW01L	AC250 (r.m.s.)	X7R (EIA)	4700 ±10%	5.7	5.0	2.0	4.0	0.3 min.

For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information

Chip Monolithic Ceramic Capacitors



Safety Standard Certified GA3 Series IEC60384-14 Class Y3 Type GD

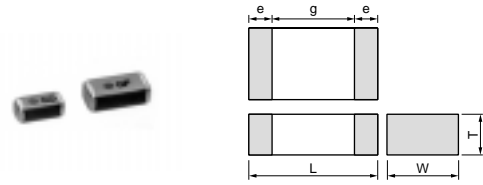
■ Features

1. Available for equipment based on IEC/EN60950 and UL1950.
2. Type GD can be used as a Y3-class capacitor.
3. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
4. +125 degree C guaranteed
5. Only for reflow soldering

■ Applications

1. Ideal for use on line filters and couplings for DAA modems without transformers
2. Ideal for use on line filters for information equipment

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GA342A	4.5 ±0.3	2.0 ±0.2	1.0 +0, -0.3	0.3	2.5
GA342D			2.0 ±0.2		
GA342Q			1.5 +0, -0.3		
GA343D	4.5 ±0.4	3.2 ±0.3	2.0 +0, -0.3		
GA343Q			1.5 +0, -0.3		

■ Standard Certification

	Standard No.	Class	Rated Voltage
UL	UL 60950-1	Y3	AC250V(r.m.s.)
SEMKO	IEC 60384-14 EN 60384-14		

Applications

Size	Switching power supplies	Communication network devices such as a modem
4.5×3.2mm and under	—	◎

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA342D1XGD100JY02L	AC250 (r.m.s.)	SL (JIS)	10 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGD120JY02L	AC250 (r.m.s.)	SL (JIS)	12 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGD150JY02L	AC250 (r.m.s.)	SL (JIS)	15 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGD180JY02L	AC250 (r.m.s.)	SL (JIS)	18 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342D1XGD220JY02L	AC250 (r.m.s.)	SL (JIS)	22 ±5%	4.5	2.0	2.0	2.5	0.3 min.
GA342A1XGD270JW31L	AC250 (r.m.s.)	SL (JIS)	27 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD330JW31L	AC250 (r.m.s.)	SL (JIS)	33 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD390JW31L	AC250 (r.m.s.)	SL (JIS)	39 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD470JW31L	AC250 (r.m.s.)	SL (JIS)	47 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD560JW31L	AC250 (r.m.s.)	SL (JIS)	56 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD680JW31L	AC250 (r.m.s.)	SL (JIS)	68 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342A1XGD820JW31L	AC250 (r.m.s.)	SL (JIS)	82 ±5%	4.5	2.0	1.0	2.5	0.3 min.
GA342QR7GD101KW01L	AC250 (r.m.s.)	X7R (EIA)	100 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD151KW01L	AC250 (r.m.s.)	X7R (EIA)	150 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD221KW01L	AC250 (r.m.s.)	X7R (EIA)	220 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD331KW01L	AC250 (r.m.s.)	X7R (EIA)	330 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD471KW01L	AC250 (r.m.s.)	X7R (EIA)	470 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD681KW01L	AC250 (r.m.s.)	X7R (EIA)	680 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD102KW01L	AC250 (r.m.s.)	X7R (EIA)	1000 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA342QR7GD152KW01L	AC250 (r.m.s.)	X7R (EIA)	1500 ±10%	4.5	2.0	1.5	2.5	0.3 min.
GA343QR7GD182KW01L	AC250 (r.m.s.)	X7R (EIA)	1800 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GA343QR7GD222KW01L	AC250 (r.m.s.)	X7R (EIA)	2200 ±10%	4.5	3.2	1.5	2.5	0.3 min.
GA343DR7GD472KW01L	AC250 (r.m.s.)	X7R (EIA)	4700 ±10%	4.5	3.2	2.0	2.5	0.3 min.

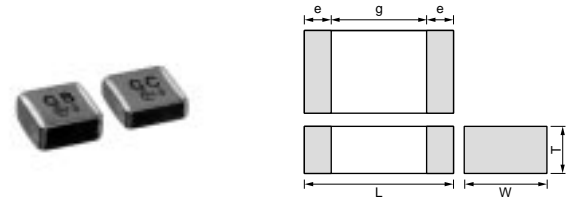
Chip Monolithic Ceramic Capacitors



Safety Standard Certified GA3 Series IEC60384-14 Class X2 Type GB

■ Features

1. Type GB can be used as an X2-class capacitor.
2. Chip monolithic ceramic capacitor (certified as conforming to safety standards) for AC lines.
3. A new monolithic structure for small, high capacitance capable of operating at high voltage levels.
4. Compared to lead type capacitors, this new capacitor is greatly downsized and low-profiled to 1/10 or less in volume, and 1/4 or less in height.
5. +125 degree C guaranteed
6. Only for reflow soldering



Part Number	Dimensions (mm)				
	L	W	T	e min.	g min.
GA355Q	5.7 ±0.4	5.0 ±0.4	1.5 +0,-0.3	0.3	3.0
GA355D			2.0 +0,-0.3		
GA355E			2.5 +0,-0.3		
GA355X			2.9 +0,-0.4		

■ Applications

Ideal for use as X capacitor for various switching power supplies

Do not use these products in any Automotive Power train or Safety equipment including Battery chargers for Electric Vehicles and Plug-in Hybrids. Only Murata products clearly stipulated as "for Automotive use" can be used for automobile applications such as Power train and Safety equipment.

■ Standard Certification

	Standard No.	Class	Rated Voltage
VDE	IEC 60384-14 EN 60384-14	X2	AC250V (r.m.s.)
SEMKO			
ESTI			

Part Number	Rated Voltage (V)	TC Code (Standard)	Capacitance (pF)	Length L (mm)	Width W (mm)	Thickness T (mm)	Electrode g min. (mm)	Electrode e (mm)
GA355QR7GB103KW01L	AC250 (r.m.s.)	X7R (EIA)	10000 ±10%	5.7	5.0	1.5	3.0	0.3 min.
GA355QR7GB153KW01L	AC250 (r.m.s.)	X7R (EIA)	15000 ±10%	5.7	5.0	1.5	3.0	0.3 min.
GA355DR7GB223KW01L	AC250 (r.m.s.)	X7R (EIA)	22000 ±10%	5.7	5.0	2.0	3.0	0.3 min.
GA355ER7GB333KW01L	AC250 (r.m.s.)	X7R (EIA)	33000 ±10%	5.7	5.0	2.5	3.0	0.3 min.
GA355ER7GB473KW01L	AC250 (r.m.s.)	X7R (EIA)	47000 ±10%	5.7	5.0	2.5	3.0	0.3 min.
GA355XR7GB563KW06L	AC250 (r.m.s.)	X7R (EIA)	56000 ±10%	5.7	5.0	2.9	3.0	0.3 min.

For General Purpose GRM/GRJ Series

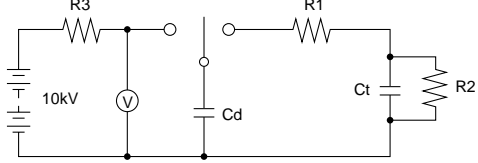
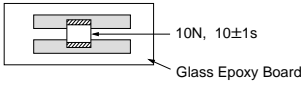
Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GA3 Series Specifications and Test Methods

No.	Item	Specifications	Test Method																				
1	Operating Temperature Range	-55 to +125°C	-																				
2	Appearance	No defects or abnormalities	Visual inspection																				
3	Dimensions	Within the specified dimensions	Using calipers and micrometers																				
4	Dielectric Strength	No defects or abnormalities	No failure should be observed when voltage in the table is applied between the terminations for 60±1 sec., provided the charge/discharge current is less than 50mA. <table border="1"> <thead> <tr> <th></th> <th>Test Voltage</th> </tr> </thead> <tbody> <tr> <td>Type GB</td> <td>DC1075V</td> </tr> <tr> <td>Type GC/GD</td> <td>AC1500V (r.m.s.)</td> </tr> <tr> <td>Type GF</td> <td>AC2000V (r.m.s.)</td> </tr> </tbody> </table>		Test Voltage	Type GB	DC1075V	Type GC/GD	AC1500V (r.m.s.)	Type GF	AC2000V (r.m.s.)												
	Test Voltage																						
Type GB	DC1075V																						
Type GC/GD	AC1500V (r.m.s.)																						
Type GF	AC2000V (r.m.s.)																						
5	Pulse Voltage (Application: Type GD/GF)	No self healing breakdowns or flash-overs have taken place in the capacitor.	10 impulses of alternating polarity are subjected. (5 impulses for each polarity) The interval between impulses is 60 sec. Applied Pulse: 1.2/50µs Applied Voltage: 2.5kVo-p																				
6	Insulation Resistance (I.R.)	More than 6,000MΩ	The insulation resistance should be measured with DC500±50V and within 60±5 sec. of charging.																				
7	Capacitance	Within the specified tolerance																					
8	Dissipation Factor (D.F.) Q	<table border="1"> <thead> <tr> <th>Char.</th> <th>Specification</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>D.F. ≤ 0.025</td> </tr> <tr> <td rowspan="2">SL</td> <td>Q ≥ 400+20C*2 (C < 30pF)</td> </tr> <tr> <td>Q ≥ 1000 (C ≥ 30pF)</td> </tr> </tbody> </table>	Char.	Specification	X7R	D.F. ≤ 0.025	SL	Q ≥ 400+20C*2 (C < 30pF)	Q ≥ 1000 (C ≥ 30pF)	The capacitance/Q/D.F. should be measured at a frequency of 1±0.2kHz (SL char.: 1±0.2MHz) and a voltage of AC1±0.2V (r.m.s.)													
Char.	Specification																						
X7R	D.F. ≤ 0.025																						
SL	Q ≥ 400+20C*2 (C < 30pF)																						
	Q ≥ 1000 (C ≥ 30pF)																						
9	Capacitance Temperature Characteristics	<table border="1"> <thead> <tr> <th>Char.</th> <th>Capacitance Change</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>Within ±15%</td> </tr> </tbody> </table> Temperature characteristic guarantee is -55 to +125°C <table border="1"> <thead> <tr> <th>Char.</th> <th>Temperature Coefficient</th> </tr> </thead> <tbody> <tr> <td>SL</td> <td>+350 to -1000ppm/°C</td> </tr> </tbody> </table> Temperature characteristic guarantee is +20 to +85°C	Char.	Capacitance Change	X7R	Within ±15%	Char.	Temperature Coefficient	SL	+350 to -1000ppm/°C	The capacitance measurement should be made at each step specified in the Table. <table border="1"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>25±2 (20±2 for SL char.)</td> </tr> <tr> <td>2</td> <td>Min. Operating Temp.±3</td> </tr> <tr> <td>3</td> <td>25±2 (20±2 for SL char.)</td> </tr> <tr> <td>4</td> <td>Max. Operating Temp.±2</td> </tr> <tr> <td>5</td> <td>25±2 (20±2 for SL char.)</td> </tr> </tbody> </table> SL char. : The capacitance should be measured at even 85°C between step 3 and step 4. •Pretreatment for X7R char. Perform a heat treatment at 150±18°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*1	Step	Temperature (°C)	1	25±2 (20±2 for SL char.)	2	Min. Operating Temp.±3	3	25±2 (20±2 for SL char.)	4	Max. Operating Temp.±2	5	25±2 (20±2 for SL char.)
Char.	Capacitance Change																						
X7R	Within ±15%																						
Char.	Temperature Coefficient																						
SL	+350 to -1000ppm/°C																						
Step	Temperature (°C)																						
1	25±2 (20±2 for SL char.)																						
2	Min. Operating Temp.±3																						
3	25±2 (20±2 for SL char.)																						
4	Max. Operating Temp.±2																						
5	25±2 (20±2 for SL char.)																						
10	Appearance	No defects or abnormalities	As in Fig., discharge is made 50 times at 5 sec. intervals from the capacitor (Cd) charged at DC voltage of specified.  Ct: Capacitor under test Cd: 0.001µF R1: 1,000Ω R2: 100MΩ R3: Surge resistance																				
	I.R.	More than 1,000MΩ																					
	Dielectric Strength	In accordance with item No.4																					
11	Adhesive Strength of Termination	No removal of the terminations or other defect should occur.	Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 1. Then apply 10N force in the direction of the arrow. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.  Fig. 1																				

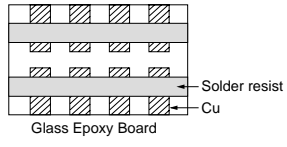
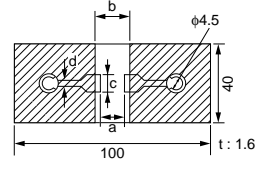
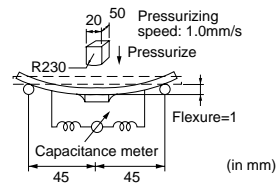
*1 "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

*2 "C" expresses nominal capacitance value (pF).

Continued on the following page. ↗

GA3 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method																														
12	Appearance	No defects or abnormalities	Solder the capacitor to the test jig (glass epoxy board). The capacitor should be subjected to a simple harmonic motion having a total amplitude of 1.5mm, the frequency being varied uniformly between the approximate limits of 10 and 55Hz. The frequency range, from 10 to 55Hz and return to 10Hz, should be traversed in approximately 1 min. This motion should be applied for a period of 2 hrs. in each of 3 mutually perpendicular directions (total of 6 hrs.).																														
	Capacitance	Within the specified tolerance																															
12	D.F. Q	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="width: 20%;">Char.</th> <th style="width: 80%;">Specification</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>D.F. ≤ 0.025</td> </tr> <tr> <td>SL</td> <td>Q ≥ 400 + 20C*2 (C < 30pF) Q ≥ 1000 (C ≥ 30pF)</td> </tr> </tbody> </table>	Char.	Specification	X7R	D.F. ≤ 0.025	SL	Q ≥ 400 + 20C*2 (C < 30pF) Q ≥ 1000 (C ≥ 30pF)																									
		Char.	Specification																														
X7R	D.F. ≤ 0.025																																
SL	Q ≥ 400 + 20C*2 (C < 30pF) Q ≥ 1000 (C ≥ 30pF)																																
13	Deflection	<p>No marking defects</p>  <p style="text-align: center;">Fig. 2</p> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th rowspan="2">LxW (mm)</th> <th colspan="4">Dimension (mm)</th> <th rowspan="2">1.0</th> </tr> <tr> <th>a</th> <th>b</th> <th>c</th> <th>d</th> </tr> </thead> <tbody> <tr> <td>4.5x2.0</td> <td>3.5</td> <td>7.0</td> <td>2.4</td> <td></td> </tr> <tr> <td>4.5x3.2</td> <td>3.5</td> <td>7.0</td> <td>3.7</td> <td></td> </tr> <tr> <td>5.7x2.8</td> <td>4.5</td> <td>8.0</td> <td>3.2</td> <td></td> </tr> <tr> <td>5.7x5.0</td> <td>4.5</td> <td>8.0</td> <td>5.6</td> <td></td> </tr> </tbody> </table>	LxW (mm)	Dimension (mm)				1.0	a	b	c	d	4.5x2.0	3.5	7.0	2.4		4.5x3.2	3.5	7.0	3.7		5.7x2.8	4.5	8.0	3.2		5.7x5.0	4.5	8.0	5.6		<p>Solder the capacitor to the testing jig (glass epoxy board) shown in Fig. 2.</p> <p>Then apply a force in the direction shown in Fig. 3. The soldering should be done using the reflow method and should be conducted with care so that the soldering is uniform and free of defects such as heat shock.</p>  <p style="text-align: center;">Fig. 3</p>
LxW (mm)	Dimension (mm)				1.0																												
	a	b	c	d																													
4.5x2.0	3.5	7.0	2.4																														
4.5x3.2	3.5	7.0	3.7																														
5.7x2.8	4.5	8.0	3.2																														
5.7x5.0	4.5	8.0	5.6																														
14	Solderability of Termination	75% of the terminations are to be soldered evenly and continuously.	<p>Immerse the capacitor in a solution of ethanol (JIS-K-8101) and rosin (JIS-K-5902) (25% rosin in weight proportion). Immerse in solder solution for 2±0.5 sec.</p> <p>Immersing speed: 25±2.5mm/s</p> <p>Temp. of solder: 245±5°C Lead Free Solder (Sn-3.0Ag-0.5Cu) 235±5°C H60A or H63A Eutectic Solder</p>																														
15	Appearance	No marking defects	<p>Preheat the capacitor as in table. Immerse the capacitor in solder solution at 260±5°C for 10±1 sec. Let sit at room condition*1 for 24±2 hrs., then measure.</p> <ul style="list-style-type: none"> Immersing speed: 25±2.5mm/s Pretreatment for X7R char. <p>Perform a heat treatment at 150±10°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*1</p> <p>*Preheating</p> <table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th>Step</th> <th>Temperature</th> <th>Time</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>100 to 120°C</td> <td>1 min.</td> </tr> <tr> <td>2</td> <td>170 to 200°C</td> <td>1 min.</td> </tr> </tbody> </table>	Step	Temperature	Time	1	100 to 120°C	1 min.	2	170 to 200°C	1 min.																					
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Resistance to Soldering Heat	<table border="1" style="width: 100%; border-collapse: collapse;"> <thead> <tr> <th style="width: 20%;">Char.</th> <th style="width: 80%;">Capacitance Change</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>Within ±10%</td> </tr> <tr> <td>SL</td> <td>Within ±2.5% or ±0.25pF (Whichever is larger)</td> </tr> </tbody> </table>	Char.	Capacitance Change	X7R	Within ±10%	SL	Within ±2.5% or ±0.25pF (Whichever is larger)																										
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*1 "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

*2 "C" expresses nominal capacitance value (pF).

Continued on the following page.

For General Purpose GRM/GRJ Series

Only for Applications

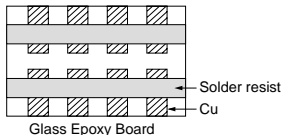
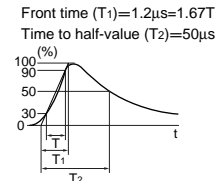
AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information

GA3 Series Specifications and Test Methods

Continued from the preceding page.

No.	Item	Specifications	Test Method															
16	Appearance	No marking defects	Fix the capacitor to the supporting jig (glass epoxy board) shown in Fig. 4. Perform the 5 cycles according to the 4 heat treatments listed in the following table. Let sit for 24±2 hrs. at room condition,*1 then measure. <table border="1" style="margin: 10px auto;"> <thead> <tr> <th>Step</th> <th>Temperature (°C)</th> <th>Time (min.)</th> </tr> </thead> <tbody> <tr> <td>1</td> <td>Min. Operating Temp.±3</td> <td>30±3</td> </tr> <tr> <td>2</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> <tr> <td>3</td> <td>Max. Operating Temp.±2</td> <td>30±3</td> </tr> <tr> <td>4</td> <td>Room Temp.</td> <td>2 to 3</td> </tr> </tbody> </table> <p>•Pretreatment for X7R char. Perform a heat treatment at 150±1°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*1</p>  <p style="text-align: center;">Fig. 4</p>	Step	Temperature (°C)	Time (min.)	1	Min. Operating Temp.±3	30±3	2	Room Temp.	2 to 3	3	Max. Operating Temp.±2	30±3	4	Room Temp.	2 to 3
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I.R.	More than 3,000MΩ																	
Dielectric Strength	In accordance with item No.4																	
17	Appearance	No marking defects	Before this test, the test shown in the following is performed. -Item 11 Adhesive Strength of Termination (applied force is 5N) -Item 13 Deflection Let the capacitor sit at 40±2°C and relative humidity of 90 to 95% for 500±24 hrs. Remove and let sit for 24±2 hrs. at room condition,*1 then measure. •Pretreatment for X7R char. Perform a heat treatment at 150±1°C for 60±5 min. and then let sit for 24±2 hrs. at room condition.*1															
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18	Appearance	No marking defects	Before this test, the test shown in the following is performed. -Item 11 Adhesive Strength of Termination (apply force is 5N) -Item 13 Deflection Impulse Voltage Each individual capacitor should be subjected to a 2.5kV (Type GC/GF: 5kV) Impulse (the voltage value means zero to peak) for three times. Then the capacitors are applied to life test.  <p style="font-size: small;">Front time (T1)=1.2μs=1.67T Time to half-value (T2)=50μs</p>															
	Capacitance Change	<table border="1" style="width: 100%;"> <thead> <tr> <th>Char.</th> <th>Capacitance Change</th> </tr> </thead> <tbody> <tr> <td>X7R</td> <td>Within ±20%</td> </tr> <tr> <td>SL</td> <td>Within ±3.0% or ±0.3pF (Whichever is larger)</td> </tr> </tbody> </table>		Char.	Capacitance Change	X7R	Within ±20%	SL	Within ±3.0% or ±0.3pF (Whichever is larger)									
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*1 "Room condition" Temperature: 15 to 35°C, Relative humidity: 45 to 75%, Atmospheric pressure: 86 to 106kPa

*2 "C" expresses nominal capacitance value (pF).

Continued on the following page.

GRM/GRJ/GR4/GR7/GA2/GA3 Series Reference Data (Typical Example)

For General Purpose
GRM/GRJ Series

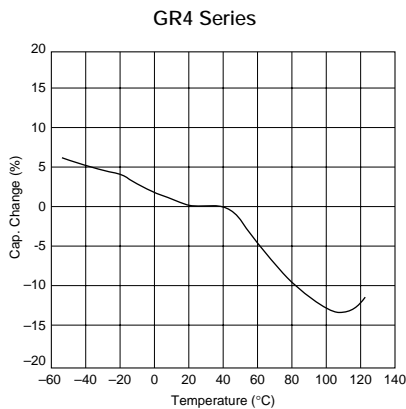
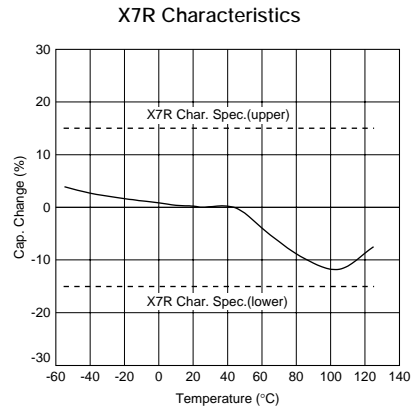
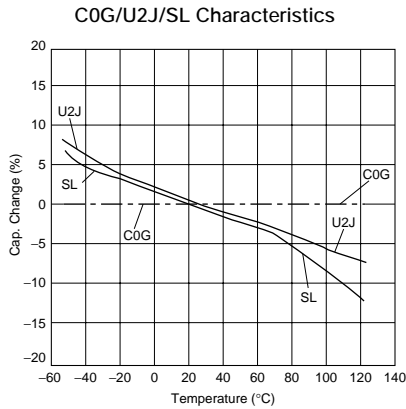
Only for Applications

AC250V Type
GA2 Series

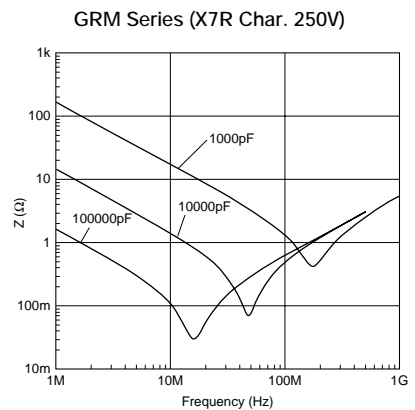
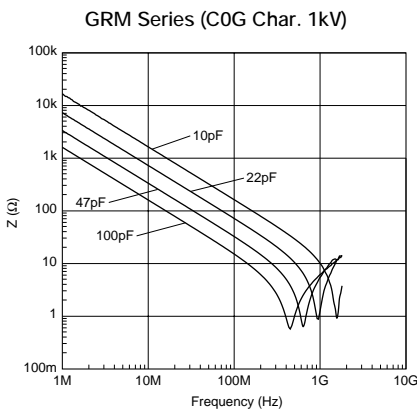
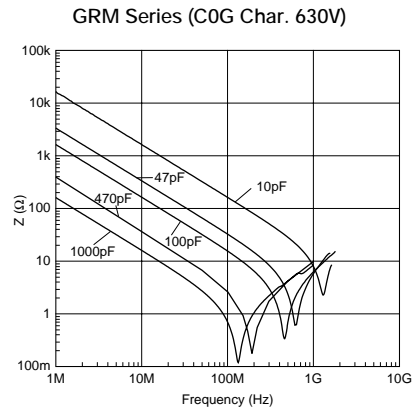
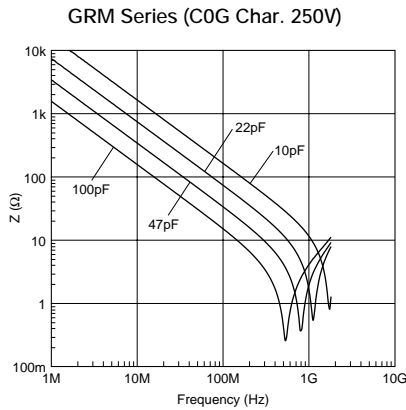
Safety Standard
Certified GA3 Series

Product Information
Reference Data

Capacitance - Temperature Characteristics



Impedance - Frequency Characteristics



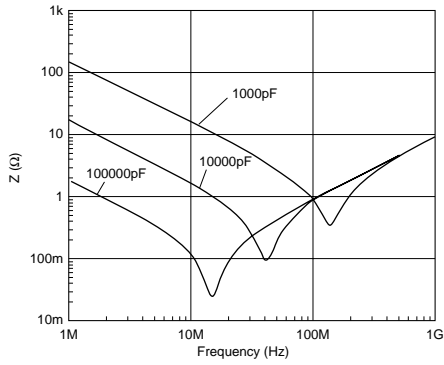
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GRM/GRJ/GR4/GR7/GA2/GA3 Series Reference Data (Typical Example)

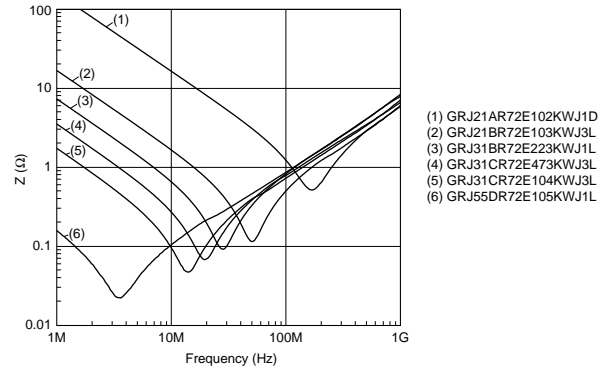
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Impedance - Frequency Characteristics

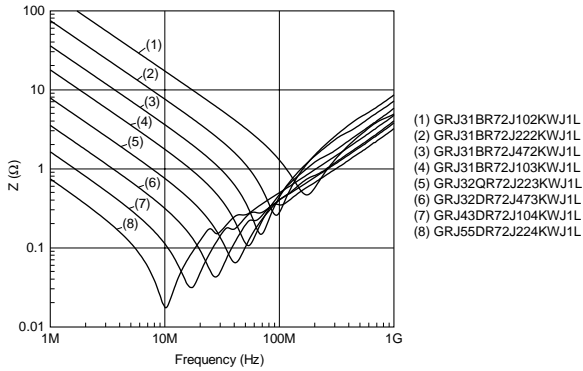
GRM Series (X7R Char. 630V)



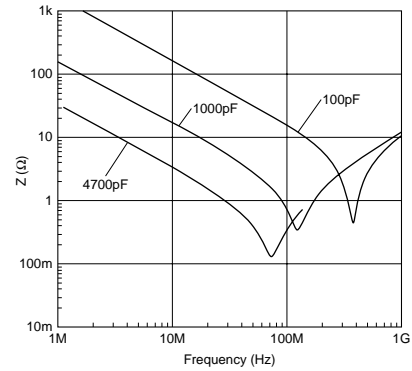
GRJ Series (X7R Char. 250V)



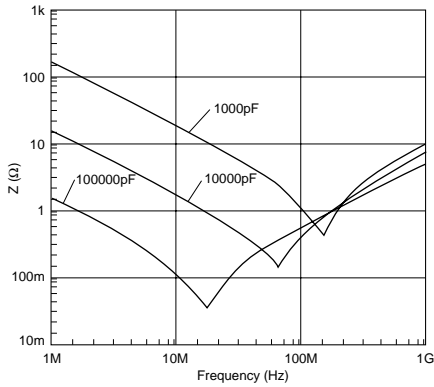
GRJ Series (X7R Char. 630V)



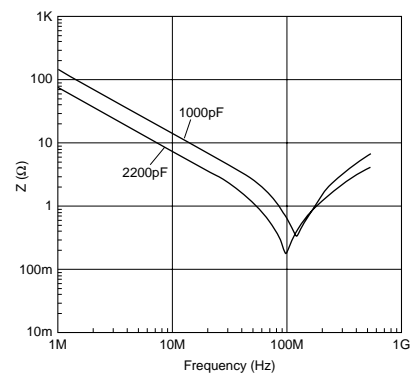
GR4 Series



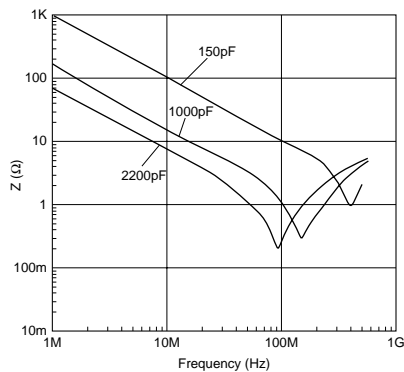
GA2 Series



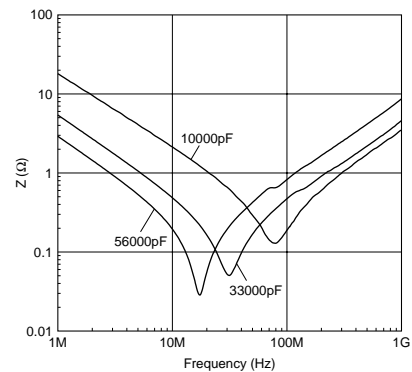
GA3 Series (Type GF)



GA3 Series (Type GD)



GA3 Series (Type GB)



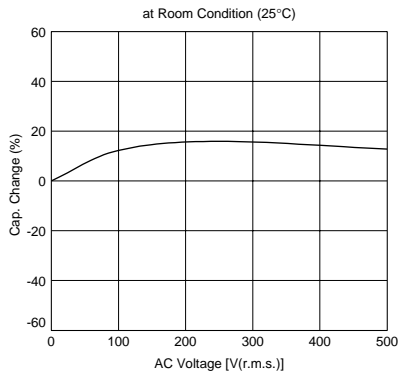
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GRM/GRJ/GR4/GR7/GA2/GA3 Series Reference Data (Typical Example)

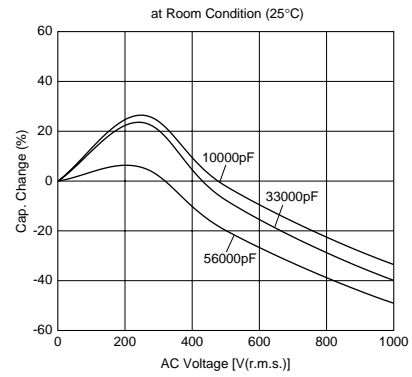
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Capacitance - AC Voltage Characteristics

GA3 Series (Type GF/GD, X7R Char.)

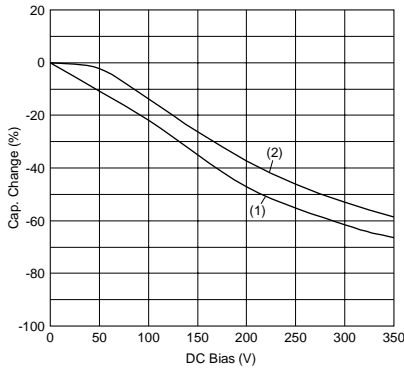


GA3 Series (Type GB)



Capacitance - DC Bias Characteristics

GR7 Series



- (1) GR721AW0BB103KW01D
 GR721AW0BB153KW01D
 GR721BW0BB223KW03L
 GR731AW0BB223KW01D
 GR721BW0BB273KW03L
 GR731AW0BB273KW01D
 GR731AW0BB333KW01D

- (2) GR731AW0BB103KW01D
 GR731AW0BB153KW01D
 GR731BW0BB223KW01L
 GR731BW0BB333KW01L
 GR731CW0BB473KW03L

Package

Taping is the standard packaging method.

■ Minimum Quantity Guide

Part Number		Dimensions (mm)			Quantity (pcs.)	
					ø180mm Reel	
		L	W	T	Paper Tape	Embossed Tape
Medium Voltage	GRM18	1.6	0.8	0.8	4,000	-
	GRJ21/GRM21/GR721	2.0	1.25	1.0	4,000	-
				1.25	-	3,000
	GRJ31/GRM31/GR731	3.2	1.6	1.0	4,000	-
				1.25	-	3,000
				1.6	-	2,000
	GRJ32/GRM32	3.2	2.5	1.0	4,000	-
				1.25	-	3,000
				1.5	-	2,000
				2.0	-	1,000
	GRM42/GR442	4.5	2.0	1.0	-	3,000
				1.5	-	2,000
GRJ43/GRM43/GR443	4.5	3.2	1.5	-	1,000	
			2.0	-	1,000	
			2.5	-	500	
GRJ55/GRM55/GR455	5.7	5.0	2.0	-	1,000	
AC250V	GA242	4.5	2.0	1.5	-	2,000
	GA243	4.5	3.2	1.5	-	1,000
				2.0	-	1,000
GA255	5.7	5.0	2.0	-	1,000	
Safety Std. Certification	GA342	4.5	2.0	1.0	-	3,000
				1.5	-	2,000
				2.0	-	2,000
	GA343	4.5	3.2	1.5	-	1,000
				2.0	-	1,000
	GA352	5.7	2.8	1.5	-	1,000
	GA355	5.7	5.0	1.5	-	1,000
				2.0	-	1,000
				2.5	-	500
2.7				-	500	
			2.9	-	500	

For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

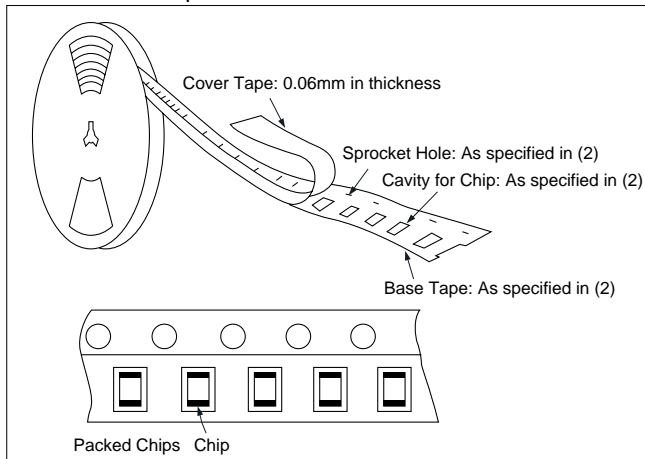
Safety Standard
Certified GA3 Series

Product Information
Package

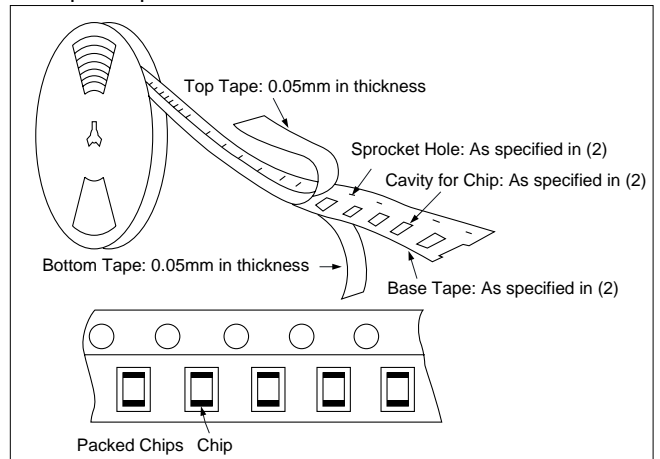
■ Tape Carrier Packaging

(1) Appearance of Taping

① Embossed Tape



② Paper Tape



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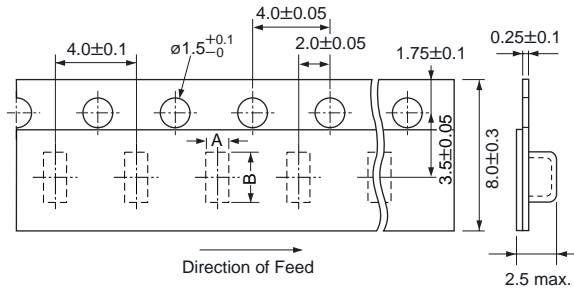
Package

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(2) Dimensions of Tape

① Embossed Tape

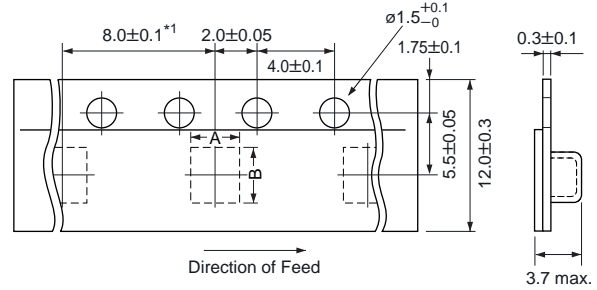
8mm width, 4mm pitch Tape



Part Number	A*	B*
GRJ21/GRM21/GR721 (T≥1.25mm)	1.45	2.25
GRJ31/GRM31/GR731 (T≥1.25mm)	2.0	3.6
GRJ32/GRM32 (T≥1.25mm)	2.9	3.6

*Nominal Value

12mm width, 8mm/4mm pitch Tape



Part Number	A*	B*
GRM42/GR442/GA242/GA342	2.5	5.1
GRJ43/GRM43/GR443/GA243/GA343	3.6	4.9
GA352	3.2	6.1
GRJ55/GRM55/GR455/GA255/GA355	5.4	6.1

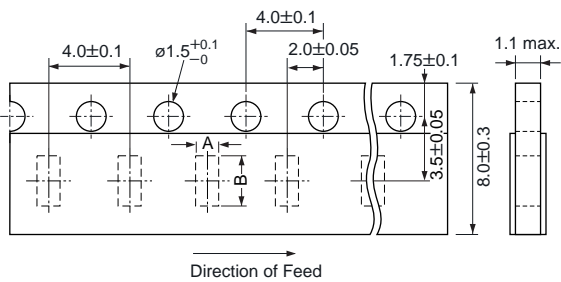
*1 4.0±0.1mm in case of GRM42/GR442/GA242/GA342

*Nominal Value

(in mm)

② Paper Tape

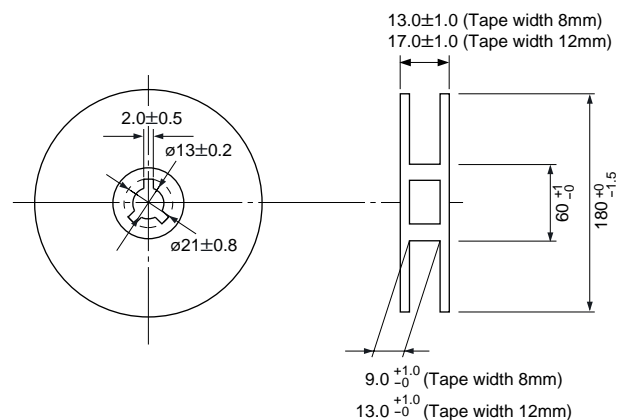
8mm width, 4mm pitch Tape



Part Number	A*	B*
GRM18	1.05	1.85
GRJ21/GRM21/GR721 (T=1.0mm)	1.45	2.25
GRM31/GR731 (T=1.0mm)	2.0	3.6
GRM32 (T=1.0mm)	2.9	3.6

*Nominal Value
(in mm)

(3) Dimensions of Reel



(in mm)

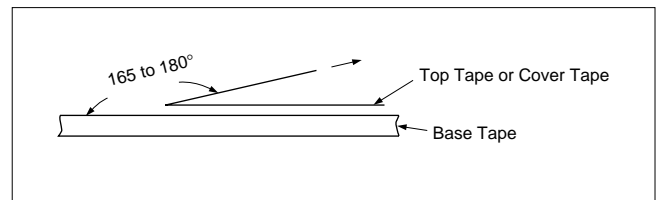
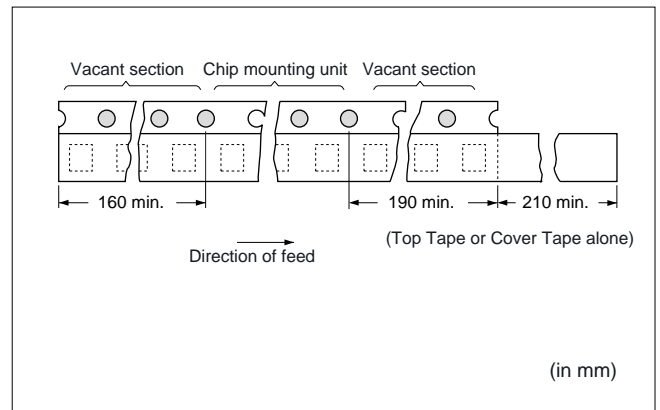
Continued on the following page.

Package

☐ Continued from the preceding page.

(4) Taping Method

- ① Tapes for capacitors are wound clockwise. The sprocket holes are to the right as the tape is pulled toward the user.
- ② Part of the leader and part of the empty tape should be attached to the end of the tape as shown at right.
- ③ The top tape or cover tape and base tape are not attached at the end of the tape for a minimum of 5 pitches.
- ④ Missing capacitors number within 0.1% of the number per reel or 1 pc, whichever is greater, and are not continuous.
- ⑤ The top tape or cover tape and bottom tape should not protrude beyond the edges of the tape and should not cover sprocket holes.
- ⑥ Cumulative tolerance of sprocket holes, 10 pitches: $\pm 0.3\text{mm}$.
- ⑦ Peeling off force: 0.1 to 0.6N in the direction shown at right.



For General Purpose
 GRM/GRJ Series

Only for Applications

AC250V Type
 GA2 Series

Safety Standard
 Certified GA3 Series

Product Information
 Package

⚠ Caution

■ Storage and Operating Conditions

Operating and storage environment

Do not use or store capacitors in a corrosive atmosphere, especially where chloride gas, sulfide gas, acid, alkali, salt or the like are present. In addition, avoid exposure to moisture. Before cleaning, bonding or molding this product, verify that these processes do not affect product quality by testing the performance of a cleaned, bonded or molded product in the intended equipment. Store the capacitors where the temperature and relative humidity do not exceed 5 to 40 degrees centigrade and 20 to 70%.

Use capacitors within 6 months of delivery.

Check the solderability after 6 months or more.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.

■ Handling

1. Vibration and impact

Do not expose a capacitor to excessive shock or vibration during use.

2. Do not directly touch the chip capacitor, especially the ceramic body. Residue from hands/fingers may create a short circuit environment.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.



■ **Caution (Rating)**

1. **Operating Voltage**

When DC-rated capacitors are to be used in AC or ripple current circuits, be sure to maintain the V_{p-p} value of the applied voltage or the V_{0-p} which contains DC bias within the rated voltage range.

When the voltage is applied to the circuit, starting or stopping may generate irregular voltage for a transit period because of resonance or switching. Be sure to use a capacitor with a rated voltage range that includes these irregular voltages.

When DC-rated capacitors are to be used in input circuits from a commercial power source (AC filter), be sure to use Safety Certified Capacitors because various regulations for withstanding voltage or impulses, established for all equipment, should be taken into consideration.

Voltage	DC Voltage	DC+AC Voltage	AC Voltage	Pulse Voltage (1)	Pulse Voltage (2)
Positional Measurement					

2. **Operating Temperature, Self-generated Heat, and Load Reduction at High-frequency Voltage Condition**

Keep the surface temperature of a capacitor below the upper limit of its rated operating temperature range.

Be sure to take into account the heat generated by the capacitor itself. When the capacitor is used in a high-frequency voltage, pulse voltage, it may self-generate heat due to dielectric loss.

(1) In the case of X7R char.

Applied voltage should be the load such as self-generated heat is within 20°C on the condition of atmosphere temperature 25°C. When measuring, use a thermocouple of small thermal capacity -K of $\phi 0.1\text{mm}$ in conditions where the capacitor is not affected by radiant heat from other components or surrounding ambient fluctuations. Excessive heat may lead to deterioration of the capacitor's characteristics and reliability. (Never attempt to perform measurement with the cooling fan running. Otherwise, accurate measurement cannot be ensured.)

Continued on the following page.

For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information
△Caution

Caution

Continued from the preceding page.

(2) In case of C0G, U2J char.

Due to the low self-heating characteristics of low-dissipation capacitors, the allowable electric power of these capacitors is generally much higher than that of X7R characteristic capacitors.

When a high frequency voltage that causes 20°C self-heating to the capacitor is applied, it will exceed the capacitor's allowable electric power.

The frequency of the applied sine wave voltage should be less than 500kHz (less than 100kHz in the case of rated voltage: DC3.15kV). The applied voltage should be less than the value shown in figure below.

In the case of non-sine wave that includes a harmonic frequency, please contact our sales representatives or product engineers. Excessive heat may lead to deterioration of the capacitor's characteristics and reliability. (Never attempt to perform measurement with the cooling fan running. Otherwise, accurate measurement cannot be ensured.)

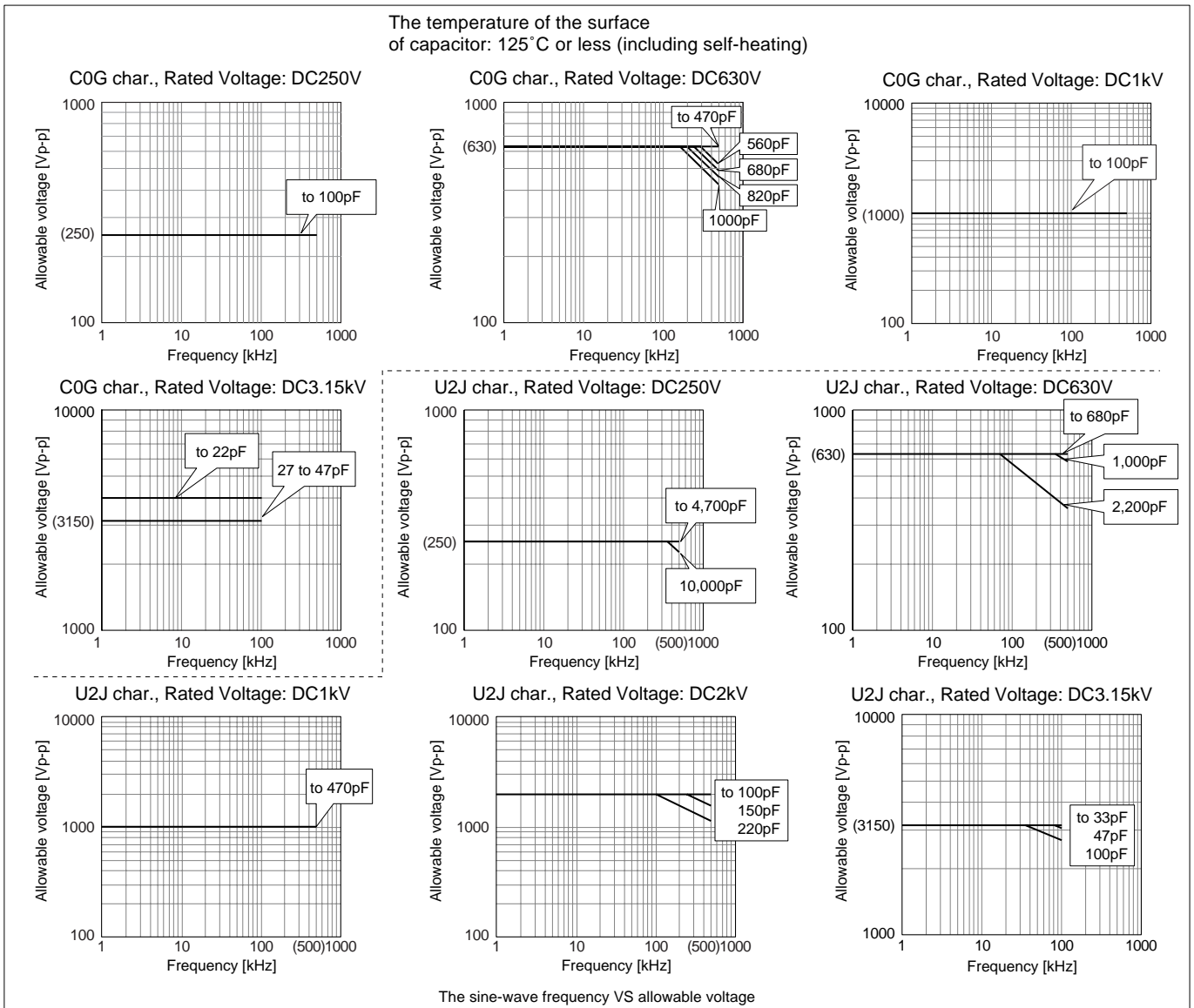
<C0G char., Rated Voltage: DC3.15kV>

The capacitors less than 22pF can be applied maximum 4.0kV peak to peak at 100kHz or less only for the ballast or the resonance usage in the LCD backlight inverter circuit.

<Capacitor Selection Tool>

We are also offering free software/the capacitor selection tool: "Murata Medium Voltage Capacitors Selection Tool by Voltage Form," which will assist you in selecting a suitable capacitor.

The software can be downloaded from Murata's Website. (<http://www.murata.com/designlib/mmcsv/index.html>). By inputting capacitance values and the applied voltage waveform of the specific capacitor series, this software will calculate the capacitor's power consumption and list suitable capacitors (non-sine wave is also available).



Continued on the following page. ↗

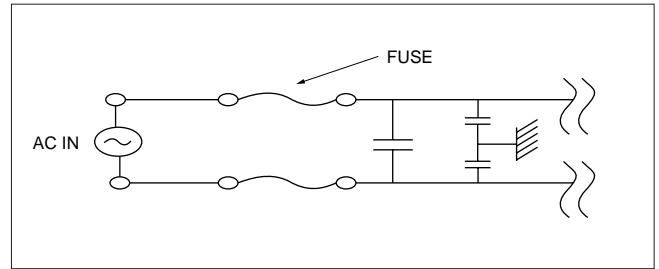
⚠Caution

☐ Continued from the preceding page.

3. Fail-safe

Failure of a capacitor may result in a short circuit. Be sure to provide an appropriate fail-safe function such as a fuse on your product to help eliminate possible electric shock, fire, or fumes.

Please consider using fuses on each AC line if the capacitors are used between the AC input lines and earth (line bypass capacitors), to prepare for the worst case, such as a short circuit.



4. Test Condition for AC Withstanding Voltage

(1) Test Equipment

Tests for AC withstanding voltage should be made with equipment capable of creating a wave similar to a 50/60 Hz sine wave.

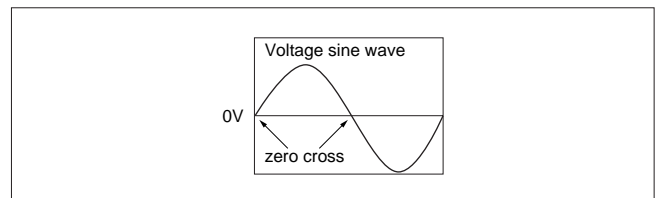
If the distorted sine wave or overload exceeding the specified voltage value is applied, a defect may be caused.

(2) Voltage Applied Method

The capacitor's leads or terminals should be firmly connected to the output of the withstanding voltage test equipment, and then the voltage should be raised from near zero to the test voltage. If the test voltage is applied directly to the capacitor without raising it from near zero, it should be applied with the zero cross.* At the end of the test time, the test voltage should be reduced to near zero, and then the capacitor's leads or terminals should be taken off the output of the withstanding voltage test equipment. If the test voltage is applied directly to the capacitor without raising it from near zero, surge voltage may occur and cause a defect.

*ZERO CROSS is the point where voltage sine wave passes 0V.

- See the figure at right -



FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND CAUSE FUMING OR PARTIAL DISPERSION WHEN THE PRODUCT IS USED.

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information ⚠Caution

△Caution

■ Caution (Soldering and Mounting)

1. Vibration and Impact

Do not expose a capacitor to excessive shock or vibration during use.

2. Circuit Board Material

It is possible for the chip to crack by the expansion and shrinkage of a metal board. Please contact us if you want to use our ceramic capacitors on a metal board such as Aluminum.

3. Land Layout for Cropping PC Board

Choose a mounting position that minimizes the stress imposed on the chip during flexing or bending of the board.

[Component Direction]

Locate chip horizontal to the direction in which stress acts.

[Chip Mounting Close to Board Separation Point]

Chip arrangement Worst A>C>B~D Best

Continued on the following page.



Continued from the preceding page.

4. Reflow Soldering

- When components are exposed to sudden heat, their mechanical strength can be decreased due to the extreme temperature changes which can cause flexing and result in internal mechanical damage, which will cause the parts to fail. In order to prevent mechanical damage, preheating is required for both the components and the PCB board. Preheating conditions are shown in Table 1. It is required to keep the temperature differential between the soldering and the components surface (ΔT) as small as possible.
- Solderability of Tin plating termination chips might be deteriorated when low temperature soldering profile where peak solder temperature is below the Tin melting point is used. Please confirm the solderability of Tin plating termination chips before use.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference (ΔT) between the component and solvent within the range shown in the Table 1.

Table 1

Part Number	Temperature Differential
G□□18/21/31	$\Delta T \leq 190^\circ\text{C}$
G□□32/42/43/52/55	$\Delta T \leq 130^\circ\text{C}$

Recommended Conditions

	Pb-Sn Solder		Lead Free Solder
	Infrared Reflow	Vapor Reflow	
Peak Temperature	230-250°C	230-240°C	240-260°C
Atmosphere	Air	Air	Air or N ₂

Pb-Sn Solder: Sn-37Pb
 Lead Free Solder: Sn-3.0Ag-0.5Cu

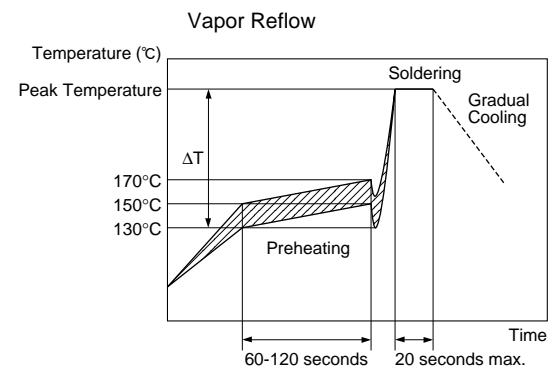
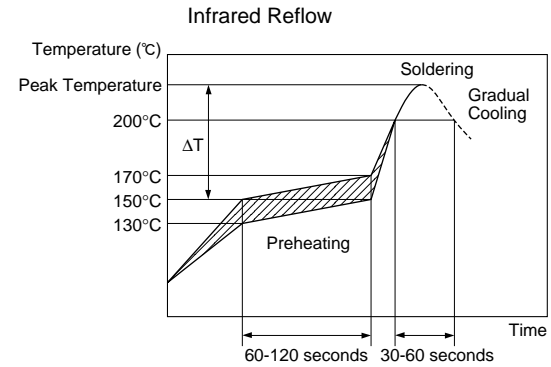
Optimum Solder Amount for Reflow Soldering

- Overly thick application of solder paste results in excessive solder fillet height. This makes the chip more susceptible to mechanical and thermal stress on the board and may cause cracked chips.
- Too little solder paste results in a lack of adhesive strength on the outer electrode, which may result in chips breaking loose from the PCB.
- Make sure the solder has been applied smoothly to the end surface to a height of 0.2mm min.

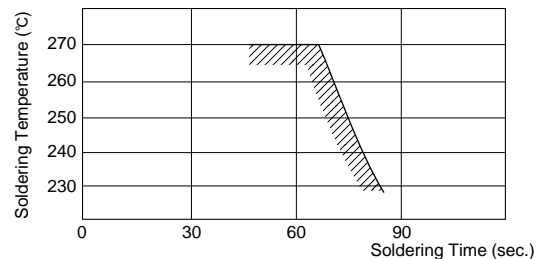
Inverting the PCB

Make sure not to impose an abnormal mechanical shock on the PCB.

[Standard Conditions for Reflow Soldering]

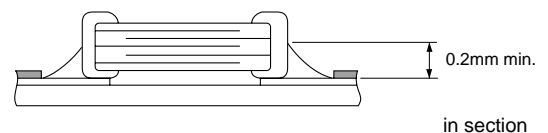


[Allowable Soldering Temperature and Time]



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.

[Optimum Solder Amount for Reflow Soldering]



For General Purpose
GRM/GRJ Series

Only for Applications

AC250V Type
GA2 Series

Safety Standard
Certified GA3 Series

Product Information
Caution

Caution

Continued from the preceding page.

5. Flow Soldering

- When components are exposed to sudden heat, their mechanical strength can be decreased due to the extreme temperature changes which can cause flexing and result in internal mechanical damage, which will cause the parts to fail. Additionally, an excessively long soldering time or high soldering temperature results in leaching by the outer electrodes, causing poor adhesion or a reduction in capacitance value due to loss of contact between electrodes and end termination.
- In order to prevent mechanical damage, preheating is required for both the components and the PCB board. Preheating conditions are shown in Table 2. It is required to keep temperature differential between the soldering and the components surface (ΔT) as small as possible.
- When components are immersed in solvent after mounting, be sure to maintain the temperature difference between the component and solvent within the range shown in Table 2.
Do not apply flow soldering to chips not listed in Table 2.

Table 2

Part Number	Temperature Differential
G□□18/21/31	$\Delta T \leq 150^\circ\text{C}$

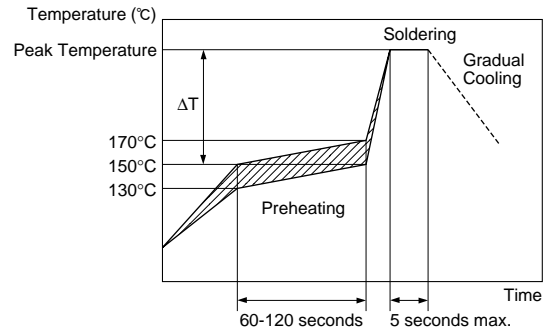
Recommended Conditions

	Pb-Sn Solder	Lead Free Solder
Peak Temperature	240-250°C	250-260°C
Atmosphere	Air	N ₂

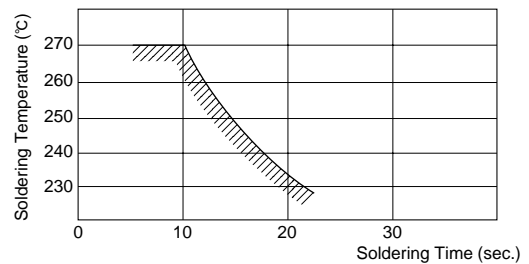
Pb-Sn Solder: Sn-37Pb
 Lead Free Solder: Sn-3.0Ag-0.5Cu

- Optimum Solder Amount for Flow Soldering**
 The top of the solder fillet should be lower than the thickness of components. If the solder amount is excessively large, the risk of cracking is higher during board bending or under any other stressful conditions.

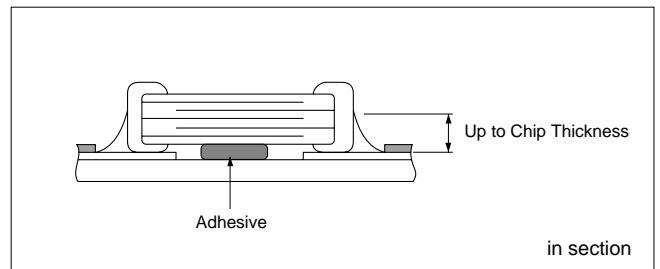
[Standard Conditions for Flow Soldering]



[Allowable Soldering Temperature and Time]



In the case of repeated soldering, the accumulated soldering time must be within the range shown above.



Continued on the following page. ↗

Caution

Continued from the preceding page.

6. Correction with a Soldering Iron

- When sudden heat is applied to the components by use of a soldering iron, the mechanical strength of the components will decrease because the extreme temperature change causes deformations inside the components.

In order to prevent mechanical damage to the components, preheating is required for both the components and the PCB board.

Preheating conditions, (The "Temperature of the Soldering Iron Tip", "Preheating Temperature," "Temperature Differential" between iron tip and the

components and the PCB), should be within the conditions of table 3.

It is required to keep the temperature differential between the soldering Iron and the component's surface (ΔT) as small as possible.

After soldering, do not allow the component/PCB to cool down rapidly.

The operating time for the re-working should be as short as possible. When re-working time is too long, it may cause solder leaching, in turn causing a reduction of the adhesive strength of the terminations.

Table 3

Part Number	Temperature of Soldering Iron tip	Preheating Temperature	Temperature Differential (ΔT)	Atmosphere
G□□18/21/31	350°C max.	150°C min.	$\Delta T \leq 190^\circ\text{C}$	air
G□□32/42/43/52/55	280°C max.	150°C min.	$\Delta T \leq 130^\circ\text{C}$	air

*Applicable for both Pb-Sn and Lead Free Solder.

Pb-Sn Solder: Sn-37Pb

Lead Free Solder: Sn-3.0Ag-0.5Cu

- Optimum Solder Amount when re-working Using a Soldering Iron

For sizes smaller than G□□18, the top of the solder fillet should be lower than 2/3 of the thickness of the component or 0.5mm whichever is smaller.

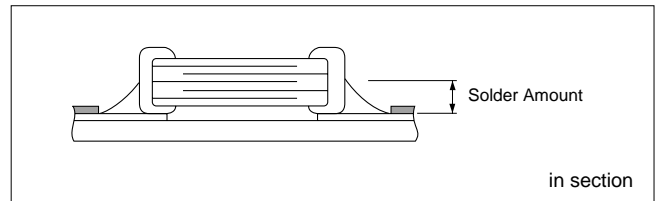
For sizes larger than G□□21, the top of the solder fillet should be lower than 2/3 of the thickness of the component.

If the solder amount is excessive, the risk of cracking is higher during board bending or under any other stressful conditions.

A Soldering iron $\varnothing 3\text{mm}$ or smaller should be used.

It is also necessary to keep the soldering iron from touching the components during the re-work.

Solder wire with $\varnothing 0.5\text{mm}$ or smaller is required for soldering.



7. Washing

Excessive output of ultrasonic oscillation during cleaning causes PCBs to resonate, resulting in cracked chips or broken solder. Take note not to vibrate PCBs.

FAILURE TO FOLLOW THE ABOVE CAUTIONS MAY RESULT, WORST CASE, IN A SHORT CIRCUIT AND FUMING WHEN THE PRODUCT IS USED.

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information △Caution

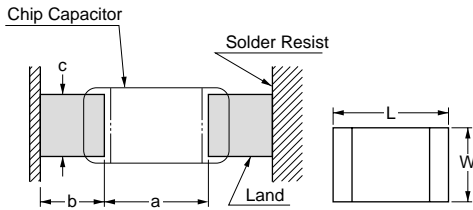
Notice

■ Notice (Soldering and Mounting)

1. Construction of Board Pattern

After installing chips, if solder is excessively applied to the circuit board, mechanical stress will cause destruction resistance characteristics to lower. To prevent this, be extremely careful in determining shape and dimension before designing the circuit board diagram.

Construction and Dimensions of Pattern (Example)



Flow Soldering

L×W	a	b	c
1.6×0.8	0.6-1.0	0.8-0.9	0.6-0.8
2.0×1.25	1.0-1.2	0.9-1.0	0.8-1.1
3.2×1.6	2.2-2.6	1.0-1.1	1.0-1.4

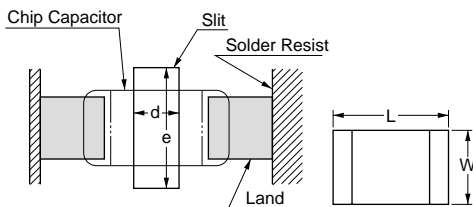
Flow soldering : 3.2×1.6 or less available.

Reflow Soldering

L×W	a	b	c
1.6×0.8	0.6-0.8	0.6-0.7	0.6-0.8
2.0×1.25	1.0-1.2	0.6-0.7	0.8-1.1
3.2×1.6	2.2-2.4	0.8-0.9	1.0-1.4
3.2×2.5	2.0-2.4	1.0-1.2	1.8-2.3
4.5×2.0	2.8-3.4	1.2-1.4	1.4-1.8
4.5×3.2	2.8-3.4	1.2-1.4	2.3-3.0
5.7×2.8	4.0-4.6	1.4-1.6	2.1-2.6
5.7×5.0	4.0-4.6	1.4-1.6	3.5-4.8

(in mm)

Dimensions of Slit (Example)



L×W	d	e
1.6×0.8	-	-
2.0×1.25	-	-
3.2×1.6	1.0-2.0	3.2-3.7
3.2×2.5	1.0-2.0	4.1-4.6
4.5×2.0	1.0-2.8	3.6-4.1
4.5×3.2	1.0-2.8	4.8-5.3
5.7×2.8	1.0-4.0	4.4-4.9
5.7×5.0	1.0-4.0	6.6-7.1

(in mm)

Preparing the slit helps flux cleaning and resin coating on the back of the capacitor.

However, the length of the slit design should be as short as possible to prevent mechanical damage in the capacitor.

A longer slit design might receive more severe mechanical stress from the PCB.

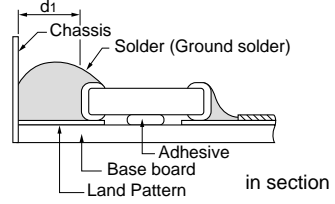
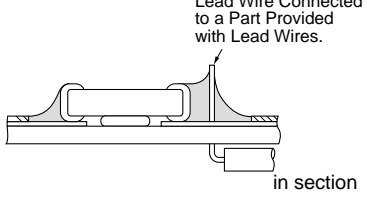
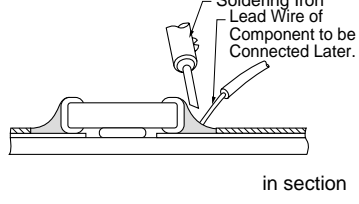
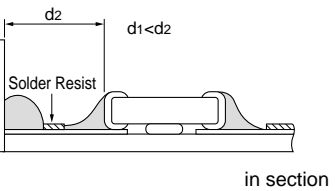
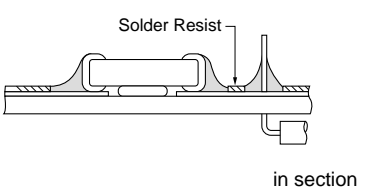
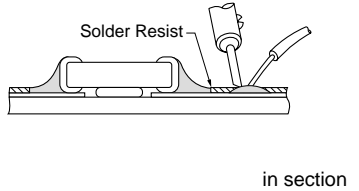
Recommended slit design is shown in the Table.

Continued on the following page.

Notice

Continued from the preceding page.

Land Layout to Prevent Excessive Solder

	Mounting Close to a Chassis	Mounting with Leaded Components	Mounting Leaded Components Later
Examples to Be Avoided			
Examples of Improvements by the Land Division			

2. Mounting of Chips

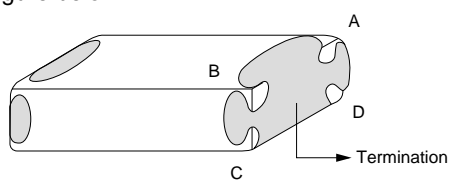
- Thickness of adhesives applied
 Keep thickness of adhesives applied (50-105µm or more) to reinforce the adhesive contact considering the thickness of the termination or capacitor (20-70µm) and the land pattern (30-35µm).
- Mechanical shock of the chip placer
 When the positioning claws and pick-up nozzle are worn, the load is applied to the chip while positioning is concentrated in one position, thus causing cracks, breakage, faulty positioning accuracy, etc.
 Careful checking and maintenance are necessary to prevent unexpected trouble.
 An excessively low bottom dead point of the suction nozzle imposes great force on the chip during mounting, causing cracked chips. Please set the suction nozzle's bottom dead point on the upper surface of the board.

3. Soldering

(1) Limit of losing effective area of the terminations and conditions needed for soldering.

Depending on the conditions of the soldering temperature and/or immersion (melting time), effective areas may be lost in some parts of the terminations.

To prevent this, be careful in soldering so that any possible loss of the effective area on the terminations will securely remain at a maximum of 25% on all edge length A-B-C-D-A of part with A, B, C, D, shown in the Figure below.



(2) Flux Application

- An excessive amount of flux generates a large quantity of flux gas, causing deteriorated solderability. So apply flux thinly and evenly throughout. (A foaming system is generally used for flow soldering.)
- Flux containing too high a percentage of halide may cause corrosion of the outer electrodes without sufficient cleaning. Use flux with a halide content of 0.2% max.
- Do not use strong acidic flux.
- Do not use water-soluble flux.*
 (*Water-soluble flux can be defined as non rosin type flux including wash-type flux and non-wash-type flux.)

(3) Solder

The use of Sn-Zn based solder will deteriorate the reliability of the MLCC.
 Please contact our sales representative or product engineers on the use of Sn-Zn based solder in advance.

Continued on the following page. ↗

For General Purpose GRM/GRJ Series

Only for Applications

AC250V Type GA2 Series

Safety Standard Certified GA3 Series

Product Information Notice

Notice

☐ Continued from the preceding page.

4. Cleaning

Please confirm there is no problem in the reliability of the product beforehand when cleaning it with the intended equipment.

The residue after cleaning it might cause a decrease in the surface resistance of the chip and the corrosion of the electrode part, etc. As a result it might cause reliability to deteriorate. Please confirm beforehand that there is no problem with the intended equipment in ultrasonic cleansing.

5. Resin Coating

Please use it after confirming there is no influence on the product with the intended equipment before the resin coating and molding.

A cracked chip might be caused at the cooling/heating cycle by the amount of resin spreading and/or bias thickness.

The resin for coating and molding must be selected as the stress is small when stiffening and the hygroscopic is low as possible.

■ Rating

1. Capacitance change of capacitor

(1) In the case of X7R char.

Capacitors have an aging characteristic, whereby the capacitor continually decreases its capacitance slightly if the capacitor is left on for a long time. Moreover, capacitance might change greatly depending on the surrounding temperature or an applied voltage. Therefore, it is not likely to be suitable for use in a time constant circuit.

Please contact us if you need detailed information.

(2) In the case of any char. except X7R

Capacitance might change a little depending on the surrounding temperature or an applied voltage.

Please contact us if you intend to use this product in a strict time constant circuit.

2. Performance check by equipment

Before using a capacitor, check that there is no problem in the equipment's performance and the specifications.

Generally speaking, CLASS 2 (X7R char.) ceramic capacitors have voltage dependence characteristics and temperature dependence characteristics in capacitance. Therefore, the capacitance value may change depending on the operating condition in the equipment.

Accordingly, be sure to confirm the apparatus performance of receiving influence in a capacitance value change of a capacitor, such as leakage current and noise suppression characteristics.

Moreover, check the surge-proof ability of a capacitor in the equipment, if needed, because the surge voltage may exceed the specific value by the inductance of the circuit.

ISO 9001 Certifications

■ Qualified Standards

The products listed here have been produced by ISO 9001 certified factory.

Plant
Fukui Murata Mfg. Co., Ltd.
Izumo Murata Mfg. Co., Ltd.
Okayama Murata Mfg. Co., Ltd.
Murata Electronics Singapore (Pte.) Ltd.
Beijing Murata Electronics Co., Ltd.
Wuxi Murata Electronics Co., Ltd.

Design assistant tool SimSurfing SimSurfing



MLCC is now available !

Design assistant tool "SimSurfing" has been updated and you can now find and view any kind of characteristics of MLCCs.

Available function for MLCCs.

- ① Products search
- ② View frequency characteristics (S parameters, Z, R, X, Q, DF, L, C)
- ③ DC voltage bias characteristics (Absolute capacitance/change rate)
- ④ Temperature characteristics (Absolute capacitance/change rate)
- ⑤ AC voltage bias characteristics (Absolute capacitance/change rate)
- ⑥ Download SPICE netlist/ S parameter

① Select the Products

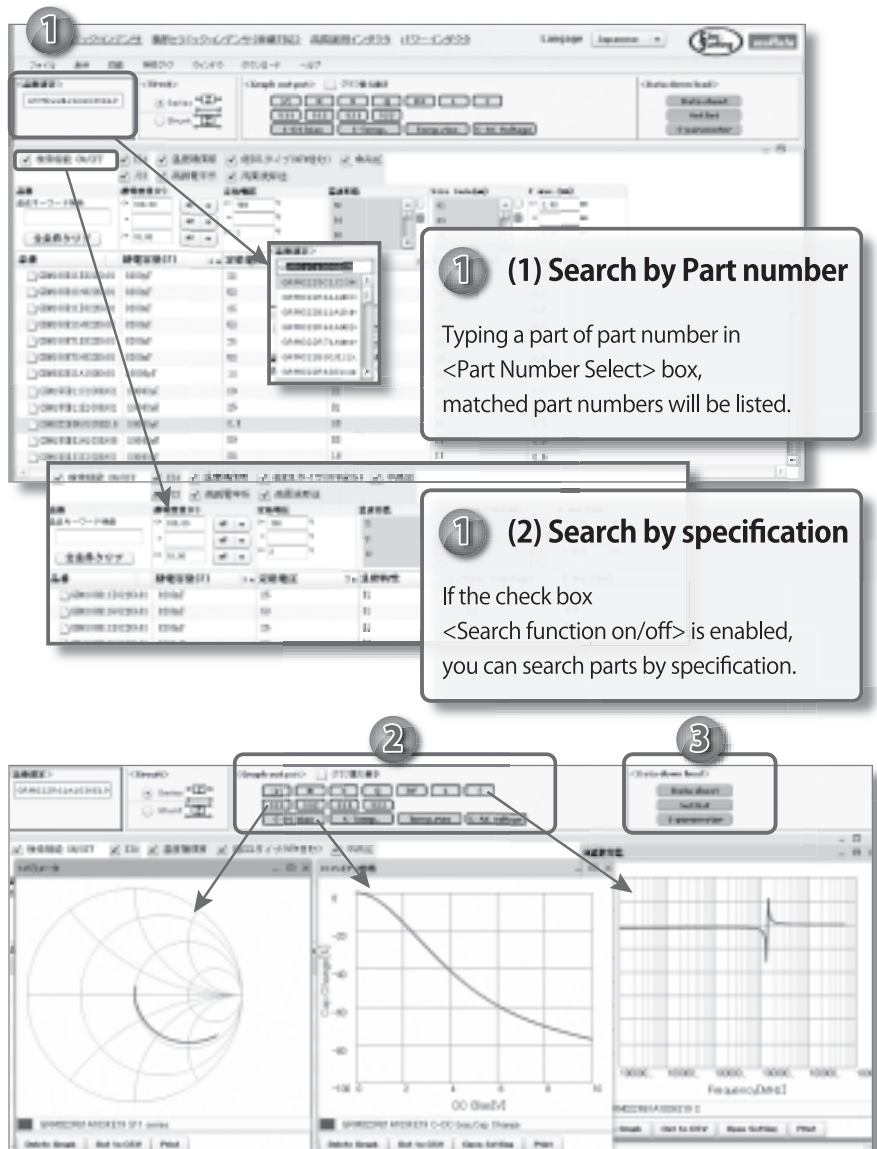
- (1) By part number
- (2) By performance

② View characteristics

Clicking buttons in this area with partnumber selected, you can view any electrical characteristics chart.

③ Data download

You can download SPICE netlist and S parameter files (S2P)



These images are captured at August/2010. Be sure that this software will be updated frequently.

<http://ds.murata.com/software/simsurfing/en-us/mlcc/>

EMICON-FUN!

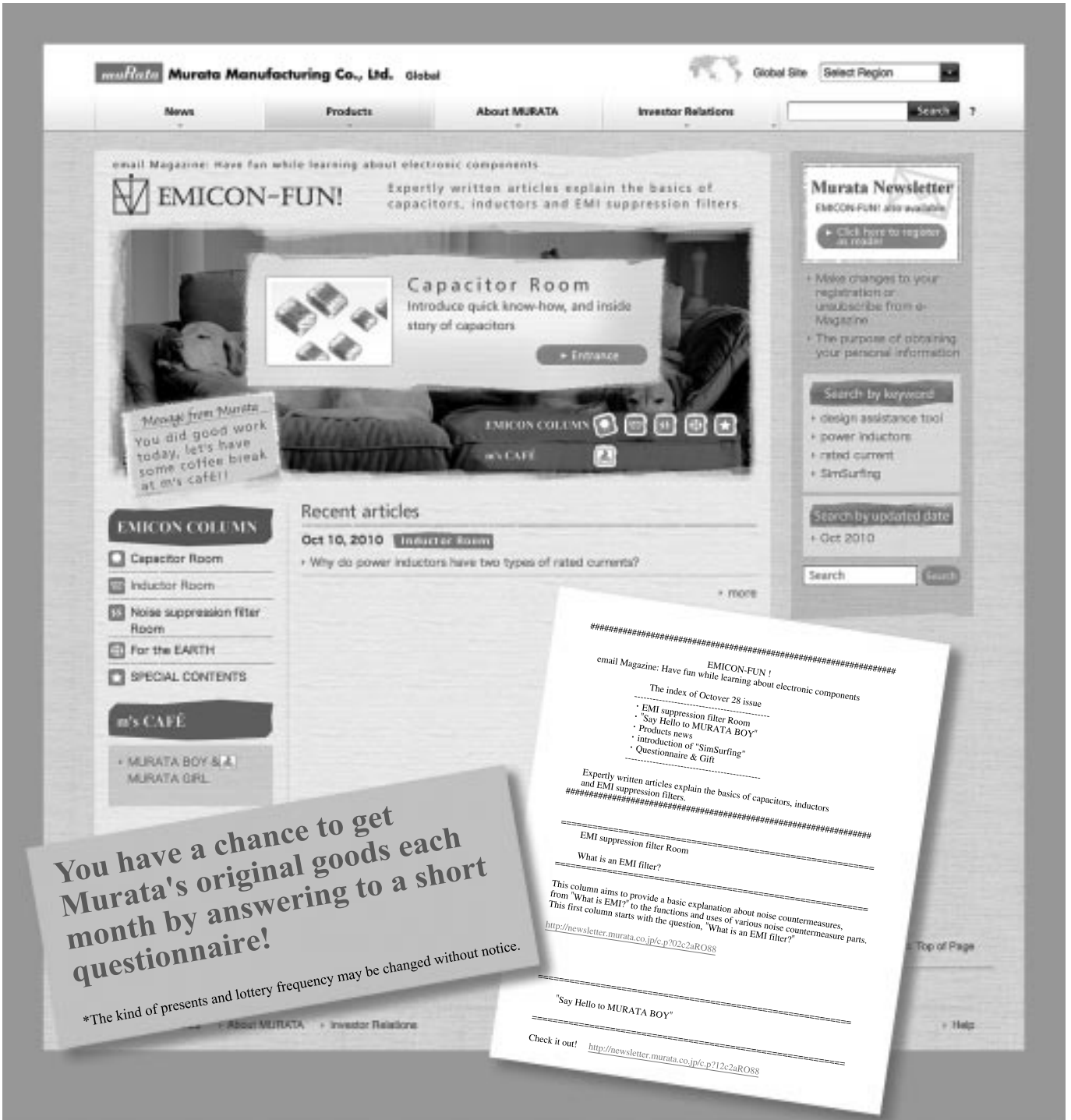
Please check Murata's newsletter!
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The index of October 28 issue

- EMI suppression filter Room
- Say Hello to MURATA BOY
- Products news
- introduction of "SimSurfing"
- Questionnaire & Gift

Expertly written articles explain the basics of capacitors, inductors and EMI suppression filters.

EMI suppression filter Room

What is an EMI filter?

This column aims to provide a basic explanation about noise countermeasures, from "What is EMI?" to the functions and uses of various noise countermeasure parts. This first column starts with the question, "What is an EMI filter?"

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Head Office
1-10-1, Higashi Kotari, Nagaokakyo-shi, Kyoto 617-8555, Japan
Phone: 81-75-951-9111

International Division
3-29-12, Shibuya, Shibuya-ku, Tokyo 150-0002, Japan
Phone: 81-3-5469-6123 Fax: 81-3-5469-6155 E-mail: intl@murata.co.jp